

JAEGER ELEKTRONIK

SEMICON 1997

Original	Fabric.	Constr.	Info	(Compl. Fig.)	JAEGER Fig.	International
BUK 427-600A.B	Phi	MOS-N-FET-e	VFET, 600/30V, 45W, 80/275ns(2.8A) A: 4.3/17A, <1Ω(6.5A), B: 3.9/16A, <1.2Ω(6.5A)	16c	SOT-199	BUK 727-600, 2SK1463, 2SK1684, 2SK1859
BUK 428-500A.B	Phi	MOS-N-FET-e	VFET, 500/30V, 45W, 120/410ns(2.9A) A: 6.8/27A, <0.4Ω(8A), B: 6.1/24A, <0.5Ω(8A)	16c	SOT-199	2SK1206, 2SK1523, 2SK1696, 2SK1832
BUK 428-800A.B	Phi	MOS-N-FET-e	VFET, 800/30V, 45W, 160/450ns(2.6A) A: 3.4/14A, <1.5Ω(4A), B: 3/12A, <2Ω(4A)	16c	SOT-199	2SK809A, 2SK1463, 2SK1684, 2SK1859
BUK 428-1000A.B	Phi	MOS-N-FET-e	VFET, 1000/30V, 45W, 160/450ns(2.5A) A: 2.9/12A, <2Ω(3.5A), B: 2.6/10A, <2.6Ω(3.5A)	16c	SOT-199	BUK 426-1000, 2SK1770
BUK 436-50A.B	Phi	MOS-N-FET-e	=BUK 426-50A.B, A=50/200A, B=46/184A, 125W	18p	TO-3P	BUZ 346, 2SK1297, 2SK1379, 2SK1514
BUK 436-60A.B	Phi	MOS-N-FET-e	=BUK 426-60A.B, A=50/200A, B=46/184A, 125W	18p	TO-3P	2SK1297, 2SK1379, 2SK1514, 2SK2096
BUK 436-100A.B	Phi	MOS-N-FET-e	=BUK 426-100A.B, A=33/132A, B=31/124A, 125W	18p	TO-3P	BUZ 345, 2SK850, 2SK906, 2SK1429, ++

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KSV 3100 ACN-....	Sam	A/D-D/A-IC	8-Bit A/D- + 10-Bit D/A-Converter	40-DIP		
KSV 3110(CN-....)	Sam	A/D-D/A-IC	8 Bit A/D- + 10 Bit D/A-Conv., Video, TTL In/Out	40-DIP		
KSV 3208(CN)	Sam	A/D-IC	8 Bit, hi-speed, TV, Video, 20Mpsps, TTL In/Out	28-DIP		
KSV 3310	Sam	D/A-IC	10 Bit, TV, Video, 20MHz	28-DIP		
KSV 3404	Sam					
KSY 13	Sie					

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BUK 441-100	KT					
BUK 442-50A	KT					
BUK 442-60A	KT 208(A...V)	GUS				
BUK 442-100	KT 209(A...V)	GUS				
BUK 443-50A	KT 814 A.B.G.V	GUS				
BUK 443-60A	KT 815 A.B.G.V	GUS				
BUK 443-100	KT 816 A.B.G.V	GUS				
BUK 444-200	KT 817 A.B.G.V	GUS				
BUK 444-400	KT 818 A.B.G.V	GUS				
BUK 444-500	KT 819 A.B.G.V	GUS				
BUK 444-600	KT 3030	Sam				
BUK 444-800	KT 3031	Sam				
BUK 445-50A	KT 3032	Sam				
BUK 445-60A	KT 3033	Sam				
BUK 445-100	KT 3040 J	Sam				
BUK 445-200	KT 3054 J	Sam				
BUK 445-400	KT 3064 J	Sam				
BUK 445-500	KT 3107(A...V)	GUS				
BUK 445-600	KT 3170 J.N	Sam				
BUK 445-800	KT 5116 J	Sam				
BUK 446-100	KT 8518	Sam				
BUK 446-200	KT 8520	Sam				
BUK 446-400	KT 8521	Sam				
BUK 446-600	KT 8554(J)	Sam				
BUK 446-800	KT 8555(J)	Sam				
BUK 447-100	KT 8557(J)	Sam				
BUK 447-200	KT 8592(N)	Sam				
BUK 447-400	KT 8593(N)	Sam				
BUK 447-600	KTA 200	Kec				
BUK 447-800	KTA 473	Kec				
BUK 448-100	KTA 940	Kec				
BUK 448-200	KTA 950	Kec				
BUK 448-400	KTA 968(A)	Kec				
BUK 448-600	KTA 1001	Kec				
BUK 448-800	KTA 1015	Kec				
BUK 449-100	KTA 1021	Kec				
BUK 449-200	KTA 1023	Kec				
BUK 449-400	KTA 1024	Kec				
BUK 449-600	KTA 1070	Kec				
BUK 449-800	KTA 1270	Kec				
BUK 450-100	KTA 1271	Kec				
BUK 450-200	KTA 1272	Kec				
BUK 450-400	KTA 1273	Kec				
BUK 450-600	KTA 1274	Kec				
BUK 450-800	KTA 1275	Kec				

80.000 types

Original	Fabric.	Constr.	Info	(Compl. Fig.	JAEGER	Fig.	International
ZTX 331	Fer	Si-N	-BCW 22	40e	=TO-92		
ZTX 337	Fer	Si-N	-BC 337	40e	=TO-92	BC 337	7a
ZTX 338	Fer	Si-N	-BC 338	40e	=TO-92	BC 337	7a
ZTX 341	Fer	Si-N	-BSV 28	40e	=TO-92		
ZTX 342	Fer	Si-N	-BSV 29	40e	=TO-92		
ZTX 350	Fer	MOS-P-FET-e	Uni	40a	=TO-92		
ZTX 360	Fer	Si-N	-BSX 59	40e	=TO-92		
ZTX 382	Fer	Si-N	-BC 382	40e	=TO-92	BC 550	7a
ZTX 383	Fer	Si-N	-BC 383	40e	=TO-92	BC 550	7a
ZTX 384	Fer	Si-N	-BC 384	40e	=TO-92	BC 550	7a
ZTX 449	Fer	Si-N	Uni, lo-sat, 50V, 1A, 1W, >150MHz	40e	=TO-92	2SD1207	7c
ZTX 450	Fer	Si-N	Uni, 60V, 1A, 1W, >150MHz	40e	=TO-92	BC 639	7c
ZTX 451	Fer	Si-N	=ZTX 450: 80V	40e	=TO-92	BC 639	7c
ZTX 452	Fer	Si-N	Uni, 100V, 1A, 1W, >150MHz	40e	=TO-92	BC 639	7c
ZTX 453	Fer	Si-N	=ZTX 452: 120V	40e	=TO-92		
ZTX 454	Fer	Si-N	Uni, 140V, 1A, 1W, >100MHz	40e	=TO-92		
ZTX 455	Fer	Si-N	=ZTX 454: 160V	40e	=TO-92		
ZTX 500	Fer	Si-P	-BCW 11	40e	=TO-92		
ZTX 501	Fer	Si-P	-BCW 13	40e	=TO-92		
ZTX 502	Fer	Si-P	-BCW 15	40e	=TO-92		
ZTX 503	Fer	Si-P	-BCW 17	40e	=TO-92		
ZTX 504	Fer	Si-P	-BCW 19	40e	=TO-92		
ZTX 510	Fer	Si-P	-BSV 33	40e	=TO-92		
ZTX 530	Fer	Si-P	-BCW 21	40e	=TO-92		
ZTX 531	Fer	Si-P	-BCW 23	40e	=TO-92		
ZTX 537	Fer	Si-P	-BC 327	40e	=TO-92	BC 327	7a
ZTX 538	Fer	Si-P	-BC 328	40e	=TO-92	BC 327	7a
ZTX 541	Fer	Si-P	Nixie, 100V, 0,1A, 0,5W	40e	=TO-92	BF 421 A	7c
ZTX 542	Fer	Si-P	=ZTX 541: 120V	40e	=TO-92	BF 421 A	7c
ZTX 549	Fer	Si-P	Uni, lo-sat, 35V, 1A, 1W, >100MHz	40e	=TO-92	2SB892	7c(9mm)
ZTX 550	Fer	Si-P	Uni, 60V, 1A, 1W, >150MHz	40e	=TO-92	BC 640	7c
ZTX 551	Fer	Si-P	=ZTX 550: 80V	40e	=TO-92	BC 640	7c
ZTX 552	Fer	Si-P	Uni, 100V, 1A, 1W, >150MHz	40e	=TO-92	BC 640	7c
ZTX 553	Fer	Si-P	=ZTX 552: 120V	40e	=TO-92		
ZTX 600(A,B)	Fer	Si-N-Darl	Uni, 160V, 1A, 1W, >150, hFE>2000	40e	=TO-92		
ZTX 601(A,B)	Fer	Si-N-Darl	=ZTX 601: 180V	40e	=TO-92		
ZTX 649	Fer	Si-N	Uni, lo-sat, 35V, 2A, 1W, >150MHz	40e	=TO-92	2SD1207	7c
ZTX 650	Fer	Si-N	Uni, lo-sat, 60V, 2A, 1W, >140MHz	40e	=TO-92	2SD1207	7c
ZTX 651	Fer	Si-N	=ZTX 650: 80V	40e	=TO-92		
ZTX 652	Fer	Si-N	=ZTX 650: 100V	40e	=TO-92		
ZTX 653	Fer	Si-N	=ZTX 650: 120V	40e	=TO-92		
ZTX 656	Fer	Si-N	Uni, 200V, 0,5A, 1W, >30MHz	40e	=TO-92	BF 420 A	7c
ZTX 657	Fer	Si-N	=ZTX 656: 300V	40e	=TO-92	BF 420 A	7c
ZTX 749	Fer	Si-P	Uni, lo-sat, 35V, 2A, 1W, >100MHz	40e	=TO-92	2SB892	7c(9mm)
ZTX 750	Fer	Si-P	Uni, lo-sat, 60V, 2A, 1W, >100MHz	40e	=TO-92	2SB892	7c(9mm)
ZTX 751	Fer	Si-P	=ZTX 750: 80V	40e	=TO-92		
ZTX 752	Fer	Si-P	=ZTX 750: 100V	40e	=TO-92		
ZTX 753	Fer	Si-P	=ZTX 750: 120V	40e	=TO-92		
ZTX 756	Fer	Si-P	Uni, 200V, 0,5A, 1A, >30MHz	40e	=TO-92	BF 421 A	7c
ZTX 757	Fer	Si-P	=ZTX 756: 300V	40e	=TO-92	BF 421 A	7c
ZTX 3702...3711	Fer	Si-P/N	*2N3702...3711	40e	=TO-92	*2N3702...11	
ZTX 3903...3906	Fer	Si-N/P	*2N3903...3906	40e	=TO-92	*2N3903...06	
ZTX 4400...4403	Fer	Si-N/P	*2N4400...4403	40e	=TO-92	*2N4400...03	
ZTX 4427	Fer	Si-N	*2N4427	2a	TO-39		
ZU...ZZ							
ZU 3,9...180	litt	Z-Di	=ZY 3,9...180: 10%	31a	DO-15	Z-Diode ...V	31a
ZW 2,7...33	litt	Z-Di	=ZF 2,7...33: 0,6W	31a	DO-15	Z-Diode ...V	31a
ZX		Si-P	=2SB1628-ZX (SMD-Marking)	39	SOT-89		*2SB1628
ZX 3,9...200	litt	Z-Di	3,9...200V, 5%, 12,5W(Tc=25°)	32a			BZX98/..., BZY93/..., 1M2970...3015
ZY		Si-P	=2SA1182-Y (SMD-Marking)	35	SOT-23		*2SA1182
ZY		Si-P	=2SA1588-Y (SMD-Marking)	35(2mm)	SOT-323		*2SA1588
ZY		Si-P	=2SB1628-ZY (SMD-Marking)	39	SOT-89		*2SB1628
ZY		Si-N	=2SC4047 (SMD-Marking)	35	SOT-23		*2SC4047
ZY 1	litt, Die	Si-St	1A, 2W, 0,71...0,82V(100mA), <1Ω	31a	DO-15		
ZY 3,9...200	litt, Die	Z-Di	=ZD 3,9...200: 2W	31a	DO-15		BZD23/..., BZV47/..., BZX70/...
ZZ		Si-P	=2SB1628-ZZ (SMD-Marking)	39	SOT-89		*2SB1628
O...1							
0		C-Di	=HVU 300(A) (SMD-Marking)	71(1,7mm)			*HVU 300(A)
01...0999...			*1...999... (Sortierung nach Zahlenwert - ohne führende Nullen!)				(Index on increasing number - leading zeros are ignored!)
001...00999...							
0001...000999...							
0,7 St 60		Se-Di				(1N4148)	31a
1		C-Di	=HVR 187 (SMD-Marking)	71(2,7mm)	SOD-123		*HVR 187
1-200		Si-Di		31a		BYD 33 M	31a
1/4 M 2,4...200(A)Z	Mot	Z-Di	2,4...200V, 0,25W, ±20%	31a	DO-7	Z-Diode ...V	31a
1/4 M...Z5		Z-Di	±5%	31a	DO-7	Z-Diode ...V	31a
1/4 M...Z10		Z-Di	±10%	31a	DO-7	Z-Diode ...V	31a
1 A/...		Si-Di	1A, 50V			1N4007	31a
1 A(p,s)		Si-N	=BC 846A (SMD-Marking)	35	SOT-23		*BC 846
1 A		Si-N	=BC 846AW (SMD-Marking)	35(2mm)	SOT-323		*BC 846R
1 A		Si-N	=FMMT 3904 (SMD-Marking)	35	SOT-23		*FMMT 3904
1 A		Si-Di	=MA 110 (SMD-Marking)	71(1,7mm)	SOD-323		*MA 110
1 A		Si-N	=MMBT 3904 (SMD-Marking)	35	SOT-23		*MMBT 3904
1 A		Si-N	=SXT 3904 (SMD-Marking)	39	SOT-89		*SXT 3904
1 A-50		Ge-P				2x AC 188 K	3a
1 AG		Si-N	=2SC3339-GR (SMD-Marking)	35	SOT-23		*2SC3339
1 AG		Si-N/P	=HN 1B01F-GR (SMD-Marking)	46	SOT-163		*HN 1B01F
1 AG		Si-N/P	=HN 1B01FU-GR (SMD-Marking)	46(2mm)	SOT-363		*HN 1B01FU
1 AL		Si-N	=2SC3339-BL (SMD-Marking)	35	SOT-23		*2SC3339
1 AO		Si-N	=2SC3339-O (SMD-Marking)	35	SOT-23		*2SC3339
1 AQ		Si-P	=2SB1584-Q (SMD-Marking)	-35	(T Mini)		*2SB1584

Original	Fabric.	Constr.	Info	{Compl. Fig.	JAEGER	Fig.	International
1 AQ		Si-P	=2SB779-Q (SMD-Marking)	35	SOT-23		=2SB779
1 AR		Si-P	=2SB1584-R (SMD-Marking)	=35	(T Mini)		=2SB1584
1 AR		Si-P	=2SB779-R (SMD-Marking)	35	SOT-23		=2SB779
1 AR		Si-N	=BC 846AR (SMD-Marking)	35	SOT-23		=BC 846R
1 AS		Si-P	=2SB1584-S (SMD-Marking)	=35	(T Mini)		=2SB1584
1 AS		Si-P	=2SB779-S (SMD-Marking)	35	SOT-23		=2SB779
1 AS 027	Tix	Si-Di	=1AS029: 800V	32	DO-1	BYD 33 M	BYD 14K...M, BYW 55...56, 2N5062, ++
1 AS 029	Tix	Si-Di	contr.av., 1000V, 1,5A, Uf<1,25V(5A)	32	DO-1	BYD 33 M	BUD 14M, BYD 34M, BYV 96E, BYW 56, ++
1 AY		Si-N	=2SC3339-Y (SMD-Marking)	35	SOT-23		=2SC3339
1 AY		Si-N/P	=HN 1B01F-Y (SMD-Marking)	46	SOT-163		=HN 1B01F
1 AY		Si-N/P	=HN 1B01FU-Y (SMD-Marking)	46(2mm)	SOT-363		=HN 1B01FU
1 B(p,s)		Si-N	=BC 846B (SMD-Marking)	35	SOT-23		=BC 846
1 B		Si-N	=BC 846BW (SMD-Marking)	35(2mm)	SOT-323		=BC 846R
1 B		Si-N	=FMMT 2222 (SMD-Marking)	35	SOT-23		=FMMT 2222
1 B		Si-Di	=MA 111 (SMD-Marking)	71(1,7mm)	SOD-323		=MA 111
1 B		Si-N	=MMBT 2222 (SMD-Marking)	35	SOT-23		=MMBT 2222
1 BG		Si-N	=2SC3340-GR (SMD-Marking)	35	SOT-23		=2SC3340
1 BL		Si-N	=2SC3340-BL (SMD-Marking)	35	SOT-23		=2SC3340
1 BR		Si-N	=BC 846BR (SMD-Marking)	35	SOT-23		=BC 846R
1 C		Si-N	=FMMT-A20 (SMD-Marking)	35	SOT-23		=FMMT-A20
1 C		Si-Di	=MA 112 (SMD-Marking)	71(1,7mm)	SOD-323		=MA 112
1 C		Si-N	=MMBTA 20 (SMD-Marking)	35	SOT-23		=MMBTA 20
1 CL		Si-N	=2SC4082-L (SMD-Marking)	35(2mm)	SOT-323		=2SC4082
1 CM		Si-N	=2SC4082-M (SMD-Marking)	35(2mm)	SOT-323		=2SC4082
1 CN		Si-N	=2SC4082-N (SMD-Marking)	35(2mm)	SOT-323		=2SC4082
1 CO		Si-N	=2SC3341-O (SMD-Marking)	35	SOT-23		=2SC3341
1 CP		Si-N	=2SC4082-P (SMD-Marking)	35(2mm)	SOT-323		=2SC4082
1 CQ		Si-N	=2SC4082-Q (SMD-Marking)	35(2mm)	SOT-323		=2SC4082
1 CY		Si-N	=2SC3341-Y (SMD-Marking)	35	SOT-23		=2SC3341
1 D(p)		Si-N	=BC 846 (SMD-Marking)	35	SOT-23		=BC 846
1 D		Si-N	=BC 846W (SMD-Marking)	35(2mm)	SOT-323		=BC 846W
1 D		Si-Di	=MA 113 (SMD-Marking)	71(1,7mm)	SOD-323		=MA 113
1 D		Si-N	=MMBTA 42 (SMD-Marking)	35	SOT-23		=MMBTA 42
1 D		Si-N	=SXTA 42 (SMD-Marking)	39	SOT-89		=SXTA 42
1 DL		Si-N	=2SC408S-L (SMD-Marking)	35(2mm)	SOT-323		=2SC4083
1 DM		Si-N	=2SC4083-M (SMD-Marking)	35(2mm)	SOT-323		=2SC4083
1 DN		Si-N	=2SC4083-N (SMD-Marking)	35(2mm)	SOT-323		=2SC4083
1 DP		Si-N	=2SC4083-P (SMD-Marking)	35(2mm)	SOT-323		=2SC4083
1 DQ		Si-N	=2SC4083-Q (SMD-Marking)	35(2mm)	SOT-323		=2SC4083
1 DR		Si-N	=2SD1328-R (SMD-Marking)	35	SOT-23		=2SD1328
1 DR		Si-N	=2SD2436-R (SMD-Marking)	=35	(T Mini)		=2SD2436
1 DS		Si-N	=2SD1328-S (SMD-Marking)	35	SOT-23		=2SD1328
1 DS		Si-N	=2SD2436-S (SMD-Marking)	=35	(T Mini)		=2SD2436
1 DT		Si-N	=2SD1328-T (SMD-Marking)	35	SOT-23		=2SD1328
1 DT		Si-N	=2SD2436-T (SMD-Marking)	=35	(T Mini)		=2SD2436
1 E(p,s)		Si-N	=BC 847A (SMD-Marking)	35	SOT-23		=BC 847
1 E		Si-N	=BC 847AW (SMD-Marking)	35(2mm)	SOT-323		=BC 847W
1 E		Si-N	=FMMT-A43 (SMD-Marking)	35	SOT-23		=FMMT-A43
1 E		Si-Di	=MA 114 (SMD-Marking)	71(1,7mm)	SOD-323		=MA 114
1 E		Si-N	=MMBTA 43 (SMD-Marking)	35	SOT-23		=MMBTA 43
1 E		Si-N	=SXTA 43 (SMD-Marking)	39	SOT-89		=SXTA 43
1 EL		Si-N	=2SC4084-L (SMD-Marking)	35(2mm)	SOT-323		=2SC4084
1 EM		Si-N	=2SC4084-M (SMD-Marking)	35(2mm)	SOT-323		=2SC4084
1 EN		Si-N	=2SC4084-N (SMD-Marking)	35(2mm)	SOT-323		=2SC4084
1 EP		Si-N	=2SC4084-P (SMD-Marking)	35(2mm)	SOT-323		=2SC4084
1 EQ		Si-N	=2SC4084-Q (SMD-Marking)	35(2mm)	SOT-323		=2SC4084
1 ER		Si-N	=BC 847AR (SMD-Marking)	35	SOT-23		=BC 847R
1 EZ 100...200D5,10	Sie	Z-Di	100...200V, 1W, D5=5%, D10=10%	31a	DO-41	Z-Diode ...V	BZW 22/..., BZX 61/..., BZX 85/..., ZPY...,+
1 F		Si-N	=2SC4543 (SMD-Marking)	39	SOT-89		=2SC4543
1 F(p,s)		Si-N	=BC 847B (SMD-Marking)	35	SOT-23		=BC 847
1 F		Si-N	=BC 847BW (SMD-Marking)	35(2mm)	SOT-323		=BC 847W
1 F		Si-Di	=MA 115 (SMD-Marking)	71(1,7mm)	SOD-323		=MA 115
1 F		Si-N	=MMBT 5550 (SMD-Marking)	35	SOT-23		=MMBT 5550
1 F 106	Fui	Si-Di	Schottky, S, 10/15V, 20mA, Uf<1V(10mA)				BAT 19, BAT 45, 1SS106
1 FP		N-FET	=2SK321-P (SMD-Marking)	35	SOT-23		=2SK321
1 FQ		N-FET	=2SK321-Q (SMD-Marking)	35	SOT-23		=2SK321
1 FR		N-FET	=2SK321-R (SMD-Marking)	35	SOT-23		=2SK321
1 FR		Si-N	=BC 847BR (SMD-Marking)	35	SOT-23		=BC 847R
1 FS		N-FET	=2SK321-S (SMD-Marking)	35	SOT-23		=2SK321
1 G		Si-N	=BC 847C (SMD-Marking)	35	SOT-23		=BC 847
1 G		Si-N	=BC 847CW (SMD-Marking)	35(2mm)	SOT-323		=BC 847W
1 G		Si-N	=FMMT-A06 (SMD-Marking)	35	SOT-23		=FMMT-A06
1 G		Si-N	=MMBTA 06 (SMD-Marking)	35	SOT-23		MMBTA 06
1 GR		Si-N	=BC 847CR (SMD-Marking)	35	SOT-23		=BC 847R
1 GT		Si-N	=SOA 06 (SMD-Marking)	35	SOT-23		=SOA 06
1 H(p)		Si-N	=BC 847 (SMD-Marking)	35	SOT-23		=BC 847
1 H		Si-N	=BC 847W (SMD-Marking)	35(2mm)	SOT-323		=BC 847W
1 H		Si-N	=FMMT-A05 (SMD-Marking)	35	SOT-23		=FMMT-A05
1 H		Si-Di	=MA 116 (SMD-Marking)	71(1,7mm)	SOD-323		=MA 116
1 H		Si-N	=MMBTA 05 (SMD-Marking)	35	SOT-23		=MMBTA 05
1 HR		Si-N	=2SD2185-R (SMD-Marking)	39	SOT-89		=2SD2185
1 HS		Si-N	=2SD2185-S (SMD-Marking)	39	SOT-89		=2SD2185
1 HT		Si-N	=SOA 05 (SMD-Marking)	35	SOT-23		=SOA 05
1 I		Si-P	=2SB1440 (SMD-Marking)	39	SOT-89		=2SB1440
1 IR		Si-P	=2SB1440-R (SMD-Marking)	39	SOT-89		=2SB1440
1 IS		Si-P	=2SB1440-S (SMD-Marking)	39	SOT-89		=2SB1440
1 J(p,s)		Si-N	=BC 848A (SMD-Marking)	35	SOT-23		=BC 848
1 J		Si-N	=BC 848AW (SMD-Marking)	35(2mm)	SOT-323		=BC 848W
1 J		Si-N	=FMMT 2369 (SMD-Marking)	35	SOT-23		=FMMT 2369
1 J		Si-N	=MMBT 2369 (SMD-Marking)	35	SOT-23		=MMBT 2369
1 Jp		Si-N	=BCV 61A (SMD-Marking)	44	SOT-143		=BCV 61
1 JR		Si-N	=BC 848AR (SMD-Marking)	35	SOT-23		=BC 848R
1 Js		Si-N	=BCV 61A (SMD-Marking)	44	SOT-143		=BCV 61

Original	Fabric.	Constr.	Info	(Compl. Fig.	JAEGER	Fig.	International
1 JZ 61		Si-Br			B250C1500	8, 33	
1 K		Si-N	=BC 848B (SMD-Marking)	35	SOT-23		-BC 848
1 K		Si-N	=BC 848BW (SMD-Marking)	35(2mm)	SOT-323		-BC 848W
1 K		Si-N	=MMBT 6428 (SMD-Marking)	35	SOT-23		-MMBT 6428
1 K 34(A)		Ge-Di	=1N34	31a		AA 133	31a
1 K 60		Ge-Di	=1N60	31a		AA 138	31a
1 K 90		Ge-Di	=1N90	31a		AA 138	31a
1 K 261		Ge-Di		31a		AA 138	31a
1 KP		N-FET	=2SK316-P (SMD-Marking)	35	SOT-23		-2SK316
1 Kp		Si-N	=BCV 61B (SMD-Marking)	44	SOT-143		-BCV 61
1 KO		N-FET	=2SK316-Q (SMD-Marking)	35	SOT-23		-2SK316
1 KR		Si-N	=2SD2210-R (SMD-Marking)	39	SOT-89		-2SD2210
1 KR		Si-N	=BC 848BR (SMD-Marking)	35	SOT-23		-BC 848R
1 KS		Si-N	=2SD2210-S (SMD-Marking)	39	SOT-89		-2SD2210
1 Ks		Si-N	=BCV 61B (SMD-Marking)	44	SOT-143		-BCV 61
1 KT		Si-N	=2SD2210-T (SMD-Marking)	39	SOT-89		-2SD2210
1 L		Si-P	=2SB1537 (SMD-Marking)	39	SOT-89		-2SB1537
1 L(p,s)		Si-N	=BC 848C (SMD-Marking)	35	SOT-23		-BC 848
1 L		Si-N	=BC 848CW (SMD-Marking)	35(2mm)	SOT-323		-BC 848W
1 L		Si-N	=MMBT 6429 (SMD-Marking)	35	SOT-23		-MMBT 6429
1 LM		Si-N	=2SC4103-M (SMD-Marking)	35(2mm)	SOT-323		-2SC4103
1 LN		Si-N	=2SC4103-N (SMD-Marking)	35(2mm)	SOT-323		-2SC4103
1 LP		Si-N	=2SC4103-P (SMD-Marking)	35(2mm)	SOT-323		-2SC4103
1 Lp		Si-N	=BCV 61C (SMD-Marking)	44	SOT-143		-BCV 61
1 LQ		Si-N	=2SC4103-Q (SMD-Marking)	35(2mm)	SOT-323		-2SC4103
1 LR		Si-N	=BC 848CR (SMD-Marking)	35	SOT-23		-BC 848R
1 Ls		Si-N	=BCV 61C (SMD-Marking)	44	SOT-143		-BCV 61
1 M		Si-N	=2SD2357 (SMD-Marking)	39	SOT-89		-2SD2357
1 M(p)		Si-N	=BC 848 (SMD-Marking)	35	SOT-23		-BC 848
1 M		Si-N	=BC 848W (SMD-Marking)	35(2mm)	SOT-323		-BC 848W
1 M		Si-N	=FMMT-A13 (SMD-Marking)	35	SOT-23		-FMMT-A13
1 M		Si-N	=IMBT 3903 (SMD-Marking)	35	SOT-23		-IMBT 3903
1 M		Si-N	=MMBTA 13 (SMD-Marking)	35	SOT-23		-MMBTA 13
1 M 3.3...200ZS	Mot	Z-Di	3.3...200V, 2.5W, ±20%	31a	DO-41		BZD23/..., BZT03/..., BZX70/...
1 M ...ZS5		Z-Di	±5%	31a	DO-41		BZD23/..., BZT03/..., BZX70/...
1 M ...ZS10		Z-Di	±10%	31a			BZD23/..., BZT03/..., BZX70/...
1 MN		Si-N	=2SC4128-N (SMD-Marking)	35(2mm)	SOT-323		-2SC4128
1 MP		Si-N	=2SC4128-P (SMD-Marking)	35(2mm)	SOT-323		-2SC4128
1 MP		Si-P	=2SJ84-P (SMD-Marking)	35	SOT-23		-2SJ84
1 Mp		Si-N	=BCV 61 (SMD-Marking)	44	SOT-143		-BCV 61
1 MQ		Si-P	=2SJ84-Q (SMD-Marking)	35	SOT-23		-2SJ84
1 MR		Si-P	=2SJ84-R (SMD-Marking)	35	SOT-23		-2SJ84
1N							
1 N		Si-P	=2SB1539 (SMD-Marking)	39	SOT-89		-2SB1539
1 N		Si-N	=FMMT-A14 (SMD-Marking)	35	SOT-23		-FMMT-A14
1 N		Si-N	=IMBT 3904 (SMD-Marking)	35	SOT-23		-IMBT 3904
1 N		Si-N	=MMBTA 14 (SMD-Marking)	35	SOT-23		-MMBTA 14
1 N 21	Nec,Tho,++	Si-Di	UHF, S-Band Mx	Koax	SOD-47		-
1 N 22	Nec	Si-Di	UHF, X-Band Dem	Koax	SOD-48		-
1 N 23	Nec,Tho,++	Si-Di	UHF, X-Band Mx	Koax	SOD-47		-
1 N 25	USA	Si-Di	UHF, L-Band Mx	Koax	SOD-47		-
1 N 26	USA	Si-Di	UHF, K-Band Mx	Koax	SOD-49		-
1 N 28	Nec	Si-Di	UHF, S-Band Dem	Koax	SOD-47		-
1 N 31(A)	USA	Si-Di	UHF, X-Band Dem	Koax	SOD-49		-
1 N 32(A)	USA	Si-Di	UHF, S-Band Dem	Koax	SOD-47		-
1 N 34(A)	EUR,USA,Nec	Ge-Di	Uni, Dem, 75V, 50mA	31a	DO-7	AA 133	31a
1 N 35	USA,Nec,Tho	Ge-Di	FM Dem, Matched Pair, 75V, 22.5mA	2x 31a	2x DO-7		AA 113, 1N34
1 N 36	Kem,Sem,Tho	Ge-Di	HF Dem, 36V, 16mA	31a	DO-7		AA 113, AA 119, 1N34, 1N60
1 N 38	USA,Nec,Tho	Ge-Di	Uni, 120V, 50mA	31a	DO-7		AA 117...118, AA 132...133
1 N 39	USA,Nec,Tho	Ge-Di	Uni, 200V, 50mA	31a	DO-7		-
1 N 40	Kem,Spe	Ge-Di	4x HF Dem, Matched Pair, 25V, 225mA	4x 31a	4x DO-7		-
1 N 41	Kem,Spe	Ge-Di	4x HF Dem, Matched Quart., 32V				-
1 N 42	Kem,Spe	Ge-Di	4x Uni, 115V, 0.1A(ss)	4x 31a	4x DO-7		AA 117...118, AA 132...133
1 N 43	USA,Tho	Ge-Di	Uni, 70V, 40mA	31a	DO-7		AA 117...118, AA 132...134, 1N34, 1N54
1 N 44	USA	Ge-Di	Uni, 115V, 35mA	31a	DO-7		AA 117...118, AA 132...134, 1N34, 1N54
1 N 44 A1	Tos	Si-Di	kV-Rr, 13kV, 0.67A				-
1 N 45	USA	Ge-Di	HF, Uni, 75V, 35mA	31a	DO-7		AA 113, AA 117...118, 1N34, 1N60
1 N 46	USA	Ge-Di	Uni, 60V, 40mA	31a	DO-7		AA 117...118, AA 132...134, 1N34, 1N54
1 N 47	USA	Ge-Di	Uni, 150V, 30mA	31a	DO-7		AA 133, 1N39
1 N 48	USA,Tho	Ge-Di	Uni, 80V, 50mA	31a	DO-7		AA 117...118, AA 132...133
1 N 49	USA,Tho	Ge-Di	Uni, 75V	31a	DO-7		AA 117...118, AA 132...133, 1N34, 1N54
1 N 50	USA,Tho	Ge-Di	Uni, 75V	31a	DO-7		AA 117...118, AA 132...133, 1N34, 1N54
1 N 51	USA,Tho	Ge-Di	Dem, Uni, 46V, 30mA	31a	DO-7		AA 113, 1N34, 1N54, 1N60
1 N 52(A)	USA,Tho	Ge-Di	Uni, 80V, 50mA	31a	DO-7		AA 117...118, AA 132...133
1 N 52 A1	Tos	Si-Di	=1N44A1: 15kV				-
1 N 53	USA	Si-Di	UHF, Ka-Band Mx	Koax	SOD-49		-
1 N 54(A)	USA,Nec,Tho	Ge-Di	Uni, 75V, 50mA	31a	DO-7	AA 133	31a
1 N 55(A,B)	USA,Tho	Ge-Di	Uni, 150...180V, 30...50mA	31a	DO-7		-
1 N 56(A)	USA,Tho	Ge-Di	Uni, 50V, 60mA	31a	DO-7		AA 117...118, AA 132...134, 1N60
1 N 57(A)	USA,Tho	Ge-Di	Uni, 80V, 40mA	31a	DO-7		AA 117...118, AA 132...133
1 N 58(A)	USA,Nec,Tho	Ge-Di	Uni, 115V, 50mA	31a	DO-7		AA 117...118, AA 132...133
1 N 59	Idc	Ge-Di	Uni, 280V, 50mA	31a	DO-7		-
1 N 60(A)	USA,EUR,JAP	Ge-Di	AM/FM Dem, TV IF Dem, 50V, 50mA	31a	DO-7	AA 138	31a
1 N 61	USA	Ge-Di	Uni, 140V, 40mA	31a	DO-7		AA 133, 1N39
1 N 61 A1	Tos	Si-Di	=1N44A1: 30kV				-
1 N 62	USA	Ge-Di	Uni, 140V, 40mA	31a	DO-7		AA 133, 1N39
1 N 63(A)	USA,Tho	Ge-Di	Uni, 100V, 30...50mA	31a	DO-7		AA 117...118, AA 132...133
1 N 64(A)	USA,Tho	Ge-Di	Uni, 25V, 50mA	31a	DO-7		AA 113, AA 119, 1N34, 1N54, 1N60, ++
1 N 65	USA,Tho	Ge-Di	HF Dem, 70V, 50mA	31a	DO-7		AA 113, 1N34, 1N54, 1N60
1 N 66	USA,Tho	Ge-Di	Uni, 60V, 50mA	31a	DO-7		AA 117...118, AA 132...134, 1N60, ++
1 N 67(A)	USA,Tho	Ge-Di	Dem, Uni, 92V, 35mA	31a	DO-7		AA 113, AA 119, 1N34, 1N54, 1N60, ++
1 N 68(A)	USA,Tho	Ge-Di	Uni, 100V, 35mA	31a	DO-7		AA 117...118, AA 132...133

Original	Fabric.	Constr.	Info	{Compl. Fig.	JAEGER	Fig.	International
1 N 69(A)	USA,Tho	Ge-Di	Uni, 70V, 40mA	31a	DO-7		AA 117...118, AA 132...134, 1N34, 1N54, ++
1 N 70(A)	USA,Tho	Ge-Di	Uni, 120V, 30...50mA	31a	DO-7		AA 117...118, AA 132...133
1 N 71	Alp	Ge-Di	=4x 1N56 Matched Quart.				-
1 N 72	Gen	Ge-Di	UHF Mx	31a	DO-7		-
1 N 73	USA	Ge-Di	4x HF Dem, Matched Quart., 75V, 22mA	4x 31a	4x DO-7		AA 113, 1N34
1 N 74	USA	Ge-Di	4x HF Dem, Matched Quart., 75V, 22mA				-
1 N 75	USA,Tho	Ge-Di	HF, Uni, 100V, 50mA	31a	DO-7		AA 117...118, AA 132...133
1 N 76	USA	Si-Di	UHF, X-Band Dem	Koax	SOD-49		-
1 N 77		Opto					-
1 N 78	USA	Si-Di	UHF, Ku-Band Mx	Koax	SOD-49		-
1 N 79	Alp	Di	Mess-Rr, Meter rectifier	Koax	SOD-48		-
1 N 81(A)	USA,Nec,Tho	Ge-Di	Uni, 50V, 30mA	31a	DO-7		AA 117...118, AA 132...134, 1N60, ++
1 N 82(A)	Tho	Si-Di	UHF Mx	31a	DO-7		-
1 N 83	Idc	Ge-Di	Uni, 375V	31a	DO-7		-
1 N 84	USA	Ge-Di	HF, Uni, 25V	31a	DO-7		AA 113, AA 119, 1N34, 1N54, 1N60
1 N 85		Opto					-
1 N 86	USA	Ge-Di	Uni, 70V, 50mA	31a	DO-7		AA 117...118, AA 132...134
1 N 87(A...T)	USA,EUR,Tos	Ge-Di	AM/FM Dem, 25...30V, 30...50mA	31a	DO-7		AA 112...114, AA 119, 1N34, 1N54, 1N60, ++
1 N 88	USA	Ge-Di	HF, Uni, 100V	31a	DO-7		AA 117...118, AA 132...133
1 N 89	USA	Ge-Di	Uni, 80V, 30mA	31a	DO-7		AA 117...118, AA 132...133
1 N 90	USA,Tho	Ge-Di	Uni, 60V, 30mA	31a	DO-7		AA 117...118, AA 132...134, 1N34, 1N54, ++
1 N 91	Gen,Mot,Slid	Ge-Di	Rr, 100V, 1A	34a	DO-1		-
1 N 92		Ge-Di	=1N91: 200V	34a			-
1 N 93(A)		Ge-Di	=1N91: 300V	34a			-
1 N 94		Ge-Di	Rr, 380V, 0,5A				-
1 N 95	USA	Ge-Di	Uni, 60V, 30mA	31a	DO-7		AA 117...118, AA 132...134, 1N34, 1N54, ++
1 N 96(A)	USA,Nec,Tho	Ge-Di	Uni, 75V, 30...70mA	31a	DO-7		AA 117...118, AA 132...134, 1N34, 1N54, ++
1 N 97(A)	USA	Ge-Di	Uni, 80...92V, 30mA	31a	DO-7		AA 117...118, AA 132...133
1 N 98(A)	USA,Tho	Ge-Di	HF Dem, 80V, 30...70mA	31a	DO-7		1N34, 1N54
1 N 99(A)	USA,Tho	Ge-Di	Uni, 80...92V, 30mA	31a	DO-7		AA 117...118, AA 132...133
1 N 100(A)	USA,Tho	Ge-Di	Uni, 100V, 30...70mA	31a	DO-7		AA 117...118, AA 132...133
1 N 101		Ge-Di	Uni, 150V, 10mA				AA 133, 1N39
1 N 102	USA	Ge-Di	Uni, 125V	31a	DO-7		AA 133, 1N39
1 N 103	USA	Ge-Di	Uni, 20V	31a	DO-7		AA 117...118, AA 132...134, 1N34, 1N54, ++
1 N 104	USA	Ge-Di	Uni, 25V	31a	DO-7		AA 117...118, AA 132...134, 1N34, 1N54, ++
1 N 105	Kem	Di	UHF				-
1 N 106		Ge-Di	Uni, 300V	31a	DO-29		-
1 N 107	USA	Ge-Di	Uni, 10V, 100mA	31a	DO-7		AA 135...136, AA 139
1 N 108	USA	Ge-Di	Uni, 50V	31a	DO-7		AA 135...136, AA 139
1 N 109	Kem	Ge-Di	Os, 15V, 50mA	31a	DO-7		-
1 N 110	Gie	Ge-Di	UHF Mx	Koax	SOD-48		-
1 N 111	USA	Ge-Di	Rr, S, 70V, 50mA	31a	DO-7		AA 117...118, AA 132...134, 1N34, 1N54, ++
1 N 112	USA	Ge-Di	Rr, S, 70V, 50mA	31a	DO-7		AA 117...118, AA 132...134, 1N34, 1N54, ++
1 N 113	USA	Ge-Di	Rr, S, 70V, 50mA	31a	DO-7		AA 117...118, AA 132...134, 1N34, 1N54, ++
1 N 114	USA	Ge-Di	Rr, S, 70V, 50mA	31a	DO-7		AA 117...118, AA 132...134, 1N34, 1N54, ++
1 N 115	USA	Ge-Di	Rr, S, 70V, 50mA	31a	DO-7		AA 117...118, AA 132...134, 1N34, 1N54, ++
1 N 116(A)	USA,Tho	Ge-Di	Uni, 60...70V, 30mA	31a	DO-7		AA 117...118, AA 132...134, 1N34, 1N54, ++
1 N 117(A)	USA,Tho	Ge-Di	Uni, 60...70V, 30mA	31a	DO-7		AA 117...118, AA 132...134, 1N34, 1N54, ++
1 N 118(A)	USA,Tho	Ge-Di	Uni, 60V, 30...70mA	31a	DO-7		AA 117...118, AA 132...134, 1N34, 1N54, ++
1 N 119	USA	Ge-Di	Uni, S, 60V, 25mA	31a	DO-7		AAY 28, 1N191...192, 1N276
1 N 120	USA	Ge-Di	Uni, S, 60V, 25mA	31a	DO-7		AAY 28, 1N191...192, 1N276
1 N 124(A)	Tun	Ge-Di	UHF Mx	Koax	SOD-48		-
1 N 125	Tun	Ge-Di	HF/S, 30V, 30mA				-
1 N 126(A)	USA,Tho	Ge-Di	Uni, 60...75V, 30mA	31a	DO-7		AA 117...118, AA 132...134, 1N34, 1N54, ++
1 N 127(A)	USA,Tho	Ge-Di	Uni, 100...125V, 30mA	31a	DO-7		AA 117...118, AA 132...133
1 N 128(A)	USA,Tho	Ge-Di	Uni, 40V, 30mA	31a	DO-7		AA 117...118, AA 132...134, 1N34, 1N54, ++
1 N 132	Kem	Ge-Di	UHF Mx	31a	DO-7		-
1 N 133	USA	Ge-Di	HF Dem, 5V	31a	DO-7		-
1 N 134	Kem	Si-Di	UHF Dem, 5V				-
1 N 135	USA,Tho	Ge-Di	Uni, 75V	31a	DO-7		AA 117...118, AA 132...133, 1N34, 1N54
1 N 136	Syl	Si-Di	UHF Mx				-
1 N 137(A,B)	USA	Si-Di	Uni, 32...36V, 30...75mA	2c	-TO-1		BA 127, BA 147/50, 1N4148, 1N5194...96, ++
1 N 137		Si-N+R	=RT 1N137L (SMD-Marking)	7(9mm)	TO-92L		-RT 1N137L
1 N 138(A,B)	USA	Si-Di	Uni, 16...18V, 9...50mA	2c	-TO-1		BA 127, BA 147/25, 1N4148, 1N5194...96, ++
1 N 139	USA	Ge-Di	Uni, 46V, 70mA	31a	DO-7		AA 117...118, AA 132...134, 1N34, 1N54, ++
1 N 140	USA	Ge-Di	Uni, 80V, 85mA	31a	DO-7		AA 117...118, AA 132...133, 1N34, 1N54
1 N 141	USA	Ge-Di	Uni, HF Dem, 80V, 70mA	31a	DO-7		AA 113, 1N34, 1N54
1 N 142	USA	Ge-Di	Uni, 115V, 60mA	31a	DO-7		AA 117...118, AA 132...133
1 N 143	USA	Ge-Di	Uni, 115V, 85mA	31a	DO-7		AA 117...118, AA 132...133
1 N 144	USA	Ge-Di	Uni, 35V, 150mA	31a	DO-7		AA 136, 1N270
1 N 145	USA	Ge-Di	Uni, 40V, 0,7A(ss)	31a	DO-7		AA 117...118, AA 132...134, 1N34, 1N54, ++
1 N 147(A)	Phc,Tho	Ge-Di	UHF Mx, 900MHz	31a	DO-29, -7		-
1 N 148	Cbs	Ge-Di	Dem, 15V				-
1 N 149	USA	Si-Di	UHF, X-Band Mx	Koax	SOD-47		-
1 N 150	USA	Si-Di	UHF, C-Band Mx	Koax	SOD-47		-
1 N 151	Gen	Ge-Di	Rr, 100V, 1,2A	(Stack)			-
1 N 152	Gen	Ge-Di	Rr, 200V, 1A	(Stack)			-
1 N 153	Gen	Ge-Di	Rr, 300V, 0,75A	(Stack)			-
1 N 155(A)	Syl	Si-Di	UHF Dem, 9GHz	Koax	SOD-47		-
1 N 156	Syl	Si-Di	UHF, X-Band Mx	Koax	SOD-47		-
1 N 157		Si-Di	=1N21				-
1 N 158	Gen	Ge-Di	Rr, 300V, 0,5A	(Stack)			-
1 N 160	USA	Si-Di	UHF, C-Band Mx	Koax	SOD-47		-
1 N 172	Syl	Di					-
1 N 173(A)	USA	Di	UHF Mx				-
1 N 174	Del	Ge-Di					-
1 N 175	USA	Ge-Di	Uni, 125V,	31a	DO-7		AA 133
1 N 188		Opto					-
1 N 189		Opto					-
1 N 190		Ge-Di	3V				-
1 N 191	USA,Tho	Ge-Di	S, 90V, 30mA, <100ns	31a	DO-7		AAY 28
1 N 192	USA,Tho	Ge-Di	=1N191: 70V	31a	DO-7		AAY 28
1 N 193	Syl	Si-Di	40V, <500ns				-

Original	Fabric.	Constr.	Info	(Compl. Fig.	JAEGER	Fig.	International
1 N 194(A)	USA	Si-Di	S, 40V, 30mA, 200ns	31a	DO-7		BAV 18...21, BAX 15...17, 1N4148, ++
1 N 195	USA	Si-Di	S, 40V, 30mA, 300ns	31a	DO-7		BAV 18...21, BAX 15...17, 1N4148, ++
1 N 196	USA	Si-Di	S, 40V, 30mA, 100ns	31a	DO-7		BAV 18...21, BAX 15...17, 1N4148, ++
1 N 197		Si-Di	=2x 1N21				-
1 N 198(A...N)	USA,Tho	Ge-Di	Uni, S, 100V, 30mA, <300ns	31a	DO-7		AAY 28, 1N191
1 N 200	USA	Z-Di	6,8V, 10%, 0,15W	2c	=TO-1		BZX55/..., BZX79/..., ZPD..., 1N5235...81,++
1 N 201		Z-Di	=1N200: 8,2V	2c	=TO-1		
1 N 202		Z-Di	=1N200: 10V	2c	=TO-1		
1 N 203		Z-Di	=1N200: 12V	2c	=TO-1		
1 N 204		Z-Di	=1N200: 15V	2c	=TO-1		
1 N 205		Z-Di	=1N200: 18V	2c	=TO-1		
1 N 206		Z-Di	=1N200: 22V	2c	=TO-1		
1 N 207		Z-Di	=1N200: 27V	2c	=TO-1		
1 N 208		Z-Di	=1N200: 33V	2c	=TO-1		
1 N 209		Z-Di	=1N200: 39V	2c	=TO-1		
1 N 210		Z-Di	=1N200: 47V	2c	=TO-1		
1 N 211		Z-Di	=1N200: 56V	2c	=TO-1		
1 N 212		Z-Di	=1N200: 68V	2c	=TO-1		
1 N 213		Z-Di	=1N200: 82V	2c	=TO-1		
1 N 214		Z-Di	=1N200: 100V	2c	=TO-1		
1 N 215		Z-Di	=1N200: 120V	2c	=TO-1		
1 N 216		Z-Di	=1N200: 150V	2c	=TO-1		
1 N 217		Z-Di	=1N200: 180V	2c	=TO-1		
1 N 218		Z-Di	=1N200: 220V	2c	=TO-1		
1 N 219		Z-Di	=1N200: 270V	2c	=TO-1		
1 N 220		Z-Di	=1N200: 330V	2c	=TO-1		
1 N 221		Z-Di	=1N200: 390V	2c	=TO-1		
1 N 222		Z-Di	=1N200: 470V	2c	=TO-1		
1 N 225	USA	Z-Di	8,75V, 10%, 0,15W	2c	=TO-1		BZX55/..., BZX79/..., ZPD..., 1N5238...74,++
1 N 226		Z-Di	=1N225: 10,5V	2c	=TO-1		
1 N 227		Z-Di	=1N225: 12,8V	2c	=TO-1		
1 N 228		Z-Di	=1N225: 15,7V	2c	=TO-1		
1 N 229		Z-Di	=1N225: 19V	2c	=TO-1		
1 N 230		Z-Di	=1N225: 23,5V	2c	=TO-1		
1 N 231		Z-Di	=1N225: 28,5V	2c	=TO-1		
1 N 232		Z-Di	=1N225: 34,5V	2c	=TO-1		
1 N 233		Z-Di	=1N225: 41V	2c	=TO-1		
1 N 234		Z-Di	=1N225: 48V	2c	=TO-1		
1 N 235		Z-Di	=1N225: 58V	2c	=TO-1		
1 N 225A...235A		Z-Di	=1N225...235: 5%	2c	=TO-1		
1 N 236		Z-Di	71V, 10%, 0,15W	2c	=TO-1		
1 N 237		Z-Di	=1N236: 88V	2c	=TO-1		
1 N 238		Z-Di	=1N236: 105V	2c	=TO-1		
1 N 239		Z-Di	=1N236: 128V	2c	=TO-1		
1 N 248(A...C)	Mot,Rca,++	Si-Di	P Rr, 50...55V, 10...20A	32a	DO-5		BYX 25/600
1 N 248(A...C)R		Si-Di	=1N248(A...C):	32b	DO-5		BYX 25/600R, DS 17-02A, SSI2040
1 N 249(A...C)	Mot,Rca,++	Si-Di	P Rr, 100...110V, 10...20A	32a	DO-5		BYX 25/600
1 N 249(A...C)R		Si-Di	=1N249(A...C):	32b	DO-5		BYX 25/600R, DS 17-02A, SSI2040
1 N 250(A...C)	Mot,Rca,++	Si-Di	P Rr, 200...220V, 10...20A	32a	DO-5		BYX 25/600
1 N 250(A...C)R		Si-Di	=1N250(A...C):	32b	DO-5		BYX 25/600R, DS 17-02A, SSI2040
1 N 251	Sgs,Tix,++	Si-Di	S, 40V, 75mA, <150ns	31a	DO-7		BAV 18...21, BAX 15...17, 1N3070, ++
1 N 251 A		Si-Di	=1N251: 125V, 100mA	31a	DO-7		BAV 19...21, BAX 15...17, 1N3070, ++
1 N 252	Sgs,Tix,++	Si-Di	S, 20V, 100mA, <150ns	31a	DO-7		BAV 18...21, BAX 15...17, 1N3070, ++
1 N 252 A		Si-Di	=1N252: 125V	31a	DO-7		BAV 19...21, BAX 15...17, 1N3070, ++
1 N 253	Ssi,Tix,++	Si-Di	P Rr, 95V, 1A	32a	DO-4		BYX 38/300, BYX 39/600
1 N 254	Ssi,Tix,++	Si-Di	=1N253: 190V, 0,4A	32a	DO-4		BYX 38/300, BYX 39/600
1 N 255	Ssi,Tix,++	Si-Di	=1N253: 380V, 0,4A	32a	DO-4		BYX 38/600, BYX 39/600
1 N 256	Ssi,Tix,++	Si-Di	=1N253: 570V, 0,2A	32a	DO-4		BYX 38/600, BYX 39/600
1 N 258	USA	Si-Di	UHF, S-Band Dem	Koax	SOD-47		-
1 N 259		Si-Di	=2x 1N23 Matched Pair				-
1 N 261		Di	400V				-
1 N 263	Miv,Nec,Pai	Ge-Di	UHF Ms	Koax	SOD-48		-
1 N 264		Si-Di	=2x 1N21 Matched Pair				-
1 N 265	USA	Ge-Di	Uni, 80V	31a	DO-7		AA 117...118, AA 132...133
1 N 266	USA	Ge-Di	Uni, 50V	31a	DO-7		AA 117...118, AA 132...134, 1N34, 1N54, ++
1 N 267	USA	Ge-Di	Uni, 30V	31a	DO-7		AA 117...118, AA 132...134, 1N34, 1N54, ++
1 N 268	USA	Ge-Di	Uni, 30V, 300mA	31a	DO-7		AA 139, 1N270
1 N 270	USA,Itt,Tho	Ge-Di	Uni, 100V, 60mA	31a	DO-7	(AA 133)	31a AA 117...118, AA 132...133
1 N 273	USA	Ge-Di	Uni, 32V, 80mA	31a	DO-7		AA 117...118, AA 132...133, 1N34, 1N54, ++
1 N 276	USA,Itt,Tho	Ge-Di	Uni, S, 100V, 60mA, <300ns	31a	DO-7		AAY 28, AAZ 15
1 N 277(M)	USA,Itt,Tho	Ge-Di	Uni, 100...125V, 50mA	31a	DO-7		AA 117...118, AA 132...133
1 N 278	USA,Itt	Ge-Di	Uni, 58V, 0,17A(ss)	31a	DO-7		AA 117...118, AA 132...134, 1N34, 1N54, ++
1 N 279	USA,Itt	Ge-Di	Uni, 32V, 70mA	31a	DO-7		AA 117...118, AA 132...134, 1N34, 1N54, ++
1 N 281	USA,Tho	Ge-Di	Uni, 75V, 75mA	31a	DO-7		AA 117...118, AA 132...134, 1N34, 1N54, ++
1 N 282	USA	Ge-Di	Uni, 15V	31a	DO-7		AA 113...119, 1N34, 1N54, 1N60, ++
1 N 283	USA,Itt,Tho	Ge-Di	Uni, 25V	31a	DO-7		AA 139
1 N 285	Gen	Ge-Di	UHF Mx				-
1 N 286(A)	Syl	Si-Di	UHF, X/K-Band Mx	Koax	SOD-49		-
1 N 287	USA	Ge-Di	Uni, 40V, 60mA	31a	DO-7		AA 117...118, AA 132...134, 1N34, 1N54, ++
1 N 288	USA	Ge-Di	Uni, 70V, 0,75A(ss)	31a	DO-7		AA 117...118, AA 132...134, 1N34, 1N54, ++
1 N 289	USA	Ge-Di	Uni, 80V, 80mA	31a	DO-7		AA 117...118, AA 132...134, 1N34, 1N54, ++
1 N 290	USA	Ge-Di	Uni, 100V, -/0,3A	31a	DO-7		AA 117...118, AA 132...133
1 N 291	USA	Ge-Di	Uni, 100V, -/0,4A	31a	DO-7		AA 117...118, AA 132...133
1 N 292	USA	Ge-Di	Uni, 70V, 70mA	31a	DO-7		AA 117...118, AA 132...134, 1N34, 1N54, ++
1 N 294(A)	USA,Tho	Ge-Di	Uni, 60V, 50mA	31a	DO-7		AA 117...118, AA 132...134, 1N34, 1N54, ++
1 N 295(A,S,X)	USA,Tho	Ge-Di	Uni, 30...40V, 20...35mA	31a	DO-7		AA 117...118, AA 132...134, 1N34, 1N54, ++
1 N 296		Ge-Di	40V				-
1 N 297(A)	USA,Tho	Ge-Di	Uni, 80V, 35mA	31a	DO-7		AA 117...118, AA 132...134, 1N34, 1N54, ++
1 N 298(A)	USA	Ge-Di	Uni, 70V, 30...50mA	31a	DO-7		AA 117...118, AA 132...134, 1N34, 1N54, ++
1 N 299	Kem	Ge-Di	Uni, 50V	31a	DO-7		AA 117...118, AA 132...134, 1N34, 1N54, ++
1 N 300(A,B)	USA	Si-Di	Uni, 15V, 65...100mA	31a	DO-7		BA 127, BA 147/25, 1N4148, 1N5194...96,++
1 N 301(A,B)	USA	Si-Di	Uni, 70V, 45...75mA				BA 127, BA 147/100, 1N4148, 1N5194...96,++
1 N 302(A,B)	USA	Si-Di	Uni, 225V, 30...55mA				BA 147/230, BAY 21, BAY 46, 1N5196, ++

Original	Fabric.	Constr.	Info	{Compl. Fig.	JAEGER	Fig.	International
1 N 303(A,B)	USA	Si-Di	Uni, 125V, 40...65mA	31a	DO-7		BA 147/150, BAY 20, BAY 45, 1N5195...96++
1 N 304	USA	Ge-Di	Uni, 55V	31a	DO-7		AA 117...118, AA 132...134, 1N34, 1N54, ++
1 N 305	USA	Ge-Di	Uni, 60V, 125mA	31a	DO-7		AA 136, 1N270
1 N 306	USA	Ge-Di	Uni, 15V, 150mA	31a	DO-7		AA 135...136, AA 139, 1N270
1 N 307	USA	Ge-Di	Uni, 125V, 50mA				AA 117...118, AA 132...133
1 N 308	USA	Ge-Di	Uni, 8V, 100mA	31a	DO-7		AA 139
1 N 309	USA	Ge-Di	Uni, 30V, 100mA	31a	DO-7		AA 135...136, AA 139, 1N270
1 N 310	USA	Ge-Di	Uni, 100V, 40mA	31a	DO-7		AA 117...118, AA 132...133
1 N 311		Si-Di	UHF Mx, 9.5GHz				-
1 N 312	USA	Ge-Di	Uni, 50V, 70mA	31a	DO-7		AA 117...118, AA 132...134, 1N34, 1N54, ++
1 N 313	USA	Ge-Di	Uni, 100V, 40mA	31a	DO-7		AA 117...118, AA 132...133
1 N 314	USA	Ge-Di	Uni, 75V, 100mA	31a	DO-7		1N270
1 N 315(A)	Gen.Spe,Ssi	Ge-Di	Rr, 200...300V, 75...100mA	34a	DO-1		-
1 N 316(A)	USA	Si-Di	Rr, 50V, 0,25A	34a	DO-1		BA 157...159, BAY 18...21, BAY 86...90, ++
1 N 317(A)	USA	Si-Di	=1N316: 100V	34a	DO-1		BA 157...159, BAY 19...21, BAY 87...90, ++
1 N 318(A)	USA	Si-Di	=1N316: 200V	34a	DO-1		BA 157...159, BAY 21, BAY 88...90, ++
1 N 319(A)	USA	Si-Di	=1N316: 350V	34a	DO-1		BA 157...159, BAY 21, BAY 88...90, ++
1 N 320(A)	USA	Si-Di	=1N316: 500V	34a	DO-1		BA 158...159, BAY 89...90
1 N 321(A)	USA	Si-Di	=1N316: 850V	34a	DO-1		BA 159, BAY 90...91
1 N 322(A)	USA	Si-Di	=1N316: 1000V	34a	DO-1		BA 159, BAY 90...91
1 N 323(A)	USA	Si-Di	Rr, 50V, 0,4A	34a	DO-1		BA 157...159, BY 126...127, 1N4001...07, ++
1 N 324(A)	USA	Si-Di	=1N323: 100V	34a	DO-1		BA 157...159, BY 126...127, 1N4002...07, ++
1 N 325(A)	USA	Si-Di	=1N323: 200V	34a	DO-1		BA 157...159, BY 126...127, 1N4003...07, ++
1 N 326(A)	USA	Si-Di	=1N323: 350V	34a	DO-1		BA 157...159, BY 126...127, 1N4004...07, ++
1 N 327(A)	USA	Si-Di	=1N323: 500V	34a	DO-1		BA 158...159, BY 126...127, 1N4005...07, ++
1 N 328(A)	USA	Si-Di	=1N323: 850V	34a	DO-1		BA 159, BY 127, BY 133, 1N4007, ++
1 N 329(A)	USA	Si-Di	=1N323: 1000V	34a	DO-1		BA 159, BY 127, BY 133, 1N4007, ++
1 N 330	USA	Si-Di	Uni, 32V	31a	DO-7		BA 127...128, BA 147/50, BA 222, ++
1 N 331	USA	Si-Di	Uni, 16V	31a	DO-7		BA 127...128, BA 147/25, BA 222, ++
1 N 332	USA	Si-Di	P Rr, 400V, 1,2A	32a	DO-4		BYX 38/600, BYX 39/600
1 N 333	USA	Si-Di	=1N332: 0,6A	32a	DO-4		BYX 38/600, BYX 39/600
1 N 334	USA	Si-Di	=1N332: 300V	32a	DO-4		BYX 38/300, BYX 39/600
1 N 335	USA	Si-Di	=1N332: 300V, 0,6A	32a	DO-4		BYX 38/300, BYX 39/600
1 N 336	USA	Si-Di	=1N332: 200V	32a	DO-4		BYX 38/300, BYX 39/600
1 N 337	USA	Si-Di	=1N332: 200V, 0,6A	32a	DO-4		BYX 38/300, BYX 39/600
1 N 338	USA	Si-Di	Rr P, 100V, 3A	32a	DO-4		BYX 38/300, BYX 39/600
1 N 339	USA	Si-Di	=2N338: 1,2A	32a	DO-4		BYX 38/300, BYX 39/600
1 N 340	USA	Si-Di	=2N338: 0,6A	32a	DO-4		BYX 38/300, BYX 39/600
1 N 341	USA	Si-Di	=2N338: 400V, 1,2A	32a	DO-4		BYX 38/600, BYX 39/600
1 N 342	USA	Si-Di	=2N338: 400V, 0,6A	32a	DO-4		BYX 38/600, BYX 39/600
1 N 343	USA	Si-Di	=2N338: 300V, 1,2A	32a	DO-4		BYX 38/600, BYX 39/600
1 N 344	USA	Si-Di	Rr P, 300V, 0,6A	32a	DO-4		BYX 38/300, BYX 39/600
1 N 345	USA	Si-Di	=1N344: 200V, 1,2A	32a	DO-4		BYX 38/300, BYX 39/600
1 N 346	USA	Si-Di	=1N344: 200V, 0,6A	32a	DO-4		BYX 38/300, BYX 39/600
1 N 347	USA	Si-Di	=1N344: 100V, 3A	32a	DO-4		BYX 38/300, BYX 39/600
1 N 348	USA	Si-Di	=1N344: 100V, 1,2A	32a	DO-4		BYX 38/300, BYX 39/600
1 N 349	USA	Si-Di	=1N344: 100V, 0,6A	32a	DO-4		BYX 38/300, BYX 39/600
1 N 350	USA	Si-Di	Uni, 70V, 15mA	2c	=TO-1		BA 147/100, BAY 19...21, BAY 45...46, ++
1 N 351	USA	Si-Di	=1N350: 120V	2c	=TO-1		BA 147/150, BAY 20...21, BAY 45...46, ++
1 N 352	USA	Si-Di	=1N350: 170V	2c	=TO-1		BA 147/230, BAY 20...21, BAY 46, ++
1 N 353	USA	Si-Di	=1N350: 225V	2c	=TO-1		BA 147/300, BAY 21, BAY 46, BAY 88, ++
1 N 354	USA	Si-Di	=1N350: 325V	2c	=TO-1		BA 147/300, BAY 21, BAY 46, BAY 88, ++
1 N 355	USA	Ge-Di	Uni, 80V, 50mA	31a	DO-7		AA 117...118, AA 132...134, 1N34, 1N54, ++
1 N 358	USA	Si-Di	UHF, L/X-Band Dem	Koax	SOD-49		-
1 N 359(A)	USA	Si-Di	Rr, 50V, 0,15A	34a	DO-1		BA 147/50, BAY 18...21, 1N4001...07, ++
1 N 360(A)	USA	Si-Di	=1N359: 100V	34a	DO-1		BA 147/100, BAY 19...21, 1N4002...07, ++
1 N 361(A)	USA	Si-Di	=1N359: 200V	34a	DO-1		BA 147/230, BAY 21, 1N4003...07, ++
1 N 362(A)	USA	Si-Di	=1N359: 350V	34a	DO-1		BAY 21, BAY 88...90, 1N4003...07, ++
1 N 363(A)	USA	Si-Di	=1N359: 500V	34a	DO-1		BA 158...159, BAY 89...90, 1N4005...07, ++
1 N 364(A)	USA	Si-Di	=1N359: 850V	34a	DO-1		BA 159, BAY 90...91, 1N4007
1 N 365(A)	USA	Si-Di	=1N359: 1000V	34a	DO-1		BA 159, BAY 90...91, 1N4007
1 N 367	USA	Ge-Di	Uni, 60V	31a	DO-7		AA 117...118, AA 132...134, 1N34, 1N54, ++
1 N 368(A)	USA	Ge-Di	Rr, 200V, 0,1A	34a	DO-1		-
1 N 369(A)	USA	Si-Di	UHF, L/S/X-Band-Dem	Koax	SOD-49		-
1 N 370	USA	Z-Di	1,85V, 20%, 0,2W	31a	DO-27		BZX55/..., BZX79/..., ZPD..., 1N5221...36, ++
1 N 371		Z-Di	=1N370: 2,35V, 15%	31a	DO-27		
1 N 372		Z-Di	=1N370: 2,9V, 15%	31a	DO-27		
1 N 373		Z-Di	=1N370: 3,5V, 15%	31a	DO-27		
1 N 374		Z-Di	=1N370: 4,1V, 10%	31a	DO-27		
1 N 375		Z-Di	=1N370: 4,1V, 5%	31a	DO-27		
1 N 376		Z-Di	=1N370: 4,95V, 5%	31a	DO-27		
1 N 377		Z-Di	=1N370: 5,9V, 5%	31a	DO-27		
1 N 378		Z-Di	=1N370: 7,15V, 5%	31a	DO-27		
1 N 379	USA	Z-Di	8,2V, 0,15W	31a	DO-7		BZX55/..., BZX79/..., ZPD..., 1N5221...81, ++
1 N 380		Z-Di	=1N379: 10V	31a	DO-7		
1 N 381		Z-Di	=1N379: 12V	31a	DO-7		
1 N 382		Z-Di	=1N379: 15V	31a	DO-7		
1 N 383		Z-Di	=1N379: 18V	31a	DO-7		
1 N 384		Z-Di	=1N379: 22V	31a	DO-7		
1 N 385		Z-Di	=1N379: 27V	31a	DO-7		
1 N 386		Z-Di	=1N379: 33V	31a	DO-7		
1 N 387		Z-Di	=1N379: 39V	31a	DO-7		
1 N 388		Z-Di	=1N379: 47V	31a	DO-7		
1 N 389		Z-Di	=1N379: 56V	31a	DO-7		
1 N 390		Z-Di	=1N379: 68V	31a	DO-7		
1 N 391		Z-Di	=1N379: 82V	31a	DO-7		
1 N 392		Z-Di	=1N379: 100V	31a	DO-7		
1 N 393		Z-Di	=1N379: 120V	31a	DO-7		
1 N 394		Z-Di	=1N379: 150V	31a	DO-7		
1 N 395		Z-Di	=1N379: 180V	31a	DO-7		
1 N 396		Z-Di	=1N379: 220V	31a	DO-7		
1 N 397		Z-Di	=1N379: 270V	31a	DO-7		
1 N 398		Z-Di	=1N379: 330V	31a	DO-7		

Original	Fabric.	Constr.	Info	(Compl. Fig.	JAEGER	Fig.	International
1 N 399		Z-Di	=1N379: 390V	31a	DO-7		
1 N 400		Z-Di	=1N379: 470V	31a	DO-7		
1 N 401	Syl	Si-St	1.5V	2c	=TO-1	-	
1 N 402		Si-St	2V	2c	=TO-1	-	
1 N 403		Si-St	2.5V	2c	=TO-1	-	
1 N 404		Si-St	3.1V	2c	=TO-1	-	
1 N 405		Si-St	3.7V, Uf<1V(225mA)	2c	=TO-1	-	
1 N 406		Si-St	4.3V, Uf<1V(200mA)	2c	=TO-1	-	
1 N 407		Si-St	5.2V, Uf<1V(170mA)	2c	=TO-1	-	
1 N 408		Si-St	6.2V, Uf<1V(130mA)	2c	=TO-1	-	
1 N 409		Si-St		2c	=TO-1	-	
1 N 410	Syl	Si-Di					
1 N 411(A,B)	USA	Si-Di	P Rr, 50V, 25...50A	=32/a	SOD-5		BYX 56/600, BYX 97/300
1 N 412(A,B)		Si-Di	=1N411(A,B): 100V				BYX 56/600, BYX 97/300
1 N 413(A,B)		Si-Di	=1N411(A,B): 200V				BYX 56/600, BYX 97/300
1 N 415(A....H)	USA	Si-Di	UHF, X-Band Mx	Koax	SOD-47	-	
1 N 416(A....G)	USA	Si-Di	UHF, S-Band Mx	Koax	SOD-47	-	
1 N 417	USA	Ge-Di	S, 60V, 60mA, <300ns	31a	DO-7		AAZ 15, AAZ 17, 1N276
1 N 418	USA	Ge-Di	S, 60V, 16mA, <300ns	31a	DO-7		AAZ 28, 1N191...192
1 N 419	USA	Ge-Di	S, 80V, 60mA, <300ns	31a	DO-7		AAZ 15
1 N 424 A	Tho	Si-Di	Uni, 150V, -0.225A	31a	DO-7		BA 147/150, BA 190, 1N5195...96, ++
1 N 429	Inr,Mot,++	Ref-Di	6.2V(7.5mA), 5%, 0.01%/°C, <20Ω, 0.2W	2c	=TO-1		BZV 10, BZV 27, BZX 90, 1N821, 1N4580, ++
1 N 430(A,B)	USA	Ref-Di	8.4V(10mA), 5%, 0.001...0.002%/°C, <15Ω, 0.25W				-
1 N 431(B)	USA	Si-Di	Uni, 68...75V, 10mA	2c	=TO-1		BA 147/100, BA 188, 1N5194...96, ++
1 N 432(A,B)	USA	Si-Di	S, 40V, 55...85mA, 3ns				BA 318, BAY 38, BAX 13, 1N3062...64, ++
1 N 433(A,B)	USA	Si-Di	S, 145V, 40...60mA, 3ns				BA 203
1 N 434(A,B)	USA	Si-Di	S, 180V, 35...60mA, 3ns				-
1 N 435	Spe	Ge-Di	4x Uni, 40V, 60mA				-
1 N 436	Ray	Ref-Di	4V				-
1 N 437(A)	Ray	Ref-Di	5V				-
1 N 438(A)	Ray	Ref-Di	7V				-
1 N 439		Ref-Di	10V				-
1 N 440(B)	Rca,Tix,++	Si-Di	Rr P, 100V, 0.3...0.75A	34a	DO-1		BY 126...127, BY 133...135, 1N4002...07, ++
1 N 441(B)		Si-Di	=1N440(B): 200V	34a	DO-1		BY 126...127, BY 133...134, 1N4003...07, ++
1 N 442(B)		Si-Di	=1N440(B): 300V	34a	DO-1		BY 126...127, BY 133...134, 1N4004...07, ++
1 N 443(B)		Si-Di	=1N440(B): 400V	34a	DO-1		BY 126...127, BY 133...134, 1N4004...07, ++
1 N 444(B)		Si-Di	=1N440(B): 500V	34a	DO-1		BY 126...127, BY 133...134, 1N4005...07, ++
1 N 445(B)		Si-Di	=1N440(B): 600V	34a	DO-1		BY 126...127, BY 133...134, 1N4005...07, ++
1 N 446	Syl	Si-Di	UHF, K/Ka-Band Dem	Koax	SOD-49	-	
1 N 447	USA	Ge-Di	Uni, 40V, 60mA	31a	DO-7		AA 117...118, AA 132...134, 1N34, 1N54, ++
1 N 448	USA	Ge-Di	Uni, 100V, 60mA	31a	DO-7		AA 117...118, AA 132...133
1 N 449	USA	Ge-Di	Uni, 40V, 60mA	31a	DO-7		AA 117...118, AA 132...134, 1N34, 1N54, ++
1 N 450	USA	Ge-Di	Uni, 100V, 60mA	31a	DO-7		AA 117...118, AA 132...133
1 N 451	USA	Ge-Di	Uni, 175V, 60mA	31a	DO-7		1N39
1 N 452	USA	Ge-Di	Uni, 35V	31a	DO-7		AA 136
1 N 453	USA	Ge-Di	Uni, 115V	31a	DO-7		1N270
1 N 454	USA	Ge-Di	Uni, 60V	31a	DO-7		AA 136, 1N270
1 N 455	USA	Ge-Di	Uni, 35V	31a	DO-7		AA 136, AA 139, 1N270
1 N 456(A)	Fch,Tix,++	Si-Di	Uni, 35V, 0.09...0.2A	31a	DO-7,DO-35		BA 127, BA 187...190, BA 215, 1N484A, ++
1 N 457(A)	Fch,Tix,++	Si-Di	Uni, 75V, 0.075...0.2A	31a	DO-7,DO-35		BA 188...190, BAY 45, BAY 73, 1N484A, ++
1 N 458(A)	Fch,Tix,++	Si-Di	Uni, 150V, 0.055...0.2A	31a	DO-7,DO-35		BA 189...190, BAY 45, BAW 52, 1N484A, ++
1 N 459(A)	Fch,Tix,++	Si-Di	Uni, 200V, 0.04...0.2A	31a	DO-7,DO-35		BA 190, BAY 46, BAW 52, BAY 20...21, ++
1 N 460(A,B)	USA	Si-Di	Uni, S, 90V, 0.045A				BA 147/100, BA 189...190, 1N5195...96, ++
1 N 461(A)	Fch,Tix,++	Si-Di	Uni, 30V, 0.06...0.2A	31a	DO-7,DO-35		BA 127, BA 187...190, BA 215, 1N484A, ++
1 N 462(A)	Fch,Tix,++	Si-Di	Uni, 70V, 0.05...0.2A	31a	DO-7,DO-35		BA 127, BA 188...190, BA 215, 1N484A, ++
1 N 463(A)	Fch,Tix,++	Si-Di	Uni, 200V, 0.03...0.2A	31a	DO-7,DO-35		BA 190, BAW 52, BAY 46, BAY 21, ++
1 N 464(A)	Fch,Tix,++	Si-Di	Uni, 150V, 0.04...0.2A	31a	DO-7,DO-35		BA 189...190, BAW 52, BAY 45, 1N484A, ++
1 N 465	USA	Z-Di	2.6V, 10%, 0.25W	2c	=TO-1		BZX55/..., BZX79/..., ZPD..., 1N5221...36, ++
1 N 466		Z-Di	=1N465: 3.5V	2c	=TO-1		
1 N 467		Z-Di	=1N465: 4.1V	2c	=TO-1		
1 N 468		Z-Di	=1N465: 4.85V	2c	=TO-1		
1 N 469		Z-Di	=1N465: 5.8V	2c	=TO-1		
1 N 470		Z-Di	=1N465: 7.1V	2c	=TO-1		
1 N 465A....470A		Z-Di	=1N465...470: 5%	2c	=TO-1		
1 N 465B....470B		Z-Di	=1N465...470: 1%	2c	=TO-1		
1 N 471	USA	Z-Di	3.5V, 10%, 0.2W	2c	=TO-1		BZX55/..., BZX79/..., ZPD..., 1N5221...36, ++
1 N 472		Z-Di	=1N471: 4.1V	2c	=TO-1		
1 N 473		Z-Di	=1N471: 4.85V	2c	=TO-1		
1 N 474		Z-Di	=1N471: 5.8V	2c	=TO-1		
1 N 475		Z-Di	=1N471: 7.1V	2c	=TO-1		
1 N 471A....475A		Z-Di	=1N471...475: 5%	2c	=TO-1		
1 N 471B....475B		Z-Di	=1N471...475: 1%	2c	=TO-1		
1 N 476	USA	Ge-Di	Uni, 90V, 50mA	31a	DO-7		AA 117...118, AA 132...133
1 N 477	USA	Ge-Di	Uni, 90V, 50mA	31a	DO-7		AA 117...118, AA 132...133
1 N 478	USA	Ge-Di	Uni, 90V, 50mA	31a	DO-7		AA 117...118, AA 132...133
1 N 479	USA	Ge-Di	Uni, 90V, 50mA	31a	DO-7		AA 117...118, AA 132...133
1 N 480	USA	Ge-Di	S, 60V, 35mA, <500ns	31a	DO-7		AAZ 28, AAZ 15, AAZ 17, 1N276
1 N 481		Ge-Di	Rr, 200V, 0.1A				
1 N 482(A....C)	Fch,Tix,++	Si-Di	Uni, 40V, 0.1...0.2A	31a	DO-7,DO-35		BA 127, BA 187...190, BA 215, BAY 45, ++
1 N 483(A....C)	Fch,Tix,++	Si-Di	=1N482(A....C): 80V	31a	DO-7,DO-35		BA 188...190, BAW 52, BAY 19, BAY 45, ++
1 N 484(A....C)	Fch,Tix,++	Si-Di	=1N482(A....C): 150V	31a	DO-7,DO-35		BA 189...190, BAW 52, BAY 20, BAY 45, ++
1 N 485(A....C)	Fch,Tix,++	Si-Di	=1N482(A....C): 200V	31a	DO-7,DO-35		BA 190, BAW 52, BAY 21, BAY 46, ++
1 N 486(A,B)	Gie,Tix,++	Si-Di	Uni, 225V, 0.1...0.2A	31a	DO-7		BA 157...159, BAY 21, BAY 46, BAY 88...90
1 N 487(A,B)		Si-Di	=1N486(A,B): 300V	31a	DO-7		BA 157...159, BAY 21, BAY 46, BAY 88...90
1 N 488(A,B)		Si-Di	=1N486(A,B): 380V	31a	DO-7		BA 158...159, BAY 21, BAY 88...90
1 N 490	USA	Ge-Di	S, 60V, 35mA, <500ns	31a	SOD-6		AAZ 28, AAZ 15, AAZ 17, 1N276
1 N 497	USA	Ge-Di	Uni, 25V, 80mA	31a	DO-7		AA 135...136, 1N270
1 N 498	USA	Ge-Di	Uni, 46V, 70mA	31a	DO-7		AA 136, 1N270
1 N 499	USA	Ge-Di	Uni, 62V, 80mA	31a	DO-7		AA 136, 1N270
1 N 500	USA	Ge-Di	Uni, 70V, 80mA	31a	DO-7		1N270
1 N 501	USA	Ge-Di	Uni, 92V, 80mA	31a	DO-7		1N270
1 N 502	USA	Ge-Di	Uni, 115V, 70mA	31a	DO-7		1N270
1 N 503	old	Si-Di	Rr, 50V, 0.33A				BY 126...127, BY 133...135, 1N4001...07, ++

Original	Fabric.	Constr.	Info	{Compl. Fig.	JAEGER	Fig.	International
1 N 504		Si-Di	=1N503: 100V				BY 126...127, BY 133...135, 1N4002...07, ++
1 N 505		Si-Di	=1N503: 200V				BY 126...127, BY 133...134, 1N4003...07, ++
1 N 506		Si-Di	=1N503: 300V				BY 126...127, BY 133...134, 1N4004...07, ++
1 N 507		Si-Di	=1N503: 400V				BY 126...127, BY 133...134, 1N4004...07, ++
1 N 508		Si-Di	=1N503: 600V				BY 126...127, BY 133...134, 1N4005...07, ++
1 N 509		Si-Di	=1N503: 800V				BY 127, BY 133, BYW 42, 1N4006...07, ++
1 N 510		Si-Di	=1N503: 1000V				BY 127, BY 133, BYW 43, 1N4007, ++
1 N 511	old	Si-Di	Rr, 50V, 1A				BY 126...127, BY 133...135, 1N4001...07, ++
1 N 512		Si-Di	=1N511: 100V				BY 126...127, BY 133...135, 1N4002...07, ++
1 N 513		Si-Di	=1N511: 200V				BY 126...127, BY 133...134, 1N4003...07, ++
1 N 514		Si-Di	=1N511: 300V				BY 126...127, BY 133...134, 1N4004...07, ++
1 N 515		Si-Di	=1N511: 400V				BY 126...127, BY 133...134, 1N4004...07, ++
1 N 516		Si-Di	=1N511: 600V				BY 126...127, BY 133...134, 1N4005...07, ++
1 N 517		Si-Di	=1N511: 800V				BY 127, BY 133, BYW 42, 1N4006...07, ++
1 N 518		Si-Di	=1N511: 1000V				BY 127, BY 133, BYW 43, 1N4007, ++
1 N 519	old	Si-Di	Rr, 50V, 1.25A				BY 126...127, BY 133...135, 1N4001...07, ++
1 N 520		Si-Di	=1N519: 100V				BY 126...127, BY 133...135, 1N4002...07, ++
1 N 521		Si-Di	=1N519: 200V				BY 126...127, BY 133...134, 1N4003...07, ++
1 N 522		Si-Di	=1N519: 300V				BY 126...127, BY 133...134, 1N4004...07, ++
1 N 523		Si-Di	=1N519: 400V				BY 126...127, BY 133...134, 1N4004...07, ++
1 N 524		Si-Di	=1N519: 600V				BY 126...127, BY 133...134, 1N4005...07, ++
1 N 525		Si-Di	=1N519: 800V				BY 127, BY 133, BYW 42, 1N4006...07, ++
1 N 526		Si-Di	=1N519: 1000V				BY 127, BY 133, BYW 43, 1N4007, ++
1 N 527	USA	Ge-Di	Uni, 10V	31a	DO-7		AA 112...114, AA 116, AA 119, 1N60, ++
1 N 530	Sem,Slid,Tix	Si-Di	Rr, 100V, 0.3A	34a	DO-1		BA 157...159, BY 402...405, 1N4002...07, ++
1 N 531		Si-Di	=1N530: 200V	34a	DO-1		BA 157...159, BY 403...405, 1N4003...07, ++
1 N 532		Si-Di	=1N530: 300V	34a	DO-1		BA 157...159, BY 404...405, 1N4004...07, ++
1 N 533		Si-Di	=1N530: 400V	34a	DO-1		BA 157...159, BY 404...405, 1N4004...07, ++
1 N 534		Si-Di	=1N530: 500V	34a	DO-1		BA 158...159, BY 405, 1N4005...07, ++
1 N 535		Si-Di	=1N530: 600V	34a	DO-1		BA 158...159, BY 405, 1N4005...07, ++
1 N 536	Rca,Tix,++	Si-Di	Rr, 50V, 0.75A	34a	DO-1		BY 126...127, BY 133...135, 1N4001...07, ++
1 N 537		Si-Di	=1N536: 100V	34a	DO-1		BY 126...127, BY 133...135, 1N4002...07, ++
1 N 538		Si-Di	=1N536: 200V	34a	DO-1		BY 126...127, BY 133...134, 1N4003...07, ++
1 N 539		Si-Di	=1N536: 300V	34a	DO-1		BY 126...127, BY 133...134, 1N4004...07, ++
1 N 540		Si-Di	=1N536: 400V	34a	DO-1		BY 126...127, BY 133...134, 1N4004...07, ++
1 N 541	USA,Tho	Ge-Di	Dem, hi-ohm, 50V, 30mA	31a	DO-7	AA 119	AA 113, AA 119, 1N34, 1N54, 1N60
1 N 542		Ge-Di	=1N541: Matched Pair	2x 31a	2x DO-7	AA 119	AA 113, AA 119, 1N34, 1N54, 1N60
1 N 543(A)	old	Si-Di	Rr, 1500V, 10...35mA	34a	DO-13		DM 513, EM 516, RGP 01-16, SHG 1,5
1 N 544(A)	old	Si-Di	Rr, 1200V, 15...75mA	34a	DO-13		DM 513, EM 516, RGP 01-16, SHG 1,5
1 N 547(S)	Rca,Tix,++	Si-Di	Rr, 600V, 0.75A	34a	DO-1		BY 126...127, BY 133...134, 1N4005, ++
1 N 548	old	Si-Di	Rr, 900V, 0.3A	31a	(23x9mm0)		BA 159, BY 127, BY 133, 1N4007, ++
1 N 549	old	Si-Di	=1N548: 1200V	31a	(23x9mm0)		BY 127, BY 133, BYX 95, EM 513, ++
1 N 550	Sem,Tix,++	Si-Di	Rr P, 100V, 0.5A	32a	DO-4		BYX 38/300, BYX 39/600
1 N 551		Si-Di	=1N550: 200V	32a	DO-4		BYX 38/300, BYX 39/600
1 N 552		Si-Di	=1N550: 300V	32a	DO-4		BYX 38/300, BYX 39/600
1 N 553		Si-Di	=1N550: 400V	32a	DO-4		BYX 38/600, BYX 39/600
1 N 554		Si-Di	=1N550: 500V	32a	DO-4		BYX 38/600, BYX 39/600
1 N 555		Si-Di	=1N550: 600V	32a	DO-4		BYX 38/600, BYX 39/600
1 N 558	Tix	Si-Di	Rr, 1500V, 15mA	34a	DO-1		BAY 91, RGP 01-16,
1 N 560	Sem,Tix,++	Si-Di	Rr, 800V, 0.25A	34a	DO-1		BY 127, BY 133, BYW 42, G 1K, 1N4006, ++
1 N 561		Si-Di	=1N560: 1000V	34a	DO-1		BY 127, BY 133, BYW 43, G 1M, 1N4007, ++
1 N 562	USA	Si-Di	Rr P, 800V, 0.4A	32a	DO-4		BYX 38/900, BYX 39/800
1 N 563		Si-Di	=1N562: 1000V	32a	DO-4		BYX 38/1200, BYX 39/1000
1 N 566	Idc	Ge-Di	Uni, 275V	31a	DO-7		-
1 N 567	Idc,Sem	Ge-Di	S, 125V, 300ns	31a	DO-7		-
1 N 568	Idc,Itt,Sem	Ge-Di	S, 50V, 80ns	31a	DO-7		-
1 N 569	Idc,Itt,Sem	Ge-Di	Uni, 25V	31a	DO-7		AA 139, 1N270
1 N 570	USA	Si-Di	Rr, 1500V, 0.75A				-
1 N 571	USA,Itt	Ge-Di	S, 15V, <4μ	34a	DO-13		-
1 N 573		Ge-Di	Rr, 380V, 0.25A				-
1 N 574		Ge-Di	Rr, 380V, 0.3A				-
1 N 575(A)		Ge-Di	Rr, 380V, 0.35A				-
1 N 576(A)		Ge-Di	Rr, 380V, 0.4A				-
1 N 581	Gen	Ge-Di	Rr, 380V, 0.25A				-
1 N 582	Gen	Ge-Di	Rr, 380V, 0.3A				-
1 N 583	Gen	Ge-Di	Rr, 380V, 0.35A				-
1 N 584	Gen	Ge-Di	Rr, 380V, 0.4A				-
1 N 588	USA	Si-Di	Rr, 1500V, 0.1A	34a	DO-1		BAY 91, RGP 01-16
1 N 589	USA	Si-Di	Rr, 1500V, 0.25A	34a	DO-1		BAY 91, DM 513, EM 516, GP 10Y
1 N 590	Ssi	Si-Di	Rr, 1500V, 25mA	-34a	-DO-1		BAY 91, RGP 01-16
1 N 591		Si-Di	=1N590:	-34b	-DO-1		BAY 91, RGP 01-16
1 N 596	USA	Si-Di	Rr, 600V, 0.15A	34a	DO-1		BA 158...159, BAY 89...90, BY 207
1 N 597		Si-Di	=1N596: 800V	34a	DO-1		BA 159, BAY 90, BY 204/8
1 N 598		Si-Di	=1N596: 1000V	34a	DO-1		BA 159, BAY 90, BY 204/10
1 N 599(A)	USA,Tix	Si-Di	Rr, 50V, 0.4A	34a	DO-1		BA 157...159, BY 401...405, 1N4001...07, ++
1 N 600(A)		Si-Di	=1N599: 100V	34a	DO-1		BA 157...159, BY 402...405, 1N4002...07, ++
1 N 601(A)		Si-Di	=1N599: 150V	34a	DO-1		BA 157...159, BY 403...405, 1N4003...07, ++
1 N 602(A)		Si-Di	=1N599: 200V	34a	DO-1		BA 157...159, BY 403...405, 1N4003...07, ++
1 N 603(A)		Si-Di	=1N599: 300V	34a	DO-1		BA 157...159, BY 404...405, 1N4004...07, ++
1 N 604(A)		Si-Di	=1N599: 400V	34a	DO-1		BA 157...159, BY 404...405, 1N4004...07, ++
1 N 605(A)		Si-Di	=1N599: 500V	34a	DO-1		BA 158...159, BY 405, 1N4005...07, ++
1 N 606(A)		Si-Di	=1N599: 600V	34a	DO-1		BA 158...159, BY 405, 1N4005...07, ++
1 N 607(A)	USA,Tix	Si-Di	P Rr, 50V, 1A	32a	DO-4		BYX 38/300, BYX 39/600
1 N 608(A)		Si-Di	=1N607(A): 100V	32a	DO-4		BYX 38/300, BYX 39/600
1 N 609(A)		Si-Di	=1N607(A): 150V	32a	DO-4		BYX 38/300, BYX 39/600
1 N 610(A)		Si-Di	=1N607(A): 200V	32a	DO-4		BYX 38/300, BYX 39/600
1 N 611(A)		Si-Di	=1N607(A): 300V	32a	DO-4		BYX 38/300, BYX 39/600
1 N 612(A)		Si-Di	=1N607(A): 400V	32a	DO-4		BYX 38/600, BYX 39/600
1 N 613(A)		Si-Di	=1N607(A): 500V	32a	DO-4		BYX 38/600, BYX 39/600
1 N 614(A)		Si-Di	=1N607(A): 600V	32a	DO-4		BYX 38/600, BYX 39/600
1 N 607R...614R		Si-Di	=1N607(A)...614(A):	32b	DO-4		BYX 38/600R, BYX 39/600R
1 N 615	USA	Ge-Di	Uni, 300V, 75mA	31a	DO-7		-
1 N 616	USA	Ge-Di	Dem, 30V, 30mA	31a	DO-7		AA 113...114, AA 116, AA 119, 1N60, ++

Original	Fabric.	Constr.	Info	(Compl. Fig.	JAEGER	Fig.	International
1 N 617	USA	Ge-Di	Uni, 90V, 50mA	31a	DO-7		AA 117...118, AA 132...133
1 N 618	USA	Ge-Di	Uni, 90V, 50mA	31a	DO-7		AA 117...118, AA 132...133
1 N 619	USA	Si-Di	Uni, 30V	31a	DO-7		BA 127...128, BA 222, BA 147/50, 1N4148++
1 N 622	USA	Si-Di	Uni, 150V	31a	DO-7		BA 147/150, 1N5195...96, 1N5606...07, ++
1 N 625(A)	Fch,Tix,++	Si-Di	S, 30V, 20mA, <500...1000ns	31a	DO-7,DO-35		BA 195, BAW 49, BAX 15...17, 1N3070, ++
1 N 626(A)		Si-Di	=1N625: 50V	31a	DO-7,DO-35		BA 195, BAW 49, BAX 15...17, 1N3070, ++
1 N 627(A)		Si-Di	=1N625: 100V	31a	DO-7,DO-35		BA 195, BAW 49, BAX 15...17, 1N3070, ++
1 N 628(A)		Si-Di	=1N625: 150V	31a	DO-7,DO-35		BA 195, BAW 50, BAX 15...17, 1N3070, ++
1 N 629(A)		Si-Di	=1N625: 200V	31a	DO-7,DO-35		BA 195, BA 197, BAW 50, BAX 17, ++
1 N 630(A)	Miv,Syl	Si-Di	UHF, L/X-Band Dem	Koax	SOD-49		-
1 N 631	USA	Ge-Di	S, 60V, 60mA, <300ns	31a	DO-7		AAY 28, 1N276
1 N 632	USA	Ge-Di	S, 60V, <300ns	31a	DO-7		AAY 28, 1N276
1 N 633	USA	Ge-Di	S, 90V, 60mA, <300ns	31a	DO-7		AAY 28, 1N276
1 N 634	USA	Ge-Di	Uni, 125V, 100mA	31a	DO-7		-
1 N 635	USA	Ge-Di	Uni, 175V, 150mA	31a	DO-7		-
1 N 636	USA	Ge-Di	Uni, 50V, 30mA	31a	DO-7		AA 117...118, AA 132...134, 1N34, 1N54, ++
1 N 643(A)	Fch,Tix,++	Si-Di	S, 200V, 0.04A, <300ns	31a	DO-7		BA 195, BA 197...198, BAW 50, BAX 17, ++
1 N 645(A,B,GP,J)	Gie,Tix,++	Si-Di	Rr, 225V, 0.4A	31a	DO-7		BA 157...159, BY 206...207, BY 404...405,++
1 N 646(GP)		Si-Di	=1N645: 300V	31a	DO-7		BA 157...159, BY 206...207, BY 404...405,++
1 N 647(GP)		Si-Di	=1N645: 400V	31a	DO-7		BA 157...159, BY 207, BY 404...405, ++
1 N 648(GP)		Si-Di	=1N645: 500V	31a	DO-7		BA 158...159, BY 207, BY 405, 1N4005, ++
1 N 649(GP)		Si-Di	=1N645: 600V	31a	DO-7		BA 158...159, BY 207, BY 405, 1N4005, ++
1 N 650	Tix	GaAs-Di	Tunnel-Di	2	TO-18		-
1 N 651	Tix	GaAs-Di	Tunnel-Di	2	TO-18		-
1 N 652	Tix	GaAs-Di	Tunnel-Di	2	TO-18		-
1 N 653	Tix	GaAs-Di	Tunnel-Di	2	TO-18		-
1 N 658(A)	Fch,Tix,++	Si-Di	S, 50V, 60mA, <300ns	31a	DO-7		BA 195, BAW 49, BAX 15...17, 1N3070, ++
1 N 659(A)	Fch,Tix,++	Si-Di	S, 50V, 100mA, <300ns	31a	DO-7		BA 195, BAW 49, BAX 15...17, 1N3070, ++
1 N 660(A)	Fch,Tix,++	Si-Di	S, 100V, 100mA, <300ns	31a	DO-7		BA 195, BAW 49, BAX 15...17, 1N3070, ++
1 N 661(A)	Fch,Tix,++	Si-Di	S, 200V, 100mA, <300ns	31a	DO-7		BA 195, BA 197...98, BAW 50, BAX 17, ++
1 N 662(A)	Fch,Tix,++	Si-Di	S, 80V, 40mA, <500ns	31a	DO-7		BA 195, BAW 49, BAX 15...17, 1N3070, ++
1 N 663(A)	Fch,Tix,++	Si-Di	S, 80V, 60mA, <500ns	31a	DO-7		BA 195, BAW 49, BAX 15...17, 1N3070, ++
1 N 664	USA	Z-Di	8.2V, 5%, 0.4W	34a	=DO-13		BZX55/... BZX83/... ZPD... 1N5230...76,++
1 N 665		Z-Di	=1N664: 12V	34a	=DO-13		
1 N 666		Z-Di	=1N664: 15V	34a	=DO-13		
1 N 667		Z-Di	=1N664: 18V	34a	=DO-13		
1 N 668		Z-Di	=1N664: 22V	34a	=DO-13		
1 N 669		Z-Di	=1N664: 27V	34a	=DO-13		
1 N 670		Z-Di	=1N664: 68V	34a	=DO-13		
1 N 671		Z-Di	=1N664: 100V	34a	=DO-13		
1 N 672		Z-Di	=1N664: 150V	34a	=DO-13		
1 N 673	USA	Si-Di	Rr, 350V, 0.4A	=34a	=DO-1		BA 157...159, BY 206...207, BY 404...405,++
1 N 674	USA	Z-Di	=1N664: 4.7V	34a	=DO-13		+1N664...
1 N 675	USA	Z-Di	=1N664: 6.2V	34a	=DO-13		+1N664...
1 N 676	Fch,Itt,++	Si-Di	Rr, Uni, 100V, 0.2A	31a	DO-7		BA 157...159, BA 193...194, BA 199/250, ++
1 N 677	Fch,Itt,++	Si-Di	Rr, Uni, 100V, 0.4A	31a	DO-7		BA 157...159, BA 193...194, BA 199/250, ++
1 N 678	Fch,Itt,++	Si-Di	Rr, Uni, 200V, 0.2A	31a	DO-7		BA 157...159, BA 199/250, BAS 11, ++
1 N 679	Fch,Itt,++	Si-Di	Rr, Uni, 200V, 0.4A	31a	DO-7		BA 157...159, BA 199/250, BAS 11, ++
1 N 681	Fch,Itt,++	Si-Di	Rr, Uni, 300V, 0.075A	31a	DO-7		BA 199/350, BAS 11, BAY 21, BAY 88...90++
1 N 682	Fch,Itt,++	Si-Di	Rr, Uni, 300V, 0.15A	31a	DO-7		BA 199/350, BAS 11, BAY 21, BAY 88...90++
1 N 683	Fch,Itt,++	Si-Di	Rr, Uni, 400V, 0.075A	31a	DO-7		BA 157...159, BA 199/450, BAY 89...90, ++
1 N 684	Fch,Itt,++	Si-Di	Rr, Uni, 400V, 0.15A	31a	DO-7		BA 157...159, BA 199/450, BAY 89...90, ++
1 N 685	Fch,Itt,++	Si-Di	Rr, Uni, 500V, 0.075A	31a	DO-7		BA 158...159, BA 199/550, BAY 89...90, ++
1 N 686	Fch,Itt,++	Si-Di	Rr, Uni, 500V, 0.15A	31a	DO-7		BA 158...159, BA 199/550, BAY 89...90, ++
1 N 687	Fch,Itt,++	Si-Di	Rr, Uni, 600V, 0.075A	31a	DO-7		BA 158...159, BA 199/550, BAY 89...90, ++
1 N 689	Fch,Itt,++	Si-Di	Rr, Uni, 600V, 0.15A	31a	DO-7		BA 158...159, BA 199/550, BAY 89...90, ++
1 N 690	Ssi,Tix,++	Si-Di	Uni, S, 36V, 0.25A, <800ns	31a	DO-7		BAV 17...21, BAW 48...50, BAY 72, BAX 12++
1 N 691		Si-Di	=1N690: 80V	31a	DO-7		BAV 19...21, BAW 49...50, BAY 72, BAX 12++
1 N 692		Si-Di	=1N690: 100V	31a	DO-7		BAV 19...21, BAW 49...50, BAY 72, BAX 12++
1 N 693		Si-Di	=1N690: 130V	31a	DO-7		BAV 16, BAV 19...21, BAW 50, BAX 15, ++
1 N 695(A)	USA	Ge-Di	S, 20...25V, 0.1...0.15A, 300ns	31a	DO-7		AAY 49, AAZ 15, AAZ 17
1 N 696	USA	Si-Di	S, 40V, <5ns				BA 318, BAY 38, 1N3062...64, 1N4305, ++
1 N 697	USA	Si-Di	S, 120V, 0.25A, <100ns	=34a	=DO-1		BA 197...98, BAV 19...21, BAW 50, ++
1 N 698	USA	Ge-Di	S, 15V, 500ns	31a	DO-7		AAY 49, AAZ 15, AAZ 18, 1N276
1 N 699	USA	Ge-Di	S, 105V, 30mA, <300ns	31a	DO-7		AAY 28, 1N191, 1N633
1 N 701	USA	Z-Di	10V, 5%, 0.4W	=34a	=DO-13		BZX55/C10, BZX83/C10, ZPD10, 1N5240,++
1 N 702	USA,Tho	Z-Di	2.6V, 10%, 0.25W	31a	DO-7	Z-Diode 2.4V	31a
1 N 703		Z-Di	=1N702: 3.5V	31a	DO-7	Z-Diode 3.6V	31a
1 N 704		Z-Di	=1N702: 4.1V	31a	DO-7	Z-Diode 4.3V	31a
1 N 705		Z-Di	=1N702: 4.8V	31a	DO-7	Z-Diode 4.7V	31a
1 N 706		Z-Di	=1N702: 5.8V	31a	DO-7	Z-Diode 5.6V	31a
1 N 707		Z-Di	=1N702: 7.1V	31a	DO-7	Z-Diode 6.8V	31a
1 N 708		Z-Di	=1N702: 5.6V	31a	DO-7	Z-Diode 5.6V	31a
1 N 709		Z-Di	=1N702: 6.2V	31a	DO-7	Z-Diode 6.2V	31a
1 N 710		Z-Di	=1N702: 6.8V	31a	DO-7	Z-Diode 6.8V	31a
1 N 711		Z-Di	=1N702: 7.5V	31a	DO-7	Z-Diode 7.5V	31a
1 N 712		Z-Di	=1N702: 8.2V	31a	DO-7	Z-Diode 8.2V	31a
1 N 713		Z-Di	=1N702: 9.1V	31a	DO-7	Z-Diode 9.1V	31a
1 N 714		Z-Di	=1N702: 10V	31a	DO-7	Z-Diode 10V	31a
1 N 715		Z-Di	=1N702: 11V	31a	DO-7	Z-Diode 11V	31a
1 N 716		Z-Di	=1N702: 12V	31a	DO-7	Z-Diode 12V	31a
1 N 717		Z-Di	=1N702: 13V	31a	DO-7	Z-Diode 13V	31a
1 N 718		Z-Di	=1N702: 15V	31a	DO-7	Z-Diode 15V	31a
1 N 719		Z-Di	=1N702: 16V	31a	DO-7	Z-Diode 16V	31a
1 N 720		Z-Di	=1N702: 18V	31a	DO-7	Z-Diode 18V	31a
1 N 721		Z-Di	=1N702: 20V	31a	DO-7	Z-Diode 20V	31a
1 N 722		Z-Di	=1N702: 22V	31a	DO-7	Z-Diode 22V	31a
1 N 723		Z-Di	=1N702: 24V	31a	DO-7	Z-Diode 24V	31a
1 N 724		Z-Di	=1N702: 27V	31a	DO-7	Z-Diode 27V	31a
1 N 725		Z-Di	=1N702: 30V	31a	DO-7	Z-Diode 30V	31a
1 N 726		Z-Di	=1N702: 33V	31a	DO-7	Z-Diode 33V	31a
1 N 727		Z-Di	=1N702: 36V	31a	DO-7	Z-Diode 36V	31a
1 N 728		Z-Di	=1N702: 39V	31a	DO-7	Z-Diode 39V	31a

Original	Fabric.	Constr.	Info	{Compl. Fig.	JAEGER	Fig.	International
1 N 729		Z-Di	=1N702: 43V	31a	DO-7	Z-Diode 43V	31a
1 N 730		Z-Di	=1N702: 47V	31a	DO-7	Z-Diode 47V	31a
1 N 731		Z-Di	=1N702: 51V	31a	DO-7	Z-Diode 51V	31a
1 N 732		Z-Di	=1N702: 56V	31a	DO-7	Z-Diode 56V	31a
1 N 733		Z-Di	=1N702: 62V	31a	DO-7	Z-Diode 62V	31a
1 N 734		Z-Di	=1N702: 68V	31a	DO-7	Z-Diode 68V	31a
1 N 735		Z-Di	=1N702: 75V	31a	DO-7	Z-Diode 75V	31a
1 N 736		Z-Di	=1N702: 82V	31a	DO-7	Z-Diode 82V	31a
1 N 737		Z-Di	=1N702: 91V	31a	DO-7	Z-Diode 91V	31a
1 N 738		Z-Di	=1N702: 100V	31a	DO-7	Z-Diode 100V	31a
1 N 739		Z-Di	=1N702: 110V	31a	DO-7	Z-Diode 110V	31a
1 N 740		Z-Di	=1N702: 120V	31a	DO-7	Z-Diode 120V	31a
1 N 741		Z-Di	=1N702: 130V	31a	DO-7	Z-Diode 130V	31a
1 N 742		Z-Di	=1N702: 150V	31a	DO-7	Z-Diode 150V	31a
1 N 743		Z-Di	=1N702: 160V	31a	DO-7	Z-Diode 160V	31a
1 N 744		Z-Di	=1N702: 180V	31a	DO-7	Z-Diode 180V	31a
1 N 745		Z-Di	=1N702: 200V	31a	DO-7	Z-Diode 200V	31a
1 N 702A...745A		Z-Di	=1N702...745: 5%	31a	DO-7		
1 N 702B...745B		Z-Di	=1N702...745: 20%	31a	DO-7		
1 N 746	USA,Tho	Z-Di	3.3V, 10%, 0.4W	31a	DO-7	Z-Diode 3.3V	31a BZX55/..., BZX83/..., ZPD..., 1N5226...42,++
1 N 747		Z-Di	=1N746: 3.6V	31a	DO-7	Z-Diode 3.6V	31a
1 N 748		Z-Di	=1N746: 3.9V	31a	DO-7	Z-Diode 3.9V	31a
1 N 749		Z-Di	=1N746: 4.3V	31a	DO-7	Z-Diode 4.3V	31a
1 N 750		Z-Di	=1N746: 4.7V	31a	DO-7	Z-Diode 4.7V	31a
1 N 751		Z-Di	=1N746: 5.1V	31a	DO-7	Z-Diode 5.1V	31a
1 N 752		Z-Di	=1N746: 5.6V	31a	DO-7	Z-Diode 5.6V	31a
1 N 753		Z-Di	=1N746: 6.2V	31a	DO-7	Z-Diode 6.2V	31a
1 N 754		Z-Di	=1N746: 6.8V	31a	DO-7	Z-Diode 6.8V	31a
1 N 755		Z-Di	=1N746: 7.5V	31a	DO-7	Z-Diode 7.5V	31a
1 N 756		Z-Di	=1N746: 8.2V	31a	DO-7	Z-Diode 8.2V	31a
1 N 757		Z-Di	=1N746: 9.1V	31a	DO-7	Z-Diode 9.1V	31a
1 N 758		Z-Di	=1N746: 10V	31a	DO-7	Z-Diode 10V	31a
1 N 759		Z-Di	=1N746: 12V	31a	DO-7	Z-Diode 12V	31a
1 N 746A...759A		Z-Di	=1N746...759: 5%	31a	DO-7		
1 N 760	USA	Ge-Di	S, 60V, 100ns	31a	DO-7		1N631, 1N633
1 N 761	Mot,Tix,++	Z-Di	4.85V, 10%, 0.25W	31a	DO-7		BZX55/..., BZX79/..., ZPD..., 1N5230...52,++
1 N 762		Z-Di	=1N761: 5.8V	31a	DO-7		
1 N 763		Z-Di	=1N761: 7.1V	31a	DO-7		
1 N 764		Z-Di	=1N761: 8.75V	31a	DO-7		
1 N 765		Z-Di	=1N761: 10.5V	31a	DO-7		
1 N 766		Z-Di	=1N761: 12.7V	31a	DO-7		
1 N 767		Z-Di	=1N761: 15.7V	31a	DO-7		
1 N 768		Z-Di	=1N761: 19V	31a	DO-7		
1 N 769		Z-Di	=1N761: 23.5V	31a	DO-7		
1 N 761A...769A		Z-Di	=1N761...769: 5%	31a	DO-7		
1 N 770	USA	Ge-Di	S, 20V, 40mA, 350ns	31a	DO-7		AAY 29, 1N191...192
1 N 771(A,B)	USA,Gie	Ge-Di	Uni, 100V, 50...75mA	31a	DO-7		AA 117...118, AA 132...133
1 N 772(A)	USA,Gie	Ge-Di	Uni, 80V, 50...65mA	31a	DO-7		AA 117...118, AA 132...133
1 N 773(A)	USA,Gie	Ge-Di	Uni, 75V, 50...65mA	31a	DO-7		AA 117...118, AA 132...134, 1N34, 1N54, ++
1 N 774(A)	USA,Gie	Ge-Di	Uni, 70V, 50...65mA	31a	DO-7		AA 117...118, AA 132...134, 1N34, 1N54, ++
1 N 775	USA,Gie	Ge-Di	Uni, 70V, 50mA	31a	DO-7		AA 117...118, AA 132...134, 1N34, 1N54, ++
1 N 776	USA,Gie	Ge-Di	Uni, 30V, 45mA	31a	DO-7		AA 117...118, AA 132...134, 1N34, 1N54, ++
1 N 777	USA	Ge-Di	S, 75V, 50mA, 500ns	31a	DO-7		AAY 28, 1N276, 1N633
1 N 778	USA	Si-Di	S, 118V, 50mA, 300ns	31a	DO-7		BA 195, BAV 19...21, BAX 15...17, ++
1 N 779	USA	Si-Di	S, 200V, 50mA, 300ns	31a	DO-7		BA 195, BA 197...198, BAV 20...21, BAX 17
1 N 781(A)	USA	Ge-Di	S, 40V, 60mA, <500ns	31a	DO-7		AAY 28, 1N191...192, 1N276
1 N 788	USA	Ge-Di	S, 60V, 200ns	31a	DO-7		-
1 N 789	USA	Si-Di	S, 30V, 0.12A, <500ns	31a	DO-7		BA 195, BAV 17...21, BAX 15...17, 1N3070++
1 N 790	USA	Si-Di	S, 30V, 0.12A, <250ns	31a	DO-7		BA 195, BAV 17...21, BAX 15...17, 1N3070++
1 N 791	USA	Si-Di	S, 30V, 0.16A, <500ns	31a	DO-7		BA 195, BAV 17...21, BAX 15...17, 1N3070++
1 N 792	USA	Si-Di	S, 30V, 0.2A, <500ns	31a	DO-7		BA 195, BAV 17...21, BAX 15...17, 1N3070++
1 N 793	USA	Si-Di	S, 60V, 0.12A, <500ns	31a	DO-7		BA 195, BAV 18...21, BAX 15...17, 1N3070++
1 N 794	USA	Si-Di	S, 60V, 0.12A, <250ns	31a	DO-7		BA 195, BAV 18...21, BAX 15...17, 1N3070++
1 N 795	USA	Si-Di	S, 60V, 0.16A, <500ns	31a	DO-7		BA 195, BAV 18...21, BAX 15...17, 1N3070++
1 N 796	USA	Si-Di	S, 60V, 0.2A, <500ns	31a	DO-7		BA 195, BAV 18...21, BAX 15...17, 1N3070++
1 N 797	USA	Si-Di	S, 120V, 0.12A, <500ns	31a	DO-7		BA 195, BAV 19...21, BAX 15...17, 1N3070++
1 N 798	USA	Si-Di	S, 120V, 0.12A, <250ns	31a	DO-7		BA 195, BAV 19...21, BAX 15...17, 1N3070++
1 N 799	USA	Si-Di	S, 120V, 0.16A, <500ns	31a	DO-7		BA 195, BAV 19...21, BAX 15...17, 1N3070++
1 N 800	USA	Si-Di	S, 120V, 0.2A, <500ns	31a	DO-7		BA 195, BAV 19...21, BAX 15...17, 1N3070++
1 N 801	USA	Si-Di	S, 150V, 0.12A, <500ns	31a	DO-7		BA 195, BAV 20...21, BAX 15...17, 1N3070++
1 N 802	USA	Si-Di	S, 150V, 0.16A, <500ns	31a	DO-7		BA 195, BAV 20...21, BAX 15...17, 1N3070++
1 N 803	USA	Si-Di	S, 200V, 0.12A, <500ns	31a	DO-7		BA 195, BA 197...198, BAV 20...21, ++
1 N 804	USA	Si-Di	S, 200V, 0.16A, <500ns	31a	DO-7		BA 195, BA 197...198, BAV 20...21, ++
1 N 805	USA	Ge-Di	Uni, 40V	31a	DO-7		AA 117...118, AA 132...134, 1N34, 1N54, ++
1 N 806	USA	Si-Di	S, 125V, 60mA, <300ns	31a	DO-7		BA 195, BAV 19...21, BAX 15...17, 1N3070++
1 N 807	USA	Si-Di	S, 200V, 60mA, <300ns	31a	DO-7		BA 195, BA 197...198, BAV 20...21, BAX 17
1 N 808	USA	Si-Di	S, 110V, 100mA, <300ns	31a	DO-7		BA 195, BAV 19...21, BAX 15...17, 1N3070++
1 N 809	USA	Si-Di	S, 220V, 100mA, <300ns	31a	DO-7		BA 195, BA 197...198, BAV 20...21, BAX 17
1 N 810	USA	Si-Di	S, 50V, <50ns	~34a			BY 208/600, BY 295/150, BY 406...407, ++
1 N 811	USA	Si-Di	S, 30V, 0.04A, <250ns	31a	DO-7		BAV 17...21, BAX 15...17, 1N3070, ++
1 N 812	USA	Si-Di	S, 40V, 0.06A, <250ns	31a	DO-7		BAV 18...21, BAX 15...17, 1N3070, ++
1 N 813	USA	Si-Di	S, 20V, 0.075A, <250ns	31a	DO-7		BAV 17...21, BAX 15...17, 1N3070, ++
1 N 814	USA	Si-Di	S, 50V, 0.06A, <250ns	31a	DO-7		BAV 18...21, BAX 15...17, 1N3070, ++
1 N 815	USA	Si-Di	S, 25V, 0.12A, <250ns	31a	DO-7		BAV 17...21, BAX 15...17, 1N3070, ++
1 N 816	USA,Mot	Si-St	0.15A, Uf=0.58...0.7V(1mA), 50Ω	31a	DO-7		BA 220, BZ 102/0V7, BZX55/COV8, BZX62,++
1 N 817	old	Si-Di	S, 200V, <1μs	31a	DO-7		BA 147/230, BA 190, 1N5195...96, ++
1 N 818	USA	Si-Di	S, 80V, 0.055A, <500ns	31a	DO-7		BA 195, BAV 19...20, BAX 15...17, 1N3070++
1 N 819		Si-Di	80V				
1 N 821(A)	USA,EUR	Ref-Di	6.2V(7.5mA), 5%, ±0.01%/°C, <15Ω, 0.25W, A=hi-rel	31a	DO-7,DO-35		BZV 10, BZV 27, BZX 90, 1N4575, 1N4580
1 N 822(A)		Ref-Di	=1N821: bidirectional	31a	DO-7		-
1 N 823(A)		Ref-Di	=1N821: ±0.005%/°C	31a	DO-7,DO-35		BZV 11, BZV 28, BZX 91, 1N4576, 1N4581++
1 N 824(A)		Ref-Di	=1N823: bidirectional	31a	DO-7		-
1 N 825(A)		Ref-Di	=1N821: ±0.002%/°C	31a	DO-7,DO-35		BZV 12, BZV 29, BZX 92, 1N4577, 1N4582

Original	Fabric.	Constr.	Info	(Compl. Fig.	JAEGER	Fig.	International
1 N 826(A)		Ref-Di	=1N821: 6.55V(7.5mA), ±0.002%/°C	31a			BZV 12, BZV 29, BZX 92, 1N4577, 1N4582
1 N 827(A)		Ref-Di	=1N821: ±0.001%/°C	31a			BZV 13, BZV 30, BZX 93, 1N4578, 1N4583
1 N 828(A)		Ref-Di	=1N821: 6.55V(7.5mA), ±0.001%/°C	31a			BZV 13, BZV 30, BZX 93, 1N4578, 1N4583
1 N 829(A)		Ref-Di	=1N821: ±0.0005%/°C	31a			BZV 14, BZV 51, BZX 94, 1N4579, 1N4584
1 N 830(A)	USA	Si-Di	UHF Dem	31a			-
1 N 831(A,B,C)	USA	Si-Di	UHF, S-Band Mx	31a			-
1 N 832(A,B,C)	USA	Si-Di	UHF, X-Band Mx	31a			-
1 N 833(A)	USA	Si-Di	UHF, X-Band Dem	31a			-
1 N 835	USA	Ge-Di	S, 30V, 70mA, <500ns	31a			AAY 49, AAZ 15, AAZ 17
1 N 836	old	Ge-Di	UHF, 5V	31a			-
1 N 837(A)	USA	Si-Di	S, 100V, 0.1A, <500ns	31a			BA 195, BAV 19...21, BAX 15...17, 1N3070++
1 N 838	USA	Si-Di	S, 150V, 0.1A, <500ns	31a			BA 195, BAV 20...21, BAX 15...17, 1N3070++
1 N 839	USA	Si-Di	S, 200V, 0.1A, <500ns	31a			BA 195, BA 197...198, BAV 20...21, BAX 17
1 N 840	USA	Si-Di	S, 50V, 0.1A, <300ns	31a			BA 195, BAV 18...21, BAX 15...17, 1N3070++
1 N 841	USA	Si-Di	S, 150V, 0.1A, <300ns	31a			BA 195, BAV 20...21, BAX 15...17, 1N3070++
1 N 842	USA	Si-Di	S, 200V, 0.1A, <300ns	31a			BA 195, BA 197...198, BAV 20...21, BAX 17
1 N 843	USA	Si-Di	S, 250V, 0.1A, <300ns	31a			BA 198, BAV 21, BAW 173
1 N 844	USA	Si-Di	S, 100V, 0.2A, <500ns	31a			BA 195, BAV 19...21, BAX 15...17, 1N3070++
1 N 845	USA	Si-Di	S, 200V, 0.2A, <500ns	31a			BA 195, BA 197...198, BAV 19...21, BAX 17
1 N 846	USA	Si-Di	Rr, Uni, 50V, 0.2A	31a			BA 157...159, BAY 86...90, BY 204/4, ++
1 N 847		Si-Di	=1N846: 100V	31a			BA 157...159, BAY 87...90, BY 204/4, ++
1 N 848		Si-Di	=1N846: 200V	31a			BA 157...159, BAY 88...90, BY 204/4, ++
1 N 849		Si-Di	=1N846: 300V	31a			BA 157...159, BAY 89...90, BY 204/4, ++
1 N 850		Si-Di	=1N846: 400V	31a			BA 157...159, BAY 89...90, BY 204/4, ++
1 N 851		Si-Di	=1N846: 500V	31a			BA 158...159, BAY 89...90, BY 204/8, ++
1 N 852		Si-Di	=1N846: 600V	31a			BA 158...159, BAY 89...90, BY 204/8, ++
1 N 853		Si-Di	=1N846: 700V	31a			BA 158...159, BAY 90...91, BY 204/8, ++
1 N 854		Si-Di	=1N846: 800V	31a			BA 158...159, BAY 90...91, BY 204/8, ++
1 N 855		Si-Di	=1N846: 900V	31a			BA 159, BAY 90...91, BY 204/10, ++
1 N 856		Si-Di	=1N846: 1000V	31a			BA 159, BAY 90...91, BY 204/10, ++
1 N 857	USA	Si-Di	Rr, Uni, 50V, 0.15A	31a			BA 157...159, BAY 86...90, BY 204/4, ++
1 N 858		Si-Di	=1N857: 100V	31a			BA 157...159, BAY 87...90, BY 204/4, ++
1 N 859		Si-Di	=1N857: 200V	31a			BA 157...159, BAY 88...90, BY 204/4, ++
1 N 860		Si-Di	=1N857: 300V	31a			BA 157...159, BAY 88...90, BY 204/4, ++
1 N 861		Si-Di	=1N857: 400V	31a			BA 157...159, BAY 89...90, BY 204/4, ++
1 N 862		Si-Di	=1N857: 500V	31a			BA 157...159, BAY 89...90, BY 204/4, ++
1 N 863		Si-Di	=1N857: 600V	31a			BA 158...159, BAY 89...90, BY 204/8, ++
1 N 864		Si-Di	=1N857: 700V	31a			BA 158...159, BAY 89...90, BY 204/8, ++
1 N 865		Si-Di	=1N857: 800V	31a			BA 158...159, BAY 90...91, BY 204/8, ++
1 N 866		Si-Di	=1N857: 900V	31a			BA 158...159, BAY 90...91, BY 204/8, ++
1 N 867		Si-Di	=1N857: 1000V	31a			BA 159, BAY 90...91, BY 204/10, ++
1 N 868	USA	Si-Di	Rr, Uni, 50V, 0.1A	31a			BA 157...159, BAY 86...90, BY 204/4, ++
1 N 869		Si-Di	=1N868: 100V	31a			BA 157...159, BAY 87...90, BY 204/4, ++
1 N 870		Si-Di	=1N868: 200V	31a			BA 157...159, BAY 88...90, BY 204/4, ++
1 N 871		Si-Di	=1N868: 300V	31a			BA 157...159, BAY 88...90, BY 204/4, ++
1 N 872		Si-Di	=1N868: 400V	31a			BA 157...159, BAY 89...90, BY 204/4, ++
1 N 873		Si-Di	=1N868: 500V	31a			BA 158...159, BAY 89...90, BY 204/8, ++
1 N 874		Si-Di	=1N868: 600V	31a			BA 158...159, BAY 89...90, BY 204/8, ++
1 N 875		Si-Di	=1N868: 700V	31a			BA 158...159, BAY 90...91, BY 204/8, ++
1 N 876		Si-Di	=1N868: 800V	31a			BA 158...159, BAY 90...91, BY 204/8, ++
1 N 877		Si-Di	=1N868: 900V	31a			BA 159, BAY 90...91, BY 204/10, ++
1 N 878		Si-Di	=1N868: 1000V	31a			BA 159, BAY 90...91, BY 204/10, ++
1 N 879	USA	Si-Di	Rr, Uni, 50V, 0.05A	31a			BA 157...159, BAY 86...90, BY 204/4, ++
1 N 880		Si-Di	=1N879: 100V	31a			BA 157...159, BAY 87...90, BY 204/4, ++
1 N 881		Si-Di	=1N879: 200V	31a			BA 157...159, BAY 88...90, BY 204/4, ++
1 N 882		Si-Di	=1N879: 300V	31a			BA 157...159, BAY 88...90, BY 204/4, ++
1 N 883		Si-Di	=1N879: 400V	31a			BA 157...159, BAY 89...90, BY 204/4, ++
1 N 884		Si-Di	=1N879: 500V	31a			BA 158...159, BAY 89...90, BY 204/8, ++
1 N 885		Si-Di	=1N879: 600V	31a			BA 158...159, BAY 89...90, BY 204/8, ++
1 N 886		Si-Di	=1N879: 700V	31a			BA 158...159, BAY 90...91, BY 204/8, ++
1 N 887		Si-Di	=1N879: 800V	31a			BA 158...159, BAY 90...91, BY 204/8, ++
1 N 888		Si-Di	=1N879: 900V	31a			BA 159, BAY 90...91, BY 204/10, ++
1 N 889		Si-Di	=1N879: 1000V	31a			BA 159, BAY 90...91, BY 204/10, ++
1 N 890	USA	Si-Di	Uni, 80V, 0.1A	31a			BA 147/100, BA 188...190, 1N5606...09, ++
1 N 891	USA	Si-Di	S, 60V, 0.2A, 300ns	31a			BA 197...198, BAV 18...21, BAX 15...17, ++
1 N 892	USA	Si-Di	S, 120V, 0.2A, 300ns	31a			BA 197...198, BAV 20...21, BAX 15...17, ++
1 N 893	USA	Si-Di	S, 240V, 0.2A, 300ns	31a			BA 173, BA 198, BAV 21
1 N 894	old	Ge-Di	UHF, 5V				-
1 N 895	old	Ge-Di	UHF, 5V				-
1 N 896	old	Ge-Di	UHF, 5V				-
1 N 897	Sem	Si-Di	Min, S, Uni, 50V, 0.03A, <1µs	31a			(BAX 85, BAX 89, BAX 90, BAX 94,++) ⁶
1 N 898	Sem	Si-Di	Min, S, Uni, 50V, 0.06A, <300ns	31a			(BAX 85, BAX 89, BAX 90, BAX 94,++) ⁶
1 N 899	Sem	Si-Di	Min, S, Uni, 100V, 0.03A, <300ns	31a			(BA 197...198, BAV 19...21, BAX 15...17,++) ⁶
1 N 900	Sem	Si-Di	Min, S, Uni, 100V, 0.05A, <300ns	31a			(BA 197...198, BAV 19...21, BAX 15...17,++) ⁶
1 N 901	Sem	Si-Di	Min, S, Uni, 100V, 0.06A, <300ns	31a			(BA 197...198, BAV 19...21, BAX 15...17,++) ⁶
1 N 902	Sem	Si-Di	Min, S, Uni, 200V, 0.03A, <300ns	31a			(BA 197...198, BAV 20...21, BAX 17,++) ⁶
1 N 903(A)	USA,Sgs	Si-Di	S, 20...40V, 0.05...0.075A, <4ns	31a			BA 218, BAX 13, BAX 91, 1N4148, ++
1 N 904(A)	USA,Sgs	Si-Di	S, 30V, 0.05...0.075A, <4ns	31a			BA 218, BAX 13, BAX 91, 1N4148, ++
1 N 905(A)	USA,Sgs	Si-Di	S, 20V, 0.05...0.075A, <4ns	31a			BA 218, BAX 13, BAX 91, 1N4148, ++
1 N 906(A)	USA,Sgs	Si-Di	S, 20V, 0.05...0.075A, <4ns	31a			BA 218, BAX 13, BAX 91, 1N4148, ++
1 N 907(A)	USA,Sgs	Si-Di	S, 30V, 0.05...0.075A, <4ns	31a			BA 218, BAX 13, BAX 91, 1N4148, ++
1 N 908(A)	USA,Sgs	Si-Di	S, 40V, 0.05...0.075A, <4ns	31a			BA 218, BAX 13, BAX 91, 1N4148, ++
1 N 909	USA	Ge-Di	Uni, 60V, 100mA	31a			AA 136, 1N270, 1N634...635
1 N 910		Ge-Di	=1N909: 30V	31a			AA 135...136, 1N270, 1N634...635
1 N 911		Ge-Di	=1N909: 30V	31a			AA 135...136, 1N270, 1N634...635
1 N 912(A)	USA	Ref-Di	0.62V, 10%, ±0.0032%/°C, <60Ω, 0.5W, (A=5%)	31a			-
1 N 913(A)	USA	Ref-Di	=1N912(A), 0.6W	31a			-
1 N 914(A,B)	USA, EUR, JAP	Si-Di	SS, 75/100V, 75/225mA, Uf<1V(10mA), <4ns A: Uf<1V(20mA), B: Uf<1V(100mA)	31a		1N4148	31a BAW 62, BAX 95, 1N4148...49, 1N4151, ++
1 N 915	Hit,Tix	Si-Di	S, 50/65V, 75/225mA, Uf<1V(50mA), <10ns	31a		1N4148	31a BAW 62, BAX 95, 1N4148...49, 1N4151, ++
1 N 916(A,B)	USA, EUR, JAP	Si-Di	SS, 75/100V, 75/225mA, Uf<1V(10mA), <4ns A: Uf<1V(20mA), B: Uf<1V(30mA)	31a		1N4148	31a BAW 62, BAX 95, 1N4148...49, 1N4151, ++
1 N 917	Hit,Tix	Si-Di	SS, 30/40V, 50/150mA, Uf<1V(10mA), <3ns	31a		1N4148	31a BAW 62, BAX 95, 1N4148...49, 1N4151, ++

Original	Fabric.	Constr.	Info	{Compl. Fig.	JAEGER	Fig.	International	
1 N 918	Syl	Si-Di	UHF, Ku-Band Mx	31a	DO-7		-	
1 N 919	USA	Si-Di	S, 150V, 0,1A, <300ns	31a	DO-7		BA 195, BAV 20...21, BAX 15...17, 1N3070++	
1 N 920	USA	Si-Di	S, 36V, 0,25A, <300ns	31a	DO-7		BA 197...189, BAV 17...21, BAX 15...17, ++	
1 N 921	USA	Si-Di	S, 70V, 0,25A, <300ns	31a	DO-7		BA 197...189, BAV 19...21, BAX 15...17, ++	
1 N 922	USA	Si-Di	S, 100V, 0,25A, <300ns	31a	DO-7		BA 197...189, BAV 19...21, BAX 15...17, ++	
1 N 923	USA	Si-Di	S, 130V, 0,25A, <300ns	31a	DO-7		BA 197...189, BAV 19...21, BAX 15...17, ++	
1 N 924	USA	Si-Di	Uni, S, 60V, 2µs	31a	DO-7		BA 127, BA 188...190, BAY 19...21, ++	
1 N 925	USA	Si-Di	S, 40V, 0,12A, <150ns	31a	DO-7		BA 195, BAX 16...17, BAY 41...43, 1N3070++	
1 N 926	USA	Si-Di	S, 40V, 0,12A, <150ns	31a	DO-7		BA 195, BAX 16...17, BAY 41...43, 1N3070++	
1 N 927	USA	Si-Di	S, 65V, 0,12A, <150ns	31a	DO-7		BA 195, BAX 16...17, BAY 42...43, 1N3070++	
1 N 928		Si-Di	=1N927: 120V	31a	DO-7		BA 195, BAX 16...17, BAY 19...21, 1N3070++	
1 N 929	USA	Si-Di	Uni, 23V, 0,25A	31a	DO-7		BA 192...194, BAW 51...52, BAY 17...21, ++	
1 N 930	USA	Si-Di	Uni, 58V, 0,25A	31a	DO-7		BA 193...194, BAW 51...52, BAY 19...21, ++	
1 N 931	USA	Si-Di	Uni, 115V, 0,25A	31a	DO-7		BA 194, BAW 52, BAY 20...21, BAY 45, ++	
1 N 932	USA	Si-Di	Uni, 230V, 0,25A	31a	DO-7		BA 199/250, BAY 21, BAY 46, BAY 88, ++	
1 N 933	USA	Ge-Di	S, 100V, 30mA, <400ns	31a	DO-7		AAY 28, AAZ 15, 1N633	
1 N 934	USA	Si-Di	S, 60V, 30mA, 1µs	31a	DO-7		BA 127, BA 147/100, BA 188...190, ++	
1 N 935(A,B)	USA, EUR	Ref-Di	9V(7,5mA), 5%, ±0,01%/°C, <20Ω, 0,5W, 0...+75° A: -55...+100°, B: -55...+150°	31a	DO-7, DO-35		1N4765	
1 N 936(A,B)		Ref-Di	=1N935: ±0,005%/°C	31a	DO-7, DO-35		1N4766, 1N4771	
1 N 937(A,B)		Ref-Di	=1N935: ±0,002%/°C	31a	DO-7, DO-35		1N4767, 1N4772	
1 N 938(A,B)		Ref-Di	=1N935: ±0,001%/°C	31a	DO-7, DO-35		1N4768, 1N4773	
1 N 939(A,B)		Ref-Di	=1N935: ±0,0005%/°C	31a	DO-7, DO-35		1N4769, 1N4774	
1 N 940(A,B)		Ref-Di	=1N935: ±0,0002%/°C	31a	DO-7, DO-35		-	
1 N 941(A,B)	USA, JAP	Ref-Di	11,7V(7,5mA), 5%, ±0,01%/°C, <30Ω, 0,5W, 0...+75° A: -55...+100°, B: -55...+150°	31a	DO-7		1N3580	
1 N 942(A,B)		Ref-Di	=1N941: ±0,005%/°C	31a	DO-7		1N3581	
1 N 943(A,B)		Ref-Di	=1B941: ±0,002%/°C	31a	DO-7		1N3582	
1 N 944(A,B)		Ref-Di	=1N941: ±0,001%/°C	31a	DO-7		1N3583	
1 N 945(A,B)		Ref-Di	=1N941: ±0,0005%/°C	31a	DO-7		1N3584	
1 N 946(A,B)		Ref-Di	=1N941: ±0,0002%/°C	31a	DO-7		-	
1 N 947	USA	Si-Di	Rr, 600V, 0,4A	=34a	=DO-1		BA 158...159, BY 204/8, BY 207, BY 405, ++	
1 N 948	USA	Si-Di	S, 36V, 0,08A, <1µs	31a	DO-7		BA 127, BA 147/50, BA 187...190, ++	
1 N 949	USA	Ge-Di	Uni, 50V, 0,5A(ss)	31a	DO-7		AA 117...118, AA 132...134, 1N34, 1N54, ++	
1 N 950(A)	USA	Si-Di	VHF Tuning, 130V, 6...88pF	31a	DO-7		-	
1 N 951(A)	USA	Si-Di	VHF Tuning, 80V, 12...120pF	31a	DO-7		-	
1 N 952(A)	USA	Si-Di	VHF Tuning, 60V, 20...170pF	31a	DO-7		-	
1 N 953(A)	USA	Si-Di	VHF Tuning, 25V, 46...240pF	31a	DO-7		-	
1 N 954	USA	Si-Di	VHF Tuning, 25V, 14...88pF	31a	DO-7		-	
1 N 955	USA	Si-Di	VHF Tuning, 25V, 22...120pF	31a	DO-7		-	
1 N 956	USA	Si-Di	VHF Tuning, 25V, 32...170pF	31a	DO-7		-	
1 N 957	USA, EUR, JAP	Z-Di	6,8V, 20%, 0,4W	31a	DO-7	Z-Diode 6,8V	31a	BZX55/..., BZX83/..., ZPD..., 1N5235...81, ++
1 N 958		Z-Di	=1N957: 7,5V	31a	DO-7	Z-Diode 7,5V	31a	
1 N 959		Z-Di	=1N957: 8,2V	31a	DO-7	Z-Diode 8,2V	31a	
1 N 960		Z-Di	=1N957: 9,1V	31a	DO-7	Z-Diode 9,1V	31a	
1 N 961		Z-Di	=1N957: 10V	31a	DO-7	Z-Diode 10V	31a	
1 N 962		Z-Di	=1N957: 11V	31a	DO-7	Z-Diode 11V	31a	
1 N 963		Z-Di	=1N957: 12V	31a	DO-7	Z-Diode 12V	31a	
1 N 964		Z-Di	=1N957: 13V	31a	DO-7	Z-Diode 13V	31a	
1 N 965		Z-Di	=1N957: 15V	31a	DO-7	Z-Diode 15V	31a	
1 N 966		Z-Di	=1N957: 16V	31a	DO-7	Z-Diode 16V	31a	
1 N 967		Z-Di	=1N957: 18V	31a	DO-7	Z-Diode 18V	31a	
1 N 968		Z-Di	=1N957: 20V	31a	DO-7	Z-Diode 20V	31a	
1 N 969		Z-Di	=1N957: 22V	31a	DO-7	Z-Diode 22V	31a	
1 N 970		Z-Di	=1N957: 24V	31a	DO-7	Z-Diode 24V	31a	
1 N 971		Z-Di	=1N957: 27V	31a	DO-7	Z-Diode 27V	31a	
1 N 972		Z-Di	=1N957: 30V	31a	DO-7	Z-Diode 30V	31a	
1 N 973		Z-Di	=1N957: 33V	31a	DO-7	Z-Diode 33V	31a	
1 N 974		Z-Di	=1N957: 36V	31a	DO-7	Z-Diode 36V	31a	
1 N 975		Z-Di	=1N957: 39V	31a	DO-7	Z-Diode 39V	31a	
1 N 976		Z-Di	=1N957: 43V	31a	DO-7	Z-Diode 43V	31a	
1 N 977		Z-Di	=1N957: 47V	31a	DO-7	Z-Diode 47V	31a	
1 N 978		Z-Di	=1N957: 51V	31a	DO-7	Z-Diode 51V	31a	
1 N 979		Z-Di	=1N957: 56V	31a	DO-7	Z-Diode 56V	31a	
1 N 980		Z-Di	=1N957: 62V	31a	DO-7	Z-Diode 62V	31a	
1 N 981		Z-Di	=1N957: 68V	31a	DO-7	Z-Diode 68V	31a	
1 N 982		Z-Di	=1N957: 75V	31a	DO-7	Z-Diode 75V	31a	
1 N 983		Z-Di	=1N957: 82V	31a	DO-7	Z-Diode 82V	31a	
1 N 984		Z-Di	=1N957: 91V	31a	DO-7	Z-Diode 91V	31a	
1 N 985		Z-Di	=1N957: 100V	31a	DO-7	Z-Diode 100V	31a	
1 N 986		Z-Di	=1N957: 110V	31a	DO-7	Z-Diode 110V	31a	
1 N 987		Z-Di	=1N957: 120V	31a	DO-7	Z-Diode 120V	31a	
1 N 988		Z-Di	=1N957: 130V	31a	DO-7	Z-Diode 130V	31a	
1 N 989		Z-Di	=1N957: 150V	31a	DO-7	Z-Diode 150V	31a	
1 N 990		Z-Di	=1N957: 160V	31a	DO-7	Z-Diode 160V	31a	
1 N 991		Z-Di	=1N957: 180V	31a	DO-7	Z-Diode 180V	31a	
1 N 992		Z-Di	=1N957: 200V	31a	DO-7	Z-Diode 200V	31a	
1 N 957A...992A		Z-Di	=1N957...992: 10%	31a	DO-7			
1 N 957B...992B		Z-Di	=1N957...992: 5%	31a	DO-7			
1 N 993	USA	Si-Di	SS, 20V, 0,02A, <4ns	31a	DO-7		BA 218, BAX 13, BAX 91, 1N4148...49, ++	
1 N 994	USA	Ge-Di	SS, 6,5V, 0,02A, <2ns	31a	DO-7		-	
1 N 995	USA	Ge-Di	SS, 10V, 0,03A, <6ns	31a	DO-7		-	
1 N 996	USA	Ge-Di	S, 20V, 0,05A, <300ns	31a	DO-7		AAY 27...28, 1N631, 1N633, 1N3592	
1 N 997	USA	Si-Di	S, 35V, 0,05A, 150ns	31a	DO-7		BAX 85, BAX 89...90, BAX 94, 1N4148, ++	
1 N 998	USA	Si-Di	Rr, Uni, 150V	31a	DO-7		BA 157...159, BA 194, BAS 11, BAW 52, ++	
1 N 999	USA	Si-Di	SS, 100V, <4ns	31a	DO-7		BA 219, BAX 96	
1 N 1005		Ge-Di	Rr, 380V, 0,25A				-	
1 N 1007		Ge-Di	Rr, 380V, 0,35A				-	
1 N 1008		Ge-Di	Rr, 380V, 0,4A				-	
1 N 1013		Ge-Di	Rr, 380V, 0,25A				-	
1 N 1016		Ge-Di	Rr, 380V, 0,4A				-	
1 N 1021		Ge-Di	Rr, 380V, 0,25A				-	
1 N 1022		Ge-Di	Rr, 380V, 0,3A				-	

Original	Fabric.	Constr.	Info	(Compl. Fig.	JAEGER	Fig.	International
1 N 1023		Ge-Di	Rr, 380V, 0,35A				-
1 N 1024		Ge-Di	Rr, 380V, 0,4A				-
1 N 1028	USA	Si-Di	Rr, 50V, 0,5A(Ta=100°), Uf<1,5V(0,5A)	-34a	=D0-1		BY 126...127, BY 133...135, 1N4001...07, ++
1 N 1029		Si-Di	=1N1028: 100V	-34a	=D0-1		BY 126...127, BY 133...135, 1N4002...07, ++
1 N 1030		Si-Di	=1N1028: 150V	-34a	=D0-1		BY 126...127, BY 133...135, 1N4003...07, ++
1 N 1031		Si-Di	=1N1028: 200V	-34a	=D0-1		BY 126...127, BY 133...134, 1N4003...07, ++
1 N 1032		Si-Di	=1N1028: 300V	-34a	=D0-1		BY 126...127, BY 133...134, 1N4004...07, ++
1 N 1033		Si-Di	=1N1028: 400V	-34a	=D0-1		BY 126...127, BY 133...134, 1N4004...07, ++
1 N 1034	USA	Si-Di	P Rr, 50V, 1A(Tc=100°), Uf<1,5V(1A)	-32b	=D0-4		BYX 38/300R, BYX 39/600R
1 N 1035		Si-Di	=1N1034: 100V	-32b	=D0-4		BYX 38/300R, BYX 39/600R
1 N 1036		Si-Di	=1N1034: 150V	-32b	=D0-4		BYX 38/300R, BYX 39/600R
1 N 1037		Si-Di	=1N1034: 200V	-32b	=D0-4		BYX 38/300R, BYX 39/600R
1 N 1038		Si-Di	=1N1034: 300V	-32b	=D0-4		BYX 38/300R, BYX 39/600R
1 N 1039		Si-Di	=1N1034: 400V	-32b	=D0-4		BYX 38/600R, BYX 39/600R
1 N 1040	USA	Si-Di	P Rr, 50V, 1A(Tc=100°), Uf<1,5V(1A)	-32b	=D0-4		BYX 38/300R, BYX 39/600R
1 N 1041		Si-Di	=1N1040: 100V	-32b	=D0-4		BYX 38/300R, BYX 39/600R
1 N 1042		Si-Di	=1N1040: 150V	-32b	=D0-4		BYX 38/300R, BYX 39/600R
1 N 1043		Si-Di	=1N1040: 200V	-32b	=D0-4		BYX 38/300R, BYX 39/600R
1 N 1044		Si-Di	=1N1040: 300V	-32b	=D0-4		BYX 38/300R, BYX 39/600R
1 N 1045		Si-Di	=1N1040: 400V	-32b	=D0-4		BYX 38/600R, BYX 39/600R
1 N 1046	USA	Si-Di	Rr, 50V, 1A(Tc=100°), Uf<1,5V(1A)				-
1 N 1047		Si-Di	=1N1046: 100V				-
1 N 1048		Si-Di	=1N1046: 150V				-
1 N 1049		Si-Di	=1N1046: 200V				-
1 N 1050		Si-Di	=1N1046: 300V				-
1 N 1051		Si-Di	=1N1046: 400V				-
1 N 1052	USA	Si-Di	Rr, 50V, 1,5A(Tc=100°), Uf<1,5V(1,5A)	-34a	=D0-13		BYW 52...56, BYX 82...87, 1N5391...97, ++
1 N 1053		Si-Di	=1N1052: 100V	-34a	=D0-13		BYW 52...56, BYX 82...87, 1N5392...97, ++
1 N 1054		Si-Di	=1N1052: 150V	-34a	=D0-13		BYW 52...56, BYX 82...87, 1N5393...97, ++
1 N 1055		Si-Di	=1N1052: 200V	-34a	=D0-13		BYW 52...56, BYX 82...87, 1N5393...97, ++
1 N 1056		Si-Di	=1N1052: 300V	-34a	=D0-13		BYW 53...56, BYX 83...87, 1N5394...97, ++
1 N 1057		Si-Di	=1N1052: 400V	-34a	=D0-13		BYW 53...56, BYX 83...87, 1N5395...97, ++
1 N 1058	USA	Si-Di	P Rr, 50V, 5A(Tc=100°), Uf<1,5V(5A)	32b	D0-4		BYX 38/300R, BYX 39/600R
1 N 1059		Si-Di	=1N1058: 100V	32b	D0-4		BYX 38/300R, BYX 39/600R
1 N 1060		Si-Di	=1N1058: 150V	32b	D0-4		BYX 38/300R, BYX 39/600R
1 N 1061		Si-Di	=1N1058: 200V	32b	D0-4		BYX 38/300R, BYX 39/600R
1 N 1062		Si-Di	=1N1058: 300V	32b	D0-4		BYX 38/300R, BYX 39/600R
1 N 1063		Si-Di	=1N1058: 400V	32b	D0-4		BYX 38/600R, BYX 39/600R
1 N 1064	USA	Si-Di	P Rr, 50V, 5A(Tc=100°), Uf<1,5V(5A)	32b	D0-4		BYX 38/300R, BYX 39/600R
1 N 1065		Si-Di	=1N1064: 100V	32b	D0-4		BYX 38/300R, BYX 39/600R
1 N 1066		Si-Di	=1N1064: 150V	32b	D0-4		BYX 38/300R, BYX 39/600R
1 N 1067		Si-Di	=1N1064: 200V	32b	D0-4		BYX 38/300R, BYX 39/600R
1 N 1068		Si-Di	=1N1064: 300V	32b	D0-4		BYX 38/300R, BYX 39/600R
1 N 1069		Si-Di	=1N1064: 400V	32b	D0-4		BYX 38/600R, BYX 39/600R
1 N 1070	USA	Si-Di	P Rr, 50V, 5A(Tc=100°), Uf<1,5V(5A)				-
1 N 1071		Si-Di	=2N1070: 100V				-
1 N 1072		Si-Di	=2N1070: 150V				-
1 N 1073		Si-Di	=2N1070: 200V				-
1 N 1074		Si-Di	=2N1070: 300V				-
1 N 1075		Si-Di	=2N1070: 400V				-
1 N 1076	USA	Si-Di	P Rr, 50V, 15A(Tc=100°), Uf<1,5V(15A)				-
1 N 1077		Si-Di	=1N1076: 100V				-
1 N 1078		Si-Di	=1N1076: 150V				-
1 N 1079		Si-Di	=1N1076: 200V				-
1 N 1080		Si-Di	=1N1076: 300V				-
1 N 1081(A)	USA	Si-Di	Rr, 100V, 0,5A(A=0,75A)(Ta=100°), Uf<1,5V(0,5A)				BY 126...127, BY 133...135, 1N4002...07, ++
1 N 1082(A)		Si-Di	=1N1081(A): 200V				BY 126...127, BY 133...134, 1N4003...07, ++
1 N 1083(A)		Si-Di	=1N1081(A): 300V				BY 126...127, BY 133...134, 1N4004...07, ++
1 N 1084(A)		Si-Di	=1N1081(A): 400V				BY 126...127, BY 133...134, 1N4004...07, ++
1 N 1085(A)	USA	Si-Di	Rr, 100V, 1,5A(A=2A)(Ta=100°), Uf<1,5V(1,5A)				BY 251...255, BYW 52...56, 1N5060...62, ++
1 N 1086(A)		Si-Di	=1N1085: 200V				BY 251...255, BYW 52...56, 1N5060...62, ++
1 N 1087(A)		Si-Di	=1N1085: 300V				BY 252...255, BYW 53...56, 1N5060...62, ++
1 N 1088(A)		Si-Di	=1N1085: 400V				BY 252...255, BYW 53...56, 1N5060...62, ++
1 N 1089(A)	USA	Si-Di	Rr, 100V, 5A(Ta=100°), Uf<1,5V(5A)				BY 214/100, MR 751...760
1 N 1090(A)		Si-Di	=1N1089: 200V				BY 214/200, MR 752...760
1 N 1091(A)		Si-Di	=1N1089: 300V				BY 214/400, MR 754...760
1 N 1092(A)		Si-Di	=1N1089: 400V				BY 214/400, MR 754...760
1 N 1093	USA	Ge-Di	S, 15V, 500ns	31a	D0-7		AAV 27...28, 1N191...192, 1N3592
1 N 1095	Rca,Tix,++	Si-Di	Rr, 500V, 0,75A(Tc=50°)	34a	D0-1		BY 126...127, BY 133...134, 1N4005...07, ++
1 N 1096		Si-Di	=1N1095: 600V	34a	D0-1		BY 126...127, BY 133...134, 1N4005...07, ++
1 N 1100	USA	Si-Di	Rr, 100V, 0,75A(Tc=50°), Uf<1,5V(0,75A)	34a	D0-1		BY 126...127, BY 133...135, 1N4002...07, ++
1 N 1101		Si-Di	=1N1100: 200V	34a	D0-1		BY 126...127, BY 133...134, 1N4003...07, ++
1 N 1102		Si-Di	=1N1100: 300V	34a	D0-1		BY 126...127, BY 133...134, 1N4004...07, ++
1 N 1103		Si-Di	=1N1100: 400V	34a	D0-1		BY 126...127, BY 133...134, 1N4004...07, ++
1 N 1104		Si-Di	=1N1100: 500V	34a	D0-1		BY 126...127, BY 133...134, 1N4005...07, ++
1 N 1105		Si-Di	=1N1100: 600V	34a	D0-1		BY 126...127, BY 133...134, 1N4005...07, ++
1 N 1108	USA	Si-Di	Rr, 800V, 0,45A, Uf<3V				BA 158...159, BY 127, BY 133, BY 268, ++
1 N 1109	USA	Si-Di	Rr, 1200V, 0,43A, Uf<4,5V				BY 127, BY 133, BY 268...269, ++
1 N 1110	USA	Si-Di	Rr, 1600V, 0,4A, Uf<6V				BY 269, BY 400, DM 513, EM 516, GP 10Y
1 N 1111	USA	Si-Di	Rr, 2000V, 0,38A, Uf<7,5V				1N1732A...1734A
1 N 1112	USA	Si-Di	Rr, 2400V, 0,35A, Uf<9V				1N1733A...1734A
1 N 1113	USA	Si-Di	Rr, 2800V, 0,33A, Uf<11V				1N1733A...1734A
1 N 1115	USA,Tix	Si-Di	Rr, 100V, 1,5A(Tc=85°), Uf<1,1A(1A)	32a	D0-4		BYX 38/300, BYX 39/600
1 N 1116		Si-Di	=1N1115: 200V	32a	D0-4		BYX 38/300, BYX 39/600
1 N 1117		Si-Di	=1N1115: 300V	32a	D0-4		BYX 38/300, BYX 39/600
1 N 1118		Si-Di	=1N1115: 400V	32a	D0-4		BYX 38/600, BYX 39/600
1 N 1119		Si-Di	=1N1115: 500V	32a	D0-4		BYX 38/600, BYX 39/600
1 N 1120		Si-Di	=1N1115: 600V	32a	D0-4		BYX 38/600, BYX 39/600
1 N 1115R.....1120R		Si-Di	=1N1115...1120:	32b	D0-4		BYX 38/600R, BYX 39/600R
1 N 1124(A)	USA,Tix	Si-Di	P Rr, 200V, 3A(A=3,3A)(Tc=50°), Uf<1,1V(1A)	32a	D0-4		BYX 38/600, BYX 39/600
1 N 1125(A)		Si-Di	=1N1124(A): 300V	32a	D0-4		BYX 38/600, BYX 39/600
1 N 1126(A)		Si-Di	=1N1124(A): 400V	32a	D0-4		BYX 38/600, BYX 39/600
1 N 1127(A)		Si-Di	=1N1124(A): 500V	32a	D0-4		BYX 38/600, BYX 39/600

Original	Fabric.	Constr.	Info	{Compl. Fig.	JAEGER	Fig.	International
1 N 1128(A)		Si-Di	=1N1124(A): 600V	32a	DO-4		BYX 38/600, BYX 39/600
1 N 1124R...1128R		Si-Di	=1N1124(A)...1128(A):	32b	DO-4		BYX 38/600R, BYX 39/600R
1 N 1130	USA	Si-Di	P Rr, 1500V, 0,3A, Uf<15V(0,3A)	32a	DO-4		-
1 N 1131		Si-Di	=1N1130:	32b	DO-4		-
1 N 1132(R)	USA	Si-Di	UHF, S/X-Band Mx	Koax	SOD-49		-
1 N 1133	USA	Si-Di	kV-Rr, 1,5kV, 0,075A	31a			1N5181
1 N 1134	USA	Si-Di	kV-Rr, 1,5kV, 0,1A	31a			1N5181
1 N 1135	USA	Si-Di	kV-Rr, 1,8kV, 0,065A	31a			1N5181
1 N 1136	USA	Si-Di	kV-Rr, 1,8kV, 0,085A	31a			1N5181
1 N 1137	USA	Si-Di	kV-Rr, 2,4kV, 0,05A	31a			1N5181
1 N 1138	USA	Si-Di	kV-Rr, 2,4kV, 0,06A	31a			1N5181
1 N 1139	USA	Si-Di	kV-Rr, 3,6kV, 0,065A	31a			1N5181
1 N 1140	USA	Si-Di	kV-Rr, 3,6kV, 0,065A	31a			1N5181
1 N 1141	USA	Si-Di	kV-Rr, 4,8kV, 0,06A	31a			1N5182
1 N 1142	USA	Si-Di	kV-Rr, 4,8kV, 0,05A	31a			1N5182
1 N 1143	USA	Si-Di	kV-Rr, 6kV, 0,05A	31a			1N5183
1 N 1143 A	USA	Si-Di	=1N1143: 0,065mA	31a			1N5183
1 N 1144	USA	Si-Di	kV-Rr, 7,2kV, 0,05A	31a			1N5183
1 N 1145	USA	Si-Di	kV-Rr, 7,2kV, 0,06A	31a			1N5183
1 N 1146	USA	Si-Di	kV-Rr, 8kV, 0,045A	31a			1N5184
1 N 1147	USA	Si-Di	kV-Rr, 12kV, 0,045A	31a			1N3052
1 N 1148	USA	Si-Di	kV-Rr, 14kV, 0,05A	31a			1N3053
1 N 1149	USA	Si-Di	kV-Rr, 16kV, 0,045A	31a			1N3054
1 N 1150(A)	USA	Si-Di	kV-Rr, 1,6kV, 0,75A				-
1 N 1157	Edi	Si-Di	P Rr, 50V, 20A(Tc=100°), Uf<1,2V(20A)				BYX 25/600, SSI E2040
1 N 1158		Si-Di	=1N1157: 100V				BYX 25/600, SSI E2040
1 N 1159		Si-Di	=1N1157: 200V				BYX 25/600, SSI E2040
1 N 1160		Si-Di	=1N1157: 300V				BYX 25/600, SSI E2040
1 N 1161	Edi	Si-Di	P Rr, 50V, 35A(Tc=100°), Uf<1,2V(35A)				BYX 96/300
1 N 1162		Si-Di	=1N1161: 100V				BYX 96/300
1 N 1163		Si-Di	=1N1161: 200V				BYX 96/300
1 N 1164		Si-Di	=1N1161: 300V				BYX 96/300
1 N 1165	Edi	Si-Di	P Rr, 50V, 100A(Tc=100°), Uf<1,2V(100A)				DS 75-02B
1 N 1166		Si-Di	=1N1165: 100V				DS 75-02B
1 N 1167		Si-Di	=1N1165: 200V				DS 75-02B
1 N 1168		Si-Di	=1N1165: 300V				DS 75-04B
1 N 1169	Inr,Sem	Si-Di	Rr, 400V, 0,79ATA=80°, Uf<0,9V(0,5A)	31a	DO-27		BY 126...127, BY 133...134, 1N4004...07, ++
1 N 1169 A		Si-Di	=1N1169: 0,5A(Tc=100°)	34a	DO-1		BY 126...127, BY 133...134, 1N4004...07, ++
1 N 1170		Ge-Di	Uni, 50/75V, Uf<1V(4mA)	31a	DO-7		AA 117...118, AA 132...134, 1N34, 1N54, ++
1 N 1171	Edi	Si-Di	=1N1157				-1N1157
1 N 1172	Edi	Si-Di	=1N1158				-1N1158
1 N 1173	Edi	Si-Di	=1N1159				-1N1159
1 N 1174	Edi	Si-Di	=1N1160				-1N1160
1 N 1175	Edi	Si-Di	=1N1161				-1N1161
1 N 1176	Edi	Si-Di	=1N1162				-1N1162
1 N 1177	Edi	Si-Di	=1N1163				-1N1163
1 N 1178	Edi	Si-Di	=1N1164				-1N1164
1 N 1179	Edi	Si-Di	=1N1165				-1N1165
1 N 1180	Edi	Si-Di	=1N1166				-1N1166
1 N 1181	Edi	Si-Di	=1N1167				-1N1167
1 N 1182	Edi	Si-Di	=1N1168				-1N1168
1 N 1183	USA, EUR	Si-Di	P Rr, 50V, 35A(Tc=140°), Uf<1,3V(100A)	32a	DO-5		1N3765, 1N4525
1 N 1184		Si-Di	=1N1183: 100V	32a	DO-5		1N3765, 1N4525
1 N 1185		Si-Di	=1N1183: 150V	32a	DO-5		1N3765, 1N4525
1 N 1186		Si-Di	=1N1183: 200V	32a	DO-5		1N3765, 1N4525
1 N 1187		Si-Di	=1N1183: 300V	32a	DO-5		1N3765, 1N4526
1 N 1188		Si-Di	=1N1183: 400V	32a	DO-5		1N3765, 1N4526
1 N 1189		Si-Di	=1N1183: 500V	32a	DO-5		1N3765, 1N4527
1 N 1190		Si-Di	=1N1183: 600V	32a	DO-5		1N3765, 1N4527
1 N 1183A...1190A...		Si-Di	=1N1183...1190: 40A(Tc=150°), Uf<1,1V(100A)				
1 N 1183R...1190R		Si-Di	=1N1183...1190:	32b	DO-5		1N3765R
1 N 1183T...1190T		Si-Di	=1N1183...1190:	73a	SOD-5		1N3765T
1 N 1183TR...1190TR		Si-Di	=1N1183...1190:	73b	SOD-5		1N3765TR
1 N 1191(A)	USA, EUR	Si-Di	P Rr, 50V, 20A(Tc=150°), Uf<1,5V(100A)	32a	DO-5		1N3765, 1N4525
1 N 1192(A)		Si-Di	=1N1191: 100V	32a	DO-5		1N3765, 1N4525
1 N 1193(A)		Si-Di	=1N1191: 150V	32a	DO-5		1N3765, 1N4525
1 N 1194(A)		Si-Di	=1N1191: 200V	32a	DO-5		1N3765, 1N4525
1 N 1195(A)		Si-Di	=1N1191: 300V	32a	DO-5		1N3765, 1N4526
1 N 1196(A)		Si-Di	=1N1191: 400V	32a	DO-5		1N3765, 1N4526
1 N 1197(A)		Si-Di	=1N1191: 500V	32a	DO-5		1N3765, 1N4527
1 N 1198(A)		Si-Di	=1N1191: 600V	32a	DO-5		1N3765, 1N4527
1 N 1191R...1198R		Si-Di	=1N1191...1198:	32b	DO-5		1N3765R
1 N 1199(A,B,C)	Gen, Inr, Mot Rca, Tix, ++	Si-Di	P Rr, 50V, 12A(150°), Uf<1,4A(20A) A: Uf<1,3V(12A), B: Uf<1,1V(12A), C: Uf<1,1V(12A)	32a	DO-4		BYW 88/50, BYX 75
1 N 1200(A,B,C)		Si-Di	=1N1199: 100V	32a	DO-4		BYW 88/100, BYX 76
1 N 1201(A,B,C)		Si-Di	=1N1199: 150V	32a	DO-4		BYW 88/200, BYX 77
1 N 1202(A,B,C)		Si-Di	=1N1199: 200V	32a	DO-4		BYW 88/200, BYX 77
1 N 1203(A,B,C)		Si-Di	=1N1199: 300V	32a	DO-4		BYW 88/300, BYX 78
1 N 1204(A,B,C)		Si-Di	=1N1199: 400V	32a	DO-4		BYW 88/400, BYX 78
1 N 1205(A,B,C)		Si-Di	=1N1199: 500V	32a	DO-4		BYW 88/500, BYX 79
1 N 1206(A,B,C)		Si-Di	=1N1199: 600V	32a	DO-4		BYW 88/600, BYX 79
1 N 1201R...1206R		Si-Di	=1N1199...1206:	32b	DO-4		BYW 88...R, BYX 75R...79R
1 N 1217(A,B)	USA	Si-Di	Rr, 50V, 1,6A(Tc=135°), Uf<1,5V(2,5A), Ir<500µA A: Ir<50µA, B: Uf<1,7V(1,3A), Ir<300µA	34a	DO-1		BY 251...255, BYW 52...56, 1N5060...62, ++
1 N 1218(A,B)		Si-Di	=1N1217: 100V	34a	DO-1		BY 251...255, BYW 52...56, 1N5060...62, ++
1 N 1219(A,B)		Si-Di	=1N1217: 150V	34a	DO-1		BY 251...255, BYW 52...56, 1N5060...62, ++
1 N 1220(A,B)		Si-Di	=1N1217: 200V	34a	DO-1		BY 251...255, BYW 52...56, 1N5060...62, ++
1 N 1221(A,B)		Si-Di	=1N1217: 300V	34a	DO-1		BY 252...255, BYW 53...56, 1N5060...62, ++
1 N 1222(A,B)		Si-Di	=1N1217: 400V	34a	DO-1		BY 252...255, BYW 53...56, 1N5060...62, ++
1 N 1223(A,B)		Si-Di	=1N1217: 500V	34a	DO-1		BY 253...255, BYW 54...56, 1N5061...62, ++
1 N 1224(A,B)		Si-Di	=1N1217: 600V	34a	DO-1		BY 253...255, BYW 54...56, 1N5061...62, ++
1 N 1225(A,B)		Si-Di	=1N1217: 700V	34a	DO-1		BY 254...255, BYW 55...56, 1N5062, ++
1 N 1226(A,B)		Si-Di	=1N1217: 800V	34a	DO-1		BY 254...255, BYW 55...56, 1N5062, ++

Original	Fabric.	Constr.	Info	{Compl. Fig.	JAEGER	Fig.	International
1 N 1227(A,B)		Si-Di	=1N1217:	32a	DO-4		BYX 38/300, BYX 39/600
1 N 1228(A,B)		Si-Di	=1N1218:	32a	DO-4		BYX 38/300, BYX 39/600
1 N 1229(A,B)		Si-Di	=1N1219:	32a	DO-4		BYX 38/300, BYX 39/600
1 N 1230(A,B)		Si-Di	=1N1220:	32a	DO-4		BYX 38/300, BYX 39/600
1 N 1231(A,B)		Si-Di	=1N1221:	32a	DO-4		BYX 38/300, BYX 39/600
1 N 1232(A,B)		Si-Di	=1N1222:	32a	DO-4		BYX 38/300, BYX 39/600
1 N 1233(A,B)		Si-Di	=1N1223:	32a	DO-4		BYX 38/600, BYX 39/600
1 N 1234(A,B)		Si-Di	=1N1224:	32a	DO-4		BYX 38/600, BYX 39/600
1 N 1235(A,B)		Si-Di	=1N1225:	32a	DO-4		BYX 38/900, BYX 39/800
1 N 1236(A,B)		Si-Di	=1N1226:	32a	DO-4		BYX 38/900, BYX 39/800
1 N 1237	USA	Si-Di	Dual Rr, 1600V, 0,75A				-
1 N 1238	USA	Si-Di	Dual Rr, 1600V, 0,75A				-
1 N 1239	USA	Si-Di	Dual Rr, 2800V, 0,5A				-
1 N 1240....1250	USA	Si-Di	=1N1251...1261				--1N1251...1261
1 N 1251	USA	Si-Di	Rr, 50V, 0,5A, Uf<1V(0,5A)	34a	DO-1		BY 126...127, BY 133...135, 1N4001...07, ++
1 N 1252		Si-Di	=1N1251: 100V	34a	DO-1		BY 126...127, BY 133...135, 1N4002...07, ++
1 N 1253		Si-Di	=1N1251: 200V	34a	DO-1		BY 126...127, BY 133...134, 1N4003...07, ++
1 N 1254		Si-Di	=1N1251: 300V	34a	DO-1		BY 126...127, BY 133...134, 1N4004...07, ++
1 N 1255(A)		Si-Di	=1N1251: 400V	34a	DO-1		BY 126...127, BY 133...134, 1N4004...07, ++
1 N 1256		Si-Di	=1N1251: 500V, 0,32A, Uf<1V(0,23A)	34a	DO-1		BY 126...127, BY 133...134, 1N4005...07, ++
1 N 1257		Si-Di	=1N1251: 600V, 0,3A, Uf<1V(0,3A)	34a	DO-1		BY 126...127, BY 133...134, 1N4005...07, ++
1 N 1258		Si-Di	=1N1251: 700V, 0,28A, Uf<1V(0,28A)	34a	DO-1		BY 127, BY 133, BYX 95, 1N4006...07, ++
1 N 1259		Si-Di	=1N1251: 800V, 0,27A, Uf<1V(0,27A)	34a	DO-1		BY 127, BY 133, BYX 95, 1N4006...07, ++
1 N 1260		Si-Di	=1N1251: 900V, 0,25A, Uf<1V(0,25A)	34a	DO-1		BY 127, BY 133, BYX 95, 1N4007, ++
1 N 1261		Si-Di	=1N1251: 1000V, 0,24A, Uf<1V(0,24A)	34a	DO-1		BY 127, BY 133, BYX 95, 1N4007, ++
1 N 1262	USA	Si-Di	kv-Rr, 4,5kV, 0,25A, Uf<12V(0,25A)				-
1 N 1263		Si-Di	P Rr, 50V, 150A, Uf<1V(45A)				-
1 N 1264		Si-Di	=1N1263: 100V				-
1 N 1265		Si-Di	=1N1263: 200V				-
1 N 1266		Si-Di	=1N1263: 300V				-
1 N 1263A....1266A		Si-Di	=1N1263...1266: 200A, Uf<1V(70A)				-
1 N 1267		Si-Di	P Rr, 50V, 150A, Uf<1V(45A)				-
1 N 1268		Si-Di	=1N1267: 100V				-
1 N 1269		Si-Di	=1N1267: 200V				-
1 N 1270		Si-Di	=1N1267: 300V				-
1 N 1267A....1270A		Si-Di	=1N1267...1270: 200A, Uf<1V(70A)				-
1 N 1271....1277		Si-Di	=1N1281...1287				-
1 N 1281	USA	Si-Di	P Rr, 50V, 160A(Tc=125°), Uf<1,3V(210A)	73a	-DO-30		-
1 N 1282		Si-Di	=1N1281: 100V	73a	-DO-30		-
1 N 1283		Si-Di	=1N1281: 150V	73a	-DO-30		-
1 N 1284		Si-Di	=1N1281: 200V	73a	-DO-30		-
1 N 1285		Si-Di	=1N1281: 300V	73a	-DO-30		-
1 N 1286		Si-Di	=1N1281: 400V	73a	-DO-30		-
1 N 1287		Si-Di	=1N1281: 500V	73a	-DO-30		-
1 N 1291....1297		Si-Di	=1N1281...1287	73a	-DO-30		-
1 N 1301	USA	Si-Di	P Rr, 50V, 37A(Tc=120°), Uf<1,5V(50A)	32a	DO-5		1N3765, 1N4525
1 N 1302		Si-Di	=1N1301: 100V	32a	DO-5		1N3765, 1N4525
1 N 1304		Si-Di	=1N1301: 200V	32a	DO-5		1N3765, 1N4525
1 N 1306		Si-Di	=1N1301: 300V	32a	DO-5		1N3765, 1N4526
1 N 1313	USA	Z-Di	8,75V, 10%, 0,15W	2c	=TO-1		BZX55/..., BZX79/..., ZPD..., 1N5238...74, ++
1 N 1314		Z-Di	=1N1313: 10,5V	2c	=TO-1		
1 N 1315		Z-Di	=1N1313: 12,75V	2c	=TO-1		
1 N 1316		Z-Di	=1N1313: 15,75V	2c	=TO-1		
1 N 1317		Z-Di	=1N1313: 19V	2c	=TO-1		
1 N 1318		Z-Di	=1N1313: 23,5V	2c	=TO-1		
1 N 1319		Z-Di	=1N1313: 28,5V	2c	=TO-1		
1 N 1320		Z-Di	=1N1313: 34,5V	2c	=TO-1		
1 N 1321		Z-Di	=1N1313: 41V	2c	=TO-1		
1 N 1322		Z-Di	=1N1313: 48,5V	2c	=TO-1		
1 N 1323		Z-Di	=1N1313: 58V	2c	=TO-1		
1 N 1324		Z-Di	=1N1313: 71V	2c	=TO-1		
1 N 1325		Z-Di	=1N1313: 87,5V	2c	=TO-1		
1 N 1326		Z-Di	=1N1313: 105V	2c	=TO-1		
1 N 1327		Z-Di	=1N1313: 127,5V	2c	=TO-1		
1 N 1313A....1327A		Z-Di	=1N1313...1327: 5%	2c	=TO-1		
1 N 1329	Tix	Si-Di	Rr, 1500V, 0,1A, Uf<1,1V				BAY 91, BY 203/16, BY 584, RGP 01/16, ++
1 N 1330	Sem,Ssi	Si-Di	P Rr, 50V, 240A(Tc=125°), Uf<1,25V(300A)	=73a	=DO-30		-
1 N 1331		Si-Di	=1N1330: 100V	=73a	=DO-30		-
1 N 1332		Si-Di	=1N1330: 150V	=73a	=DO-30		-
1 N 1333		Si-Di	=1N1330: 200V	=73a	=DO-30		-
1 N 1334		Si-Di	=1N1330: 300V	=73a	=DO-30		-
1 N 1335		Si-Di	=1N1330: 400V	=73a	=DO-30		-
1 N 1336		Si-Di	=1N1330: 500V	=73a	=DO-30		-
1 N 1341(A,B,C)	Gen,Mot, Tho,++	Si-Di	P Rr, 50V, 6A(Tc=150°), Uf<1,2V(10A) A: Uf<0,64V(6A), B: Uf<1,1V(6A), C: Uf<1,6V	32a	DO-4		BYX 38/300, BYX 39/600
1 N 1342(A,B,C)		Si-Di	=1N1341: 100V	32a	DO-4		BYX 38/300, BYX 39/600
1 N 1343(A,B,C)		Si-Di	=1N1341: 150V	32a	DO-4		BYX 38/300, BYX 39/600
1 N 1344(A,B,C)		Si-Di	=1N1341: 200V	32a	DO-4		BYX 38/300, BYX 39/600
1 N 1345(A,B,C)		Si-Di	=1N1341: 300V	32a	DO-4		BYX 38/300, BYX 39/600
1 N 1346(A,B,C)		Si-Di	=1N1341: 400V	32a	DO-4		BYX 38/600, BYX 39/600
1 N 1347(A,B,C)		Si-Di	=1N1341: 500V	32a	DO-4		BYX 38/600, BYX 39/600
1 N 1348(A,B,C)		Si-Di	=1N1341: 600V	32a	DO-4		BYX 38/600, BYX 39/600
1 N 1341R....1348R		Si-Di	=1N1341...1348:	32b	DO-4		BYX 38/600R, BYX 39/600R
1 N 1351	USA,Sie	Z-Di	10V, 10%, 10W(Tc=55°)	32b	DO-4		BZX98/..., BZY93/..., ZX..., 1N2974...3005
1 N 1352		Z-Di	=1N1351: 11V	32b	DO-4		
1 N 1353		Z-Di	=1N1351: 12V	32b	DO-4		
1 N 1354		Z-Di	=1N1351: 13V	32b	DO-4		
1 N 1355		Z-Di	=1N1351: 15V	32b	DO-4		
1 N 1356		Z-Di	=1N1351: 16V	32b	DO-4		
1 N 1357		Z-Di	=1N1351: 18V	32b	DO-4		
1 N 1358		Z-Di	=1N1351: 20V	32b	DO-4		
1 N 1359		Z-Di	=1N1351: 22V	32b	DO-4		
1 N 1360		Z-Di	=1N1351: 24V	32b	DO-4		

Original	Fabric.	Constr.	Info	(Compl. Fig.	JAEGER	Fig.	International
1 N 1361		Z-Di	=1N1351: 27V	32b		DO-4	
1 N 1362		Z-Di	=1N1351: 30V	32b		DO-4	
1 N 1363		Z-Di	=1N1351: 33V	32b		DO-4	
1 N 1364		Z-Di	=1N1351: 36V	32b		DO-4	
1 N 1365		Z-Di	=1N1351: 39V	32b		DO-4	
1 N 1366		Z-Di	=1N1351: 43V	32b		DO-4	
1 N 1367		Z-Di	=1N1351: 47V	32b		DO-4	
1 N 1368		Z-Di	=1N1351: 51V	32b		DO-4	
1 N 1369		Z-Di	=1N1351: 56V	32b		DO-4	
1 N 1370		Z-Di	=1N1351: 62V	32b		DO-4	
1 N 1371		Z-Di	=1N1351: 68V	32b		DO-4	
1 N 1372		Z-Di	=1N1351: 75V	32b		DO-4	
1 N 1373		Z-Di	=1N1351: 82V	32b		DO-4	
1 N 1374		Z-Di	=1N1351: 91V	32b		DO-4	
1 N 1375		Z-Di	=1N1351: 100V	32b		DO-4	
1 N 1351A.....1375A		Z-Di	=1N1351...1375: 5%	32b		DO-4	
1 N 1351B.....1375B		Z-Di	=1N1351...1375: 20%	32b		DO-4	
1 N 1351C.....1375C		Z-Di	=1N1351...1375: bidirectional	32b		DO-4	
1 N 1351CA.....1375CA		Z-Di	=1N1351...1375: bidirectional, 5%	32b		DO-4	
1 N 1351R.....1375R		Z-Di	=1N1351...1375:	32a		DO-4	
1 N 1376	Sem,Ssi	Si-Di	P Rr, 50V, 240A(Tc=125°C), Uf<1,25V(300A)	=73a		=DO-30	
1 N 1377		Si-Di	=1N1376: 100V	=73a		=DO-30	
1 N 1378		Si-Di	=1N1376: 150V	=73a		=DO-30	
1 N 1379		Si-Di	=1N1376: 200V	=73a		=DO-30	
1 N 1380		Si-Di	=1N1376: 300V	=73a		=DO-30	
1 N 1381		Si-Di	=1N1376: 400V	=73a		=DO-30	
1 N 1382		Si-Di	=1N1376: 500V	=73a		=DO-30	
1 N 1396	Sem,Ssi	Si-Di	P Rr, 50V, 70A(Tc=150°), Uf<1,25V(70A)	73a		DO-8	1N3288
1 N 1397		Si-Di	=2N1396: 100V	73a		DO-8	1N3288
1 N 1398		Si-Di	=2N1396: 150V	73a		DO-8	1N3289
1 N 1399		Si-Di	=2N1396: 200V	73a		DO-8	1N3289
1 N 1400		Si-Di	=2N1396: 300V	73a		DO-8	1N3290
1 N 1401		Si-Di	=2N1396: 400V	73a		DO-8	1N3291
1 N 1402		Si-Di	=2N1396: 500V	73a		DO-8	1N3292
1 N 1403		Si-Di	=2N1396: 600V	73a		DO-8	1N3293
1 N 1406	Inr,Sem,Ssi	Si-Di	Rr, 600V, 0,125A, Uf<5V(1,2A)	34a		DO-1	BY 203/12, RGP 01/10, SHG 1
1 N 1407		Si-Di	=1N1406: 800V	34a		DO-1	BY 203/12, RGP 01/10, SHG 1
1 N 1408		Si-Di	=1N1406: 1000V	34a		DO-1	BY 203/12, RGP 01/10, SHG 1
1 N 1409		Si-Di	=1N1406: 1200V	34a		DO-1	BY 203/12, RGP 01/12, SHG 1,5
1 N 1410		Si-Di	=1N1406: 1500V, Uf<6,25V(1,2A)	31a		DO-1	BY 203/16, RGP 01/16, SHG 1,5
1 N 1411		Si-Di	=1N1406: 1800V, Uf<7,5V(1,2A)	31a		DO-1	BY 203/20, SHG 2
1 N 1412		Si-Di	=1N1406: 2000V, Uf<6,25V(1,2A)	31a		DO-1	BY 203/20, SHG 2
1 N 1413		Si-Di	=1N1406: 2400V, Uf<7,5V(1,2A)	31a		DO-1	SHG 2,5
1 N 1414	Whs	Si-Di	Rr, 400V, 10A, Uf<1,25V(10A)				BYX 42/600, BYX 98/600, SSI D0440
1 N 1415	USA	Si-Di	Rr, 400V, 1A, Uf<1,1V(1A)	=34a		=DO-1	BY 126...127, BY 133...134, 1N4004...07, ++
1 N 1416	Sem,Ssi	Z-Di	8,2V, 5%, 10W	32		DO-4	BZX98/..., BZY93/..., ZX..., 1N2972...3011
1 N 1417		Z-Di	=1N1416: 12V	32		DO-4	
1 N 1418		Z-Di	=1N1416: 15V	32		DO-4	
1 N 1419		Z-Di	=1N1416: 18V	32		DO-4	
1 N 1420		Z-Di	=1N1416: 22V	32		DO-4	
1 N 1421		Z-Di	=1N1416: 27V	32		DO-4	
1 N 1422		Z-Di	=1N1416: 68V	32		DO-4	
1 N 1423		Z-Di	=1N1416: 100V	32		DO-4	
1 N 1424		Z-Di	=1N1416: 150V	32		DO-4	
1 N 1425	Sem,Ssi	Z-Di	8,2V, 5%, 1W	=34a		=DO-1	BZW22/..., BZX61/..., ZPY..., 1N5923...53, ++
1 N 1426		Z-Di	=1N1425: 12V	=34a		=DO-1	
1 N 1427		Z-Di	=1N1425: 15V	=34a		=DO-1	
1 N 1428		Z-Di	=1N1425: 18V	=34a		=DO-1	
1 N 1429		Z-Di	=1N1425: 22V	=34a		=DO-1	
1 N 1430		Z-Di	=1N1425: 27V	=34a		=DO-1	
1 N 1431		Z-Di	=1N1425: 68V	=34a		=DO-1	
1 N 1432		Z-Di	=1N1425: 100V	=34a		=DO-1	
1 N 1433		Z-Di	=1N1425: 150V	=34a		=DO-1	
1 N 1434	USA	Si-Di	P Rr, 50V, 30A(Tc=25°), Uf<1,2V(60A)	32a		DO-5	1N3765, 1N4525
1 N 1435		Si-Di	=1N1434: 100V	32a		DO-5	1N3765, 1N4525
1 N 1436		Si-Di	=1N1434: 200V	32a		DO-5	1N3765, 1N4525
1 N 1437		Si-Di	=1N1434: 400V	32a		DO-5	1N3765, 1N4526
1 N 1438		Si-Di	=1N1434: 600V	32a		DO-5	1N3765, 1N4526
1 N 1439	USA	Si-Di	Rr, 100V, 0,75A, Uf<1V(0,75A)	31a		DO-7	BY 126...127, BY 133...135, 1N4002...07, ++
1 N 1440		Si-Di	=1N1439: 200V	31a		DO-7	BY 126...127, BY 133...134, 1N4003...07, ++
1 N 1441		Si-Di	=1N1439: 300V	31a		DO-7	BY 126...127, BY 133...134, 1N4004...07, ++
1 N 1442		Si-Di	=1N1439: 400V	31a		DO-7	BY 126...127, BY 133...134, 1N4004...07, ++
1 N 1443(A,B)	USA	Si-Di	Rr, 1000V, 0,95...1,6A	34a		DO-1	BY 255, BYW 56, GP 15M, 1N5399, ++
1 N 1444(A,B)		Si-Di	=1N1443(A,B):	=32a		=DO-4	
1 N 1445		Si-Di	Rr, 300V, 0,2A, Uf<2V				BA 157...159, BAY 21, BAY 88...90, ++
1 N 1446	Scn,Sem	Si-Di	Rr, 100V, 1,5A(Tc=120°), Uf<1,3V(1,8A)				
1 N 1447		Si-Di	=1N1446: 200V				
1 N 1448		Si-Di	=1N1446: 300V				
1 N 1449		Si-Di	=1N1446: 400V				
1 N 1450	Scn,Sem	Si-Di	Rr, 100V, 1,5A(Tc=100°), Uf<1V(2,4A)				
1 N 1451		Si-Di	=1N1450: 200V				
1 N 1452		Si-Di	=1N1450: 300V				
1 N 1453		Si-Di	=1N1450: 400V				
1 N 1454	Ssi	Si-Di	P Rr, 100V, 25A, Uf<1,5V(25A)				
1 N 1455		Si-Di	=1N1454: 200V				
1 N 1456		Si-Di	=1N1454: 300V				
1 N 1457		Si-Di	=1N1454: 400V				
1 N 1458	Ssi	Si-Di	P Rr, 100V, 35A, Uf<1,5V(35A)				
1 N 1459		Si-Di	=1N1458: 200V				
1 N 1460		Si-Di	=1N1458: 300V				
1 N 1461		Si-Di	=1N1458: 400V				
1 N 1462	Ssi	Si-Di	P Rr, 100V, 50A, Uf<1,5V(50A)				
1 N 1463		Si-Di	=1N1462: 200V				

Original	Fabric.	Constr.	Info	(Compl. Fig.	JAEGER	Fig.	International
1 N 1464		Si-Di	=1N1462: 300V				-
1 N 1465		Si-Di	=1N1462: 400V				-
1 N 1466	Ssi	Si-Di	P Rr, 100V, 75A, Uf<1,5V(75A)				-
1 N 1467		Si-Di	=1N1466: 200V				-
1 N 1468		Si-Di	=1N1466: 300V				-
1 N 1469		Si-Di	=1N1466: 400V				-
1 N 1470	Ssi	Si-Di	P Rr, 100V, 100A, Uf<1,5V(100A)				-
1 N 1471		Si-Di	=1N1470: 200V				-
1 N 1472		Si-Di	=1N1470: 300V				-
1 N 1473		Si-Di	=1N1470: 400V				-
1 N 1474	Ssi	Si-Di	P Rr, 100V, 150A, Uf<1,5V(150A)				-
1 N 1475		Si-Di	=1N1474: 200V				-
1 N 1476		Si-Di	=1N1474: 300V				-
1 N 1477		Si-Di	=1N1474: 400V				-
1 N 1478	Ssi	Si-Di	P Rr, 100V, 200A, Uf<1,5V(200A)				-
1 N 1479		Si-Di	=1N1478: 200V				-
1 N 1480		Si-Di	=1N1478: 300V				-
1 N 1481		Si-Di	=1N1478: 400V				-
1 N 1482	USA	Z-Di	4,7V, 5%, 10W(Tc=25°)	32	DO-4		BZX98/..., BZY93/..., ZX..., 1N3995...3998
1 N 1483		Z-Di	6,2V, 5%, 10W	32	DO-4		
1 N 1484	USA	Z-Di	4,7V, 5%, 1W	-34a	=DO-1		BZW22/..., BZX61/..., ZPY..., 1N5917...20,++
1 N 1485		Z-Di	6,2V, 5%, 1W	-34a	=DO-1		
1 N 1486	USA	Si-Di	Rr, 500V, 0,78A, Uf<0,5V	34a	DO-1		BY 126...127, BY 133...134, 1N4005...07, ++
1 N 1487	USA,Tix	Si-Di	Rr, 100V, 0,75A, Uf<0,55V(0,25A)	34a	DO-1		BY 126...127, BY 133...135, 1N4002...07, ++
1 N 1488		Si-Di	=1N1487: 200V	34a	DO-1		BY 126...127, BY 133...134, 1N4003...07, ++
1 N 1489		Si-Di	=1N1487: 300V	34a	DO-1		BY 126...127, BY 133...134, 1N4004...07, ++
1 N 1490		Si-Di	=1N1487: 400V	34a	DO-1		BY 126...127, BY 133...134, 1N4004...07, ++
1 N 1491		Si-Di	=1N1487: 500V	34a	DO-1		BY 126...127, BY 133...134, 1N4005...07, ++
1 N 1492		Si-Di	=1N1487: 600V	34a	DO-1		BY 126...127, BY 133...134, 1N4005...07, ++
1 N 1507	USA,Mot	Z-Di	3,9V, 10%, 0,75W	34a	DO-12		BZV85/..., BZW22/..., ZPY..., 1N4730...50,++
1 N 1508		Z-Di	=1N1507: 4,7V	34a	DO-12		
1 N 1509		Z-Di	=1N1507: 5,6V	34a	DO-12		
1 N 1510		Z-Di	=1N1507: 6,8V	34a	DO-12		
1 N 1511		Z-Di	=1N1507: 8,2V	34a	DO-12		
1 N 1512		Z-Di	=1N1507: 10V	34a	DO-12		
1 N 1513		Z-Di	=1N1507: 12V	34a	DO-12		
1 N 1514		Z-Di	=1N1507: 15V	34a	DO-12		
1 N 1515		Z-Di	=1N1507: 18V	34a	DO-12		
1 N 1516		Z-Di	=1N1507: 22V	34a	DO-12		
1 N 1517		Z-Di	=1N1507: 27V	34a	DO-12		
1 N 1507A...1517A		Z-Di	=1N1507...1517: 5%	34a	DO-12		
1 N 1518	USA,Mot	Z-Di	3,9V, 10%, 1W	34a	DO-1		BZW22/..., BZX61/..., ZPY..., 1N5915...35,++
1 N 1519		Z-Di	=1N1518: 4,7V	34a	DO-1		
1 N 1520		Z-Di	=1N1518: 5,6V	34a	DO-1		
1 N 1521		Z-Di	=1N1518: 6,8V	34a	DO-1		
1 N 1522		Z-Di	=1N1518: 8,2V	34a	DO-1		
1 N 1523		Z-Di	=1N1518: 10V	34a	DO-1		
1 N 1524		Z-Di	=1N1518: 12V	34a	DO-1		
1 N 1525		Z-Di	=1N1518: 15V	34a	DO-1		
1 N 1526		Z-Di	=1N1518: 18V	34a	DO-1		
1 N 1527		Z-Di	=1N1518: 22V	34a	DO-1		
1 N 1528		Z-Di	=1N1518: 27V	34a	DO-1		
1 N 1518A...1528A		Z-Di	=1N1518...1528: 5%	34a	DO-1		
1 N 1530	Inr,Mot,++	Ref-Di	8,4V(10mA), 5%, ±0,002%/°C, <15Ω, 0,25W				BZX 53, 1N3156, 1N4777, 1N4782
1 N 1530 A		Ref-Di	=1N1530: 0,001%/°C				BZX 54, 1N3157, 1N4778, 1N4783
1 N 1537	USA	Si-Di	P Rr, 50V, 1,6A(Tc=140°), Uf<1,5V(2,5A)	32a	DO-4		BYX 38/300, BYX 39/600
1 N 1538		Si-Di	=1N1537: 100V	32a	DO-4		BYX 38/300, BYX 39/600
1 N 1539		Si-Di	=1N1537: 150V	32a	DO-4		BYX 38/300, BYX 39/600
1 N 1540		Si-Di	=1N1537: 200V	32a	DO-4		BYX 38/300, BYX 39/600
1 N 1541		Si-Di	=1N1537: 300V	32a	DO-4		BYX 38/300, BYX 39/600
1 N 1542		Si-Di	=1N1537: 400V	32a	DO-4		BYX 38/600, BYX 39/600
1 N 1543		Si-Di	=1N1537: 500V	32a	DO-4		BYX 38/600, BYX 39/600
1 N 1544		Si-Di	=1N1537: 600V	32a	DO-4		BYX 38/600, BYX 39/600
1 N 1552	USA	Si-Di	P Rr, 100V, 1A(Tc=100°), Uf<1,4V(0,6A)	32a	DO-4		BYX 38/300, BYX 39/600
1 N 1551		Si-Di	=1N1551: 200V	32a	DO-4		BYX 38/300, BYX 39/600
1 N 1553		Si-Di	=1N1551: 300V	32a	DO-4		BYX 38/300, BYX 39/600
1 N 1554		Si-Di	=1N1551: 400V	32a	DO-4		BYX 38/600, BYX 39/600
1 N 1555		Si-Di	=1N1551: 500V	32a	DO-4		BYX 38/600, BYX 39/600
1 N 1556	USA	Si-Di	Rr, 100V, 0,75A(Tc=100°), Uf<1,4V(0,6A)	34a	DO-1		BY 126...127, BY 133...135, 1N4002...07, ++
1 N 1557		Si-Di	=1N1556: 200V	34a	DO-1		BY 126...127, BY 133...134, 1N4003...07, ++
1 N 1558		Si-Di	=1N1556: 300V	34a	DO-1		BY 126...127, BY 133...134, 1N4004...07, ++
1 N 1559		Si-Di	=1N1556: 400V	34a	DO-1		BY 126...127, BY 133...134, 1N4004...07, ++
1 N 1560		Si-Di	=1N1556: 500V	34a	DO-1		BY 126...127, BY 133...134, 1N4005...07, ++
1 N 1561		Ge-Di	25V, Uf<0,4V(12mA)				-
1 N 1562		Ge-Di	25V, Uf<0,4V(8mA)				-
1 N 1563(A)	Sem,Ssi	Si-Di	Rr, 100V, 1,5A, Uf<1,2V(0,5A)	=2c	=TO-1		BY 251...255, BYW 52...56, 1N5392...99, ++
1 N 1564(A)		Si-Di	=1N1563: 200V	=2c	=TO-1		BY 251...255, BYW 52...56, 1N5393...99, ++
1 N 1565(A)		Si-Di	=1N1563: 300V	=2c	=TO-1		BY 252...255, BYW 53...56, 1N5394...99, ++
1 N 1566(A)		Si-Di	=1N1563: 400V	=2c	=TO-1		BY 252...255, BYW 53...56, 1N5395...99, ++
1 N 1567(A)		Si-Di	=1N1563: 500V	=2c	=TO-1		BY 253...255, BYW 54...56, 1N5396...99, ++
1 N 1568(A)		Si-Di	=1N1563: 600V	=2c	=TO-1		BY 253...255, BYW 54...56, 1N5398...99, ++
1 N 1569	Mot	Rr	100V, 1A, Uf<1,5V(1A)				BY 126...127, BY 133...135, 1N4002...07, ++
1 N 1570		Si-Di	=1N1569: 200V				BY 126...127, BY 133...134, 1N4003...07, ++
1 N 1571		Si-Di	=1N1569: 300V				BY 126...127, BY 133...134, 1N4004...07, ++
1 N 1572		Si-Di	=1N1569: 400V				BY 126...127, BY 133...134, 1N4004...07, ++
1 N 1573		Si-Di	=1N1569: 500V				BY 126...127, BY 133...134, 1N4005...07, ++
1 N 1574		Si-Di	=1N1569: 600V				BY 126...127, BY 133...134, 1N4005...07, ++
1 N 1575	Gie,Mot,Ssi	Si-Di	P Rr, 100V, 3,5A(Tc=25°), Uf<1,2V(3,5A)	21	TO-64		BYX 38/300, BYX 39/600
1 N 1576		Si-Di	=1N1575: 200V	21	TO-64		BYX 38/300, BYX 39/600
1 N 1577		Si-Di	=1N1575: 300V	21	TO-64		BYX 38/300, BYX 39/600
1 N 1578		Si-Di	=1N1575: 400V	21	TO-64		BYX 38/600, BYX 39/600
1 N 1579		Si-Di	=1N1575: 500V	21	TO-64		BYX 38/600, BYX 39/600
1 N 1580		Si-Di	=1N1575: 600V	21	TO-64		BYX 38/600, BYX 39/600

Original	Fabric.	Constr.	Info	{Compl. Fig.	JAEGER	Fig.	International
1 N 1581	USA,Tho	Si-Di	P Rr, 50V, 10A(Tc=50°), Uf<1,5V(6A)	32a	DO-4		BYW 88/50, BYX 42/300, BYX 98/300, ++
1 N 1582		Si-Di	=1N1581: 100V	32a	DO-4		BYW 88/100, BYX 42/300, BYX 98/300, ++
1 N 1583		Si-Di	=1N1581: 200V	32a	DO-4		BYW 88/200, BYX 42/300, BYX 98/300, ++
1 N 1584		Si-Di	=1N1581: 300V	32a	DO-4		BYW 88/300, BYX 42/300, BYX 98/300, ++
1 N 1585		Si-Di	=1N1581: 400V	32a	DO-4		BYW 88/400, BYX 42/600, BYX 98/600, ++
1 N 1586		Si-Di	=1N1581: 500V	32a	DO-4		BYW 88/500, BYX 42/600, BYX 98/600, ++
1 N 1587		Si-Di	=1N1581: 600V	32a	DO-4		BYW 88/600, BYX 42/600, BYX 98/600, ++
1 N 1581R...1587R		Si-Di	=1N1581...1587:	32b	DO-4		BYW 88/...R, BYX 42/...R, BYX 98/...R, ++
1 N 1588	USA,Mot	Z-Di	3,9V, 10%, 3,5W	32a	DO-4		BZX98/..., BZY93/..., ZX..., 1N2970...2988
1 N 1589		Z-Di	=1N1588: 4,7V	32a	DO-4		
1 N 1590		Z-Di	=1N1588: 5,6V	32a	DO-4		
1 N 1591		Z-Di	=1N1588: 6,8V	32a	DO-4		
1 N 1592		Z-Di	=1N1588: 8,2V	32a	DO-4		
1 N 1593		Z-Di	=1N1588: 10V	32a	DO-4		
1 N 1594		Z-Di	=1N1588: 12V	32a	DO-4		
1 N 1595		Z-Di	=1N1588: 15V	32a	DO-4		
1 N 1596		Z-Di	=1N1588: 18V	32a	DO-4		
1 N 1597		Z-Di	=1N1588: 22V	32a	DO-4		
1 N 1598		Z-Di	=1N1588: 27V	32a	DO-4		
1 N 1588A...1598A		Z-Di	=1N1588...1598: 5%	32a	DO-4		
1 N 1599	USA,Mot	Z-Di	3,9V, 10%, 10W(Tc=25°)	32a	DO-4		BZX98/..., BZY93/..., ZX..., 1N2970...2988
1 N 1600		Z-Di	=1N1599: 4,7V	32a	DO-4		
1 N 1601		Z-Di	=1N1599: 5,6V	32a	DO-4		
1 N 1602		Z-Di	=1N1599: 6,8V	32a	DO-4		
1 N 1603		Z-Di	=1N1599: 8,2V	32a	DO-4		
1 N 1604		Z-Di	=1N1599: 10V	32a	DO-4		
1 N 1605		Z-Di	=1N1599: 12V	32a	DO-4		
1 N 1606		Z-Di	=1N1599: 15V	32a	DO-4		
1 N 1607		Z-Di	=1N1599: 18V	32a	DO-4		
1 N 1608		Z-Di	=1N1599: 22V	32a	DO-4		
1 N 1609		Z-Di	=1N1599: 27V	32a	DO-4		
1 N 1599A...1609A		Z-Di	=1N1599...1609: 5%	32a	DO-4		
1 N 1610	USA	Si-Di	UHF, S/X-Band-Dem	Koax	SOD-49		-
1 N 1611(A,B)	USA	Si-Di	UHF, C/X-Band Dem	Koax	SOD-47		-
1 N 1612(A)	Gen.Idc,Rca Tix,++	Si-Di	P Rr, 50V, 15A(Tc=50°), Uf<1,5V(10A) A: Uf<1,1V(6A)	32a	DO-4	BY 329/1200 ⁴	17k BYX 25/600, BYX 99/300
1 N 1613(A)		Si-Di	=1N1612: 100V	32a	DO-4	BY 329/1200 ⁴	17k BYX 25/600, BYX 99/300
1 N 1614(A)		Si-Di	=1N1612: 200V	32a	DO-4	BY 329/1200 ⁴	17k BYX 25/600, BYX 99/300
1 N 1615(A)		Si-Di	=1N1612: 400V	32a	DO-4	BY 329/1200 ⁴	17k BYX 25/600, BYX 99/600
1 N 1616(A)		Si-Di	=1N1612: 600V	32a	DO-4	BY 329/1200 ⁴	17k BYX 25/600, BYX 99/600
1 N 1612R...1616R		Si-Di	=1N1612...1616:	32b	DO-4	BY 329/1200 ⁴	17k BYX 25/...R, BYX 99/...R, SSI E2040
1 N 1617	Sem	Si-Di	Rr, 100V, 1,5A, Uf<1,2V(1,5A)	31a	(12x6mm0)		BY 251...255, BY 226...227, 1N5392...99, ++
1 N 1618		Si-Di	=1N1617: 200V	31a	(12x6mm0)		BY 251...255, BY 226...227, 1N5393...99, ++
1 N 1619		Si-Di	=1N1617: 300V	31a	(12x6mm0)		BY 252...255, BY 226...227, 1N5394...99, ++
1 N 1620		Si-Di	=1N1617: 400V	31a	(12x6mm0)		BY 252...255, BY 226...227, 1N5395...99, ++
1 N 1621	Sem	Si-Di	P Rr, 100V, 10A(Tc=100°), Uf<1,2V(10A)	32a	DO-4		BYW 88/100, BYX 76...81, 2N4506...11, ++
1 N 1622		Si-Di	=1N1621: 200V	32a	DO-4		BYW 88/200, BYX 77...81, 2N4506...11, ++
1 N 1623		Si-Di	=1N1621: 300V	32a	DO-4		BYW 88/300, BYX 78...81, 2N4507...11, ++
1 N 1624		Si-Di	=1N1621: 400V	32a	DO-4		BYW 88/400, BYX 78...81, 2N4507...11, ++
1 N 1625(A)	Edl	Se-Di	Rr, 48V, 0,25mA(A=0,5mA), Uf<1V(0,1mA/A=0,2mA)	-36			-
1 N 1626(A)	Edl	Se-Di	Rr, 96V, 0,25mA(A=0,5mA), Uf<2V(0,1mA/A=0,2mA)	-36			-
1 N 1627	Edl	Se-Di	Rr, 48V, 3,8mA, Uf<1V(1,5mA)	-36			-
1 N 1628	Edl	Se-Di	Rr, 96V, 3,8mA, Uf<2V(1,5mA)	-36			-
1 N 1629	Edl	Se-Di	Rr, 144V, 3,8mA, Uf<3V(1,5mA)	-36			-
1 N 1630	Edl	Se-Di	Rr, 192V, 3,8mA, Uf<4V(1,5mA)	-36			-
1 N 1631	Edl	Se-Di	Rr, 240V, 3,8mA, Uf<5V(1,5mA)	-36			-
1 N 1632	Edl	Se-Di	Rr, 288V, 3,8mA, Uf<6V(1,5mA)	-36			-
1 N 1633	Edl	Se-Di	Rr, 336V, 3,8mA, Uf<7V(1,5mA)	-36			-
1 N 1634	Edl	Se-Di	Rr, 384V, 3,8mA, Uf<8V(1,5mA)	-36			-
1 N 1635	Edl	Se-Di	Rr, 48V, 13mA, Uf<1V(5mA)	-36			-
1 N 1636	Edl	Se-Di	Rr, 96V, 13mA, Uf<2V(5mA)	-36			-
1 N 1637	Edl	Se-Di	Rr, 144V, 13mA, Uf<3V(5mA)	-36			-
1 N 1638	Edl	Se-Di	Rr, 192V, 13mA, Uf<4V(5mA)	-36			-
1 N 1639	Edl	Se-Di	Rr, 240V, 13mA, Uf<5V(5mA)	-36			-
1 N 1640	Edl	Se-Di	Rr, 48V, 28mA, Uf<1V(11mA)	-36			-
1 N 1641	Edl	Se-Di	Rr, 96V, 28mA, Uf<2V(11mA)	-36			-
1 N 1642	Edl	Se-Di	Rr, 144V, 28mA, Uf<3V(11mA)	-36			-
1 N 1644	USA	Si-Di	Rr, 50V, 0,75A, Uf<0,5V(0,25A)	34a	DO-1		BY 126...127, BY 133...135, 1N4001...07, ++
1 N 1645		Si-Di	=1N1644: 100V	34a	DO-1		BY 126...127, BY 133...135, 1N4002...07, ++
1 N 1646		Si-Di	=1N1644: 150V	34a	DO-1		BY 126...127, BY 133...134, 1N4003...07, ++
1 N 1647		Si-Di	=1N1644: 200V	34a	DO-1		BY 126...127, BY 133...134, 1N4003...07, ++
1 N 1648		Si-Di	=1N1644: 250V	34a	DO-1		BY 126...127, BY 133...134, 1N4004...07, ++
1 N 1649		Si-Di	=1N1644: 300V	34a	DO-1		BY 126...127, BY 133...134, 1N4004...07, ++
1 N 1650		Si-Di	=1N1644: 350V	34a	DO-1		BY 126...127, BY 133...134, 1N4004...07, ++
1 N 1651		Si-Di	=1N1644: 400V	34a	DO-1		BY 126...127, BY 133...134, 1N4004...07, ++
1 N 1652		Si-Di	=1N1644: 500V	34a	DO-1		BY 126...127, BY 133...134, 1N4005...07, ++
1 N 1653		Si-Di	=1N1644: 600V	34a	DO-1		BY 126...127, BY 133...134, 1N4005...07, ++
1 N 1660	USA	Si-Di	P Rr, 50V, 116A(Tc=120°), Uf<1,3V(200A)	73a	DO-30		1N4587...96
1 N 1661		Si-Di	=1N1660: 100V	73a	DO-30		1N4587...96
1 N 1662		Si-Di	=1N1660: 150V	73a	DO-30		1N4588...96
1 N 1663		Si-Di	=1N1660: 200V	73a	DO-30		1N4588...96
1 N 1664		Si-Di	=1N1660: 300V	73a	DO-30		1N4589...96
1 N 1665		Si-Di	=1N1660: 400V	73a	DO-30		1N4590...96
1 N 1666		Si-Di	=1N1660: 500V	73a	DO-30		1N4591...96
1 N 1670	Sem,Ssi	Si-Di	P Rr, 50V, 240A(Tc=120°), Uf<1,25V(300A)	73a	DO-30		1N3735...44
1 N 1671		Si-Di	=1N1670: 100V	73a	DO-30		1N3735...44
1 N 1672		Si-Di	=1N1670: 150V	73a	DO-30		1N3736...44
1 N 1673		Si-Di	=1N1670: 200V	73a	DO-30		1N3736...44
1 N 1674		Si-Di	=1N1670: 300V	73a	DO-30		1N3737...44
1 N 1675		Si-Di	=1N1670: 400V	73a	DO-30		1N3738...44
1 N 1676		Si-Di	=1N1670: 500V	73a	DO-30		1N3739...44
1 N 1680	Ssi	Si-Di	P Rr, 150V, 50A(Tc=150°), Uf<1,2V(50A)	73a	DO-8		1N3289...97
1 N 1681		Si-Di	=1N1680: 250V	73a	DO-8		1N3290...97

Original	Fabric.	Constr.	Info	{Compl. Fig.	JAEGER	Fig.	International
1 N 1682		Si-Di	=1N1680: 300V	73a		DO-8	1N3290...97
1 N 1683		Si-Di	=1N1680: 350V	73a		DO-8	1N3291...97
1 N 1684		Si-Di	=1N1680: 400V	73a		DO-8	1N3291...97
1 N 1685		Si-Di	=1N1680: 450V	73a		DO-8	1N3292...97
1 N 1686		Si-Di	=1N1680: 500V	73a		DO-8	1N3292...97
1 N 1687		Si-Di	=1N1680: 600V	73a		DO-8	1N3293...97
1 N 1688		Si-Di	=1N1680: 700V	73a		DO-8	1N3294...97
1 N 1689		Si-Di	=1N1680: 800V	73a		DO-8	1N3294...97
1 N 1690		Si-Di	=1N1680: 900V	73a		DO-8	1N3295...97
1 N 1691		Si-Di	=1N1680: 1000V	73a		DO-8	1N3295...97
1 N 1692	USA,Tix	Si-Di	Rr, 100V, 0,75A, Uf<0,6V(0,25A)	34a		DO-1	BY 126...127, BY 133...135, 1N4002...07, ++
1 N 1693		Si-Di	=1N1692: 200V	34a		DO-1	BY 126...127, BY 133...134, 1N4003...07, ++
1 N 1694		Si-Di	=1N1692: 300V	34a		DO-1	BY 126...127, BY 133...134, 1N4004...07, ++
1 N 1695		Si-Di	=1N1692: 400V	34a		DO-1	BY 126...127, BY 133...134, 1N4004...07, ++
1 N 1696		Si-Di	=1N1692: 500V	34a		DO-1	BY 126...127, BY 133...134, 1N4005...07, ++
1 N 1697		Si-Di	=1N1692: 600V	34a		DO-1	BY 126...127, BY 133...134, 1N4005...07, ++
1 N 1698	Scn,Sem	Si-Di	kV-Rr, 6,6kV, 0,062A, Uf<33V(100mA)	31a	(109x140)		1N5183...84
1 N 1699	Scn,Sem	Si-Di	kV-Rr, 10kV, 0,058A, Uf<37V(90mA)	31a	(109x140)		1N5184
1 N 1700	Scn,Sem	Si-Di	kV-Rr, 12kV, 0,05A, Uf<45V(80mA)	31a	(109x140)		1N3052
1 N 1701	USA	Si-Di	Rr, 50V, 0,3A	34a		DO-12	BA 157...159, BY 206...207, BY 401...405, ++
1 N 1702		Si-Di	=1N1701: 100V	34a		DO-12	BA 157...159, BY 206...207, BY 402...405, ++
1 N 1703		Si-Di	=1N1701: 200V	34a		DO-12	BA 157...159, BY 206...207, BY 403...405, ++
1 N 1704		Si-Di	=1N1701: 300V	34a		DO-12	BA 157...159, BY 206...207, BY 404...405, ++
1 N 1705		Si-Di	=1N1701: 400V	34a		DO-12	BA 157...159, BY 207, BY 404...405, ++
1 N 1706		Si-Di	=1N1701: 500V	34a		DO-12	BA 158...159, BY 207, BY 405, ++
1 N 1707	USA	Si-Di	Rr, 50V, 0,5A, Uf<1,3V(1A)	34a		DO-12	BY 126...127, BY 133...135, 1N4001...07, ++
1 N 1708		Si-Di	=1N1707: 100V	34a		DO-12	BY 126...127, BY 133...135, 1N4002...07, ++
1 N 1709		Si-Di	=1N1707: 200V	34a		DO-12	BY 126...127, BY 133...134, 1N4003...07, ++
1 N 1710		Si-Di	=1N1707: 300V	34a		DO-12	BY 126...127, BY 133...134, 1N4004...07, ++
1 N 1711		Si-Di	=1N1707: 400V	34a		DO-12	BY 126...127, BY 133...134, 1N4004...07, ++
1 N 1712		Si-Di	=1N1707: 500V	34a		DO-12	BY 126...127, BY 133...134, 1N4005...07, ++
1 N 1730	Gen,Gie,I,dc	Si-Di	kV-Rr, 1kV, 0,2A, Uf<5V(0,1A)	31a	(13x10mm0)		GP 02-20, HVG 2, MR 250-2
1 N 1730 A	Mot,++	Si-Di	=1N1730: 0,35A, Uf<3V(0,4A)	31a	(13x10mm0)		-
1 N 1731		Si-Di	=1N1730: 1,5kV	31a	(13x10mm0)		GP 02-20, HVG 2, MR 250-2
1 N 1731 A		Si-Di	=1N1731: 0,35A, Uf<3V(0,4A)	31a	(13x10mm0)		-
1 N 1732		Si-Di	=1N1730: 2kV, Uf<9V(0,1A)	31a	(25x10mm0)		GP 02-20, HVG 2, MR 250-2
1 N 1732 A		Si-Di	=1N1732: 0,35A, Uf<3V(0,4A)	31a	(25x10mm0)		-
1 N 1733		Si-Di	=1N1730: 3kV, Uf<12V(0,1A)	31a	(25x10mm0)		GP 02-30, HVG 3, MR 250-3
1 N 1733 A		Si-Di	=1N1733: 0,35A, Uf<6V(0,4A)	31a	(25x10mm0)		-
1 N 1734		Si-Di	=1N1730: 5kV, Uf<18V(0,1A)	31a	(25x10mm0)		HVG 5, MR 250-5
1 N 1734 A		Si-Di	=1N1734: 0,35A, Uf<8V(0,4A)	31a	(25x10mm0)		-
1 N 1735(A)	USA,Mot	Ref-Di	6,2V(7,5mA), 5%, ±0,01(A=0,005)%/°C, <20Ω, 0,2W	31a	(13x7mm0)		BZV 10...11, BZV 27...28, 1N4580...81, ++
1 N 1736(A)	USA,Mot	Ref-Di	12,4V(7,5mA), 5%, ±0,01(A=0,005)%/°C, <40Ω, 0,4W	31a	(26x9mm0)		1N4908...09, 1N4912...13
1 N 1737(A)	USA,Mot	Ref-Di	18,6V(7,5mA), 5%, ±0,01(A=0,005)%/°C, <60Ω, 0,6W	31a	(16x16mm0)		-
1 N 1738(A)	USA,Mot	Ref-Di	24,8V(7,5mA), 5%, ±0,01(A=0,005)%/°C, <80Ω, 0,8W	31a	(16x16mm0)		-
1 N 1739(A)	USA,Mot	Ref-Di	31V(7,5mA), 5%, ±0,01(A=0,005)%/°C, <100Ω, 1W	31a	(30x16mm0)		-
1 N 1740(A)	USA,Mot	Ref-Di	37,2V(7,5mA), 5%, ±0,01(A=0,005)%/°C, <120Ω, 1,2W	31a	(30x16mm0)		-
1 N 1741(A)	USA,Mot	Ref-Di	43,4V(7,5mA), 5%, ±0,01(A=0,005)%/°C, <140Ω, 1,4W	31a	(30x16mm0)		-
1 N 1742(A)	USA,Mot	Ref-Di	49,6V(7,5mA), 5%, ±0,01(A=0,005)%/°C, <180Ω, 1,6W	31a	(30x16mm0)		-
1 N 1743	Wes	Z-Di	10V, 5%, 10W(Tc=25°)	32a		DO-4	BZX98/C10, BZY93/C10, ZX10, 1N2974
1 N 1744	Sem	Z-Di	10V, 5%, 1W	34a		DO-1	BZW22/C10, BZX61/C10, ZPY10, 1N5925, ++
1 N 1745	USA	Si-Di	kV-Rr, 1,5kV, 0,38A, Uf<15V(0,6A)	31a	(63x14mm0)		1N1731A
1 N 1746	USA	Si-Di	kV-Rr, 1,5kV, 0,44A, Uf<7,5V(0,7A)	31a	(46x14mm0)		-
1 N 1747	USA	Si-Di	kV-Rr, 1,8kV, 0,36A, Uf<18V(0,6V)	31a	(63x14mm0)		1N1732A
1 N 1748	USA	Si-Di	kV-Rr, 1,8kV, 0,42A, Uf<9V(0,7A)	31a	(46x14mm0)		-
1 N 1749	USA	Si-Di	kV-Rr, 2,4kV, 0,23A, Uf<24V(0,6A)	31a	(64x14mm0)		1N1733A
1 N 1750	USA	Si-Di	kV-Rr, 2,4kV, 0,38A, Uf<12V(0,6A)	31a	(46x14mm0)		-
1 N 1751	USA	Si-Di	kV-Rr, 3,6kV, 0,37A, Uf<27V(0,6A)	31a	(109x140)		1N1734A
1 N 1752	USA	Si-Di	kV-Rr, 3,6kV, 0,36A, Uf<18V(0,6A)	31a	(63x14mm0)		1N1734A
1 N 1753	USA	Si-Di	kV-Rr, 4,8kV, 0,33A, Uf<36V(0,6A)	31a	(109x140)		1N1734A
1 N 1754	USA	Si-Di	kV-Rr, 4,8kV, 0,32A, Uf<24V(0,6V)	31a	(63x14mm0)		1N1734A
1 N 1755	USA	Si-Di	kV-Rr, 6kV, 0,29A, Uf<45V(0,5A)	31a	(109x140)		-
1 N 1756	USA	Si-Di	kV-Rr, 6kV, 0,36A, Uf<30V(0,6A)	31a	(109x140)		-
1 N 1757	USA	Si-Di	kV-Rr, 7,2kV, 0,29A, Uf<54V(0,5A)	31a	(154x140)		-
1 N 1758	USA	Si-Di	kV-Rr, 7,2kV, 0,33A, Uf<36V(0,6A)	31a	(154x140)		-
1 N 1759	USA	Si-Di	kV-Rr, 8kV, 0,25A, Uf<60V(0,4A)	31a	(154x140)		-
1 N 1760	USA	Si-Di	kV-Rr, 12kV, 0,25A, Uf<60V(0,4A)	31a	(154x140)		-
1 N 1761	USA	Si-Di	kV-Rr, 14kV, 0,3A, Uf<52V(0,5A)	31a	(154x140)		-
1 N 1762	USA	Si-Di	kV-Rr, 16kV, 0,25A, Uf<60V(0,4A)	31a	(154x140)		-
1 N 1763(A)	USA,Rca	Si-Di	Rr, 400V, 0,5A(A=1A), Uf<3V(0,5A, A: Uf<1,2V(1A)	34a		DO-1	BY 126...127, BY 133...134, 1N4004...07, ++
1 N 1764(A)		Si-Di	=1N1763: 500V	34a		DO-1	BY 126...127, BY 133...134, 1N4005...07, ++
1 N 1765	USA,Mot	Z-Di	5,6V, 10%, 1W	34a		DO-13	BZW22/..., BZX61/..., ZPY..., 1M5919...56, ++
1 N 1766		Z-Di	=1N1765: 6,2V	34a		DO-13	
1 N 1767		Z-Di	=1N1765: 6,8V	34a		DO-13	
1 N 1768		Z-Di	=1N1765: 7,5V	34a		DO-13	
1 N 1769		Z-Di	=1N1765: 8,2V	34a		DO-13	
1 N 1770		Z-Di	=1N1765: 9,1V	34a		DO-13	
1 N 1771		Z-Di	=1N1765: 10V	34a		DO-13	
1 N 1772		Z-Di	=1N1765: 11V	34a		DO-13	
1 N 1773		Z-Di	=1N1765: 12V	34a		DO-13	
1 N 1774		Z-Di	=1N1765: 13V	34a		DO-13	
1 N 1775		Z-Di	=1N1765: 15V	34a		DO-13	
1 N 1776		Z-Di	=1N1765: 16V	34a		DO-13	
1 N 1777		Z-Di	=1N1765: 18V	34a		DO-13	
1 N 1778		Z-Di	=1N1765: 20V	34a		DO-13	
1 N 1779		Z-Di	=1N1765: 22V	34a		DO-13	
1 N 1780		Z-Di	=1N1765: 24V	34a		DO-13	
1 N 1781		Z-Di	=1N1765: 27V	34a		DO-13	
1 N 1782		Z-Di	=1N1765: 30V	34a		DO-13	
1 N 1783		Z-Di	=1N1765: 33V	34a		DO-13	
1 N 1784		Z-Di	=1N1765: 36V	34a		DO-13	
1 N 1785		Z-Di	=1N1765: 39V	34a		DO-13	
1 N 1786		Z-Di	=1N1765: 43V	34a		DO-13	

Original	Fabric.	Constr.	Info	{Compl. Fig.	JAEGER	Fig.	International
1 N 1787		Z-Di	=1N1765: 47V	34a		00-13	
1 N 1788		Z-Di	=1N1765: 51V	34a		00-13	
1 N 1789		Z-Di	=1N1765: 56V	34a		00-13	
1 N 1790		Z-Di	=1N1765: 62V	34a		00-13	
1 N 1791		Z-Di	=1N1765: 68V	34a		00-13	
1 N 1792		Z-Di	=1N1765: 75V	34a		00-13	
1 N 1793		Z-Di	=1N1765: 82V	34a		00-13	
1 N 1794		Z-Di	=1N1765: 91V	34a		00-13	
1 N 1795		Z-Di	=1N1765: 100V	34a		00-13	
1 N 1796		Z-Di	=1N1765: 110V	34a		00-13	
1 N 1797		Z-Di	=1N1765: 120V	34a		00-13	
1 N 1798		Z-Di	=1N1765: 130V	34a		00-13	
1 N 1799		Z-Di	=1N1765: 150V	34a		00-13	
1 N 1800		Z-Di	=1N1765: 160V	34a		00-13	
1 N 1801		Z-Di	=1N1765: 180V	34a		00-13	
1 N 1802		Z-Di	=1N1765: 200V	34a		00-13	
1 N 1765A....1802A		Z-Di	=1N1765...1802: 5%	34a		00-13	
1 N 1803	USA, Mot, Sie	Z-Di	5.6V, 10%, 10W(Tc=25°)	32b		00-4	BZX98/..., BZY93/..., ZX..., 1N2970...3015
1 N 1804		Z-Di	=1N1803: 6.2V	32b		00-4	
1 N 1805		Z-Di	=1N1803: 6.8V	32b		00-4	
1 N 1806		Z-Di	=1N1803: 7.5V	32b		00-4	
1 N 1807		Z-Di	=1N1803: 8.2V	32b		00-4	
1 N 1808		Z-Di	=1N1803: 9.1V	32b		00-4	
1 N 1809		Z-Di	=1N1803: 110V	32b		00-4	
1 N 1810		Z-Di	=1N1803: 120V	32b		00-4	
1 N 1811		Z-Di	=1N1803: 130V	32b		00-4	
1 N 1812		Z-Di	=1N1803: 150V	32b		00-4	
1 N 1813		Z-Di	=1N1803: 160V	32b		00-4	
1 N 1814		Z-Di	=1N1803: 180V	32b		00-4	
1 N 1815		Z-Di	=1N1803: 200V	32b		00-4	
1 N 1803A....1815A		Z-Di	=1N1803...1815: 5%	32b		00-4	
1 N 1803B....1815B		Z-Di	=1N1803...1815: 20%	32b		00-4	
1 N 1803C....1815C		Z-Di	=1N1803...1815: bidirectional	32b		00-4	
1 N 1803CA....1815CA		Z-Di	=1N1803...1815: bidirectional, 5%	32b		00-4	
1 N 1803R....1815R		Z-Di	=1N1803...1815:	32a		00-4	
1 N 1816	USA, Mot, Sie	Z-Di	13V, 10%, 10W	32b		00-4	BZX98/..., BZY93/..., ZX..., 1N2977...3004
1 N 1817		Z-Di	=1N1816: 15V	32b		00-4	
1 N 1818		Z-Di	=1N1816: 16V	32b		00-4	
1 N 1819		Z-Di	=1N1816: 18V	32b		00-4	
1 N 1820		Z-Di	=1N1816: 20V	32b		00-4	
1 N 1821		Z-Di	=1N1816: 22V	32b		00-4	
1 N 1822		Z-Di	=1N1816: 24V	32b		00-4	
1 N 1823		Z-Di	=1N1816: 27V	32b		00-4	
1 N 1824		Z-Di	=1N1816: 30V	32b		00-4	
1 N 1825		Z-Di	=1N1816: 33V	32b		00-4	
1 N 1826		Z-Di	=1N1816: 36V	32b		00-4	
1 N 1827		Z-Di	=1N1816: 39V	32b		00-4	
1 N 1828		Z-Di	=1N1816: 43V	32b		00-4	
1 N 1829		Z-Di	=1N1816: 47V	32b		00-4	
1 N 1830		Z-Di	=1N1816: 51V	32b		00-4	
1 N 1831		Z-Di	=1N1816: 56V	32b		00-4	
1 N 1832		Z-Di	=1N1816: 62V	32b		00-4	
1 N 1833		Z-Di	=1N1816: 68V	32b		00-4	
1 N 1834		Z-Di	=1N1816: 75V	32b		00-4	
1 N 1835		Z-Di	=1N1816: 82V	32b		00-4	
1 N 1836		Z-Di	=1N1816: 91V	32b		00-4	
1 N 1816A....1836A		Z-Di	=1N1816...1836: 5%	32b		00-4	
1 N 1816C....1836C		Z-Di	=1N1816...1836: bidirectional	32b		00-4	
1 N 1816CA....1836CA		Z-Di	=1N1816...1836: bidirectional, 5%	32b		00-4	
1 N 1816R....1836R		Z-Di	=1N1816...1836:	32a		00-4	
1 N 1838	USA	Ge-Di	UHF, X/Ku-Band Mx	Koax		SOD-48	-
1 N 1839	USA	Si-Di	Rr, 6.8V, 85mA, Uf<1V(50mA)	2c		=TO-1	-
1 N 1840	USA	Si-Di	Rr, 10V, 77mA, Uf<1V(35mA)	2c		=TO-1	-
1 N 1841	USA	Si-Di	Rr, 15V, 63mA, Uf<1V(23mA)	2c		=TO-1	-
1 N 1842	USA	Si-Di	Rr, 22V, 50mA, Uf<1V(12mA)	2c		=TO-1	-
1 N 1843	USA	Si-Di	Rr, 33V, 40mA, Uf<1V(7mA)	2c		=TO-1	-
1 N 1844	USA	Si-Di	Rr, 47V, 30mA, Uf<1V(4.5mA)	2c		=TO-1	-
1 N 1845	USA	Si-Di	Rr, 68V, 23mA, Uf<1V(2.7mA)	2c		=TO-1	-
1 N 1846	USA	Si-Di	Rr, 100V, 16mA, Uf<1V(1.5mA)	2c		=TO-1	-
1 N 1847	USA	Si-Di	Rr, 150V, 11mA, Uf<1V(1mA)	2c		=TO-1	-
1 N 1848	USA	Si-Di	Rr, 330V, 7.5mA, Uf<4V(3mA)	2c		=TO-1	-
1 N 1850	USA	Si-Di	Rr, 470V, 6mA, Uf<4V(2mA)	2c		=TO-1	-
1 N 1851		Si-Di	=1N1839			-	-
1 N 1852		Si-Di	=1N1840			-	-
1 N 1853		Si-Di	=1N1841			-	-
1 N 1854		Si-Di	=1N1842			-	-
1 N 1855		Si-Di	=1N1843			-	-
1 N 1856		Si-Di	=1N1844			-	-
1 N 1857		Si-Di	=1N1845			-	-
1 N 1858		Si-Di	=1N1846			-	-
1 N 1859		Si-Di	=1N1847			-	-
1 N 1860		Si-Di	=1N1848			-	-
1 N 1861		Si-Di	=1N1849			-	-
1 N 1862		Si-Di	=1N1850			-	-
1 N 1863		Si-Di	=1N1839			-	-
1 N 1864		Si-Di	=1N1840			-	-
1 N 1865		Si-Di	=1N1841			-	-
1 N 1866		Si-Di	=1N1842			-	-
1 N 1867		Si-Di	=1N1843			-	-
1 N 1868		Si-Di	=1N1844			-	-
1 N 1869		Si-Di	=1N1845			-	-
1 N 1870		Si-Di	=1N1846			-	-
1 N 1871		Si-Di	=1N1847			-	-

Original	Fabric.	Constr.	Info	(Compl. Fig.	JAEGER	Fig.	International
1 N 1872		Si-Di	=1N1848				
1 N 1873		Si-Di	=1N1849				
1 N 1874		Si-Di	=1N1850				
1 N 1875	USA	Z-Di	8,2V, 10%, 1W	34a	DO-13		BZW22/..., BZX61/..., ZPY..., 1N5923...49,++
1 N 1876		Z-Di	=1N1875: 10V	34a	DO-13		
1 N 1877		Z-Di	=1N1875: 12V	34a	DO-13		
1 N 1878		Z-Di	=1N1875: 15V	34a	DO-13		
1 N 1879		Z-Di	=1N1875: 18V	34a	DO-13		
1 N 1880		Z-Di	=1N1875: 22V	34a	DO-13		
1 N 1881		Z-Di	=1N1875: 27V	34a	DO-13		
1 N 1882		Z-Di	=1N1875: 33V	34a	DO-13		
1 N 1883		Z-Di	=1N1875: 39V	34a	DO-13		
1 N 1884		Z-Di	=1N1875: 47V	34a	DO-13		
1 N 1885		Z-Di	=1N1875: 56V	34a	DO-13		
1 N 1886		Z-Di	=1N1875: 68V	34a	DO-13		
1 N 1887		Z-Di	=1N1875: 82V	34a	DO-13		
1 N 1888		Z-Di	=1N1875: 100V	34a	DO-13		
1 N 1875A...1888A		Z-Di	=1N1875...1888: 5%	34a	DO-13		
1 N 1875B...1888B		Z-Di	=1N1875...1888: 1%	34a	DO-13		
1 N 1889	USA	Z-Di	120V, 10%, 3W	32a	DO-4		BZX98/..., BZY93/..., ZX..., 1N3008...3011
1 N 1890		Z-Di	=1N1889: 145V	32a	DO-4		
1 N 1889A...1890A		Z-Di	=1N1889...1890: 5%	32a	DO-4		
1 N 1889B...1890B		Z-Di	=1N1889...1890: 1%	32a	DO-4		
1 N 1891	Idc,Ssi	Z-Di	8,2V, 10%, 10W(Tc=25°)	32	=DO-4		BZX98/..., BZY93/..., ZX..., 1N2972...3011
1 N 1892		Z-Di	=1N1891: 10V	32	=DO-4		
1 N 1893		Z-Di	=1N1891: 12V	32	=DO-4		
1 N 1894		Z-Di	=1N1891: 15V	32	=DO-4		
1 N 1895		Z-Di	=1N1891: 18V	32	=DO-4		
1 N 1896		Z-Di	=1N1891: 22V	32	=DO-4		
1 N 1897		Z-Di	=1N1891: 27V	32	=DO-4		
1 N 1898		Z-Di	=1N1891: 33V	32	=DO-4		
1 N 1899		Z-Di	=1N1891: 39V	32	=DO-4		
1 N 1900		Z-Di	=1N1891: 47V	32	=DO-4		
1 N 1901		Z-Di	=1N1891: 56V	32	=DO-4		
1 N 1902		Z-Di	=1N1891: 68V	32	=DO-4		
1 N 1903		Z-Di	=1N1891: 82V	32	=DO-4		
1 N 1904		Z-Di	=1N1891: 100V	32	=DO-4		
1 N 1905		Z-Di	=1N1891: 120V	32	=DO-4		
1 N 1906		Z-Di	=1N1891: 150V	32	=DO-4		
1 N 1891A...1906A		Z-Di	=1N1891...1906: 5%	32	=DO-4		
1 N 1907	USA	Si-Di	Rr, 50V, 1,5A, Uf<1V(1A)	34a	DO-13		BY 251...255, BY 226...227, 1N5391...99, ++
1 N 1908		Si-Di	=1N1907: 100V	34a	DO-13		BY 251...255, BY 226...227, 1N5392...99, ++
1 N 1909		Si-Di	=1N1907: 200V	34a	DO-13		BY 251...255, BY 226...227, 1N5393...99, ++
1 N 1910		Si-Di	=1N1907: 300V	34a	DO-13		BY 252...255, BY 226...227, 1N5394...99, ++
1 N 1911		Si-Di	=1N1907: 400V	34a	DO-13		BY 252...255, BY 226...227, 1N5395...99, ++
1 N 1912		Si-Di	=1N1907: 500V	34a	DO-13		BY 253...255, BY 226...227, 1N5396...99, ++
1 N 1913		Si-Di	=1N1907: 600V	34a	DO-13		BY 253...255, BY 226...227, 1N5397...99, ++
1 N 1914		Si-Di	=1N1907: 700V	34a	DO-13		BY 254...255, BY 227, 1N5398...99, ++
1 N 1915		Si-Di	=1N1907: 800V	34a	DO-13		BY 254...255, BY 227, 1N5399, ++
1 N 1916		Si-Di	=1N1907: 900V	34a	DO-13		BY 255, BY 227, BYW 56, GP 15M, ++
1 N 1917	Idc,Ssi	Si-Di	P Rr, 50V, 4A, Uf<1V(1A)	32	=DO-4		BYX 38/300, BYX 39/600
1 N 1918		Si-Di	=1N1917: 100V	32	=DO-4		BYX 38/300, BYX 39/600
1 N 1919		Si-Di	=1N1917: 200V	32	=DO-4		BYX 38/300, BYX 39/600
1 N 1920		Si-Di	=1N1917: 300V	32	=DO-4		BYX 38/300, BYX 39/600
1 N 1921		Si-Di	=1N1917: 400V	32	=DO-4		BYX 38/600, BYX 39/600
1 N 1922		Si-Di	=1N1917: 500V	32	=DO-4		BYX 38/600, BYX 39/600
1 N 1923		Si-Di	=1N1917: 600V	32	=DO-4		BYX 38/600, BYX 39/600
1 N 1924		Si-Di	=1N1917: 700V	32	=DO-4		BYX 38/900, BYX 39/800
1 N 1925		Si-Di	=1N1917: 800V	32	=DO-4		BYX 38/900, BYX 39/800
1 N 1926		Si-Di	=1N1917: 900V	32	=DO-4		BYX 38/900, BYX 39/1000
1 N 1927	USA	Z-Di	3,9V, 10%, 0,2W	34a	DO-1		BZX55/..., BZX79/..., ZPD..., 1N5228...71,++
1 N 1928		Z-Di	=1N1927: 4,7V	34a	DO-1		
1 N 1929		Z-Di	=1N1927: 5,6V	34a	DO-1		
1 N 1930		Z-Di	=1N1927: 6,8V	34a	DO-1		
1 N 1931		Z-Di	=1N1927: 8,2V	34a	DO-1		
1 N 1932		Z-Di	=1N1927: 10V	34a	DO-1		
1 N 1933		Z-Di	=1N1927: 12V	34a	DO-1		
1 N 1934		Z-Di	=1N1927: 15V	34a	DO-1		
1 N 1935		Z-Di	=1N1927: 18V	34a	DO-1		
1 N 1936		Z-Di	=1N1927: 22V	34a	DO-1		
1 N 1937		Z-Di	=1N1927: 27V	34a	DO-1		
1 N 1938		Z-Di	=1N1927: 33V	34a	DO-1		
1 N 1939		Z-Di	=1N1927: 39V	34a	DO-1		
1 N 1940		Z-Di	=1N1927: 47V	34a	DO-1		
1 N 1941		Z-Di	=1N1927: 56V	34a	DO-1		
1 N 1942		Z-Di	=1N1927: 68V	34a	DO-1		
1 N 1943		Z-Di	=1N1927: 82V	34a	DO-1		
1 N 1944		Z-Di	=1N1927: 100V	34a	DO-1		
1 N 1927A...1944A		Z-Di	=1N1927...1944: 5%	34a	DO-1		
1 N 1927B...1944B		Z-Di	=1N1927...1944: 1%	34a	DO-1		
1 N 1945	USA	Z-Di	120V, 10%, 0,2W	31a	DO-7		BZX55/..., BZX79/..., ZPD..., 1N5273...81,...
1 N 1946		Z-Di	=1N1945: 145V	31a	DO-7		
1 N 1947		Z-Di	=1N1945: 180V	31a	DO-7		
1 N 1948		Z-Di	=1N1945: 220V	31a	DO-7		
1 N 1949		Z-Di	=1N1945: 270V	31a	DO-7		
1 N 1950		Z-Di	=1N1945: 330V	31a	DO-7		
1 N 1951		Z-Di	=1N1945: 395V	31a	DO-7		
1 N 1952		Z-Di	=1N1945: 470V	31a	DO-7		
1 N 1953		Z-Di	=1N1945: 565V	31a	DO-7		
1 N 1945A...1953A		Z-Di	=1N1945...1953: 5%	31a	DO-7		
1 N 1945B...1953B		Z-Di	=1N1945...1953: 1%	31a	DO-7		
1 N 1954	USA	Z-Di	3,95V, 10%, 0,4W	31a	DO-7		BZX55/..., BZX83/..., ZPD..., 1N5228...57,++
1 N 1955		Z-Di	=1N1954: 4,7V	31a	DO-7		

Original	Fabric.	Constr.	Info	{Compl. Fig.	JAEGER	Fig.	International
1 N 1956		Z-Di	=1N1954: 5,65V	31a		DO-7	
1 N 1957		Z-Di	=1N1954: 6,85V	31a		DO-7	
1 N 1958		Z-Di	=1N1954: 8,3V	31a		DO-7	
1 N 1959		Z-Di	=1N1954: 9,7V	31a		DO-7	
1 N 1960		Z-Di	=1N1954: 12V	31a		DO-7	
1 N 1961		Z-Di	=1N1954: 14,5V	31a		DO-7	
1 N 1962		Z-Di	=1N1954: 18V	31a		DO-7	
1 N 1963		Z-Di	=1N1954: 22V	31a		DO-7	
1 N 1964		Z-Di	=1N1954: 27V	31a		DO-7	
1 N 1965		Z-Di	=1N1954: 33V	31a		DO-7	
1 N 1954A...1965A		Z-Di	=1N1954...1965: 5%	31a		DO-7	
1 N 1954B...1965B		Z-Di	=1N1954...1965: 1%	31a		DO-7	
1 N 1966	Sem	Z-Di	39,5V, 10%, 0,4W	34a		DO-1	BZX55/..., BZX83/..., ZPD..., 1N5259...81,++
1 N 1967		Z-Di	=1N1966: 47V	34a		DO-1	
1 N 1968		Z-Di	=1N1966: 56,5V	34a		DO-1	
1 N 1969		Z-Di	=1N1966: 68,5V	34a		DO-1	
1 N 1970		Z-Di	=1N1966: 83V	34a		DO-1	
1 N 1971		Z-Di	=1N1966: 100V	34a		DO-1	
1 N 1972		Z-Di	=1N1966: 120V	34a		DO-1	
1 N 1973		Z-Di	=1N1966: 150V	34a		DO-1	
1 N 1974		Z-Di	=1N1966: 180V	34a		DO-1	
1 N 1975		Z-Di	=1N1966: 220V	34a		DO-1	
1 N 1976		Z-Di	=1N1966: 270V	34a		DO-1	
1 N 1977		Z-Di	=1N1966: 330V	34a		DO-1	
1 N 1978		Z-Di	=1N1966: 390V	34a		DO-1	
1 N 1979		Z-Di	=1N1966: 470V	34a		DO-1	
1 N 1980		Z-Di	=1N1966: 560V	34a		DO-1	
1 N 1981	USA	Z-Di	3,9V, 10%, 0,15W	2c		-TO-1	BZX55/..., BZX79/..., ZPD..., 1N5228...81,++
1 N 1982		Z-Di	=1N1981: 4,7V	2c		-TO-1	
1 N 1983		Z-Di	=1N1981: 5,6V	2c		-TO-1	
1 N 1984		Z-Di	=1N1981: 6,8V	2c		-TO-1	
1 N 1985		Z-Di	=1N1981: 8,2V	2c		-TO-1	
1 N 1986		Z-Di	=1N1981: 10V	2c		-TO-1	
1 N 1987		Z-Di	=1N1981: 12V	2c		-TO-1	
1 N 1988		Z-Di	=1N1981: 15V	2c		-TO-1	
1 N 1989		Z-Di	=1N1981: 18V	2c		-TO-1	
1 N 1990		Z-Di	=1N1981: 22V	2c		-TO-1	
1 N 1991		Z-Di	=1N1981: 27V	2c		-TO-1	
1 N 1992		Z-Di	=1N1981: 33V	2c		-TO-1	
1 N 1993		Z-Di	=1N1981: 39V	2c		-TO-1	
1 N 1994		Z-Di	=1N1981: 47V	2c		-TO-1	
1 N 1995		Z-Di	=1N1981: 56V	2c		-TO-1	
1 N 1996		Z-Di	=1N1981: 68V	2c		-TO-1	
1 N 1997		Z-Di	=1N1981: 82V	2c		-TO-1	
1 N 1998		Z-Di	=1N1981: 100V	2c		-TO-1	
1 N 1999		Z-Di	=1N1981: 120V	2c		-TO-1	
1 N 2000		Z-Di	=1N1981: 150V	2c		-TO-1	
1 N 2001		Z-Di	=1N1981: 180V	2c		-TO-1	
1 N 2002		Z-Di	=1N1981: 220V	2c		-TO-1	
1 N 2003		Z-Di	=1N1981: 270V	2c		-TO-1	
1 N 2004		Z-Di	=1N1981: 330V	2c		-TO-1	
1 N 2005		Z-Di	=1N1981: 390V	2c		-TO-1	
1 N 2006		Z-Di	=1N1981: 470V	2c		-TO-1	
1 N 2007		Z-Di	=1N1981: 560V	2c		-TO-1	
1 N 1981A...2007A		Z-Di	=1N1981...2007: 5%	2c		-TO-1	
1 N 1981B...2007B		Z-Di	=1N1981...2007: 1%	2c		-TO-1	
1 N 2008	USA, Mot, Sie	Z-Di	100V, 10%, 10W(Tc=25°)	32b		DO-4	BZX98/..., BZY93/..., ZX..., 1N3005...3011
1 N 2009		Z-Di	=1N2008: 110V	32b		DO-4	
1 N 2010		Z-Di	=1N2008: 120V	32b		DO-4	
1 N 2011		Z-Di	=1N2008: 130V	32b		DO-4	
1 N 2012		Z-Di	=1N2008: 150V	32b		DO-4	
1 N 2008A...2012A		Z-Di	=1N2008...2012: 5%	32b		DO-4	
1 N 2008C...2012C		Z-Di	=1N2008...2012: bidirectional	32b		DO-4	
1 N 2008CA...2012CA		Z-Di	=1N2008...2012: bidirectional, 5%	32b		DO-4	
1 N 2008R...2012R		Z-Di	=1N2008...2012:	32a		DO-4	
1 N 2013	USA	Si-Di	Rr, 50V, 0,2A, Uf<1,5V(0,5A)	34a		DO-12	BA 157...159, BY 206...207, BY 204/4, ++
1 N 2014		Si-Di	=1N2013: 100V	34a		DO-12	BA 157...159, BY 206...207, BY 204/4, ++
1 N 2015		Si-Di	=1N2013: 150V	34a		DO-12	BA 157...159, BY 206...207, BY 204/4, ++
1 N 2016		Si-Di	=1N2013: 200V	34a		DO-12	BA 157...159, BY 206...207, BY 204/4, ++
1 N 2017		Si-Di	=1N2013: 250V	34a		DO-12	BA 157...159, BY 206...207, BY 204/4, ++
1 N 2018		Si-Di	=1N2013: 300V	34a		DO-12	BA 157...159, BY 206...207, BY 204/4, ++
1 N 2019		Si-Di	=1N2013: 350V	34a		DO-12	BA 157...159, BY 206...207, BY 204/4, ++
1 N 2020		Si-Di	=1N2013: 400V	34a		DO-12	BA 157...159, BY 207, BY 204/4, ++
1 N 2021	USA	Si-Di	P Rr, 150V, 10A(Tc=150°), Uf<1,5V(25A)	32a		DO-5	BYW 88/200, BYX 42/300, BYX 77...81, ++
1 N 2022		Si-Di	=1N2021: 250V	32a		DO-5	BYW 88/300, BYX 42/300, BYX 78...81, ++
1 N 2023		Si-Di	=1N2021: 300V	32a		DO-5	BYW 88/300, BYX 42/300, BYX 78...81, ++
1 N 2024		Si-Di	=1N2021: 350V	32a		DO-5	BYW 88/400, BYX 42/600, BYX 78...81, ++
1 N 2025		Si-Di	=1N2021: 400V	32a		DO-5	BYW 88/400, BYX 42/600, BYX 78...81, ++
1 N 2026	USA	Si-Di	P Rr, 50V, 1A(Tc=150°), Uf<2V(2A)	32a		DO-4	BYX 38/300, BYX 39/600
1 N 2027		Si-Di	=1N2026: 200V	32a		DO-4	BYX 38/300, BYX 39/600
1 N 2028		Si-Di	=1N2026: 300V	32a		DO-4	BYX 38/300, BYX 39/600
1 N 2029		Si-Di	=1N2026: 400V	32a		DO-4	BYX 38/600, BYX 39/600
1 N 2030		Si-Di	=1N2026: 500V	32a		DO-4	BYX 38/600, BYX 39/600
1 N 2031		Si-Di	=1N2026: 600V	32a		DO-4	BYX 38/600, BYX 39/600
1 N 2032	USA, Mot	Z-Di	4,85V, 10%, 0,75W	34a		DO-13	BZV85/..., BZW22/..., ZPY..., 1N3016...29,++
1 N 2033		Z-Di	=1N2032: 5,8V	34a		DO-13	
1 N 2034		Z-Di	=1N2032: 7,1V	34a		DO-13	
1 N 2035		Z-Di	=1N2032: 8,75V	34a		DO-13	
1 N 2036		Z-Di	=1N2032: 10,5V	34a		DO-13	
1 N 2037		Z-Di	=1N2032: 12,7V	34a		DO-13	
1 N 2038		Z-Di	=1N2032: 15,7V	34a		DO-13	
1 N 2039		Z-Di	=1N2032: 19V	34a		DO-13	
1 N 2040		Z-Di	=1N2032: 23,5V	34a		DO-13	

Original	Fabric.	Constr.	Info	(Compl. Fig.	JAEGER	Fig.	International
1 N 2032A...2040A		Z-Di	=1N2032...2040: 5%	34a		DO-13	
1 N 2041	USA, Mot, Sie	Z-Di	4,85V, 10%, 10W(Tc=25°)	32		DO-4	BZX98/..., BZY93/..., ZX..., 1N2970...86
1 N 2042		Z-Di	=1N2041: 5,8V	32		DO-4	
1 N 2043		Z-Di	=1N2041: 7,1V	32		DO-4	
1 N 2044		Z-Di	=1N2041: 8,75V	32		DO-4	
1 N 2045		Z-Di	=1N2041: 10,5V	32		DO-4	
1 N 2046		Z-Di	=1N2041: 12,7V	32		DO-4	
1 N 2047		Z-Di	=1N2041: 15,7V	32		DO-4	
1 N 2048		Z-Di	=1N2041: 19V	32		DO-4	
1 N 2049		Z-Di	=1N2041: 23,5V	32		DO-4	
1 N 2041...49-1...-4		Z-Di	=1N2041...2049: -5%	32		DO-4	
1 N 2041...49A...D		Z-Di	=1N2041...2049: -5%	32		DO-4	
1 N 2054	USA	Si-Di	P Rr, 50V, 250A(Tc=135°), Uf<1,25V(250A)	73a		DO-9	1N3735...44
1 N 2055		Si-Di	=1N2054: 100V	73a		DO-9	1N3735...44
1 N 2056		Si-Di	=1N2054: 150V	73a		DO-9	1N3736...44
1 N 2057		Si-Di	=1N2054: 200V	73a		DO-9	1N3736...44
1 N 2058		Si-Di	=1N2054: 250V	73a		DO-9	1N3737...44
1 N 2059		Si-Di	=1N2054: 300V	73a		DO-9	1N3737...44
1 N 2060		Si-Di	=1N2054: 350V	73a		DO-9	1N3738...44
1 N 2061		Si-Di	=1N2054: 400V	73a		DO-9	1N3738...44
1 N 2062		Si-Di	=1N2054: 450V	73a		DO-9	1N3739...44
1 N 2063		Si-Di	=1N2054: 500V	73a		DO-9	1N3739...44
1 N 2064		Si-Di	=1N2054: 600V	73a		DO-9	1N3740...44
1 N 2065		Si-Di	=1N2054: 700V	73a		DO-9	1N3741...44
1 N 2066		Si-Di	=1N2054: 800V	73a		DO-9	1N3741...44
1 N 2067		Si-Di	=1N2054: 900V	73a		DO-9	1N3742...44
1 N 2068		Si-Di	=1N2054: 1000V	73a		DO-9	1N3742...44
1 N 2069(A)	Gie, Tix, ++	Si-Di	Rr, 200V, 0,75A, Uf<1,2V(0,5A)	31a	BYD 33 M	31a	BY 126...127, BY 133...134, 1N4003...07, ++
1 N 2070(A)		Si-Di	=1N2069: 400V	31a	BYD 33 M	31a	BY 126...127, BY 133...134, 1N4004...07, ++
1 N 2071(A)		Si-Di	=1N2069: 600V	31a	BYD 33 M	31a	BY 126...127, BY 133...134, 1N4005...07, ++
1 N 2072	USA	Si-Di	Rr, 50V, 0,75A, Uf<1,2V(0,5A)	34a		DO-1	BY 126...127, BY 133...135, 1N4001...07, ++
1 N 2073		Si-Di	=1N2072: 100V	34a		DO-1	BY 126...127, BY 133...135, 1N4002...07, ++
1 N 2074		Si-Di	=1N2072: 150V	34a		DO-1	BY 126...127, BY 133...135, 1N4003...07, ++
1 N 2075		Si-Di	=1N2072: 200V	34a		DO-1	BY 126...127, BY 133...134, 1N4003...07, ++
1 N 2076		Si-Di	=1N2072: 250V	34a		DO-1	BY 126...127, BY 133...134, 1N4004...07, ++
1 N 2077		Si-Di	=1N2072: 300V	34a		DO-1	BY 126...127, BY 133...134, 1N4004...07, ++
1 N 2078		Si-Di	=1N2072: 400V	34a		DO-1	BY 126...127, BY 133...134, 1N4004...07, ++
1 N 2079		Si-Di	=1N2072: 500V	34a		DO-1	BY 126...127, BY 133...134, 1N4005...07, ++
1 N 2080	USA	Si-Di	Rr, 50V, 0,5A, Uf<0,75V(0,5A)	34a		DO-1	BY 126...127, BY 133...135, 1N4001...07, ++
1 N 2081		Si-Di	=1N2080: 100V	34a		DO-1	BY 126...127, BY 133...135, 1N4002...07, ++
1 N 2082		Si-Di	=1N2080: 200V	34a		DO-1	BY 126...127, BY 133...134, 1N4003...07, ++
1 N 2083		Si-Di	=1N2080: 300V	34a		DO-1	BY 126...127, BY 133...134, 1N4004...07, ++
1 N 2084		Si-Di	=1N2080: 400V	34a		DO-1	BY 126...127, BY 133...134, 1N4004...07, ++
1 N 2085		Si-Di	=1N2080: 500V	34a		DO-1	BY 126...127, BY 133...134, 1N4005...07, ++
1 N 2086		Si-Di	=1N2080: 600V	34a		DO-1	BY 126...127, BY 133...134, 1N4005...07, ++
1 N 2088		Si-Di	Rr, 500V, 0,75A, Uf<1,2V				BY 126...127, BY 133...134, 1N4005...07, ++
1 N 2089		Si-Di	=1N2088: 600V				BY 126...127, BY 133...134, 1N4005...07, ++
1 N 2090	USA	Si-Di	Rr, 50V, 0,75A, Uf<0,5V(0,5A)	~36a			BY 126...127, BY 133...135, 1N4001...07, ++
1 N 2091		Si-Di	=1N2090: 100V	~36a			BY 126...127, BY 133...135, 1N4002...07, ++
1 N 2092		Si-Di	=1N2090: 200V	~36a			BY 126...127, BY 133...134, 1N4003...07, ++
1 N 2093		Si-Di	=1N2090: 300V	~36a			BY 126...127, BY 133...134, 1N4004...07, ++
1 N 2094		Si-Di	=1N2090: 400V	~36a			BY 126...127, BY 133...134, 1N4004...07, ++
1 N 2095		Si-Di	=1N2090: 500V	~36a			BY 126...127, BY 133...134, 1N4005...07, ++
1 N 2096		Si-Di	=1N2090: 600V	~36a			BY 126...127, BY 133...134, 1N4005...07, ++
1 N 2102	USA	Si-Di	UHF, L/S-Band Dem	Koax		SOD-48	-
1 N 2103	USA	Si-Di	Rr, 50V, 0,75A, Uf<1,2V(0,75A)	34a		DO-1	BY 126...127, BY 133...135, 1N4001...07, ++
1 N 2104		Si-Di	=1N2103: 100V	34a		DO-1	BY 126...127, BY 133...135, 1N4002...07, ++
1 N 2105		Si-Di	=1N2103: 200V	34a		DO-1	BY 126...127, BY 133...134, 1N4003...07, ++
1 N 2106		Si-Di	=1N2103: 300V	34a		DO-1	BY 126...127, BY 133...134, 1N4004...07, ++
1 N 2107		Si-Di	=1N2103: 400V	34a		DO-1	BY 126...127, BY 133...134, 1N4004...07, ++
1 N 2108		Si-Di	=1N2103: 500V	34a		DO-1	BY 126...127, BY 133...134, 1N4005...07, ++
1 N 2109	Idc, Sem	Si-Di	P Rr, 50V, 2A, Uf<1,2V(0,75A)	32		~DO-4	(BY 249/300, BYX 38/300, BYX 39/600,++) [†]
1 N 2110		Si-Di	=1N2109: 100V	32		~DO-4	(BY 249/300, BYX 38/300, BYX 39/600,++) [†]
1 N 2111		Si-Di	=1N2109: 200V	32		~DO-4	(BY 249/300, BYX 38/300, BYX 39/600,++) [†]
1 N 2112		Si-Di	=1N2109: 300V	32		~DO-4	(BY 249/300, BYX 38/300, BYX 39/600,++) [†]
1 N 2113		Si-Di	=1N2109: 400V	32		~DO-4	(BY 249/600, BYX 38/600, BYX 39/600,++) [†]
1 N 2114		Si-Di	=1N2109: 500V	32		~DO-4	(BY 249/600, BYX 38/600, BYX 39/600,++) [†]
1 N 2115	USA	Si-Di	Rr, 365V, 0,3A, Uf<0,8V(0,2A)	~36a			BA 157...159, BY 206...207, BY 204/4, ++
1 N 2116	USA	Si-Di	Rr, 400V, 0,75A	34a		DO-12	BY 126...127, BY 133...134, 1N4004...07, ++
1 N 2117	USA	Si-Di	Rr, 720V, 0,75A, 0,9V(0,75A)	34a		DO-1	BY 127, BY 133, BYW 42, 1N4006...07, ++
1 N 2127(A)	USA	Si-Di	UHF, L/X-Band Dem	Koax		SOD-49	-
1 N 2128	USA	Si-Di	P Rr, 50V, 60A(Tc=115°), Uf<1,4V(60A,115°)	32a		DO-5	-
1 N 2129		Si-Di	=1N2128: 100V	32a		DO-5	-
1 N 2130		Si-Di	=1N2128: 150V	32a		DO-5	-
1 N 2131		Si-Di	=1N2128: 200V	32a		DO-5	-
1 N 2132		Si-Di	=1N2128: 250V	32a		DO-5	-
1 N 2133		Si-Di	=1N2128: 300V	32a		DO-5	-
1 N 2134		Si-Di	=1N2128: 350V	32a		DO-5	-
1 N 2135		Si-Di	=1N2128: 400V	32a		DO-5	-
1 N 2136		Si-Di	=1N2128: 450V	32a		DO-5	-
1 N 2137		Si-Di	=1N2128: 500V	32a		DO-5	-
1 N 2138		Si-Di	=1N2128: 600V	32a		DO-5	-
1 N 2128A...2138A		Si-Di	=1N2128...2138: 60A(Tc=140°), Uf<1,3V(60A,140°)	32a		DO-5	-
1 N 2128R...2138R		Si-Di	=1N2128...2138:	32b		DO-5	DS 75-02B...-16B
1 N 2139	USA	Si-Di	kV-Rr, 20kV, 0,045A, Uf<60V(80mA)	31a			1N3057
1 N 2146	Wes	Si-Di	FRr, 120V, Uf<1,1V(0,5A), <50ns	34a		~DO-1	BAV 15...16, EGP 10C, FE 1C
1 N 2147(A)	USA	Si-Di	P Rr, 50V, 6A(Tc=150°), Uf<1,2V(A=<1V)(10A)	32a		DO-4	BYX 38/300, BYX 39/600
1 N 2148(A)		Si-Di	=1N2147: 100V	32a		DO-4	BYX 38/300, BYX 39/600
1 N 2149(A)		Si-Di	=1N2147: 200V	32a		DO-4	BYX 38/300, BYX 39/600
1 N 2150(A)		Si-Di	=1N2147: 300V	32a		DO-4	BYX 38/300, BYX 39/600
1 N 2151(A)		Si-Di	=1N2147: 400V	32a		DO-4	BYX 38/600, BYX 39/600
1 N 2152(A)		Si-Di	=1N2147: 500V	32a		DO-4	BYX 38/600, BYX 39/600
1 N 2153(A)		Si-Di	=1N2147: 600V	32a		DO-4	BYX 38/600, BYX 39/600

Original	Fabric.	Constr.	Info	{Compl. Fig.	JAEGER	Fig.	International
1 N 2154	USA	Si-Di	P Rr, 50V, 25A(Tc=145°), Uf<0.6V(25A,145°)	32a	DO-5		1N3765...68, 1N4525...30
1 N 2155		Si-Di	=1N2154: 100V	32a	DO-5		1N3765...68, 1N4525...30
1 N 2156		Si-Di	=1N2154: 200V	32a	DO-5		1N3765...68, 1N4525...30
1 N 2157		Si-Di	=1N2154: 300V	32a	DO-5		1N3765...68, 1N4526...30
1 N 2158		Si-Di	=1N2154: 400V	32a	DO-5		1N3765...68, 1N4526...30
1 N 2159		Si-Di	=1N2154: 500V	32a	DO-5		1N3765...68, 1N4527...30
1 N 2160		Si-Di	=1N2154: 600V	32a	DO-5		1N3765...68, 1N4527...30
1 N 2154R...2160R		Si-Di	=1N2154...2160:	32b	DO-5		1N3765R...68R
1 N 2163(A)	USA, Mot, Sie	Ref-Di	9,4±0,4V(10mA), ±0,005%/°C, <15Ω, 0,75W, 0...+70° A=9,4±0,2V	34a	DO-13		-
1 N 2164(A)		Ref-Di	=1N2163: -55...+125°	34a	DO-13		-
1 N 2165(A)		Ref-Di	=1N2163: -55...+185°	34a	DO-13		-
1 N 2166(A)		Ref-Di	=1N2163: ±0,001%/°C	34a	DO-13		-
1 N 2167(A)		Ref-Di	=1N2163: ±0,001%/°C, -55...+125°	34a	DO-13		-
1 N 2168(A)		Ref-Di	=1N2163: ±0,001%/°C, -55...+185°	34a	DO-13		-
1 N 2169(A)		Ref-Di	=1N2163: ±0,0005%/°C	34a	DO-13		-
1 N 2170(A)		Ref-Di	=1N2163: ±0,0005%/°C, -55...+125°	34a	DO-13		-
1 N 2171(A)		Ref-Di	=1N2163: ±0,0005%/°C, -55...+185°	34a	DO-13		-
1 N 2172	USA	Si-Di	P Rr, 50V, 50A(Tc=150°), Uf<1,5V(50A)	73a	DO-8		1N3288...97
1 N 2173		Si-Di	=1N2172: 100V	73a	DO-8		1N3288...97
1 N 2174		Si-Di	=1N2172: 200V	73a	DO-8		1N3289...97
1 N 2175		Opto					
1 N 2176		Si-Di	Rr, 50V, 3A, Uf<1,1V(3A)				BY251...255, BYW82, GP30A, 1N5400...08, ++
1 N 2177		Si-Di	=1N2176: 100V				BY251...255, BYW82, GP30B, 1N5401...08, ++
1 N 2178		Si-Di	=1N2176: 150V				BY251...255, BYW82, GP30D, 1N5402...08, ++
1 N 2179		Si-Di	=1N2176: 200V				BY251...255, BYW82, GP30D, 1N5402...08, ++
1 N 2180		Si-Di	=1N2176: 300V				BY252...255, BYW83, GP30G, 1N5403...08, ++
1 N 2181		Si-Di	=1N2176: 400V				BY252...255, BYW83, GP30G, 1N5403...08, ++
1 N 2182		Si-Di	=1N2176: 500V				BY253...255, BYW84, GP30J, 1N5405...08, ++
1 N 2183		Si-Di	=1N2176: 600V				BY253...255, BYW84, GP30J, 1N5406...08, ++
1 N 2184		Si-Di	Rr, 50V, 3A, Uf<1,5V(3A)				BY251...255, BYW82, GP30A, 1N5400...08, ++
1 N 2185		Si-Di	=1N2184: 100V				BY251...255, BYW82, GP30B, 1N5401...08, ++
1 N 2186		Si-Di	=1N2184: 150V				BY251...255, BYW82, GP30D, 1N5402...08, ++
1 N 2187		Si-Di	=1N2184: 200V				BY251...255, BYW82, GP30D, 1N5402...08, ++
1 N 2188		Si-Di	=1N2184: 300V				BY252...255, BYW83, GP30G, 1N5403...08, ++
1 N 2189		Si-Di	=1N2184: 400V				BY252...255, BYW83, GP30G, 1N5403...08, ++
1 N 2190		Si-Di	=1N2184: 500V				BY253...255, BYW84, GP30J, 1N5405...08, ++
1 N 2191		Si-Di	=1N2184: 600V				BY253...255, BYW84, GP30J, 1N5405...08, ++
1 N 2192		Si-Di	=1N2184: 800V				BY254...255, BYW85, GP30K, 1N5407...08, ++
1 N 2193		Si-Di	=1N2184: 1000V				BY 255, BYW 86, GP 30M, 1N5408, ++
1 N 2194		Si-Di	P Rr, 50V, 6A, Uf<1,25V(6A)	32	DO-4		BYX 38/300, BYX 39/600
1 N 2195		Si-Di	=1N2194: 100V	32	DO-4		BYX 38/300, BYX 39/600
1 N 2196		Si-Di	=1N2194: 150V	32	DO-4		BYX 38/300, BYX 39/600
1 N 2197		Si-Di	=1N2194: 200V	32	DO-4		BYX 38/300, BYX 39/600
1 N 2198		Si-Di	=1N2194: 300V	32	DO-4		BYX 38/300, BYX 39/600
1 N 2199		Si-Di	=1N2194: 400V	32	DO-4		BYX 38/600, BYX 39/600
1 N 2200		Si-Di	=1N2194: 500V	32	DO-4		BYX 38/600, BYX 39/600
1 N 2201		Si-Di	=1N2194: 600V	32	DO-4		BYX 38/600, BYX 39/600
1 N 2202		Si-Di	=1N2194: 800V	32	DO-4		BYX 38/900, BYX 39/800
1 N 2203		Si-Di	=1N2194: 1000V	32	DO-4		BYX 38/1200, BYX 39/1000
1 N 2204		Si-Di	P Rr, 50V, 12A, Uf<1,25V(12A)	32	DO-4		BYW 88/50, BYX 75...81, BYX 99/300, ++
1 N 2205		Si-Di	=1N2204: 100V	32	DO-4		BYW 88/100, BYX 76...81, BYX 99/300, ++
1 N 2206		Si-Di	=1N2204: 150V	32	DO-4		BYW 88/200, BYX 77...81, BYX 99/300, ++
1 N 2207		Si-Di	=1N2204: 200V	32	DO-4		BYW 88/200, BYX 77...81, BYX 99/300, ++
1 N 2208		Si-Di	=1N2204: 300V	32	DO-4		BYW 88/300, BYX 78...81, BYX 99/300, ++
1 N 2209		Si-Di	=1N2204: 400V	32	DO-4		BYW 88/400, BYX 78...81, BYX 99/600, ++
1 N 2210		Si-Di	=1N2204: 500V	32	DO-4		BYW 88/500, BYX 79...81, BYX 99/600, ++
1 N 2211		Si-Di	=1N2204: 600V	32	DO-4		BYW 88/600, BYX 79...81, BYX 99/600, ++
1 N 2212		Si-Di	=1N2204: 800V	32	DO-4		BYW 88/800, BYX 80...81, BYX 99/900, ++
1 N 2213		Si-Di	=1N2204: 1000V	32	DO-4		BYW 88/1000, BYX 81, BYX 99/1200, ++
1 N 2214	USA	Z-Di	5,5V, 2%, 1W	34a	DO-1		BZW22/C5V6, BZX61/C5V6, ZPY5,6, 1N5919++
1 N 2216(A)	USA	Si-Di	P Rr, 50V, 1,5A, Uf<0,6V(1,5A)	32a	DO-4		BYX 38/300, BYX 39/600
1 N 2217(A)		Si-Di	=1N2216: Iso	32a	DO-10		-
1 N 2218(A)		Si-Di	=1N2216: 500V	32a	DO-4		BYX 38/600, BYX 39/600
1 N 2219(A)		Si-Di	=1N2216: 500V, Iso	32a	DO-10		-
1 N 2220(A)		Si-Di	=1N2216: 600V	32a	DO-4		BYX 38/600, BYX 39/600
1 N 2221(A)		Si-Di	=1N2216: 600V, Iso	32a	DO-10		-
1 N 2222(A)	USA	Si-Di	P Rr, 800V, 1A, Uf<0,6V(1,5A), A: Uf<0,6V(1A)	32a	DO-4		BYX 38/900, BYX 39/800
1 N 2223(A)		Si-Di	=1N2222: Iso	32a	DO-10		-
1 N 2224(A)		Si-Di	=1N2222: 1000V	32a	DO-4		BYX 38/1200, BYX 39/1000
1 N 2225(A)		Si-Di	=1N2222: 1000V, Iso	32a	DO-10		-
1 N 2226(A)		Si-Di	=1N2222: 1200V	32a	DO-4		BYX 38/1200, BYX 39/1200
1 N 2227(A)		Si-Di	=1N2222: 1200V, Iso	32a	DO-10		-
1 N 2228(A)	USA	Si-Di	P Rr, 50V, 5A, Uf<0,6V(1,5A), A: Uf<0,6V(5A)	32a	DO-4		BYX 38/300, BYX 39/600
1 N 2229(A)		Si-Di	=1N2228: Iso	32a	DO-10		-
1 N 2230(A)		Si-Di	=1N2228: 200V	32a	DO-4		BYX 38/300, BYX 39/600
1 N 2231(A)		Si-Di	=1N2228: 200V, Iso	32a	DO-10		-
1 N 2232(A)		Si-Di	=1N2228: 300V	32a	DO-4		BYX 38/300, BYX 39/600
1 N 2233(A)		Si-Di	=1N2228: 300V, Iso	32a	DO-10		-
1 N 2234(A)		Si-Di	=1N2228: 400V	32a	DO-4		BYX 38/600, BYX 39/600
1 N 2235(A)		Si-Di	=1N2228: 400V, Iso	32a	DO-10		-
1 N 2236(A)		Si-Di	=1N2228: 500V	32a	DO-4		BYX 38/600, BYX 39/600
1 N 2237(A)		Si-Di	=1N2228: 500V, Iso	32a	DO-10		-
1 N 2238(A)		Si-Di	=1N2228: 600V	32a	DO-4		BYX 38/600, BYX 39/600
1 N 2239(A)		Si-Di	=1N2228: 600V, Iso	32a	DO-10		-
1 N 2240(A)		Si-Di	=1N2228: 800V	32a	DO-4		BYX 38/900, BYX 39/800
1 N 2241(A)		Si-Di	=1N2228: 800V, Iso	32a	DO-10		-
1 N 2242(A)		Si-Di	=1N2228: 1000V	32a	DO-4		BYX 38/1200, BYX 39/1000
1 N 2243(A)		Si-Di	=1N2228: 1000V, Iso	32a	DO-10		-
1 N 2244(A)		Si-Di	=1N2228: 1200V	32a	DO-4		BYX 38/1200, BYX 39/1200
1 N 2245(A)		Si-Di	=1N2228: 1200V, Iso	32a	DO-10		-
1 N 2246(A)	USA	Si-Di	P Rr, 50V, 10A, Uf<0,6V(10A), Ir<1mA, A: Ir<0,5mA	32a	DO-4		BYX 42/300, BYX 98/300
1 N 2247(A)		Si-Di	=1N2246: Iso	32a	DO-10		-

Original	Fabric.	Constr.	Info	(Compl. Fig.	JAEGER	Fig.	International
1 N 2248(A)		Si-Di	=1N2246: 100V	32a		DO-4	BYX 42/300, BYX 98/300
1 N 2249(A)		Si-Di	=1N2246: 100V, Iso	32a		DO-10	-
1 N 2250(A)		Si-Di	=1N2246: 200V	32a		DO-4	BYX 42/300, BYX 98/300
1 N 2251(A)		Si-Di	=1N2246: 200V, Iso	32a		DO-10	-
1 N 2252(A)		Si-Di	=1N2246: 300V	32a		DO-4	BYX 42/300, BYX 98/300
1 N 2253(A)		Si-Di	=1N2246: 300V, Iso	32a		DO-10	-
1 N 2254(A)		Si-Di	=1N2246: 400V	32a		DO-4	BYX 42/600, BYX 98/600
1 N 2255(A)		Si-Di	=1N2246: 400V, Iso	32a		DO-10	-
1 N 2256(A)		Si-Di	=1N2246: 500V	32a		DO-4	BYX 42/600, BYX 98/600
1 N 2257(A)		Si-Di	=1N2246: 500V, Iso	32a		DO-10	-
1 N 2258(A)		Si-Di	=1N2246: 600V	32a		DO-4	BYX 42/600, BYX 98/600
1 N 2259(A)		Si-Di	=1N2246: 600V, Iso	32a		DO-10	-
1 N 2260(A)		Si-Di	=1N2246: 800V	32a		DO-4	BYX 42/900, BYX 98/900
1 N 2261(A)		Si-Di	=1N2246: 800V, Iso	32a		DO-10	-
1 N 2262(A)		Si-Di	=1N2246: 1000V	32a		DO-4	BYX 42/1200, BYX 98/1200
1 N 2263(A)		Si-Di	=1N2246: 1000V, Iso	32a		DO-10	-
1 N 2264(A)		Si-Di	=1N2246: 1200V	32a		DO-4	BYX 42/1200, BYX 98/1200
1 N 2265(A)		Si-Di	=1N2246: 1200V, Iso	32a		DO-10	-
1 N 2266	USA	Si-Di	P Rr, 50V, 1A(Tc=25°), Uf<0.6V(1A)	32a		DO-4	BYX 38/300, BYX 39/600
1 N 2267		Si-Di	=1N2266: Iso	32a		DO-10	-
1 N 2268		Si-Di	=1N2266: 500V	32a		DO-4	BYX 38/600, BYX 39/600
1 N 2269		Si-Di	=1N2266: 500V, Iso	32a		DO-10	-
1 N 2270		Si-Di	=1N2266: 600V	32a		DO-4	BYX 38/600, BYX 39/600
1 N 2271		Si-Di	=1N2266: 600V, Iso	32a		DO-10	-
1 N 2272	USA	Si-Di	P Rr, 50V, 6A(Tc=150°), Uf<1.2V, 20A	32a		DO-5	BYX 38/300, BYX 39/600
1 N 2273		Si-Di	=1N2272: 100V	32a		DO-5	BYX 38/300, BYX 39/600
1 N 2274		Si-Di	=1N2272: 200V	32a		DO-5	BYX 38/300, BYX 39/600
1 N 2275		Si-Di	=1N2272: 300V	32a		DO-5	BYX 38/300, BYX 39/600
1 N 2276		Si-Di	=1N2272: 400V	32a		DO-5	BYX 38/600, BYX 39/600
1 N 2277		Si-Di	=1N2272: 500V	32a		DO-5	BYX 38/600, BYX 39/600
1 N 2278		Si-Di	=1N2272: 600V	32a		DO-5	BYX 38/600, BYX 39/600
1 N 2279		Si-Di	=1N2272: 800V	32a		DO-5	BYX 38/900, BYX 39/800
1 N 2280		Si-Di	=1N2272: 1000V	32a		DO-5	BYX 38/1200, BYX 39/1000
1 N 2281		Si-Di	=1N2272: 1200V	32a		DO-5	BYX 38/1200, BYX 39/1200
1 N 2282	USA	Si-Di	P Rr, 300V, 20A(Tc=150°), Uf<1.5V(50A)	32a		DO-5	1N3765...68, 1N4525...30
1 N 2283		Si-Di	=1N2282: 400V	32a		DO-5	1N3765...68, 1N4526...30
1 N 2284		Si-Di	=1N2282: 500V	32a		DO-5	1N3765...68, 1N4527...30
1 N 2285		Si-Di	=1N2282: 600V	32a		DO-5	1N3765...68, 1N4527...30
1 N 2286		Si-Di	=1N2282: 800V	32a		DO-5	1N3766...68, 1N4528...30
1 N 2287		Si-Di	=1N2282: 1000V	32a		DO-5	1N3768, 1N4529...30
1 N 2288		Si-Di	=1N2282: 1200V	32a		DO-5	1N4530
1 N 2289...2293		Si-Di	=1N2289A...2293A: Iso	32a		DO-10	-
1 N 2289 A	USA	Si-Di	P Rr, 100V, 1.5A(Tc=25°), Uf<0.6V(1.5A)	32a		DO-4	BYX 38/300, BYX 39/600
1 N 2290 A		Si-Di	=1N2289A: 5A(Tc=25°), Uf<0.6V(5A)	32a		DO-4	BYX 38/300, BYX 39/600
1 N 2291 A		Si-Di	=1N2289A: 200V	32a		DO-4	BYX 38/300, BYX 39/600
1 N 2292 A		Si-Di	=1N2289A: 300V	32a		DO-4	BYX 38/300, BYX 39/600
1 N 2293 A		Si-Di	=1N2289A: 400V	32a		DO-4	BYX 38/600, BYX 39/600
1 N 2294		Si-Di	P Rr, 50V, 22A, Uf<1.1V(22A)				BYX 25/600, SSI E2040
1 N 2295		Si-Di	=1N2294: 100V				BYX 25/600, SSI E2040
1 N 2296		Si-Di	=1N2294: 150V				BYX 25/600, SSI E2040
1 N 2297		Si-Di	=1N2294: 200V				BYX 25/600, SSI E2040
1 N 2298		Si-Di	=1N2294: 250V				BYX 25/600, SSI E2040
1 N 2299		Si-Di	=1N2294: 300V				BYX 25/600, SSI E2040
1 N 2300		Si-Di	=1N2294: 350V				BYX 25/600, SSI E2040
1 N 2301		Si-Di	=1N2294: 400V				BYX 25/600, SSI E2040
1 N 2302		Si-Di	P Rr, 50V, 22A, Uf<1.1V(22A)				BYX 25/600, SSI E2040
1 N 2303		Si-Di	=1N2302: 100V				BYX 25/600, SSI E2040
1 N 2304		Si-Di	=1N2302: 150V				BYX 25/600, SSI E2040
1 N 2305		Si-Di	=1N2302: 200V				BYX 25/600, SSI E2040
1 N 2306		Si-Di	=1N2302: 250V				BYX 25/600, SSI E2040
1 N 2307		Si-Di	=1N2302: 300V				BYX 25/600, SSI E2040
1 N 2308		Si-Di	=1N2302: 350V				BYX 25/600, SSI E2040
1 N 2309		Si-Di	=1N2302: 400V				BYX 25/600, SSI E2040
1 N 2310		Si-Di	P Rr, 50V, 35A, Uf<1.1V(35A)				1N3765...68, 1N4525...30
1 N 2311		Si-Di	=1N2310: 100V				1N3765...68, 1N4525...30
1 N 2312		Si-Di	=1N2310: 150V				1N3765...68, 1N4525...30
1 N 2313		Si-Di	=1N2310: 200V				1N3765...68, 1N4525...30
1 N 2314		Si-Di	=1N2310: 250V				1N3765...68, 1N4526...30
1 N 2315		Si-Di	=1N2310: 300V				1N3765...68, 1N4526...30
1 N 2316		Si-Di	=1N2310: 350V				1N3765...68, 1N4526...30
1 N 2317		Si-Di	=1N2310: 400V				1N3765...68, 1N4526...30
1 N 2318		Si-Di	P Rr, 50V, 35A, Uf<1.1V(35A)				1N3765...68, 1N4525...30
1 N 2319		Si-Di	=1N2318: 100V				1N3765...68, 1N4525...30
1 N 2320		Si-Di	=1N2318: 150V				1N3765...68, 1N4525...30
1 N 2321		Si-Di	=1N2318: 200V				1N3765...68, 1N4525...30
1 N 2322		Si-Di	=1N2318: 250V				1N3765...68, 1N4526...30
1 N 2323		Si-Di	=1N2318: 300V				1N3765...68, 1N4526...30
1 N 2324		Si-Di	=1N2318: 350V				1N3765...68, 1N4526...30
1 N 2325		Si-Di	=1N2318: 400V				1N3765...68, 1N4526...30
1 N 2326	Rca	Ge-Di	Stabi, 1V, 0.2A, Uf<0.28V(0.1A)	2c		=TO-1	-
1 N 2327	Sem,Ssi	Si-Di	Rr, 1000/1100V, 0.4A, Uf<3.3V(0.4A)	34a		=DO-1	BY 127, BY 133, BYX 94...95, GP 100, ++
1 N 2328		Si-Di	=1N2327: 2000/2200V	34a		=DO-1	1N1732A, 1N1733A
1 N 2348	Sem,Ssi	Si-Di	P Rr, 50V, 3A(Tc=50°), Uf<1.1V(1A)	32a		DO-4	BYX 38/300, BYX 39/600
1 N 2349		Si-Di	=1N2348: 100V	32a		DO-4	BYX 38/300, BYX 39/600
1 N 2350		Si-Di	=1N2348: 150V	32a		DO-4	BYX 38/300, BYX 39/600
1 N 2357	USA	Si-Di	Rr, 1400V, 0.4A, Uf<2V(0.65A)	34a		DO-1	BY 231/1400, BY 268...269, GP 10V, ++
1 N 2358		Si-Di	=1N2357: 1500V	34a		DO-1	BY 231/1500, BY 269, DM 513, GP 10W
1 N 2359		Si-Di	=1N2357: 1600V	34a		DO-1	BY 269, DM 513, EM 516, GP 10V
1 N 2360		Si-Di	=1N2357: 1800V	34a		DO-1	DM 516, 1N1732A
1 N 2361		Si-Di	=1N2357: 2000V	34a		DO-1	1N1732A
1 N 2362	USA	Si-Di	P Rr, 1400V, 1A(Tc=25°), Uf<2V(1.5A)	32a		DO-4	-
1 N 2363		Si-Di	=1N2362: Iso	32a		DO-10	-
1 N 2364		Si-Di	=1N2362: 1500V	32a		DO-4	-

Original	Fabric.	Constr.	Info	{Compl. Fig.	JAEGER	Fig.	International
1 N 2365		Si-Di	=1N2362: 1500V, Iso	32a	DO-10	-	-
1 N 2366		Si-Di	=1N2362: 1600V	32a	DO-4	-	-
1 N 2367		Si-Di	=1N2362: 1600V, Iso	32a	DO-10	-	-
1 N 2368		Si-Di	=1N2362: 1800V	32a	DO-4	-	-
1 N 2369		Si-Di	=1N2362: 1800V, Iso	32a	DO-10	-	-
1 N 2370		Si-Di	=1N2362: 2000V	32a	DO-4	-	-
1 N 2371		Si-Di	=1N2362: 2000V, Iso	32a	DO-10	-	-
1 N 2362A...2371A		Si-Di	=1N2362...2371: 5A	32a	DO-4/-10	-	-
1 N 2362B...2371B		Si-Di	=1N2362...2371: 10A	32a	DO-4/-10	-	-
1 N 2372	USA	Si-Di	P Rr, 1000V, 0.2A(Tc=150°), Uf<2V(0,3A)	32a	DO-4	-	-
1 N 2373	USA	Si-Di	Rr, 600V, 0.25A, Uf<3V(100mA)	31a	(13x9mmØ)	BY 126...127, BY 133...134, 1N4005...07, ++	
1 N 2374	USA	Si-Di	Rr, 1000V, 0.25A, Uf<3V(100mA)	31a		BY 127, BY 133, GP 100, 1N4007...07, ++	
1 N 2375	USA	Si-Di	Rr, 1500V, 0.2A, Uf<4.5V(100mA)	31a		BY 231/1500, BY 269, DM 513, GP 10W	
1 N 2376	USA	Si-Di	Rr, 2000V, 0.2A, Uf<7.5V(100mA)	31a	(23x9mmØ)	HVG 2, GP 02-20, MR 250-2, 1N1732(A)	
1 N 2377	USA	Si-Di	Rr, 2400V, 0.15A, Uf<9V(75mA)	31a	(23x9mmØ)	HVG 3, GP 02-30, MR 250-3, 1N1733(A)	
1 N 2378	USA	Si-Di	Rr, 3000V, 0.15A, Uf<9V(75mA)	31a	(26x9mmØ)	HVG 3, GP 02-30, MR 250-3, 1N1733(A)	
1 N 2379	USA	Si-Di	Rr, 4000V, 0.15A, Uf<15V(50mA)	31a	(35x9mmØ)	HVG 4, GP 02-40, MR 250-4, 1N1734(A)	
1 N 2380	USA	Si-Di	Rr, 6000V, 0.1A, Uf<22.5V(50mA)	31a	(54x9mmØ)	BYX 90, 1N5183	
1 N 2381	USA	Si-Di	Rr, 10kV, 0.075A, Uf<37.5V(30mA)	31a	(54x9mmØ)	1N3052	
1 N 2382	Gen,Mot,++	Si-Di	kV-Rr, 4kV, 0.15A, Uf<18V(100mA)	31a	(38x12mmØ)	HVG 4, GP 02-40, MR 250-4, 1N1734(A)	
1 N 2382 A		Si-Di	=1N2382: 0.35A, Uf<6V(400mA)	31a	(12x10mmØ)	1N1734A	
1 N 2383	Gen,Mot,++	Si-Di	kV-Rr, 6kV, 0.1A, Uf<27V(100mA)	31a	(38x12mmØ)	BYX 90, 1N5183	
1 N 2383 A		Si-Di	=1N2383: 0.35A, Uf<9V(400mA)	31a	(12x10mmØ)	-	
1 N 2384	Gen,Mot,++	Si-Di	kV-Rr, 8kV, 0.07A, Uf<27V(100mA)	31a	(38x12mmØ)	1N5184	
1 N 2384 A		Si-Di	=1N2384: 0.275A, Uf<12V(400mA)	31a	(12x10mmØ)	-	
1 N 2385	Gen,Mot,++	Si-Di	kV-Rr, 10kV, 0.07A, Uf<39V(100mA)	31a	(51x12mmØ)	1N5184	
1 N 2385 A		Si-Di	=1N2384: 0.2A, Uf<15V(400mA)	31a	(12x10mmØ)	-	
1 N 2386	old	Ge-Di	UHF, 5V	Koax		-	
1 N 2387	Sem.Ssi	Z-Di	30V, 10%, 1W	34a	DO-13	BZW22/C10, BZX61/C10, ZPY10, 1N5925, ++	
1 N 2389	USA	Si-Di	Dual, Rr, 1600V, 0.6A, Uf<5V(0,6A)			-	
1 N 2390(A)	USA	Si-Di	Rr, 50V, 1.5A(Ta=55°), Uf<1,2V(1,5A)			BY 226...227, BY 251...255, 1N5391...99, ++	
1 N 2391(A)		Si-Di	=1N2390: 100V			BY 226...227, BY 251...255, 1N5392...99, ++	
1 N 2392(A)		Si-Di	=1N2390: 200V			BY 226...227, BY 251...255, 1N5393...99, ++	
1 N 2393(A)		Si-Di	=1N2390: 300V			BY 226...227, BY 252...255, 1N5394...99, ++	
1 N 2394(A)		Si-Di	=1N2390: 400V			BY 226...227, BY 252...255, 1N5395...99, ++	
1 N 2395(A)		Si-Di	=1N2390: 500V			BY 226...227, BY 253...255, 1N5396...99, ++	
1 N 2396(A)		Si-Di	=1N2390: 600V			BY 226...227, BY 253...255, 1N5397...99, ++	
1 N 2397(A)		Si-Di	=1N2390: 700V			BY 227, BY 254...255, 1N5398...99, ++	
1 N 2398(A)		Si-Di	=1N2390: 800V			BY 227, BY 254...255, 1N5398...99, ++	
1 N 2399(A)		Si-Di	=1N2390			-1N2390	
1 N 2400(A)		Si-Di	=1N2391			-1N2391	
1 N 2401(A)		Si-Di	=1N2392			-1N2392	
1 N 2402(A)		Si-Di	=1N2393			-1N2393	
1 N 2403(A)		Si-Di	=1N2394			-1N2394	
1 N 2404(A)		Si-Di	=1N2395			-1N2395	
1 N 2405(A)		Si-Di	=1N2396			-1N2396	
1 N 2406(A)		Si-Di	=1N2397			-1N2397	
1 N 2407(A)		Si-Di	=1N2398			-1N2398	
1 N 2408(A)		Si-Di	=1N2390			-1N2390	
1 N 2409(A)		Si-Di	=1N2391			-1N2391	
1 N 2410(A)		Si-Di	=1N2392			-1N2392	
1 N 2411(A)		Si-Di	=1N2393			-1N2393	
1 N 2412(A)		Si-Di	=1N2394			-1N2394	
1 N 2413(A)		Si-Di	=1N2395			-1N2395	
1 N 2414(A)		Si-Di	=1N2396			-1N2396	
1 N 2415(A)		Si-Di	=1N2397			-1N2397	
1 N 2416(A)		Si-Di	=1N2398			-1N2398	
1 N 2417(A)		Si-Di	=1N2390			-1N2390	
1 N 2418(A)		Si-Di	=1N2391			-1N2391	
1 N 2419(A)		Si-Di	=1N2392			-1N2392	
1 N 2420(A)		Si-Di	=1N2393			-1N2393	
1 N 2421(A)		Si-Di	=1N2394			-1N2394	
1 N 2422(A)		Si-Di	=1N2395			-1N2395	
1 N 2423(A)		Si-Di	=1N2396			-1N2396	
1 N 2424(A)		Si-Di	=1N2397			-1N2397	
1 N 2425(A)		Si-Di	=1N2398			-1N2398	
1 N 2426	USA	Si-Di	P Rr, 50V, 100A(Tc=75°), Uf<1,1V(50A)	73a	DO-8	1N3288...97	
1 N 2427		Si-Di	=1N2326: 100V	73a	DO-8	1N3288...97	
1 N 2428		Si-Di	=1N2326: 150V	73a	DO-8	1N3289...97	
1 N 2429		Si-Di	=1N2326: 200V	73a	DO-8	1N3289...97	
1 N 2430		Si-Di	=1N2326: 250V	73a	DO-8	1N3290...97	
1 N 2431		Si-Di	=1N2326: 300V	73a	DO-8	1N3290...97	
1 N 2432		Si-Di	=1N2326: 350V	73a	DO-8	1N3291...97	
1 N 2433		Si-Di	=1N2326: 400V	73a	DO-8	1N3291...97	
1 N 2434		Si-Di	=1N2326: 500V	73a	DO-8	1N3292...97	
1 N 2435		Si-Di	=1N2326: 600V	73a	DO-8	1N3293...97	
1 N 2436	USA	Si-Di	P Rr, 50V, 150A(Tc=75°), Uf<1,1V(70A)	73a	DO-8	1N4587...96	
1 N 2437		Si-Di	=1N2436: 100V	73a	DO-8	1N4587...96	
1 N 2438		Si-Di	=1N2436: 150V	73a	DO-8	1N4588...96	
1 N 2439		Si-Di	=1N2436: 200V	73a	DO-8	1N4588...96	
1 N 2440		Si-Di	=1N2436: 250V	73a	DO-8	1N4589...96	
1 N 2441		Si-Di	=1N2436: 300V	73a	DO-8	1N4589...96	
1 N 2442		Si-Di	=1N2436: 350V	73a	DO-8	1N4590...96	
1 N 2443		Si-Di	=1N2436: 400V	73a	DO-8	1N4590...96	
1 N 2444		Si-Di	=1N2436: 500V	73a	DO-8	1N4591...96	
1 N 2445		Si-Di	=1N2436: 600V	73a	DO-8	1N4592...96	
1 N 2446	USA	Si-Di	P Rr, 50V, 45A(Tc=60°), Uf<1,1V(20A)	32a	DO-5	-	
1 N 2447		Si-Di	=1N2446: 100V	32a	DO-5	-	
1 N 2448		Si-Di	=1N2446: 150V	32a	DO-5	-	
1 N 2449		Si-Di	=1N2446: 200V	32a	DO-5	-	
1 N 2450		Si-Di	=1N2446: 250V	32a	DO-5	-	
1 N 2451		Si-Di	=1N2446: 300V	32a	DO-5	-	
1 N 2452		Si-Di	=1N2446: 350V	32a	DO-5	-	

Original	Fabric.	Constr.	Info	(Comp. Fig.	JAEGER	Fig.	International
1 N 2453		Si-Di	=1N2446: 400V	32a		00-5	-
1 N 2454		Si-Di	=1N2446: 500V	32a		00-5	-
1 N 2455		Si-Di	=1N2446: 600V	32a		00-5	-
1 N 2456		Si-Di	=1N2446: 700V	32a		00-5	-
1 N 2457		Si-Di	=1N2446: 800V	32a		00-5	-
1 N 2458	USA	Si-Di	P Rr, 50V, 60A(Tc=60°), Uf<1,1V(30A)	32a		00-5	-
1 N 2459		Si-Di	=1N2458: 100V	32a		00-5	-
1 N 2460		Si-Di	=1N2458: 150V	32a		00-5	-
1 N 2461		Si-Di	=1N2458: 200V	32a		00-5	-
1 N 2462		Si-Di	=1N2458: 250V	32a		00-5	-
1 N 2463		Si-Di	=1N2458: 300V	32a		00-5	-
1 N 2464		Si-Di	=1N2458: 350V	32a		00-5	-
1 N 2465		Si-Di	=1N2458: 400V	32a		00-5	-
1 N 2466		Si-Di	=1N2458: 500V	32a		00-5	-
1 N 2467		Si-Di	=1N2458: 600V	32a		00-5	-
1 N 2468		Si-Di	=1N2458: 700V	32a		00-5	-
1 N 2469		Si-Di	=1N2458: 800V	32a		00-5	-
1 N 2482	USA	Si-Di	Rr, 200V, 0,75A, Uf<1,2V(0,75A)	31a		00-27	BY 126...127, BY 133...134, 1N4003...07, ++
1 N 2483		Si-Di	=1N2482: 400V	31a		00-27	BY 126...127, BY 133...134, 1N4004...07, ++
1 N 2484		Si-Di	=1N2482: 600V	31a		00-27	BY 126...127, BY 133...134, 1N4005...07, ++
1 N 2485	USA	Si-Di	Rr, 200V, 0,75A, Uf<1V(0,75A)	34a		00-1	BY 126...127, BY 133...134, 1N4003...07, ++
1 N 2486		Si-Di	=1N2485: 300V	34a		00-1	BY 126...127, BY 133...134, 1N4004...07, ++
1 N 2487		Si-Di	=1N2485: 400V	34a		00-1	BY 126...127, BY 133...134, 1N4004...07, ++
1 N 2488		Si-Di	=1N2485: 500V	34a		00-1	BY 126...127, BY 133...134, 1N4005...07, ++
1 N 2489		Si-Di	=1N2485: 600V	34a		00-1	BY 126...127, BY 133...134, 1N4005...07, ++
1 N 2490	USA	Si-Di	Dual, Rr, 1600V, 0,5A, Uf<4V(0,25A)				-
1 N 2491	USA	Si-Di	P Rr, 50V, 6A(Tc=150°), Uf<1,1V(6A)	32a		00-4	BYX 38/300, BYX 39/600
1 N 2492		Si-Di	=1N2491: 100V	32a		00-4	BYX 38/300, BYX 39/600
1 N 2493		Si-Di	=1N2491: 200V	32a		00-4	BYX 38/300, BYX 39/600
1 N 2494		Si-Di	=1N2491: 300V	32a		00-4	BYX 38/300, BYX 39/600
1 N 2495		Si-Di	=1N2491: 400V	32a		00-4	BYX 38/600, BYX 39/600
1 N 2496		Si-Di	=1N2491: 500V	32a		00-4	BYX 38/600, BYX 39/600
1 N 2497		Si-Di	=1N2491: 600V	32a		00-4	BYX 38/600, BYX 39/600
1 N 2498	USA,Mot,Sie	Z-Di	10V, 10%, 10W	32		00-4	BZX98/..., BZY93/..., ZX..., 1N2974...76
1 N 2499		Z-Di	=1N2498: 11V	32		00-4	
1 N 2500		Z-Di	=1N2498: 12V	32		00-4	
1 N 2498A...2500A		Z-Di	=1N2498...2500: 5%	32		00-4	
1 N 2498C...2500C		Z-Di	=1N2498...2500: bidirectional	32		00-4	
1 N 2501	USA	Si-Di	Rr, 800V, 0,15A, Uf<1,5V(0,1A)	34a		00-1	BA 159, BAY 90, BY 203/12, SHG 1
1 N 2502		Si-Di	=1N2501: 1000V	34a		00-1	BA 159, BAY 90, BY 203/12, SHG 1
1 N 2503		Si-Di	=1N2501: 1200V	34a		00-1	BAY 91, BY 203/12, SHG 1,5
1 N 2504		Si-Di	=1N2501: 1500V	34a		00-1	BAY 91, BY 203/15, SHG 1,5
1 N 2505	USA	Si-Di	Rr, 800V, 0,3A, Uf<1,5V(0,2A)	34a		00-1	BA 159, BAY 90, BY 203/12, GP 100, ++
1 N 2506		Si-Di	=1N2505: 1000V	34a		00-1	BA 159, BAY 90, BY 203/12, GP 100, ++
1 N 2507		Si-Di	=1N2505: 1200V	34a		00-1	BAY 91, BY 203/12, EM 513, GP 100, ++
1 N 2508		Si-Di	=1N2505: 1500V	34a		00-1	BAY 91, BY 203/15, EM 516, GP 100, ++
1 N 2509	USA	Si-Di	UHF, C-Band Mx	Koax		00-23	-
1 N 2510	USA	Si-Di	UHF, X-Band Mx	Koax		00-37	-
1 N 2512	USA	Si-Di	P Rr, 100V, 4A(Tc=30°), Uf<1,1V(1,5A)	32a		00-4	BYX 38/300, BYX 39/600
1 N 2513		Si-Di	=1N2512: 200V	32a		00-4	BYX 38/300, BYX 39/600
1 N 2514		Si-Di	=1N2512: 300V	32a		00-4	BYX 38/300, BYX 39/600
1 N 2515		Si-Di	=1N2512: 400V	32a		00-4	BYX 38/600, BYX 39/600
1 N 2516		Si-Di	=1N2512: 500V	32a		00-4	BYX 38/600, BYX 39/600
1 N 2517		Si-Di	=1N2512: 600V	32a		00-4	BYX 38/600, BYX 39/600
1 N 2518		Si-Di	=1N2512: Iso	32a		00-10	-
1 N 2519		Si-Di	=1N2513: Iso	32a		00-10	-
1 N 2520		Si-Di	=1N2514: Iso	32a		00-10	-
1 N 2521		Si-Di	=1N2515: Iso	32a		00-10	-
1 N 2522		Si-Di	=1N2516: Iso	32a		00-10	-
1 N 2523		Si-Di	=1N2517: Iso	32a		00-10	-
1 N 2512R...2523R		Si-Di	=1N2512...2523:	32b		00-4	BYX 38/...R, BYX 39/...R
1 N 2524	USA	Si-Di	P Rr, 50V, 2,5A(Tc=150°), Uf<1,2V(4A)	32a		00-10	-
1 N 2525		Si-Di	=1N2524: 100V	32a		00-10	-
1 N 2526		Si-Di	=1N2524: 200V	32a		00-10	-
1 N 2527		Si-Di	=1N2524: 300V	32a		00-10	-
1 N 2528		Si-Di	=1N2524: 400V	32a		00-10	-
1 N 2529		Si-Di	=1N2524: 500V	32a		00-10	-
1 N 2530		Si-Di	=1N2524: 600V	32a		00-10	-
1 N 2531		Si-Di	=1N2524: 700V	32a		00-10	-
1 N 2532		Si-Di	=1N2524: 800V	32a		00-10	-
1 N 2533		Si-Di	=1N2524: 900V	32a		00-10	-
1 N 2534		Si-Di	=1N2524: 1000V	32a		00-10	-
1 N 2535	USA	Si-Di	P Rr, 50V, 2,5A(Tc=150°), Uf<1V(4A)	32a		00-10	-
1 N 2536		Si-Di	=1N2535: 100V	32a		00-10	-
1 N 2537		Si-Di	=1N2535: 200V	32a		00-10	-
1 N 2538		Si-Di	=1N2535: 300V	32a		00-10	-
1 N 2539		Si-Di	=1N2535: 400V	32a		00-10	-
1 N 2540		Si-Di	=1N2535: 500V	32a		00-10	-
1 N 2541		Si-Di	=1N2535: 600V	32a		00-10	-
1 N 2542		Si-Di	=1N2535: 700V	32a		00-10	-
1 N 2543		Si-Di	=1N2535: 800V	32a		00-10	-
1 N 2544		Si-Di	=1N2535: 900V	32a		00-10	-
1 N 2545		Si-Di	=1N2535: 1000V	32a		00-10	-
1 N 2546	USA	Si-Di	P Rr, 50V, 2,5A(Tc=150°), Uf<1,5V(4A)	32a		00-10	-
1 N 2547		Si-Di	=1N2546: 100V	32a		00-10	-
1 N 2548		Si-Di	=1N2546: 200V	32a		00-10	-
1 N 2549		Si-Di	=1N2546: 300V	32a		00-10	-
1 N 2550		Si-Di	=1N2546: 400V	32a		00-10	-
1 N 2551		Si-Di	=1N2546: 500V	32a		00-10	-
1 N 2552		Si-Di	=1N2546: 600V	32a		00-10	-
1 N 2553		Si-Di	=1N2546: 700V	32a		00-10	-
1 N 2554		Si-Di	=1N2546: 800V	32a		00-10	-
1 N 2555		Si-Di	=1N2546: 900V	32a		00-10	-

Original	Fabric.	Constr.	Info	(Compl. Fig.	JAEGER	Fig.	International
1 N 2556		Si-Di	=1N2546: 1000V	32a		DO-10	-
1 N 2557	USA	Si-Di	P Rr, 700V, 6A(Tc=150°), Uf<1,2V(10A)	32a		DO-10	-
1 N 2558		Si-Di	=1N2557: 800V	32a		DO-10	-
1 N 2559		Si-Di	=1N2557: 900V	32a		DO-10	-
1 N 2560		Si-Di	=1N2557: 1000V	32a		DO-10	-
1 N 2561	USA	Si-Di	P Rr, 700V, 6A(Tc=150°), Uf<1V(10A)	32a		DO-10	-
1 N 2562		Si-Di	=1N2561: 800V	32a		DO-10	-
1 N 2563		Si-Di	=1N2561: 900V	32a		DO-10	-
1 N 2564		Si-Di	=1N2561: 1000V	32a		DO-10	-
1 N 2565	USA	Si-Di	P Rr, 50V, 6A(Tc=150°), Uf<1,5V(10A)	32a		DO-10	-
1 N 2566		Si-Di	=1N2565: 100V	32a		DO-10	-
1 N 2567		Si-Di	=1N2565: 200V	32a		DO-10	-
1 N 2568		Si-Di	=1N2565: 300V	32a		DO-10	-
1 N 2569		Si-Di	=1N2565: 400V	32a		DO-10	-
1 N 2570		Si-Di	=1N2565: 500V	32a		DO-10	-
1 N 2571		Si-Di	=1N2565: 600V	32a		DO-10	-
1 N 2572		Si-Di	=1N2565: 700V	32a		DO-10	-
1 N 2573		Si-Di	=1N2565: 800V	32a		DO-10	-
1 N 2574		Si-Di	=1N2565: 900V	32a		DO-10	-
1 N 2575		Si-Di	=1N2565: 1000V	32a		DO-10	-
1 N 2576	USA	Si-Di	P Rr, 50V, 12A(Tc=150°), Uf<1,2V(20A)	32a		DO-10	-
1 N 2577		Si-Di	=1N2576: 100V	32a		DO-10	-
1 N 2578		Si-Di	=1N2576: 200V	32a		DO-10	-
1 N 2579		Si-Di	=1N2576: 300V	32a		DO-10	-
1 N 2580		Si-Di	=1N2576: 400V	32a		DO-10	-
1 N 2581		Si-Di	=1N2576: 500V	32a		DO-10	-
1 N 2582		Si-Di	=1N2576: 600V	32a		DO-10	-
1 N 2583		Si-Di	=1N2576: 700V	32a		DO-10	-
1 N 2584		Si-Di	=1N2576: 800V	32a		DO-10	-
1 N 2585		Si-Di	=1N2576: 900V	32a		DO-10	-
1 N 2586		Si-Di	=1N2576: 1000V	32a		DO-10	-
1 N 2587	USA	Si-Di	P Rr, 50V, 12A(Tc=150°), Uf<1V(12A)	32a		DO-10	-
1 N 2588		Si-Di	=1N2587: 100V	32a		DO-10	-
1 N 2589		Si-Di	=1N2587: 200V	32a		DO-10	-
1 N 2590		Si-Di	=1N2587: 300V	32a		DO-10	-
1 N 2591		Si-Di	=1N2587: 400V	32a		DO-10	-
1 N 2592		Si-Di	=1N2587: 500V	32a		DO-10	-
1 N 2593		Si-Di	=1N2587: 600V	32a		DO-10	-
1 N 2594		Si-Di	=1N2587: 700V	32a		DO-10	-
1 N 2595		Si-Di	=1N2587: 800V	32a		DO-10	-
1 N 2596		Si-Di	=1N2587: 900V	32a		DO-10	-
1 N 2597		Si-Di	=1N2587: 1000V	32a		DO-10	-
1 N 2598	USA	Si-Di	P Rr, 50V, 12A(Tc=150°), Uf<1,5V(20A)	32a		DO-10	-
1 N 2599		Si-Di	=1N2598: 100V	32a		DO-10	-
1 N 2600		Si-Di	=1N2598: 200V	32a		DO-10	-
1 N 2601		Si-Di	=1N2598: 300V	32a		DO-10	-
1 N 2602		Si-Di	=1N2598: 400V	32a		DO-10	-
1 N 2603		Si-Di	=1N2598: 500V	32a		DO-10	-
1 N 2604		Si-Di	=1N2598: 600V	32a		DO-10	-
1 N 2605		Si-Di	=1N2598: 700V	32a		DO-10	-
1 N 2606		Si-Di	=1N2598: 800V	32a		DO-10	-
1 N 2607		Si-Di	=1N2598: 900V	32a		DO-10	-
1 N 2608		Si-Di	=1N2598: 1000V	32a		DO-10	-
1 N 2609	USA,Mot	Si-Di	Rr, 50V, 0,75A, Uf<1,1V(0,75A)	34a		DO-13	BY 126...127, BY 133...135, 1N4001...07, ++
1 N 2610		Si-Di	=1N2609: 100V	34a		DO-13	BY 126...127, BY 133...135, 1N4002...07, ++
1 N 2611		Si-Di	=1N2609: 200V	34a		DO-13	BY 126...127, BY 133...134, 1N4003...07, ++
1 N 2612		Si-Di	=1N2609: 300V	34a		DO-13	BY 126...127, BY 133...134, 1N4004...07, ++
1 N 2613		Si-Di	=1N2609: 400V	34a		DO-13	BY 126...127, BY 133...134, 1N4004...07, ++
1 N 2614		Si-Di	=1N2609: 500V	34a		DO-13	BY 126...127, BY 133...134, 1N4005...07, ++
1 N 2615		Si-Di	=1N2609: 600V	34a		DO-13	BY 126...127, BY 133...134, 1N4005...07, ++
1 N 2616		Si-Di	=1N2609: 800V	34a		DO-13	BY 127, BY 133, EM 513, 1N4006...07, ++
1 N 2617		Si-Di	=1N2609: 1000V	34a		DO-13	BY 127, BY 133, EM 513, 1N4007, ++
1 N 2618		Si-Di	=1N2609: 1200V	34a		DO-13	BY 127, BY 133, EM 513, GP 100, ++
1 N 2619		Si-Di	=1N2609: 1500V	34a		DO-13	BY 400, BY 448, DM 513, EM 516, GP 10W
1 N 2620(A,B)	USA,Mot,Sie	Ref-Di	9,3V(10mA), ±0,01%/°C, <15Ω, 5%, 0,75W, 0...+75° A=-55...+100°, B=-55...+150°	34a		DO-13	-
1 N 2621(A,B)		Ref-Di	=1N2620: ±0,005%/°C	34a		DO-13	-
1 N 2622(A,B)		Ref-Di	=1N2620: ±0,002%/°C	34a		DO-13	-
1 N 2623(A,B)		Ref-Di	=1N2620: ±0,001%/°C	34a		DO-13	-
1 N 2624(A,B)		Ref-Di	=1N2620: ±0,0005%/°C	34a		DO-13	-
1 N 2625(A,B)		Ref-Di	=1N2600: ±0,0002%/°C	34a		DO-13	-
1 N 2626(A,B)		Ref-Di	=1N2620: ±0,0001%/°C	34a		DO-13	-
1 N 2627	old	Ge-Di	UHF Tuning, 5V	Koax		DO-37	-
1 N 2628	old	Ge-Di	UHF Tuning, 5V	Koax		DO-37	-
1 N 2629	old	Ge-Di	UHF, 5V	Koax		DO-37	-
1 N 2630	USA	Si-Di	Dual, kV-Rr, 1500V, 85mA, Uf<2,25V(85mA)			-	-
1 N 2631	USA	Si-Di	Dual, kV-Rr, 1600V, 0,6A, Uf<3V(0,6A)			-	-
1 N 2632	USA	Si-Di	Dual, kV-Rr, 2800V, 0,2A, Uf<6V(0,2A)			-	-
1 N 2633	USA	Si-Di	Dual, kV-Rr, 1600V, 0,6A, Uf<3V(0,6A)			-	-
1 N 2634	USA	Si-Di	Dual, kV-Rr, 1600V, 0,6A, Uf<3V(0,6A)			-	-
1 N 2635	USA	Si-Di	Dual, kV-Rr, 1500V, 85mA, Uf<2,25V(85mA)			-	-
1 N 2636	USA	Si-Di	Dual, kV-Rr, 1500V, 85mA, Uf<2,25V(85mA)			-	-
1 N 2637	USA	Si-Di	Dual, kV-Rr, 10kV, 0,25A, Uf<28V(0,25A)			-	-
1 N 2638	USA	Si-Di	Rr Stack, 100V, 1,5A			-	-
1 N 2641		Si-Di	=1N2638: 200V			-	-
1 N 2644(A)		Si-Di	=1N2638: 300V			-	-
1 N 2647(A)		Si-Di	=1N2638: 400V			-	-
1 N 2650(A)		Si-Di	=1N2638: 600V			-	-
1 N 2653(A)		Si-Di	=1N2638: 800V			-	-
1 N 2656		Si-Di	=1N2638: 1200V			-	-
1 N 2659		Si-Di	=1N2638: 1600V			-	-
1 N 2662		Si-Di	=1N2638: 2000V			-	-
1 N 2664		Si-Di	=1N2638: 2400V			-	-

Original	Fabric.	Constr.	Info	(Compl. Fig.	JAEGER	Fig.	International
1 N 2666		Si-Di	=1N2638: 3200V				-
1 N 2667		Si-Di	=1N2638: 4000V				-
1 N 2668		Si-Di	=1N2638: 4800V				-
1 N 2669	USA	Si-Di	Rr Stack, 100V, 3.6A				-
1 N 2673		Si-Di	=1N2669: 200V				-
1 N 2677		Si-Di	=1N2669: 300V				-
1 N 2681		Si-Di	=1N2669: 400V				-
1 N 2685		Si-Di	=1N2669: 600V				-
1 N 2687		Si-Di	=1N2669: 800V				-
1 N 2689		Si-Di	=1N2669: 900V				-
1 N 2690		Si-Di	=1N2669: 1200V				-
1 N 2691		Si-Di	=1N2669: 1600V				-
1 N 2692	USA	Si-Di	Rr Stack, 100V, 7.2A				-
1 N 2694		Si-Di	=1N2692: 200V				-
1 N 2696		Si-Di	=1N2692: 300V				-
1 N 2698		Si-Di	=1N2692: 400V				-
1 N 2700		Si-Di	=1N2692: 600V				-
1 N 2701		Si-Di	=1N2692: 800V				-
1 N 2702	USA	Si-Di	Rr Stack, 100V, 3A				-
1 N 2705		Si-Di	=1N2702: 200V				-
1 N 2708		Si-Di	=1N2702: 300V				-
1 N 2711		Si-Di	=1N2702: 400V				-
1 N 2714		Si-Di	=1N2702: 600V				-
1 N 2717		Si-Di	=1N2702: 800V				-
1 N 2720		Si-Di	=1N2702: 1200V				-
1 N 2722		Si-Di	=1N2702: 1600V				-
1 N 2723		Si-Di	=1N2702: 2000V				-
1 N 2724		Si-Di	=1N2702: 2400V				-
1 N 2725	USA	Si-Br	Rr Stack, 100V, 3A				-
1 N 2728		Si-Br	=1N2725: 200V				-
1 N 2731		Si-Br	=1N2725: 300V				-
1 N 2734		Si-Br	=1N2725: 400V				-
1 N 2737		Si-Br	=1N2725: 600V				-
1 N 2738		Si-Br	=1N2725: 800V				-
1 N 2739		Si-Br	=1N2725: 1200V				-
1 N 2740	USA	Si-Br	Rr Stack, 100V, 3.6A				-
1 N 2742		Si-Br	=1N2740: 200V				-
1 N 2744		Si-Br	=1N2740: 300V				-
1 N 2746		Si-Br	=1N2740: 400V				-
1 N 2748		Si-Br	=1N2740: 600V				-
1 N 2749		Si-Br	=1N2740: 800V				-
1 N 2750	USA	Si-Br	Rr Stack, 100V, 3A				-
1 N 2753		Si-Br	=1N2750: 200V				-
1 N 2756		Si-Br	=1N2750: 300V				-
1 N 2759		Si-Br	=1N2750: 400V				-
1 N 2762		Si-Br	=1N2750: 600V				-
1 N 2763		Si-Br	=1N2750: 800V				-
1 N 2764		Si-Br	=1N2750: 1200V				-
1 N 2765(A)	USA	Ref-Di	6,8V(7,5mA), 5%, ±0,005(A=0,0025)%/°C, <20Ω	31a	(12x9mm0)		-
1 N 2766(A)		Ref-Di	=1N2765: 13,6V, <40Ω	31a	(12x9mm0)		-
1 N 2767(A)		Ref-Di	=1N2765: 20,4V, <60Ω	31a	(25x9mm0)		-
1 N 2768(A)		Ref-Di	=1N2765: 27,2V, <80Ω	31a	(25x9mm0)		-
1 N 2769(A)		Ref-Di	=1N2765: 34V, <100Ω	31a	(25x13mm0)		-
1 N 2770(A)		Ref-Di	=1N2765: 40,8V, <120Ω	31a	(25x13mm0)		-
1 N 2771	USA	Si-Di	UHF, P0=1W(750MHz)	Koax	DO-22		-
1 N 2772	USA	Si-Di	Rr, 700V, 0,75A, Uf<1,8V(0,75A)		34a	=DO-1	BY 127, BY 133, EM 513, 1N4006...07, ++
1 N 2773		Si-Di	=1N2772: 800V		34a	=DO-1	BY 127, BY 133, EM 513, 1N4006...07, ++
1 N 2774		Si-Di	=1N2772: 900V		34a	=DO-1	BY 127, BY 133, EM 513, 1N4007, ++
1 N 2775		Si-Di	=1N2772: 1000V		34a	=DO-1	BY 127, BY 133, EM 513, 1N4007, ++
1 N 2776		Si-Di	=1N2772: 1100V		34a	=DO-1	BY 127, BY 133, EM 513, GP 100, ++
1 N 2777		Si-Di	=1N2772: 1200V		34a	=DO-1	BY 127, BY 133, EM 513, GP 100, ++
1 N 2778		Si-Di	=1N2772: 1300V		34a	=DO-1	BY 400, BY 448, EM 513, GP 10V, ++
1 N 2779		Si-Di	=1N2772: 1400V		34a	=DO-1	BY 400, BY 448, EM 516, GP 10V, ++
1 N 2780		Si-Di	=1N2772: 1500V		34a	=DO-1	BY 400, BY 448, EM 516, GP 10V, ++
1 N 2781		Si-Di	=1N2772: 1600V		34a	=DO-1	BY 400, BY 448, EM 516, GP 10V, ++
1 N 2782	Alp	Di	UHF Dem				-
1 N 2783		Z-Di	62V, 10%, 6W				-
1 N 2784	USA	Si-Di	P Rr, 200V, 22A(Tc=40°), Uf<1,5V(25A)	32a	DO-4		BYX 96/300
1 N 2785		Si-Di	=1N2784: 400V	32a	DO-4		BYX 96/600
1 N 2786	USA	Si-Di	P Rr, 200V, 10A, Uf<1,2V(10A)	32a	DO-5		BYW 88/200, BYX 77...81
1 N 2787		Si-Di	=1N2786: 400V	32a	DO-5		BYW 88/400, BYX 78...81
1 N 2788	USA	Si-Di	P Rr, 200V, 50A(Tc=40°), Uf<1,5V(100A)	32a	DO-5		-
1 N 2789		Si-Di	=1N2788: 400V	32a			-
1 N 2790	Ssi	Ref-Di	8,5V(10mA), 5%, ±0,002%/°C, <15Ω, 1W	34a	=DO-1		BZX 53, 1N4782
1 N 2791	Ssi	Si-Di	Rr, S, 350V, Uf<1,3V(50mA)	2	=TO-1		BA 157...159, BA 199/350, BAY 21, ++
1 N 2792(A,B)	Phc	Ge-Di	UHF Mx, 70GHz				-
1 N 2793	USA	Si-Di	P Rr, 50V, 8,5A(Tc=25°), Uf<1,25V(15A)	32a	DO-5		BYW 88/50, BYX 75...81
1 N 2794		Si-Di	=1N2793: 100V	32a	DO-5		BYW 88/100, BYX 76...81
1 N 2795		Si-Di	=1N2793: 150V	32a	DO-5		BYW 88/200, BYX 77...81
1 N 2796		Si-Di	=1N2793: 200V	32a	DO-5		BYW 88/300, BYX 78...81
1 N 2797		Si-Di	=1N2793: 250V	32a	DO-5		BYW 88/400, BYX 79...81
1 N 2798		Si-Di	=1N2793: 300V	32a	DO-5		BYW 88/500, BYX 80...81
1 N 2799		Si-Di	=1N2793: 350V	32a	DO-5		BYW 88/600, BYX 81...81
1 N 2800		Si-Di	=1N2793: 400V	32a	DO-5		BYW 88/800, BYX 82...81
1 N 2801	USA	Ge-Di	FRr, 20V, Uf<0,36V(5mA), <500ns	~32a			-
1 N 2802	USA	Si-Di	UHF, X-Band Mx				-
1 N 2803		Si-Di	Rr, 400V, 250A, Uf<1,2V				-
1 N 2804	Mot,Sie,Tho	Z-Di	6,8V, 20%, 50W(Tc=75°)	23n	TO-3		-
1 N 2805		Z-Di	=1N2804: 7,5V	23n	TO-3		-
1 N 2806		Z-Di	=1N2804: 8,2V	23n	TO-3		-
1 N 2807		Z-Di	=1N2804: 9,1V	23n	TO-3		-
1 N 2808		Z-Di	=1N2804: 10V	23n	TO-3		-
1 N 2809		Z-Di	=1N2804: 11V	23n	TO-3		-

Original	Fabric.	Constr.	Info	(Compl. Fig.	JAEGER	Fig.	International
1 N 2810		Z-Di	=1N2804: 12V	23n		TO-3	-
1 N 2811		Z-Di	=1N2804: 13V	23n		TO-3	-
1 N 2812		Z-Di	=1N2804: 14V	23n		TO-3	-
1 N 2813		Z-Di	=1N2804: 15V	23n		TO-3	-
1 N 2814		Z-Di	=1N2804: 16V	23n		TO-3	-
1 N 2815		Z-Di	=1N2804: 17V	23n		TO-3	-
1 N 2816		Z-Di	=1N2804: 18V	23n		TO-3	-
1 N 2817		Z-Di	=1N2804: 19V	23n		TO-3	-
1 N 2818		Z-Di	=1N2804: 20V	23n		TO-3	-
1 N 2819		Z-Di	=1N2804: 22V	23n		TO-3	-
1 N 2820		Z-Di	=1N2804: 24V	23n		TO-3	-
1 N 2821		Z-Di	=1N2804: 25V	23n		TO-3	-
1 N 2822		Z-Di	=1N2804: 27V	23n		TO-3	-
1 N 2823		Z-Di	=1N2804: 30V	23n		TO-3	-
1 N 2824		Z-Di	=1N2804: 33V	23n		TO-3	-
1 N 2825		Z-Di	=1N2804: 36V	23n		TO-3	-
1 N 2826		Z-Di	=1N2804: 39V	23n		TO-3	-
1 N 2827		Z-Di	=1N2804: 43V	23n		TO-3	-
1 N 2828		Z-Di	=1N2804: 45V	23n		TO-3	-
1 N 2829		Z-Di	=1N2804: 47V	23n		TO-3	-
1 N 2830		Z-Di	=1N2804: 50V	23n		TO-3	-
1 N 2831		Z-Di	=1N2804: 51V	23n		TO-3	-
1 N 2832		Z-Di	=1N2804: 56V	23n		TO-3	-
1 N 2833		Z-Di	=1N2804: 62V	23n		TO-3	-
1 N 2834		Z-Di	=1N2804: 68V	23n		TO-3	-
1 N 2835		Z-Di	=1N2804: 75V	23n		TO-3	-
1 N 2836		Z-Di	=1N2804: 82V	23n		TO-3	-
1 N 2837		Z-Di	=1N2804: 91V	23n		TO-3	-
1 N 2838		Z-Di	=1N2804: 100V	23n		TO-3	-
1 N 2839		Z-Di	=1N2804: 105V	23n		TO-3	-
1 N 2840		Z-Di	=1N2804: 110V	23n		TO-3	-
1 N 2841		Z-Di	=1N2804: 120V	23n		TO-3	-
1 N 2842		Z-Di	=1N2804: 130V	23n		TO-3	-
1 N 2843		Z-Di	=1N2804: 150V	23n		TO-3	-
1 N 2844		Z-Di	=1N2804: 160V	23n		TO-3	-
1 N 2845		Z-Di	=1N2804: 180V	23n		TO-3	-
1 N 2846		Z-Di	=1N2804: 200V	23n		TO-3	-
1 N 2804A...2846A		Z-Di	=1N2804...2846: 10%	23n		TO-3	-
1 N 2804B...2846B		Z-Di	=1N2804...2846: 5%	23n		TO-3	-
1 N 2804R...2846R		Z-Di	=1N2804...2846:	23f		TO-3	-
1 N 2847(A)	USA	Si-Di	P Rr, 100V, 1.5A(Tc=75°), Uf<0,65V(0,5A,150°)	32a		DO-4	-
1 N 2848(A)		Si-Di	=1N2847: 200V	32a		DO-4	-
1 N 2849(A)		Si-Di	=1N2847: 300V	32a		DO-4	-
1 N 2850(A)		Si-Di	=1N2847: 400V	32a		DO-4	-
1 N 2851(A)		Si-Di	=1N2847: 500V	32a		DO-4	-
1 N 2852(A)		Si-Di	=1N2847: 600V	32a		DO-4	-
1 N 2855		Si-Di	P Rr, 600V, 250A, Uf<1,2V				-
1 N 2856		Si-Di	=1N2855: 800V				-
1 N 2857		Si-Di	=1N2855: 1000V				-
1 N 2858(A)	USA,Rca	Si-Di	Rr, 50V, 0,75A(A=1A), Uf<1,2V(0,5A, A=1A)	34a		DO-1	BY 126...127, BY 133...135, 1N4001...07, ++
1 N 2859(A)		Si-Di	=1N2858: 100V	34a		DO-1	BY 126...127, BY 133...135, 1N4002...07, ++
1 N 2860(A)		Si-Di	=1N2858: 200V	34a		DO-1	BY 126...127, BY 133...134, 1N4003...07, ++
1 N 2861(A)		Si-Di	=1N2858: 300V	34a		DO-1	BY 126...127, BY 133...134, 1N4004...07, ++
1 N 2862(A)		Si-Di	=1N2858: 400V	34a		DO-1	BY 126...127, BY 133...134, 1N4004...07, ++
1 N 2863(A)		Si-Di	=1N2858: 500V	34a		DO-1	BY 126...127, BY 133...134, 1N4005...07, ++
1 N 2864(A)		Si-Di	=1N2858: 600V	34a		DO-1	BY 126...127, BY 133...134, 1N4005...07, ++
1 N 2865	Scn,Sem	Si-Di	Rr, 1000V, 0,7A, Uf<2,5V(0,7A)	34a		DO-13	BY 127, BY 133, GP 100, 1N4007, ++
1 N 2866		Si-Di	=1N2865: 1500V	34a		DO-13	BY 400, BY 448, EM 516, GP 10W, ++
1 N 2867	Scn,Sem	Si-Di	Rr, 1000V, 0,7A, Uf<2,5V(0,7A)				BY 127, BY 133, GP 100, 1N4007, ++
1 N 2868		Si-Di	=1N2867: 1500V				BY 400, BY 448, EM 516, GP 10W, ++
1 N 2878	USA,Tho	Si-Di	Rr, 700V, 0,25A	33a			BA 158...159, BAY 90, BY 203/12, ++
1 N 2879		Si-Di	=1N2878: 1000V	31a			BA 159, BAY 90, BY 203/12, SHG 1, ++
1 N 2880		Si-Di	=1N2878: 1000V	31a			BA 159, BAY 90, BY 203/12, SHG 1, ++
1 N 2881		Si-Di	=1N2878: 1000V	31a			BA 159, BAY 90, BY 203/12, SHG 1, ++
1 N 2882		Si-Di	=1N2878: 1000V	31a			BA 159, BAY 90, BY 203/12, SHG 1, ++
1 N 2883		Si-Di	=1N2878: 1000V	31a			BA 159, BAY 90, BY 203/12, SHG 1, ++
1 N 2884		Si-Di	=1N2878: 1400V	31a			BAY 91, BY 203/16, GP 10W, SHG 1,5, ++
1 N 2885		Si-Di	=1N2878: 1400V	31a			BAY 91, BY 203/16, GP 10W, SHG 1,5, ++
1 N 2886		Si-Di	=1N2878: 1500V	31a			BAY 91, BY 203/16, GP 10W, SHG 1,5, ++
1 N 2887		Si-Di	=1N2878: 1500V	31a			BAY 91, BY 203/16, GP 10W, SHG 1,5, ++
1 N 2888		Si-Di	=1N2878: 1700V	31a			BAY 91, BY 203/20, DM 516, SHG 2, ++
1 N 2889		Si-Di	=1N2878: 1700V	31a			BAY 91, BY 203/20, DM 516, SHG 2, ++
1 N 2890		Si-Di	=1N2878: 2000V	31a			BAY 91, BY 203/20, SHG 2, 1N1732(A)
1 N 2891		Si-Di	=1N2878: 2000V	31a			BAY 91, BY 203/20, SHG 2, 1N1732(A)
1 N 2892		Si-Di	=1N2878: 2100V	31a			GP 02-30, MR 250-3, SHG 2,5, 1N1733(A)
1 N 2893		Si-Di	=1N2878: 2100V	31a			GP 02-30, MR 250-3, SHG 2,5, 1N1733(A)
1 N 2894		Si-Di	=1N2878: 2400V	31a			GP 02-30, MR 250-3, SHG 2,5, 1N1733(A)
1 N 2895		Si-Di	=1N2878: 2400V	31a			GP 02-30, MR 250-3, SHG 2,5, 1N1733(A)
1 N 2896		Si-Di	=1N2878: 2500V	31a			GP 02-30, MR 250-3, SHG 2,5, 1N1733(A)
1 N 2897		Si-Di	=1N2878: 2500V	31a			GP 02-30, MR 250-3, SHG 2,5, 1N1733(A)
1 N 2898		Si-Di	=1N2878: 2800V	31a			GP 02-30, MR 250-3, SHG 2,5, 1N1733(A)
1 N 2899		Si-Di	=1N2878: 2800V	31a			GP 02-30, MR 250-3, SHG 2,5, 1N1733(A)
1 N 2900		Si-Di	=1N2878: 3000V	31a			GP 02-30, MR 250-3, SHG 2,5, 1N1733(A)
1 N 2901		Si-Di	=1N2878: 3000V	31a			GP 02-30, MR 250-3, SHG 2,5, 1N1733(A)
1 N 2902		Si-Di	=1N2878: 3100V	31a			GP 02-40, HVG 4, MR 250-4, 1N1734(A)
1 N 2903		Si-Di	=1N2878: 3100V	31a			GP 02-40, HVG 4, MR 250-4, 1N1734(A)
1 N 2904		Si-Di	=1N2878: 3500V	31a			GP 02-40, HVG 4, MR 250-4, 1N1734(A)
1 N 2905		Si-Di	=1N2878: 3500V	31a			GP 02-40, HVG 4, MR 250-4, 1N1734(A)
1 N 2906		Si-Di	=1N2878: 3500V	31a			GP 02-40, HVG 4, MR 250-4, 1N1734(A)
1 N 2907		Si-Di	=1N2878: 3500V	31a			GP 02-40, HVG 4, MR 250-4, 1N1734(A)
1 N 2908		Si-Di	=1N2878: 3800V	31a			GP 02-40, HVG 4, MR 250-4, 1N1734(A)
1 N 2909		Si-Di	=1N2878: 3800V	31a			GP 02-40, HVG 4, MR 250-4, 1N1733(A)
1 N 2910		Si-Di	=1N2878: 4000V	31a			GP 02-40, HVG 4, MR 250-4, 1N1734(A)

Original	Fabric.	Constr.	Info	(Compl. Fig.	JAEGER	Fig.	International
1 N 2911		Si-Di	=1N2878: 4000V		31a		GP 02-40, HVG 4, MR 250-4, 1N1734(A)
1 N 2912		Si-Di	=1N2878: 4200V		31a		HVG 5, MR 250-5, 1N1734(A)
1 N 2913		Si-Di	=1N2878: 4200V		31a		HVG 5, MR 250-5, 1N1734(A)
1 N 2914		Si-Di	=1N2878: 4500V		31a		HVG 5, MR 250-5, 1N1734(A)
1 N 2915		Si-Di	=1N2878: 4500V		31a		HVG 5, MR 250-5, 1N1734(A)
1 N 2916		Si-Di	=1N2878: 4500V		31a		HVG 5, MR 250-5, 1N1734(A)
1 N 2917		Si-Di	=1N2878: 4500V		31a		HVG 5, MR 250-5, 1N1734(A)
1 N 2918		Si-Di	=1N2878: 5000V		31a		HVG 5, MR 250-5, 1N1734(A)
1 N 2919		Si-Di	=1N2878: 5000V		31a		HVG 5, MR 250-5, 1N1734(A)
1 N 2920		Si-Di	=1N2878: 5500V		31a		BYX 90
1 N 2921		Si-Di	=1N2878: 5500V		31a		BYX 90
1 N 2922		Si-Di	=1N2878: 6000V		31a		BYX 90
1 N 2923		Si-Di	=1N2878: 6000V		31a		BYX 90
1 N 2924		Si-Di	=1N2878: 6500V		31a		BYX 90
1 N 2925		Si-Di	=1N2878: 6500V		31a		BYX 90
1 N 2926(A)	Pal.Syl	Si-Di	UHF, K/X-Band Dem	Koax		DO-37	-
1 N 2927(A)	Msc	Si-Di	Tunnel-Di	2		TO-18	-
1 N 2928(A)	Msc	Si-Di	Tunnel-Di	2		TO-18	-
1 N 2929(A)	Msc	Si-Di	Tunnel-Di	2		TO-18	-
1 N 2930(A)	Msc	Si-Di	Tunnel-Di	2		TO-18	-
1 N 2931(A)	Msc	Si-Di	Tunnel-Di	2		TO-18	-
1 N 2932(A)	Msc	Si-Di	Tunnel-Di	2		TO-18	-
1 N 2933(A)	Msc	Si-Di	Tunnel-Di	2		TO-18	-
1 N 2934(A)	Msc	Si-Di	Tunnel-Di	2		TO-18	-
1 N 2937	USA	Z-Di	50V, 15%, 10W(Tc=25°)		32	DO-4	BZX98/C51, BZY93/C51, ZX51, 1N2996
1 N 2938	USA	Z-Di	0.9V, 15%		32	DO-4	-
1 N 2939(A)	Gen	Ge-Di	Tunnel-Di	2		TO-18	-
1 N 2940(A)	Gen	Ge-Di	Tunnel-Di	2		TO-18	-
1 N 2941(A)	Gen	Ge-Di	Tunnel-Di	2		TO-18	-
1 N 2942	Scn	Z-Di	8,2V, 5%, 50W				-
1 N 2943		Z-Di	=1N2942: 9,1V				-
1 N 2944		Z-Di	=1N2942: 10V				-
1 N 2945		Z-Di	=1N2942: 11V				-
1 N 2946		Z-Di	=1N2942: 12V				-
1 N 2947		Z-Di	=1N2942: 13V				-
1 N 2948		Z-Di	=1N2942: 15V				-
1 N 2949		Z-Di	=1N2942: 16V				-
1 N 2950		Z-Di	=1N2942: 18V				-
1 N 2951		Z-Di	=1N2942: 20V				-
1 N 2952		Z-Di	=1N2942: 22V				-
1 N 2953		Z-Di	=1N2942: 24V				-
1 N 2954		Z-Di	=1N2942: 27V				-
1 N 2955		Z-Di	=1N2942: 30V				-
1 N 2956		Z-Di	=1N2942: 33V				-
1 N 2957		Z-Di	=1N2942: 36V				-
1 N 2958		Z-Di	=1N2942: 39V				-
1 N 2959		Z-Di	=1N2942: 43V				-
1 N 2960		Z-Di	=1N2942: 47V				-
1 N 2961		Z-Di	=1N2942: 51V				-
1 N 2962		Z-Di	=1N2942: 56V				-
1 N 2963		Z-Di	=1N2942: 62V				-
1 N 2964		Z-Di	=1N2942: 68V				-
1 N 2965		Z-Di	=1N2942: 75V				-
1 N 2966		Z-Di	=1N2942: 82V				-
1 N 2967		Z-Di	=1N2942: 91V				-
1 N 2968		Z-Di	=1N2942: 100V				-
1 N 2969(A)	Gen	Ge-Di	Tunnel-Di	2			-
1 N 2970	USA,Sie,Tho	Z-Di	6,8V, 20%, 10W(Tc=55°)	32b		DO-4	BZX 98/..., BZY 93/..., ZL ..., ZX ...
1 N 2971		Z-Di	=1N2970: 7,5V	32b		DO-4	
1 N 2972		Z-Di	=1N2970: 8,2V	32b		DO-4	
1 N 2973		Z-Di	=1N2970: 9,1V	32b		DO-4	
1 N 2974		Z-Di	=1N2970: 10V	32b		DO-4	
1 N 2975		Z-Di	=1N2970: 11V	32b		DO-4	
1 N 2976		Z-Di	=1N2970: 12V	32b		DO-4	
1 N 2977		Z-Di	=1N2970: 13V	32b		DO-4	
1 N 2978		Z-Di	=1N2970: 14V	32b		DO-4	
1 N 2979		Z-Di	=1N2970: 15V	32b		DO-4	
1 N 2980		Z-Di	=1N2970: 16V	32b		DO-4	
1 N 2981		Z-Di	=1N2970: 17V	32b		DO-4	
1 N 2982		Z-Di	=1N2970: 18V	32b		DO-4	
1 N 2983		Z-Di	=1N2970: 19V	32b		DO-4	
1 N 2984		Z-Di	=1N2970: 20V	32b		DO-4	
1 N 2985		Z-Di	=1N2970: 22V	32b		DO-4	
1 N 2986		Z-Di	=1N2970: 24V	32b		DO-4	
1 N 2987		Z-Di	=1N2970: 25V	32b		DO-4	
1 N 2988		Z-Di	=1N2970: 27V	32b		DO-4	
1 N 2989		Z-Di	=1N2970: 30V	32b		DO-4	
1 N 2990		Z-Di	=1N2970: 33V	32b		DO-4	
1 N 2991		Z-Di	=1N2970: 36V	32b		DO-4	
1 N 2992		Z-Di	=1N2970: 39V	32b		DO-4	
1 N 2993		Z-Di	=1N2970: 43V	32b		DO-4	
1 N 2994		Z-Di	=1N2970: 45V	32b		DO-4	
1 N 2995		Z-Di	=1N2970: 47V	32b		DO-4	
1 N 2996		Z-Di	=1N2970: 50V	32b		DO-4	
1 N 2997		Z-Di	=1N2970: 51V	32b		DO-4	
1 N 2998		Z-Di	=1N2970: 52V	32b		DO-4	
1 N 2999		Z-Di	=1N2970: 56V	32b		DO-4	
1 N 3000		Z-Di	=1N2970: 62V	32b		DO-4	
1 N 3001		Z-Di	=1N2970: 68V	32b		DO-4	
1 N 3002		Z-Di	=1N2970: 75V	32b		DO-4	
1 N 3003		Z-Di	=1N2970: 82V	32b		DO-4	
1 N 3004		Z-Di	=1N2970: 91V	32b		DO-4	
1 N 3005		Z-Di	=1N2970: 100V	32b		DO-4	

Original	Fabric.	Constr.	Info	(Compl. Fig.	JAEGER	Fig.	International
1 N 3006		Z-Di	=1N2970: 105V	32b		DO-4	
1 N 3007		Z-Di	=1N2970: 110V	32b		DO-4	
1 N 3008		Z-Di	=1N2970: 120V	32b		DO-4	
1 N 3009		Z-Di	=1N2970: 130V	32b		DO-4	
1 N 3010		Z-Di	=1N2970: 140V	32b		DO-4	
1 N 3011		Z-Di	=1N2970: 150V	32b		DO-4	
1 N 3012		Z-Di	=1N2970: 160V	32b		DO-4	
1 N 3013		Z-Di	=1N2970: 175V	32b		DO-4	
1 N 3014		Z-Di	=1N2970: 180V	32b		DO-4	
1 N 3015		Z-Di	=1N2970: 200V	32b		DO-4	
1 N 2970A...3015A		Z-Di	=1N2970...3015: 10%	32b		DO-4	
1 N 2970B...3015B		Z-Di	=1N2970...3015: 5%	32b		DO-4	
1 N 2970R...3015R		Z-Di	=1N2970...3015	32a		DO-4	
1 N 3016	USA,Sie,Tho	Z-Di	6,8V, 20%, 1W	34a		DO-13	BZW22/... BZX61/... ZPY... 1N5921...56,++
1 N 3017		Z-Di	=1N3016: 7,5V	34a		DO-13	
1 N 3018		Z-Di	=1N3016: 8,2V	34a		DO-13	
1 N 3019		Z-Di	=1N3016: 9,1V	34a		DO-13	
1 N 3020		Z-Di	=1N3016: 10V	34a		DO-13	
1 N 3021		Z-Di	=1N3016: 11V	34a		DO-13	
1 N 3022		Z-Di	=1N3016: 12V	34a		DO-13	
1 N 3023		Z-Di	=1N3016: 13V	34a		DO-13	
1 N 3024		Z-Di	=1N3016: 15V	34a		DO-13	
1 N 3025		Z-Di	=1N3016: 16V	34a		DO-13	
1 N 3026		Z-Di	=1N3016: 18V	34a		DO-13	
1 N 3027		Z-Di	=1N3016: 20V	34a		DO-13	
1 N 3028		Z-Di	=1N3016: 22V	34a		DO-13	
1 N 3029		Z-Di	=1N3016: 24V	34a		DO-13	
1 N 3030		Z-Di	=1N3016: 27V	34a		DO-13	
1 N 3031		Z-Di	=1N3016: 30V	34a		DO-13	
1 N 3032		Z-Di	=1N3016: 33V	34a		DO-13	
1 N 3033		Z-Di	=1N3016: 36V	34a		DO-13	
1 N 3034		Z-Di	=1N3016: 39V	34a		DO-13	
1 N 3035		Z-Di	=1N3016: 43V	34a		DO-13	
1 N 3036		Z-Di	=1N3016: 47V	34a		DO-13	
1 N 3037		Z-Di	=1N3016: 51V	34a		DO-13	
1 N 3038		Z-Di	=1N3016: 56V	34a		DO-13	
1 N 3039		Z-Di	=1N3016: 62V	34a		DO-13	
1 N 3040		Z-Di	=1N3016: 68V	34a		DO-13	
1 N 3041		Z-Di	=1N3016: 75V	34a		DO-13	
1 N 3042		Z-Di	=1N3016: 82V	34a		DO-13	
1 N 3043		Z-Di	=1N3016: 91V	34a		DO-13	
1 N 3044		Z-Di	=1N3016: 100V	34a		DO-13	
1 N 3045		Z-Di	=1N3016: 110V	34a		DO-13	
1 N 3046		Z-Di	=1N3016: 120V	34a		DO-13	
1 N 3047		Z-Di	=1N3016: 130V	34a		DO-13	
1 N 3048		Z-Di	=1N3016: 150V	34a		DO-13	
1 N 3049		Z-Di	=1N3016: 160V	34a		DO-13	
1 N 3050		Z-Di	=1N3016: 180V	34a		DO-13	
1 N 3051		Z-Di	=1N3016: 200V	34a		DO-13	
1 N 3016A...3051A		Z-Di	=1N3016...3051: 10%	34a		DO-13	
1 N 3016B...3051B		Z-Di	=1N3016...3051: 5%	34a		DO-13	
1 N 3052	USA	Si-Di	kV-Rr, 12kV, 0,1A, Uf<70V(0,1A)	31a		(102x130)	-
1 N 3053		Si-Di	=1N3052: 14kV, Uf<75V(0,1A)	31a		(102x130)	-
1 N 3054		Si-Di	=1N3052: 16kV, Uf<80V(0,1A)	31a		(127x130)	-
1 N 3055		Si-Di	=1N3052: 18kV, Uf<85V(0,1A)	31a		(127x130)	-
1 N 3056		Si-Di	=1N3052: 20kV, Uf<90V(0,1A)	31a		(152x130)	-
1 N 3057		Si-Di	=1N3052: 22kV, Uf<95V(0,1A)	31a		(152x130)	-
1 N 3058		Si-Di	=1N3052: 24kV, Uf<100V(0,1A)	31a		(178x130)	-
1 N 3059		Si-Di	=1N3052: 26kV, Uf<105V(0,1A)	31a		(178x130)	-
1 N 3060		Si-Di	=1N3052: 28kV, Uf<120V(0,1A)	31a		(203x130)	-
1 N 3061		Si-Di	=1N3052: 30kV, Uf<125V(0,1A)	31a		(203x130)	-
1 N 3062	USA,Tho	Si-Di	SS, 50/50V, 75/225mA, Uf<1V(20mA), <4ns	31a		DO-7,DO-35	1N4148 31a BA 218, BAX 13, BAX 91, 1N4148...49, ++
1 N 3063		Si-Di	=1N3062: Uf<0,7...0,85V(10mA)	31a		DO-7,DO-35	1N4148 31a BA 218, BAX 13, BAX 91, 1N4148...49, ++
1 N 3064		Si-Di	=1N3062: Uf<1V(10mA)	31a		DO-7,DO-35	1N4148 31s BA 218, BAX 13, BAX 91, 1N4148...49, ++
1 N 3065	USA,Tho	Si-Di	SS, 50V, 0,115A, Uf<1V(20mA), <4ns	31a		DO-7,DO-35	1N4148 31a BA 218, BAX 13, BAX 91, 1N4148...49, ++
1 N 3066		Si-Di	=1N3065: Uf<1V(10mA)	31a		DO-7,DO-35	1N4148 31a BA 218, BAX 13, BAX 91, 1N4148...49, ++
1 N 3067		Si-Di	=1N3065: 30V, Uf<1V(5mA)	31a		DO-7,DO-35	1N4148 31a BA 218, BAX 13, BAX 91, 1N4148...49, ++
1 N 3068	Fch,Tix,++	Si-Di	S, 20/30V, 0,075A, Uf<1V(5mA), <50ns	31a		DO-7,DO-35	BAV 17...21, BAX 90, BAX 94, BAY 41, ++
1 N 3069	USA,Tho	Si-Di	S, 50/65V, 0,225A, Uf<1V(50mA), <50ns	31a		DO-7,DO-35	BAV 18...21, BAW 48...50, BAY 72, ++
1 N 3070	USA,Tho	Si-Di	Uni, S, 175/200V, 0,15/3A, Uf<1V(0,1A), <50ns	31a		DO-7,DO-35	BA 197...198, BAV 20...21, BAW 50, ++
1 N 3071	Fch,Tix,++	Si-Di	S, 150/200V, 0,225A, Uf<1V(0,1A), <50ns	31a		DO-7,DO-35	BA 197...198, BAV 20...21, BAW 50, ++
1 N 3072	USA	Si-Di	Rr, 50V, 0,2A(Tc=150°), Uf<1,5V(0,2A)	34a		DO-12	BY 126...127, BY 133...135, 1N4001...07, ++
1 N 3073		Si-Di	=1N3072: 100V	34a		DO-12	BY 126...127, BY 133...135, 1N4002...07, ++
1 N 3074		Si-Di	=1N3072: 150V	34a		DO-12	BY 126...127, BY 133...135, 1N4003...07, ++
1 N 3075		Si-Di	=1N3072: 200V	34a		DO-12	BY 126...127, BY 133...134, 1N4003...07, ++
1 N 3076		Si-Di	=1N3072: 250V	34a		DO-12	BY 126...127, BY 133...134, 1N4004...07, ++
1 N 3077		Si-Di	=1N3072: 300V	34a		DO-12	BY 126...127, BY 133...134, 1N4004...07, ++
1 N 3078		Si-Di	=1N3072: 350V	34a		DO-12	BY 126...127, BY 133...134, 1N4004...07, ++
1 N 3079		Si-Di	=1N3072: 400V	34a		DO-12	BY 126...127, BY 133...134, 1N4004...07, ++
1 N 3080		Si-Di	=1N3072: 500V	34a		DO-12	BY 126...127, BY 133...134, 1N4005...07, ++
1 N 3081		Si-Di	=1N3072: 600V	34a		DO-12	BY 126...127, BY 133...134, 1N4005...07, ++
1 N 3082	USA	Si-Di	Rr, 200V, 0,5A, Uf<1V(0,75A)	34a		DO-12	BY 126...127, BY 133...134, 1N4003...07, ++
1 N 3083		Si-Di	=1N3082: 400V	34a		DO-12	BY 126...127, BY 133...134, 1N4004...07, ++
1 N 3084		Si-Di	=1N3082: 600V	34a		DO-12	BY 126...127, BY 133...134, 1N4005...07, ++
1 N 3085	Inr,Sem,Ssi	Si-Di	P Rr, 100V, 150A(Tc=150°), Uf<1,2V(150A)	73a		DO-30	1N4587...96
1 N 3086		Si-Di	=1N3085: 200V	73a		DO-30	1N4588...96
1 N 3087		Si-Di	=1N3085: 300V	73a		DO-30	1N4589...96
1 N 3088		Si-Di	=1N3085: 400V	73a		DO-30	1N4590...96
1 N 3089		Si-Di	=1N3085: 500V	73a		DO-30	1N4591...96
1 N 3090		Si-Di	=1N3085: 600V	73a		DO-30	1N4592...96
1 N 3091		Si-Di	=1N3085: 800V	73a		DO-30	1N4593...96
1 N 3092		Si-Di	=1N3085: 1000V	73a		DO-30	1N4594...96
1 N 3093		Ge-Di	UHF, X-Band-S				

Original	Fabric.	Constr.	Info	{Compl. Fig.	JAEGER	Fig.	International
1 N 3097	Idc,Sem	Ge-Di	Uni, S, 30V, 0,05A, <500ns	31a			AAZ 49, AAZ 15, AAZ 17, 1N276
1 N 3098	Sem,Ssi	Z-Di	120V, 20%, 1W	34a			BZW22/..., BZX61/..., ZPY..., 1N5951...56,++
1 N 3099		Z-Di	=1N3098: 145V	34a			
1 N 3100		Z-Di	=1N3098: 180V	34a			
1 N 3101		Z-Di	=1N3098: 220V	34a			
1 N 3098A...3101A		Z-Di	=1N3098...3101: 10%	34a			
1 N 3102	Scn	Z-Di	120V, 10%, 10W	32			BZX98/..., BZY93/..., ZX..., 1N3008...15
1 N 3103		Z-Di	=1N3102: 150V	32			
1 N 3104		Z-Di	=1N3102: 180V	32			
1 N 3105		Z-Di	=1N3102: 220V	32			
1 N 3102A...3105A		Z-Di	=1N3102...3105: 5%	32			
1 N 3106	Scn,Sem	Si-Di	Rr, 800V, 0,75A, Uf<1,6V(0,75A)	34a			BY 127, BY 133, BYX 94...95, 1N4006...07++
1 N 3107		Si-Di	=1N3106: 1200V, 0,5A, Uf<3,2V(0,5A)	34a			BY 127, BY 133, BYX 94...95, GP 100, ++
1 N 3108	Scn,Sem	Si-Di	Rr, 800V, 1,5A, Uf<1,6V(1,5A)	32			BY 227, BY 254...255, 1N5062, 1N5398, ++
1 N 3109		Si-Di	=1N3108: 1200V, 0,7A, Uf<3,2V(0,7A)	32			BY 227, BY 255, BY 350/1300, GH 3E, ++
1 N 3110	USA	Ge-Di	S, 12V, 0,05A	31a			AAZ 27, AAZ 18, 1N3592
1 N 3111	Inr,Ssi	Si-Di	P Rr, 50V, 150A(Tc=150°), Uf<1,2V(150A)	73a			1N4587...96
1 N 3112	Sem	Z-Di	7,4V, 5%, 1W	34a			BZW22/C7V5, BZX61/C7V5, ZPY7,5, 1N5922++
1 N 3113	Gen	GaAs-Di	Tunnel-Di	34a			-
1 N 3114	Gen	GaAs-Di	Tunnel-Di	34a			-
1 N 3115	Gen	GaAs-Di	Tunnel-Di	34a			-
1 N 3116	Gen	#aAs-Di	Tunnel-Di	34a			-
1 N 3117	Gen	GaAs-Di	Tunnel-Di	34a			-
1 N 3118	Gen	GaAs-Di	Tunnel-Di	34a			-
1 N 3119	Gen	GaAs-Di	Tunnel-Di	34a			-
1 N 3120	Gen	GaAs-Di	Tunnel-Di	34a			-
1 N 3121	USA	Ge-Di	Uni, S, 50V, 0,11A, <500ns	31a			AAZ 15, AAZ 17
1 N 3122	USA	Ge-Di	S, 20V, 0,18A, <3500ns	31a			AA 139, AAZ 18
1 N 3123	USA	Si-Di	SS, 40V, 0,05A, Uf<1,5V(10mA), <4ns	31a	1N4148	31a	BA 218, BAX 13, BAX91, 1N4148...49, ++
1 N 3124		Si-Di	=1N3123: Uf<1V(20mA)	31a	1N4148	31a	BA 218, BAX 13, BAX91, 1N4148...49, ++
1 N 3125	USA	Ge-Di	S, 55V, 300ns	31a			AAZ 28, 1N631, 1N633
1 N 3128	Kmc,Rca	Ge-Di	Tunnel-Di				-
1 N 3129	Kmc,Rca	Ge-Di	Tunnel-Di				-
1 N 3130	Kmc,Rca	Ge-Di	Tunnel-Di				-
1 N 3138	Kmc,Rca	GaAs-Di	Tunnel-Di				-
1 N 3139	Edl,Sem	Si-Di	P Rr, 50V, 70A(Tc=150°), Uf<0,9V(70A)	32			=DO-5
1 N 3140		Si-Di	=1N3139: 100V	32			=DO-5
1 N 3141		Si-Di	=1N3139: 150V	32			=DO-5
1 N 3142		Si-Di	=1N3139: 200V	32			=DO-5
1 N 3143	USA	Si-Di	UHF, C/X-Band-Dem			Koax	DO-23
1 N 3144		Ge-Di	S, 20V, 500ns				AAZ 49, AAZ 15, AAZ 17, 1N276
1 N 3145		Ge-Di	Uni, 65V				AA 117...118, AA 132...134
1 N 3146	USA	Ge-Di	SS, 25V, <2ns	31a			DO-7
1 N 3147	Sem	Si-Di	Uni, 60V	31a			DO-7
1 N 3148	Idc,Sem	Ref-Di	8,5V(10mA), 5%, 0,005%/°C, <15Ω, 0,4W	34a			=DO-13
1 N 3149(A)	Gen	Ge-Di	Tunnel-Di				-
1 N 3150	Gen	Ge-Di	Tunnel-Di				-
1 N 3151	Sem	Si-Di	kV-Rr, 7,2kV, 0,1A, Uf<27V(0,1A)	31a		(55x9mm0)	BYX 90, 1N5183
1 N 3152	Wes	Si-Di	UHF, 36GHz				-
1 N 3153	Wes	Si-Di	UHF, 36GHz				-
1 N 3154(A)	USA,Sie,Tho	Ref-Di	8,4V(10mA), 5%, ±0,01%/°C, <15Ω, 0,4W, -55...+100° A: -55...+150°	31a			DO-7,DO-35
1 N 3155(A)		Ref-Di	=1N3154: ±0,005%/°C	31a			DO-7,DO-35
1 N 3156(A)		Ref-Di	=1N3154: ±0,002%/°C	31a			DO-7,DO-35
1 N 3157(A)		Ref-Di	=1N3154: ±0,001%/°C	31a			DO-7,DO-35
1 N 3159	USA	Ge-Di	S, 15V, 0,08A, <300ns	31a			DO-7
1 N 3160	Sem	Ge-Di	Uni, 60V, 0,03A	31a			DO-7
1 N 3161	USA	Si-Di	P Rr, 50V, 175A(Tc=150°), Uf<0,95V(175A)	73a			DO-9
1 N 3162		Si-Di	=1N3161: 100V	73a			DO-9
1 N 3163		Si-Di	=1N3161: 150V	73a			DO-9
1 N 3164		Si-Di	=1N3161: 200V	73a			DO-9
1 N 3165		Si-Di	=1N3161: 250V	73a			DO-9
1 N 3166		Si-Di	=1N3161: 300V	73a			DO-9
1 N 3167		Si-Di	=1N3161: 350V	73a			DO-9
1 N 3168		Si-Di	=1N3161: 400V	73a			DO-9
1 N 3169		Si-Di	=1N3161: 500V	73a			DO-9
1 N 3170		Si-Di	=1N3161: 600V	73a			DO-9
1 N 3171(A)		Si-Di	=1N3161: 700V, 240A, Uf<1,9V(A<1,25V)(240A)	73a			DO-9
1 N 3172(A)		Si-Di	=1N3171: 800V	73a			DO-9
1 N 3173(A)		Si-Di	=1N3171: 900V	73a			DO-9
1 N 3174(A)		Si-Di	=1N3171: 1000V	73a			DO-9
1 N 3175(A)		Si-Di	=1N3171: 1200V	73a			DO-9
1 N 3176(A)		Si-Di	=1N3171: 1200V	73a			DO-9
1 N 3177(A)		Si-Di	=1N3171: 1600V	73a			DO-9
1 N 3161R...3177R		Si-Di	=1N3161...3177:	73b			DO-9
1 N 3179	Sem,Trw	Si-Di	Rr, Uni, 240V, Uf<1V(0,1A)	31a			DO-14
1 N 3180	Sem,Trw	Si-Di	Rr, Uni, 130V, Uf<1,5V(0,5A)	31a			DO-14
1 N 3181	Idc,Sty	Z-Di	bidirectional, 7,7V, 10%, 0,6W	33			-
1 N 3182	USA	Si-Di	VHF Tuning	31a			DO-7
1 N 3183	Scn	Si-Br	Rr, 350V, 0,5A				B350C500
1 N 3184		Si-Br	=1N3183: 500V				B500C500
1 N 3185		Si-Br	=1N3183: 700V				B700C500
1 N 3186		Si-Br	=1N3183: 1000V				B1000C500
1 N 3187		Si-Br	=1N3183: 1500V				B1500C500
1 N 3188		Si-Br	=1N3183: 2000V				B2000C500
1 N 3189	USA,Mot,Tho	Si-Di	Rr, 200V, 1A, Uf<1V(0,75A)	34a			DO-13
1 N 3190		Si-Di	=1N3189: 400V	34a			DO-13
1 N 3191		Si-Di	=1N3189: 600V	34a			DO-13
1 N 3192	Wes	Si-Di	200V, Uf<1V(0,1A)				-
1 N 3193	USA,Rca,Tos	Si-Di	Rr, 200V, 0,75A, Uf<1,2V(0,5A)	34a			DO-12
1 N 3194		Si-Di	=1N3193: 400V	34a			DO-12
1 N 3195		Si-Di	=1N3193: 600V	34a			DO-12
1 N 3196		Si-Di	=1N3193: 800V	34a			DO-12

Original	Fabric.	Constr.	Info	{Compl. Fig.	JAEGER	Fig.	International
1 N 3197	USA	Ge-Di	S, 30V, 0,08A, <300ns	31a	DO-7		AAY 49, AAZ 15, AAZ 17
1 N 3198	Idc,Sem	Z-Di	2,25V, 2%, 0,4W	31a	(17x8mm0)		-
1 N 3199	Idc,Sem	Ref-Di	8,4V(10mA), 5%, ±0,005%/°C, <150, 0,27W	31a	(17x8mm0)		BZX 52, 1N4776, 1N4781
1 N 3200		Ref-Di	=1N3199: ±0,003%/°C	31a	(17x8mm0)		BZX 53, 1N4777, 1N4782
1 N 3201		Ref-Di	=1N3199: ±0,002%/°C	31a	(17x8mm0)		BZX 53, 1N4777, 1N4782
1 N 3202		Ref-Di	=1N3199: ±0,001%/°C	31a	(17x8mm0)		BZX 54, 1N4778, 1N4783
1 N 3203	USA	Ge-Di	S, 25V, 0,06A, 300ns	31a	DO-7		AAY 49, AAZ 15, AAZ 17, 1N276
1 N 3204	USA	Ge-Di	S, 60V, 0,06A, 300ns	31a	DO-7		AAY 28, AAZ 15, AAZ 17, 1N276
1 N 3205	USA	Si-Di	UHF, Ku-Band-M	Koax	DO-37		-
1 N 3206	USA	Si-Di	Min, SS, 100V, 0,075A, <4ns	31a	-DO-18		(BA 219, BAX 96) ⁶
1 N 3207	USA	Si-Di	Min, SS, 60V, <6ns	31a	-DO-18		(BAW 62, BAX 95, 1N4148...49, 1N4151,++) ⁶
1 N 3208	USA,Mot	Si-Di	P Rr, 50V, 15A(Tc=150°), Uf<1,5V(40A)	32a	DO-5		1N4525...30
1 N 3209		Si-Di	=1N3208: 100V	32a	DO-5		1N4525...30
1 N 3210		Si-Di	=1N3208: 200V	32a	DO-5		1N4525...30
1 N 3211		Si-Di	=1N3208: 300V	32a	DO-5		1N4526...30
1 N 3212		Si-Di	=1N3208: 400V	32a	DO-5		1N4526...30
1 N 3213		Si-Di	=1N3208: 500V	32a	DO-5		1N4527...30
1 N 3214		Si-Di	=1N3208: 600V	32a	DO-5		1N4527...30
1 N 3208R...3214R		Si-Di	=1N3208...3214:	32b	DO-5		D 24C/...
1 N 3215		Si-Di	S, 60V, Uf<0,7V(1mA), <250ns	31a	DO-7		BAW 21, BAX 15...17, 1N4148...49, ++
1 N 3217	Gen	Ge-Di	Tunnel-Di				-
1 N 3218(A)	Gen	Ge-Di	Tunnel-Di				-
1 N 3219(A)	Gen	Ge-Di	Tunnel-Di				-
1 N 3220	Gen	Ge-Di	Tunnel-Di				-
1 N 3221(A)	Gen	Ge-Di	Tunnel-Di				-
1 N 3222	Gen	Ge-Di	Tunnel-Di				-
1 N 3223	USA	Si-Di	S, 150V, 800ns	31a	DO-7		BA 196...198, BAV 20...21, BAX 15...17, ++
1 N 3225	Idc,Sem	Ge-Di	S, 40V, 0,03A, <500ns	31a	DO-7		AAY 28, 1N276, 1N631, 1N633
1 N 3227	Idc,Sem	Si-Di	Rr, Uni, 100V, 0,5A, Uf<3,3V(0,5A)	31a	DO-7		BY 126...127, BY 133...135, 1N4002...07, ++
1 N 3228		Si-Di	=1N3227: 200V	31a	DO-7		BY 126...127, BY 133...134, 1N4003...07, ++
1 N 3229		Si-Di	=1N3227: 400V	31a	DO-7		BY 126...127, BY 133...134, 1N4004...07, ++
1 N 3230		Si-Di	=1N3227: 600V	31a	DO-7		BY 126...127, BY 133...134, 1N4005...07, ++
1 N 3231		Si-Di	=1N3227: 800V	31a	DO-7		BY 127, BY 133, GP 100, 1N4006...07, ++
1 N 3232		Si-Di	=1N3227: 1000V	31a	DO-7		BY 127, BY 133, GP 100, 1N4007, ++
1 N 3233		Si-Di	=1N3227: 1200V	31a	DO-7		BY 127, BY 133, EM 513, GP 100, ++
1 N 3234		Si-Di	=1N3227: 1500V	31a	DO-7		BY 269, GP 10W, DM 513, EM 516, ++
1 N 3235		Si-Di	=1N3227: 1800V	31a	DO-7		DM 516
1 N 3236		Si-Di	=1N3227: 2000V	31a	DO-7		-
1 N 3237	USA	Si-Di	Rr, Uni, 50V, 0,75A, Uf<2,2V(0,75A)	31a	DO-7		BY 126...127, BY 133...135, 1N4001...07, ++
1 N 3238		Si-Di	=1N3237: 100V	31a	DO-7		BY 126...127, BY 133...135, 1N4002...07, ++
1 N 3239		Si-Di	=1N3237: 200V	31a	DO-7		BY 126...127, BY 133...134, 1N4003...07, ++
1 N 3240		Si-Di	=1N3237: 400V	31a	DO-7		BY 126...127, BY 133...134, 1N4004...07, ++
1 N 3241		Si-Di	=1N3237: 600V	31a	DO-7		BY 126...127, BY 133...134, 1N4005...07, ++
1 N 3242		Si-Di	=1N3237: 800V	31a	DO-7		BY 127, BY 133, GP 100, 1N4006...07, ++
1 N 3243		Si-Di	=1N3237: 1000V	31a	DO-7		BY 127, BY 133, GP 100, 1N4007, ++
1 N 3244		Si-Di	=1N3237: 1200V	31a	DO-7		BY 127, BY 133, EM 513, GP 100, ++
1 N 3245		Si-Di	=1N3237: 1500V	31a	DO-7		BY 269, DM 513, EM 516, GP 10W, ++
1 N 3246	USA	Si-Di	Rr, Uni, 50V, 1A, Uf<1,1V(1A)	31a	DO-7		BY 126...127, BY 133...135, 1N4001...07, ++
1 N 3247		Si-Di	=1N3246: 100V	31a	DO-7		BY 126...127, BY 133...135, 1N4002...07, ++
1 N 3248		Si-Di	=1N3246: 200V	31a	DO-7		BY 126...127, BY 133...134, 1N4003...07, ++
1 N 3249		Si-Di	=1N3246: 400V	31a	DO-7		BY 126...127, BY 133...134, 1N4004...07, ++
1 N 3250		Si-Di	=1N3246: 600V	31a	DO-7		BY 126...127, BY 133...134, 1N4005...07, ++
1 N 3251		Si-Di	=1N3246: 800V	31a	DO-7		BY 127, BY 133, BY 227, 1N4006...07, ++
1 N 3252		Si-Di	=1N3246: 1000V	31a	DO-7		BY 127, BY 133, BY 227, 1N4007, ++
1 N 3253	USA,Rca,Tos	Si-Di	=1N3193: Iso	34a	DO-12 Iso		-1N3193
1 N 3254		Si-Di	=1N3194: Iso	34a	DO-12 Iso		-1N3194
1 N 3255		Si-Di	=1N3195: Iso	34a	DO-12 Iso		-1N3195
1 N 3256		Si-Di	=1N3196: Iso	34a	DO-12 Iso		-1N3196
1 N 3257	USA	Si-Di	SS, 80V, <3ns	31a	DO-7		BA 219, BAW 62, BAX 95, 1N4148...49, ++
1 N 3258	USA	Si-Di	SS, 80V, <4ns	31a	DO-7		BA 219, BAW 62, BAX 95, 1N4148...49, ++
1 N 3260	USA,Gen	Si-Di	P Rr, 50V, 160A(Tc=125°), Uf<1,6V(160A)	73a	DO-9		1N4587...96
1 N 3261		Si-Di	=1N3260: 100V	73a	DO-9		1N4587...96
1 N 3262		Si-Di	=1N3260: 150V	73a	DO-9		1N4588...96
1 N 3263		Si-Di	=1N3260: 200V	73a	DO-9		1N4588...96
1 N 3264		Si-Di	=1N3260: 250V	73a	DO-9		1N4589...96
1 N 3265		Si-Di	=1N3260: 300V	73a	DO-9		1N4589...96
1 N 3266		Si-Di	=1N3260: 350V	73a	DO-9		1N4590...96
1 N 3267		Si-Di	=1N3260: 400V	73a	DO-9		1N4590...96
1 N 3268		Si-Di	=1N3260: 500V	73a	DO-9		1N4591...96
1 N 3269		Si-Di	=1N3260: 600V	73a	DO-9		1N4592...96
1 N 3270		Si-Di	=1N3260: 700V	73a	DO-9		1N4593...96
1 N 3271		Si-Di	=1N3260: 800V	73a	DO-9		1N4593...96
1 N 3272		Si-Di	=1N3260: 900V	73a	DO-9		1N4594...96
1 N 3273		Si-Di	=1N3260: 1000V	73a	DO-9		1N4594...96
1 N 3274		Si-Di	=1N3260: 1200V	73a	DO-9		1N4595...96
1 N 3275		Si-Di	=1N3260: 1400V	73a	DO-9		1N4596
1 N 3276		Si-Di	=1N3260: 1600V	73a	DO-9		-
1 N 3260R...3276R		Si-Di	=1N3260...3276:	73b	DO-9		1N4587R...4596R
1 N 3277	USA	Si-Di	Rr, Uni, 200V, 0,75A, Uf<1,2V(0,75A)	31a	DO-7		BY 126...127, BY 133...134, 1N4003...07, ++
1 N 3278		Si-Di	=1N3277: 400V	31a	DO-7		BY 126...127, BY 133...134, 1N4004...07, ++
1 N 3279		Si-Di	=1N3277: 600V	31a	DO-7		BY 126...127, BY 133...134, 1N4005...07, ++
1 N 3280		Si-Di	=1N3278: 800V	31a	DO-7		BY 127, BY 133, BY 227, 1N4006...07, ++
1 N 3281		Si-Di	=1N3278: 1000V	31a	DO-7		BY 127, BY 133, BY 227, 1N4007, ++
1 N 3282	USA,Mot,Tho	Si-Di	Rr, Uni, 1000V, 0,1A, Uf<2,5V(0,1A)	31a	DO-7		BY 203/12, RGP 01-10, SHG 1, 1N5181, ++
1 N 3283		Si-Di	=1N3282: 1500V	31a	DO-7		BY 203/16, RGP 01-16, SHG 1,5, 1N5181, ++
1 N 3284		Si-Di	=1N3282: 2000V	31a	DO-7		BY 203/20, HVG 2, SHG 2, 1N5181, ++
1 N 3285		Si-Di	=1N3282: 2500V	31a	DO-7		HVG 3, SHG 2,5, 1N1733, 1N5181, ++
1 N 3286		Si-Di	=1N3282: 3000V	31a	DO-7		HVG 3, GP 02-30, 1N1733, 1N5181, ++
1 N 3287(W)	USA,Itt	Ge-St	0,26V, 0,25W	31a	DO-7		-
1 N 3288(A)	Gen,Inr,++	Si-Di	P Rr, 100V, 100A(Tc=130°), Uf<0,6V(100A)	73a	DO-8		-
1 N 3289(A)		Si-Di	=1N3288: 200V	73a	DO-8		-
1 N 3290(A)		Si-Di	=1N3288: 300V	73a	DO-8		-
1 N 3291(A)		Si-Di	=1N3288: 400V	73a	DO-8		-

Original	Fabric.	Constr.	Info	{ Compl. Fig.	JAEGER	Fig.	International
1 N 3292(A)		Si-Di	=1N3288: 500V	73a	DO-8	-	
1 N 3293(A)		Si-Di	=1N3288: 600V	73a	DO-8	-	
1 N 3294(A)		Si-Di	=1N3288: 800V	73a	DO-8	-	
1 N 3295(A)		Si-Di	=1N3288: 1000V	73a	DO-8	-	
1 N 3296(A)		Si-Di	=1N3288: 1200V	73a	DO-8	-	
1 N 3297(A)		Si-Di	=1N3288: 1400V	73a	DO-8	-	
1 N 3288R....3297R		Si-Di	=1N3288...3297:	73b	DO-8	-	DS 85-01C....-12C
1 N 3298	USA	Si-Di	S, 60V, <200ns	31a	DO-7	-	BAV 18...21, BAX 15...17, BAY 42...43, ++
1 N 3298 A		Si-Di	=1N3288: 70V, 0,3A, <20ns	31a	DO-7	-	BAV 18...21, BAX 15...17, BAY 42...43, ++
1 N 3299	Mdc.Spe	Trigger-Di	Ub=36...44V, Ib<0,125mA, Ih=1...15mA, Itsm=10A	31a	DO-7	-	
1 N 3300	Mdc.Spe	Trigger-Di	Ub=14,4-21,6V, Ib<1µA, Ih=1-15mA,Iav=0,2A,Itsm=50A	31a	DO-41	-	
1 N 3300 A		Trigger-Di	=1N3300: Ub=16,2...19,8V	31a	DO-41	-	
1 N 3301		Trigger-Di	=1N3300: Ub=17,6...29,4V	31a	DO-41	-	
1 N 3301 A		Trigger-Di	=1N3300: Ub=19,8...24,2V	31a	DO-41	-	
1 N 3302		Trigger-Di	=1N3300: Ub=21,6...32,4V, Ih=5...20mA	31a	DO-41	-	
1 N 3302 A		Trigger-Di	=1N3300: Ub=24,3...29,7V, Ih=5...20mA	31a	DO-41	-	
1 N 3303		Trigger-Di	=1N3300: Ub=26,4...39,6V, Ih=5...20mA	31a	DO-41	-	
1 N 3303 A		Trigger-Di	=1N3300: Ub=29,7...36,3V, Ih=5...20mA	31a	DO-41	-	
1 N 3304		Trigger-Di	=1N3300: Ub=31,2...46,8V, Ih=5...20mA	31a	DO-41	-	
1 N 3304 A		Trigger-Di	=1N3300: Ub=35,1...42,9V, Ih=5...20mA	31a	DO-41	-	
1 N 3305	USA,Sie,Tho	Z-Di	6,8V, 20%, 50W(Tc=75°)	32b	DO-5	-	BZY 91/...
1 N 3306		Z-Di	=1N3305: 7,5V	32b	DO-5	-	
1 N 3307		Z-Di	=1N3305: 8,2V	32b	DO-5	-	
1 N 3308		Z-Di	=1N3305: 9,1V	32b	DO-5	-	
1 N 3309		Z-Di	=1N3305: 10V	32b	DO-5	-	
1 N 3310		Z-Di	=1N3305: 11V	32b	DO-5	-	
1 N 3311		Z-Di	=1N3305: 12V	32b	DO-5	-	
1 N 3312		Z-Di	=1N3305: 13V	32b	DO-5	-	
1 N 3313		Z-Di	=1N3305: 14V	32b	DO-5	-	
1 N 3314		Z-Di	=1N3305: 15V	32b	DO-5	-	
1 N 3315		Z-Di	=1N3305: 16V	32b	DO-5	-	
1 N 3316		Z-Di	=1N3305: 17V	32b	DO-5	-	
1 N 3317		Z-Di	=1N3305: 18V	32b	DO-5	-	
1 N 3318		Z-Di	=1N3305: 19V	32b	DO-5	-	
1 N 3319		Z-Di	=1N3305: 20V	32b	DO-5	-	
1 N 3320		Z-Di	=1N3305: 22V	32b	DO-5	-	
1 N 3321		Z-Di	=1N3305: 24V	32b	DO-5	-	
1 N 3322		Z-Di	=1N3305: 25V	32b	DO-5	-	
1 N 3323		Z-Di	=1N3305: 27V	32b	DO-5	-	
1 N 3324		Z-Di	=1N3305: 30V	32b	DO-5	-	
1 N 3325		Z-Di	=1N3305: 33V	32b	DO-5	-	
1 N 3326		Z-Di	=1N3305: 36V	32b	DO-5	-	
1 N 3327		Z-Di	=1N3305: 39V	32b	DO-5	-	
1 N 3328		Z-Di	=1N3305: 43V	32b	DO-5	-	
1 N 3329		Z-Di	=1N3305: 45V	32b	DO-5	-	
1 N 3330		Z-Di	=1N3305: 47V	32b	DO-5	-	
1 N 3331		Z-Di	=1N3305: 50V	32b	DO-5	-	
1 N 3332		Z-Di	=1N3305: 51V	32b	DO-5	-	
1 N 3333		Z-Di	=1N3305: 52V	32b	DO-5	-	
1 N 3334		Z-Di	=1N3305: 56V	32b	DO-5	-	
1 N 3335		Z-Di	=1N3305: 62V	32b	DO-5	-	
1 N 3336		Z-Di	=1N3305: 68V	32b	DO-5	-	
1 N 3337		Z-Di	=1N3305: 75V	32b	DO-5	-	
1 N 3338		Z-Di	=1N3305: 82V	32b	DO-5	-	
1 N 3339		Z-Di	=1N3305: 91V	32b	DO-5	-	
1 N 3340		Z-Di	=1N3305: 100V	32b	DO-5	-	
1 N 3341		Z-Di	=1N3305: 105V	32b	DO-5	-	
1 N 3342		Z-Di	=1N3305: 110V	32b	DO-5	-	
1 N 3343		Z-Di	=1N3305: 120V	32b	DO-5	-	
1 N 3344		Z-Di	=1N3305: 130V	32b	DO-5	-	
1 N 3345		Z-Di	=1N3305: 140V	32b	DO-5	-	
1 N 3346		Z-Di	=1N3305: 150V	32b	DO-5	-	
1 N 3347		Z-Di	=1N3305: 160V	32b	DO-5	-	
1 N 3348		Z-Di	=1N3305: 175V	32b	DO-5	-	
1 N 3349		Z-Di	=1N3305: 180V	32b	DO-5	-	
1 N 3350		Z-Di	=1N3305: 200V	32b	DO-5	-	
1 N 3305A....3350A		Z-Di	=1N3305...3350: 10%	32b	DO-5	-	
1 N 3305B....3350B		Z-Di	=1N3305...3350: 5%	32b	DO-5	-	
1 N 3305R....3350R		Z-Di	=1N3305...3350:	32a	DO-5	-	
1 N 3353	Phc	Ge-Di	Backward-Di	2	TO-18	-	
1 N 3354	Cri	Si-Di	Rr, 10V, 3A(Tc=55°), Uf<1V(1A)	32	=DO-4	-	BYX 38/300, BYX 39/600
1 N 3355		Si-Di	=1N3354: 15V	32	=DO-4	-	BYX 38/300, BYX 39/600
1 N 3356		Si-Di	=1N3354: 25V	32	=DO-4	-	BYX 38/300, BYX 39/600
1 N 3357		Si-Di	=1N3354: 50V	32	=DO-4	-	BYX 38/300, BYX 39/600
1 N 3358		Si-Di	=1N3354: 75V	32	=DO-4	-	BYX 38/300, BYX 39/600
1 N 3359		Si-Di	=1N3354: 100V	32	=DO-4	-	BYX 38/300, BYX 39/600
1 N 3360		Si-Di	=1N3354: 150V	32	=DO-4	-	BYX 38/300, BYX 39/600
1 N 3361		Si-Di	=1N3354: 200V	32	=DO-4	-	BYX 38/300, BYX 39/600
1 N 3362		Si-Di	=1N3354: 300V	32	=DO-4	-	BYX 38/300, BYX 39/600
1 N 3363		Si-Di	=1N3354: 400V	32	=DO-4	-	BYX 38/600, BYX 39/600
1 N 3364		Si-Di	=1N3354: 500V	32	=DO-4	-	BYX 38/600, BYX 39/600
1 N 3365		Si-Di	=1N3354: 600V	32	=DO-4	-	BYX 38/600, BYX 39/600
1 N 3366		Si-Di	=1N3354: 700V	32	=DO-4	-	BYX 38/900, BYX 39/800
1 N 3367		Si-Di	=1N3354: 800V	32	=DO-4	-	BYX 38/900, BYX 39/800
1 N 3368		Si-Di	=1N3354: 900V	32	=DO-4	-	BYX 38/900, BYX 39/1000
1 N 3369		Si-Di	=1N3354: 1000V	32	=DO-4	-	BYX 38/1200, BYX 39/1000
1 N 3370		Si-Di	=1N3354: 1200V	32	=DO-4	-	BYX 38/1200, BYX 39/1200
1 N 3371		Si-Di	=1N3354: 1500V	32	=DO-4	-	
1 N 3372	Cri	Si-Di	P Rr, 10V, 20A(Tc=100°), Uf<1V(20A)	75	DO-21	-	DS 25-01A, 1N3491...95
1 N 3373		Si-Di	=1N3372: 25V	75	DO-21	-	DS 25-01A, 1N3491...95
1 N 3374		Si-Di	=1N3372: 50V	75	DO-21	-	DS 25-01A, 1N3491...95
1 N 3375		Si-Di	=1N3372: 100V	75	DO-21	-	DS 25-01A, 1N3492...95
1 N 3376		Si-Di	=1N3372: 150V	75	DO-21	-	DS 25-02A, 1N3493...95

Original	Fabric.	Constr.	Info	(Compl. Fig.	JAEGER	Fig.	International
1 N 3377		Si-Di	=1N3372: 200V	75		DO-21	DS 25-02A, 1N3493...95
1 N 3378		Si-Di	=1N3372: 300V	75		DO-21	DS 25-03A, 1N3494...95
1 N 3379		Si-Di	=1N3372: 400V	75		DO-21	DS 25-05A, 1N3495
1 N 3380		Si-Di	=1N3372: 500V	75		DO-21	DS 25-05A
1 N 3381	Cri	Si-Di	Rr, 15V, Uf<1V(0,5A)				-
1 N 3382		Si-Di	=1N3381: 30V				-
1 N 3383		Si-Di	=1N3381: 50V				-
1 N 3384		Si-Di	=1N3381: 75V				-
1 N 3385		Si-Di	=1N3381: 100V				-
1 N 3386		Si-Di	=1N3381: 150V				-
1 N 3387		Si-Di	=1N3381: 200V				-
1 N 3388		Si-Di	=1N3381: 250V				-
1 N 3389		Si-Di	=1N3381: 300V				-
1 N 3390		Si-Di	=1N3381: 400V				-
1 N 3391		Si-Di	=1N3381: 500V				-
1 N 3392	Cri,Idc	Z-Di	1,5V, 10%, 0,5W				BZX55/..., BZX83/..., ZPD..., 1N5221...61,++
1 N 3393		Z-Di	=1N3392: 1,8V				
1 N 3394		Z-Di	=1N3392: 2,2V				
1 N 3395		Z-Di	=1N3392: 2,7V				
1 N 3396		Z-Di	=1N3392: 3,3V				
1 N 3397		Z-Di	=1N3392: 3,9V				
1 N 3398		Z-Di	=1N3392: 4,7V				
1 N 3399		Z-Di	=1N3392: 5,6V				
1 N 3400		Z-Di	=1N3392: 6,8V				
1 N 3401		Z-Di	=1N3392: 8,2V				
1 N 3402		Z-Di	=1N3392: 10V				
1 N 3403		Z-Di	=1N3392: 12V				
1 N 3404		Z-Di	=1N3392: 15V				
1 N 3405		Z-Di	=1N3392: 18V				
1 N 3406		Z-Di	=1N3392: 22V				
1 N 3407		Z-Di	=1N3392: 27V				
1 N 3408		Z-Di	=1N3392: 33V				
1 N 3409		Z-Di	=1N3392: 39V				
1 N 3410		Z-Di	=1N3392: 47V				
1 N 3411	Cri,Idc	Z-Di	6,2V, 10%, 0,5W				BZX55/..., BZX83/..., ZPD..., 1N5234...81,++
1 N 3412		Z-Di	=1N3411: 6,8V				
1 N 3413		Z-Di	=1N3411: 7,5V				
1 N 3414		Z-Di	=1N3411: 8,2V				
1 N 3415		Z-Di	=1N3411: 10V				
1 N 3416		Z-Di	=1N3411: 12V				
1 N 3417		Z-Di	=1N3411: 15V				
1 N 3418		Z-Di	=1N3411: 18V				
1 N 3419		Z-Di	=1N3411: 22V				
1 N 3420		Z-Di	=1N3411: 27V				
1 N 3421		Z-Di	=1N3411: 30V				
1 N 3422		Z-Di	=1N3411: 33V				
1 N 3423		Z-Di	=1N3411: 39V				
1 N 3424		Z-Di	=1N3411: 47V				
1 N 3425		Z-Di	=1N3411: 56V				
1 N 3426		Z-Di	=1N3411: 68V				
1 N 3427		Z-Di	=1N3411: 82V				
1 N 3428		Z-Di	=1N3411: 100V				
1 N 3429		Z-Di	=1N3411: 120V				
1 N 3430		Z-Di	=1N3411: 150V				
1 N 3431		Z-Di	=1N3411: 180V				
1 N 3432		Z-Di	=1N3411: 220V				
1 N 3433		Z-Di	8,2V, 2W				BZD23/..., BZV47/..., BZX70/...
1 N 3434		Z-Di	=1N3433: 10V				
1 N 3435		Z-Di	=1N3433: 12V				
1 N 3436		Z-Di	=1N3433: 15V				
1 N 3437		Z-Di	=1N3433: 18V				
1 N 3438		Z-Di	=1N3433: 22V				
1 N 3439		Z-Di	=1N3433: 27V				
1 N 3440		Z-Di	=1N3433: 33V				
1 N 3441		Z-Di	=1N3433: 39V				
1 N 3442		Z-Di	=1N3433: 47V				
1 N 3443		Z-Di	6,2V, 10%, 2W				BZD23/..., BZV47/..., BZX70/...
1 N 3444		Z-Di	=1N3443: 6,8V				
1 N 3445		Z-Di	=1N3443: 8,2V				
1 N 3446		Z-Di	=1N3443: 10V				
1 N 3447		Z-Di	=1N3443: 12V				
1 N 3448		Z-Di	=1N3443: 15V				
1 N 3449		Z-Di	=1N3443: 18V				
1 N 3450		Z-Di	=1N3443: 22V				
1 N 3451		Z-Di	=1N3443: 27V				
1 N 3452		Z-Di	=1N3443: 30V				
1 N 3453		Z-Di	=1N3443: 33V				
1 N 3454		Z-Di	=1N3443: 39V				
1 N 3455		Z-Di	=1N3443: 47V				
1 N 3456		Z-Di	=1N3443: 56V				
1 N 3457		Z-Di	=1N3443: 68V				
1 N 3458		Z-Di	=1N3443: 82V				
1 N 3459		Z-Di	=1N3443: 100V				
1 N 3460		Z-Di	=1N3443: 120V				
1 N 3461		Z-Di	=1N3443: 150V				
1 N 3462		Z-Di	=1N3443: 180V				
1 N 3463		Z-Di	=1N3443: 220V				
1 N 3464	Gen.Sol	Si-Di	kV-Rr, 12kV, 0,06A, Uf<24V(0,06A)	31a		(98x13mm0)	1N3052
1 N 3465	USA,Itt	Ge-Di	Uni, 60V, 75mA	31a		DO-7	AA 117...118, AA 132...134, 1N34, 1N54, ++
1 N 3466	USA,Itt	Ge-Di	Uni, 40V, 75mA	31a		DO-7	AA 117...118, AA 132...134, 1N34, 1N54, ++
1 N 3467	USA,Itt	Ge-Di	SS, 18V, <2ns	31a		DO-7	-
1 N 3468	USA,Itt	Ge-Di	SS, 18V, <2ns	31a		DO-7	-
1 N 3469	USA,Itt	Ge-Di	Uni, 35V, 85mA	31a		DO-7	AA 135...136, 1N634...635

Original	Fabric.	Constr.	Info	{Compl. Fig.	JAEGER	Fig.	International
1 N 3470	USA	Ge-Di	Uni, 35V, 85mA	31a		DO-7	AA 135...136, 1N634...635
1 N 3471	Idc,Wes	Si-Di	SS, 40V, 0,04A, <2ns				BA 218, BAX 13, BAX 91, 1N4148...49, ++
1 N 3473		Si-Di	Rr, 200V, Uf<1,4V(0,75A)				-
1 N 3474		Si-Di	=1N3473: 400V				-
1 N 3475		Si-Di	=1N3473: 600V				-
1 N 3476		Si-Di	=1N3473: 800V				-
1 N 3477	Idc,Gie	Z-Di	2,2V, 10%, 0,25W	31a		DO-7	BZX55/C2V4, BZX79/C2V4, 1N5221
1 N 3477 A		Z-Di	=1N3477: 5%	31a		DO-7	
1 N 3478		Si-Di	Rr, Uni, 200V, Uf<1V(0,5A)				BY 126...127, BY 133...134, 1N4003...07, ++
1 N 3479		Si-Di	=1N3478: 400V				BY 126...127, BY 133...134, 1N4004...07, ++
1 N 3480		Si-Di	=1N3478: 600V				BY 126...127, BY 133...134, 1N4005...07, ++
1 N 3481	Phc	Ge-Di	UHF, X-Band-S	Koax		DO-23	-
1 N 3482	Phc	Ge-Di	UHF, X-Band-S	Koax		DO-23	-
1 N 3483	USA	Ge-Di	Uni, 8V	31a		DO-7	-
1 N 3484	Idc,Sem	Ge-Di	Uni, 75V	31a		DO-7	AA 117...118, AA 132...133
1 N 3485	Cri	Si-Di	S, 175V, <50ns	31a		DO-7	BA 197...198, BAV 20...21, 1N3070, ++
1 N 3486	USA	Si-Di	Rr, 1000V, 0,4A, Uf<1V(0,4A)	34a		DO-1	BA 159, BY 127, BY 133, BY 204/10, ++
1 N 3487		Si-Di	=1N3486: 1200V	34a		DO-1	BY 127, BY 133, BYX 94...95, GP 100, ++
1 N 3488	Gie,Trw	Si-Di	VHF Tuning	31a		DO-7	-
1 N 3489 (A)	Mdc,Spe	Trigger-Di	Ub=16...24V, Ib<0,125mA, Ih=1...6mA, Itsm=10A	31a		DO-7	-
1 N 3490		Trigger-Di	=1N3489: Ih=14...45mA	31a		DO-7	-
1 N 3491	USA,Mot	Si-Di	P Rr, 50V, 25A(Tc=130°), Uf<1,5V(100A)	75a		DO-21	SSI E1205...1240, 1N3659...3665
1 N 3492		Si-Di	=1N3491: 100V	75a		DO-21	SSI E1210...1240, 1N3660...3665
1 N 3493		Si-Di	=1N3491: 200V	75a		DO-15	SSI E1220...1240, 1N3661...3665
1 N 3494		Si-Di	=1N3491: 300V	75a		DO-21	SSI E1220...1240, 1N3662...3665
1 N 3495		Si-Di	=1N3491: 400V	75a		DO-21	SSI E1230...1240, 1N3663...3665
1 N 3491R...3495R		Si-Di	=1N3491...3495:	75b		DO-21	DS 25...A, SSI E1105...40, 1N3659R...65R
1 N 3496	USA,Sie,Tho	Ref-Di	6,2V(7,5mA), 5%, ±0,005%/°C, <15Ω, 0,25W	31a		DO-7	BZV 11, BZV 28, BZX 91, 1N4581
1 N 3497		Ref-Di	=1N3496: ±0,002%/°C	31a		DO-7	BZV 12, BZV 29, BZX 92, 1N4582
1 N 3498		Ref-Di	=1N3496: ±0,001%/°C	31a		DO-7	BZV 13, BZV 30, BZX 93, 1N4583
1 N 3499		Ref-Di	=1N3496: ±0,0005%/°C	31a		DO-7	BZV 14, BZV 31, BZX 94, 1N4584
1 N 3500		Ref-Di	=1N3496: ±0,01%/°C	31a		DO-7	BZV 10, BZV 27, BZX 90, 1N4580
1 N 3501	USA,Sie	Ref-Di	6,35V(7,5mA), 2%, ±0,001%/°C, <12Ω, 0,25W	31a		DO-7	1N4890(A), 1N4892(A), 1N4894(A)
		Ref-Di	ultrastabil, ΔUz<635μV/1000h				
1 N 3502		Ref-Di	=1N3501: ±0,0005%/°C	31a		DO-7	1N4891(A), 1N4893(A), 1N4895(A)
1 N 3503(A)		Ref-Di	=1N3501: ±0,001(A=±0,0005)/°C, ΔUz<318μV/1000h	31a		DO-7	1N4890...95(A)
1 N 3504(A)		Ref-Di	=1N3501: ±0,001(A=±0,0005)/°C, ΔUz<127μV/1000h	31a		DO-7	1N4890...95(A)
1 N 3506	USA,Sie,Tix	Z-Di	3,3V, 5%, 0,4W	31a		DO-7	BZX55/..., BZX83/..., ZPD..., 1N5226...61,...
1 N 3507		Z-Di	=1N3506: 3,6V	31a		DO-7	
1 N 3508		Z-Di	=1N3506: 3,9V	31a		DO-7	
1 N 3509		Z-Di	=1N3506: 4,3V	31a		DO-7	
1 N 3510		Z-Di	=1N3506: 4,7V	31a		DO-7	
1 N 3511		Z-Di	=1N3506: 5,1V	31a		DO-7	
1 N 3512		Z-Di	=1N3506: 5,6V	31a		DO-7	
1 N 3513		Z-Di	=1N3506: 6,2V	31a		DO-7	
1 N 3514		Z-Di	=1N3506: 6,8V	31a		DO-7	
1 N 3515		Z-Di	=1N3506: 7,5V	31a		DO-7	
1 N 3516		Z-Di	=1N3506: 8,2V	31a		DO-7	
1 N 3517		Z-Di	=1N3506: 9,1V	31a		DO-7	
1 N 3518		Z-Di	=1N3506: 10V	31a		DO-7	
1 N 3519		Z-Di	=1N3506: 11V	31a		DO-7	
1 N 3520		Z-Di	=1N3506: 12V	31a		DO-7	
1 N 3521		Z-Di	=1N3506: 13V	31a		DO-7	
1 N 3522		Z-Di	=1N3506: 15V	31a		DO-7	
1 N 3523		Z-Di	=1N3506: 16V	31a		DO-7	
1 N 3524		Z-Di	=1N3506: 18V	31a		DO-7	
1 N 3525		Z-Di	=1N3506: 20V	31a		DO-7	
1 N 3526		Z-Di	=1N3506: 22V	31a		DO-7	
1 N 3527		Z-Di	=1N3506: 24V	31a		DO-7	
1 N 3528		Z-Di	=1N3506: 27V	31a		DO-7	
1 N 3529		Z-Di	=1N3506: 30V	31a		DO-7	
1 N 3530		Z-Di	=1N3506: 33V	31a		DO-7	
1 N 3531		Z-Di	=1N3506: 36V	31a		DO-7	
1 N 3532		Z-Di	=1N3506: 39V	31a		DO-7	
1 N 3533		Z-Di	=1N3506: 43V	31a		DO-7	
1 N 3534		Z-Di	=1N3506: 47V	31a		DO-7	
1 N 3535		Si-Di	200V				
1 N 3536		Si-Di	70V				
1 N 3537	USA	Z-Di	12V, 10%, 1W	34a		DO-13	BZW22/C12, BZX61/C12, ZPY12, 1N5927,++
1 N 3538		Si-Di	150V				
1 N 3539(A)	Msc	Si-Di	Backward-Di	2		TO-18	-
1 N 3540(A)	Msc	Si-Di	Backward-Di	2		TO-18	-
1 N 3541(A)	Msc	Si-Di	Backward-Di	2		TO-18	-
1 N 3542(A)	Msc	Si-Di	Backward-Di	2		TO-18	-
1 N 3543(A)	Msc	Si-Di	Backward-Di	2		TO-18	-
1 N 3544	USA	Si-Di	Rr, Uni, 100V, 0,6A, Uf<1V(0,5A)	31a		DO-7	BY 126...127, BY 133...134, 1N4002...07, ++
1 N 3545		Si-Di	=1N3544: 200V	31a		DO-7	BY 126...127, BY 133...134, 1N4003...07, ++
1 N 3546		Si-Di	=1N3544: 300V	31a		DO-7	BY 126...127, BY 133...134, 1N4004...07, ++
1 N 3547		Si-Di	=1N3544: 400V	31a		DO-7	BY 126...127, BY 133...134, 1N4005...07, ++
1 N 3548		Si-Di	=1N3544: 500V	31a		DO-7	BY 126...127, BY 133...134, 1N4005...07, ++
1 N 3549		Si-Di	=1N3544: 600V	31a		DO-7	BY 126...127, BY 133...134, 1N4005...07, ++
1 N 3550	USA	Si-Di	S, 180V, 0,08A, <1,5μs	31a		DO-7	BA 157...159, BA 199/250, BAY 46, ++
1 N 3551	Trw	Si-Di	VHF Tuning	31a		DO-7	-
1 N 3552(A)	Trw	Si-Di	VHF Tuning	31a		DO-7	-
1 N 3553	USA	Ref-Di	0,25V(7,5mA), 0,01%/°C, <15Ω, 0,25W	31a		DO-7	-
1 N 3554	Trw	Si-Di	VHF Tuning	31a		DO-7	-
1 N 3555	Trw	Si-Di	VHF Tuning	31a		DO-7	-
1 N 3556	Trw	Si-Di	VHF Tuning	31a		DO-7	-
1 N 3557	Trw	Si-Di	VHF Tuning	31a		DO-7	-
1 N 3558		Si-Di	=2x 1N751 Matched Pair				-1N751
1 N 3559	Idc,Sem	Ge-Di	Uni, 24V	31a		DO-7	AA 139, 1N270
1 N 3560	Phc	Ge-Di	Tunnel-Di	2		TO-18	-
1 N 3561	Phc	Ge-Di	Tunnel-Di	2		TO-18	-

Original	Fabric.	Constr.	Info	(Compl. Fig.	JAEGER	Fig.	International
1 N 3562	Phc	Ge-Di	Tunnel-Di	2		TO-18	-
1 N 3563	USA,Rca	Si-Di	Rr, 1000V, 0.4A	34a		DO-13 Iso	BA 159, BY 127, BY 133, 1N4007, ++
1 N 3564	Idc,Sem	Ge-Di	Uni, Matched Pair, 15V	31a		DO-7	AA 112...113, AA 116, 1N34, 1N54, 1N60, ++
1 N 3565	USA	Si-Di	6V, 2A	32		DO-4	
1 N 3566	Cri	Si-Di	P Rr, 800V, 1A	32a		DO-4	BYX 38/900, BYX 39/800
1 N 3567	USA	Si-Di	Min, 75V, 0.06A, <2ns	31a		-DO-18	(BA 218, BAX 13, BAX 91, 1N4148...49,++) ⁶
1 N 3568	USA	Si-Di	Min, 80V, <4ns	31a		-DO-18	(BA 218, BAX 13, BAX 91, 1N4148...49,++) ⁶
1 N 3569	USA,Gen,Mot	Si-Di	P Rr, 100V, 3.5A(Tc=85°), Uf<0.5V(3.5A)	32a		DO-4	BYX 38/300, BYX 39/600
1 N 3570		Si-Di	=1N3569: 200V	32a		DO-4	BYX 38/300, BYX 39/600
1 N 3571		Si-Di	=1N3569: 300V	32a		DO-4	BYX 38/300, BYX 39/600
1 N 3572		Si-Di	=1N3569: 400V	32a		DO-4	BYX 38/300, BYX 39/600
1 N 3573		Si-Di	=1N3569: 500V	32a		DO-4	BYX 38/600, BYX 39/600
1 N 3574		Si-Di	=1N3569: 600V	32a		DO-4	BYX 38/600, BYX 39/600
1 N 3575	USA	Si-Di	Rr, 60V, 0.15A, Uf<1V(0.1A)	34a		DO-13	BA 147/100, BA 157...159, BAY 19, ++
1 N 3576		Si-Di	=1N3575: 125V	34a		DO-13	BA 147/150, BA 157...159, BAY 20, ++
1 N 3577		Si-Di	=1N3575: 175V	34a		DO-13	BA 147/230, BA 157...159, BAY 20, ++
1 N 3578		Si-Di	=1N3575: 225V	34a		DO-13	BA 147/230, BA 157...159, BAY 21, ++
1 N 3579		Si-Di	=1N3575: 275V	34a		DO-13	BA 147/300, BA 157...159, BAY 21, ++
1 N 3580(A,B)	USA,Mot	Ref-Di	11,7V(7.5mA), 5%, ±0.1%/°C, <25Ω, 0.75W, 0...+75° A: -55...+100°, B: -55...+150°	34a		DO-13	1N941
1 N 3581(A,B)		Ref-Di	=1N3580: ±0.005%/°C	34a		DO-13	1N942
1 N 3582(A,B)		Ref-Di	=1N3580: ±0.002%/°C	34a		DO-13	1N943
1 N 3583(A,B)		Ref-Di	=1N3580: ±0.001%/°C	34a		DO-13	1N944
1 N 3584(A,B)		Ref-Di	=1N3580: ±0.0005%/°C	34a		DO-13	1N945
1 N 3585	Cri,Ssi	Si-Di	P Rr, 50V, 400A(Tc=120°), Uf<1,1V(520A)	73a		DO-9	-
1 N 3586		Si-Di	=1N3585: 100V	73a		DO-9	-
1 N 3587		Si-Di	=1N3585: 200V	73a		DO-9	-
1 N 3588		Si-Di	=1N3585: 300V	73a		DO-9	-
1 N 3589		Si-Di	=1N3585: 400V	73a		DO-9	-
1 N 3590		Si-Di	=1N3585: 500V	73a		DO-9	-
1 N 3591		Si-Di	=1N3585: 600V	73a		DO-9	-
1 N 3592	USA,Tho	Ge-Di	S, 30V, 0.05A, <70ns	31a		DO-7	AAY 27
1 N 3593	Idc,Sem	Si-Di	Min, S, 40V, 0.05A, 10ns	31a		-DO-18	(BA 218, BAX 13, BAX 91, 1N4148...49,++) ⁶
1 N 3594	Idc,Msc,Sem	Si-Di	Min, S, 60V, 6ns	31a		-DO-18	(BA 218, BAX 13, BAX 91, 1N4148...49,++) ⁶
1 N 3595	USA,Tho	Si-Di	S, 150V, 0.1A, <3μs	31a		DO-7,DO-35	BA 147/150, BA 157...159, 1N5606...07, ++
1 N 3596	USA	Si-Di	SS, 20V, 0.075A, <4ns	31a		DO-7	BA 217, BA 317, BAY 71, 1N4148...49, ++
1 N 3597	USA	Si-Di	S, 200V, 0.275A, <300ns	31a		DO-7	BA 157...159, BA 173, BY 206...207, ++
1 N 3598	USA	Si-Di	SS, 50V, 0.075A, <4ns	31a		DO-7	BA 218, BAX 13, BAX 91, 1N4148...49, ++
1 N 3599	USA	Si-Di	S, 150V, <50ns	31a		SOD-17	BA 196...198, BAV 20...21, BAY 80, ++
1 N 3600	USA,Tho	Si-Di	SS, 50V, 0.2/0.9A, Uf<1V(0.2A), <4ns	31a	1N4148	DO-7,DO-35	31a BAW 62, BAX 95, BAY 95, 1N4148...49, +
1 N 3601	USA	Si-Di	SS, 75V, <5ns	31a		DO-7	BAW 62, BAX 95, BAW 76, 1N4148...49, +
1 N 3602	USA	Si-Di	SS, 75V, 0.115A, <5ns	31a		DO-7	BAW 62, BAX 95, BAW 76, 1N4148...49, +
1 N 3603		Si-Di	=1N3602: 45V	31a		DO-7	BAW 62, BAX 95, BAW 76, 1N4148...49, +
1 N 3604	USA,Sie,Tho	Si-Di	=1N4151	31a		DO-7	+1N4151
1 N 3605		Si-Di	=1N4152	31a		DO-7	+1N4152
1 N 3606		Si-Di	=1N4153	31a		DO-7	+1N4153
1 N 3607		Si-Di	=1N4151: Min	31a		-DO-20	+1N4151
1 N 3608		Si-Di	=1N4152: Min	31a		-DO-20	+1N4152
1 N 3609		Si-Di	=1N4153: Min	31a		-DO-20	+1N4153
1 N 3611(GP)	USA,Sie	Si-Di	Rr, 200V, 1A, Uf=0.6...1.1V, IGP: SOD-22	31a		DO-41	BY 126...127, BY 133...134, 1N4003...07, ++
1 N 3612(GP)		Si-Di	=1N3611: 400V	31a		DO-41	BY 126...127, BY 133...134, 1N4004...07, ++
1 N 3613(GP)		Si-Di	=1N3611: 600V	31a		DO-41	BY 126...127, BY 133...134, 1N4005...07, ++
1 N 3614(GP)		Si-Di	=1N3611: 800V	31a		DO-41	BY 127, BY 133, 1N4006...07, ++
1 N 3615	USA,Mot	Si-Di	P Rr, 50V, 16A(Tc=150°), Uf<1,2V(16A)	32a		DO-4	BYX 25/600, BYX 99/600
1 N 3616		Si-Di	=1N3615: 100V	32a		DO-4	BYX 25/600, BYX 99/600
1 N 3617		Si-Di	=1N3615: 150V	32a		DO-4	BYX 25/600, BYX 99/600
1 N 3618		Si-Di	=1N3615: 200V	32a		DO-4	BYX 25/600, BYX 99/600
1 N 3619		Si-Di	=1N3615: 300V	32a		DO-4	BYX 25/600, BYX 99/600
1 N 3620		Si-Di	=1N3615: 400V	32a		DO-4	BYX 25/600, BYX 99/600
1 N 3621		Si-Di	=1N3615: 500V	32a		DO-4	BYX 25/600, BYX 99/600
1 N 3622		Si-Di	=1N3615: 600V	32a		DO-4	BYX 25/600, BYX 99/600
1 N 3623		Si-Di	=1N3615: 800V	32a		DO-4	BYX 25/800, BYX 99/900
1 N 3624		Si-Di	=1N3615: 1000V	32a		DO-4	BYX 25/1000, BYX 99/1200
1 N 3625	USA	Si-Di	S, 200V, 0.15A	31a		DO-7	BA 157...159, BY 204/4, BY 206...207, ++
1 N 3626	USA	Ge-Di	Uni, 50V	31a		DO-7	AA 117...118, AA 132...134, 1N34, 1N54, ++
1 N 3627	Gie,Tdy	Si-Di	VHF Tuning	31a		DO-7	-
1 N 3628	Gie,Tdy	Si-Di	VHF Tuning	31a		DO-7	-
1 N 3629	Cri,Ssi	Si-Di	Rr, 100V, 0.75A, Uf<1V(0.75A)	31a		DO-7	BY 126...127, BY 133...135, 1N4002...07, ++
1 N 3630		Si-Di	=1N3629: 200V	31a		DO-7	BY 126...127, BY 133...134, 1N4003...07, ++
1 N 3631		Si-Di	=1N3629: 300V	31a		DO-7	BY 126...127, BY 133...134, 1N4004...07, ++
1 N 3632		Si-Di	=1N3629: 400V	31a		DO-7	BY 126...127, BY 133...134, 1N4005...07, ++
1 N 3633		Si-Di	=1N3629: 500V	31a		DO-7	BY 126...127, BY 133...134, 1N4006...07, ++
1 N 3634		Si-Di	=1N3629: 600V	31a		DO-7	BY 126...127, BY 133...134, 1N4007...07, ++
1 N 3635		Si-Di	=1N3629: 700V	31a		DO-7	BY 127, BY 133, BY 227, 1N4008...07, ++
1 N 3636		Si-Di	=1N3629: 800V	31a		DO-7	BY 127, BY 133, BY 227, 1N4009...07, ++
1 N 3637		Si-Di	=1N3629: 900V	31a		DO-7	BY 127, BY 133, BY 227, 1N4010...07, ++
1 N 3638		Si-Di	=1N3629: 1000V	31a		DO-7	BY 127, BY 133, BY 227, 1N4011...07, ++
1 N 3639	USA	Si-Di	Rr, 200V, 0.75A, Uf<1.2V(0.75A)	34a		DO-13	BY 126...127, BY 133...134, 1N4003...07, ++
1 N 3640		Si-Di	=1N3639: 400V	34a		DO-13	BY 126...127, BY 133...134, 1N4004...07, ++
1 N 3641		Si-Di	=1N3639: 600V	34a		DO-13	BY 126...127, BY 133...134, 1N4005...07, ++
1 N 3642		Si-Di	=1N3639: 800V	34a		DO-13	BY 127, BY 133, BY 227, 1N4006...07, ++
1 N 3643	USA	Si-Di	Rr, 1000V, 0.25A, Uf<5V(0.25A)	31a		(10x4x4mm)	BA 159, BY 127, BY 133, 1N4007, ++
1 N 3644		Si-Di	=1N3643: 1500V	31a		(10x4x4mm)	BAY 91, BY 203/16, BY 269, GP 10W, ++
1 N 3645		Si-Di	=1N3643: 2000V	31a		(10x4x4mm)	BAY 91, BY 203/20, GP 02-20, MR 250-2, ++
1 N 3646		Si-Di	=1N3643: 2500V	31a		(10x4x4mm)	GP 02-30, MR 250-3, 1N1733A
1 N 3647		Si-Di	=1N3643: 3000V	31a		(10x4x4mm)	GP 02-30, MR 250-3, 1N1733A
1 N 3648	Cri	Si-Di	kV-Rr, 10kV, 0.35A, Uf<23V(0.35A)	31a		(70x13mmØ)	-
1 N 3649	USA,Mot,Tix	Si-Di	P Rr, 800V, 3.3A(Tc=50°), Uf<1,1V(1A)	32a		DO-4	BYX 38/900, BYX 39/800
1 N 3650		Si-Di	=1N3649: 1000V	32a		DO-4	BYX 38/1200, BYX 39/1000
1 N 3649R...3650R		Si-Di	=1N3649...3650:	32b		DO-4	BYX 38/...R, BYX 39/...R
1 N 3653	USA	Si-Di	SS, 100V, <4ns	31b		DO-35	(BAV 14)
1 N 3654	USA	Si-Di	SS, 100V, <4ns	31b		DO-35	BA 219, BAX 96
1 N 3655(A,B)	USA	Si-Di	UHF, S-Band Mx			DO-22	-

Original	Fabric.	Constr.	Info	{Compl. Fig.	JAEGER	Fig.	International
1 N 3656	USA	Si-Di	Rr, Uni, 200V, 0,75A, Uf<1,2V(0,5A)	31a	DO-35		BY 126...127, BY 133...134, 1N4003...07, ++
1 N 3657		Si-Di	=1N3656: 400V	31a	DO-35		BY 126...127, BY 133...134, 1N4004...07, ++
1 N 3658		Si-Di	=1N3656: 600V	31a	DO-35		BY 126...127, BY 133...134, 1N4005...07, ++
1 N 3659	USA, Mot	Si-Di	P Rr, 50V, 30A(Tc=100°), Uf<1,2V(25A)	75a	DO-21		SSI E1105...1140
1 N 3660		Si-Di	=1N3659: 100V	75a	DO-21		SSI E1110...1140
1 N 3661		Si-Di	=1N3659: 200V	75a	DO-21		SSI E1120...1140
1 N 3662		Si-Di	=1N3659: 300V	75a	DO-21		SSI E1120...1140
1 N 3663		Si-Di	=1N3659: 400V	75a	DO-21		SSI E1130...1140
1 N 3664		Si-Di	=1N3659: 500V	75a	DO-21		SSI E1130...1140
1 N 3665		Si-Di	=1N3659: 600V	75a	DO-21		SSI E1140
1 N 3659R...3665R		Si-Di	=1N3659...3665:	75b	DO-21		SSI E1205...1240
1 N 3666	USA	Ge-Di	Uni, S, 80V, 0,07A, <300ns	31a	DO-7		AAZ 28, AAZ 15, 1N633
1 N 3667	Cri	Si-Di	P Rr, 500V, 1,5A(Tc=120°)				-
1 N 3668	USA	Si-Di	S, 30V, 0,075A, <150ns	31a	DO-7		BAX 85, BAX 89...90, BAX 94, 1N4148...49++
1 N 3669	USA	Si-Di	S, 70V, 0,4A, <200ns	31a	DO-7		BA 157...159, BAV 15...16, BAX 12, ++
1 N 3670(A)	USA, Mot	Si-Di	P Rr, 700V, 12A(Tc=150°), Uf<2,05V(12A)	32a	DO-4		BYW 88/800, BYX 80...81, 1N4509...11
1 N 3671(A)		Si-Di	=1N3670: 800V	32a	DO-4		BYW 88/800, BYX 80...81, 1N4509...11
1 N 3672(A)		Si-Di	=1N3670: 900V	32a	DO-4		BYW 88/1000, BYX 81, 1N4510...11
1 N 3673(A)		Si-Di	=1N3670: 1000V	32a	DO-4		BYW 88/1000, BYX 81, 1N4510...11
1 N 3670R...3673R		Si-Di	=1N3670...3673:	32b	DO-4		BYW 88...R, BYX 80R...81R
1 N 3675	USA, Mot	Z-Di	6,8V, 20%, 0,75W	31a	SOD-22		BZV85/..., BZV22/..., ZPY..., 1N3016...51,++
1 N 3676		Z-Di	=1N3675: 7,5V	31a	SOD-22		
1 N 3677		Z-Di	=1N3675: 8,2V	31a	SOD-22		
1 N 3678		Z-Di	=1N3675: 9,1V	31a	SOD-22		
1 N 3679		Z-Di	=1N3675: 10V	31a	SOD-22		
1 N 3680		Z-Di	=1N3675: 11V	31a	SOD-22		
1 N 3681		Z-Di	=1N3675: 12V	31a	SOD-22		
1 N 3682		Z-Di	=1N3675: 13V	31a	SOD-22		
1 N 3683		Z-Di	=1N3675: 15V	31a	SOD-22		
1 N 3684		Z-Di	=1N3675: 16V	31a	SOD-22		
1 N 3685		Z-Di	=1N3675: 18V	31a	SOD-22		
1 N 3686		Z-Di	=1N3675: 20V	31a	SOD-22		
1 N 3687		Z-Di	=1N3675: 22V	31a	SOD-22		
1 N 3688		Z-Di	=1N3675: 24V	31a	SOD-22		
1 N 3689		Z-Di	=1N3675: 27V	31a	SOD-22		
1 N 3690		Z-Di	=1N3675: 30V	31a	SOD-22		
1 N 3691		Z-Di	=1N3675: 33V	31a	SOD-22		
1 N 3692		Z-Di	=1N3675: 36V	31a	SOD-22		
1 N 3693		Z-Di	=1N3675: 39V	31a	SOD-22		
1 N 3694		Z-Di	=1N3675: 43V	31a	SOD-22		
1 N 3695		Z-Di	=1N3675: 47V	31a	SOD-22		
1 N 3696		Z-Di	=1N3675: 51V	31a	SOD-22		
1 N 3697		Z-Di	=1N3675: 56V	31a	SOD-22		
1 N 3698		Z-Di	=1N3675: 62V	31a	SOD-22		
1 N 3699		Z-Di	=1N3675: 68V	31a	SOD-22		
1 N 3700		Z-Di	=1N3675: 75V	31a	SOD-22		
1 N 3701		Z-Di	=1N3675: 82V	31a	SOD-22		
1 N 3702		Z-Di	=1N3675: 91V	31a	SOD-22		
1 N 3703		Z-Di	=1N3675: 100V	31a	SOD-22		
1 N 3704		Z-Di	=1N3675: 110V	31a	SOD-22		
1 N 3705		Z-Di	=1N3675: 120V	31a	SOD-22		
1 N 3706		Z-Di	=1N3675: 130V	31a	SOD-22		
1 N 3707		Z-Di	=1N3675: 150V	31a	SOD-22		
1 N 3708		Z-Di	=1N3675: 160V	31a	SOD-22		
1 N 3709		Z-Di	=1N3675: 180V	31a	SOD-22		
1 N 3710		Z-Di	=1N3675: 200V	31a	SOD-22		
1 N 3675A...3710A		Z-Di	=1N3675...3710: 10%	31a	SOD-22		
1 N 3675B...3710B		Z-Di	=1N3675...3710: 5%	31a	SOD-22		
1 N 3711	Cri, Sem	Si-Di	kV-Rr, 6kV, 0,15A, Uf<8V(0,15A)	31a	(75x12mm0)		BYX 90
1 N 3712	Gen	Ge-Di	Tunnel-Di	34a	DO-17		-
1 N 3713	Gen	Ge-Di	Tunnel-Di	34a	DO-17		-
1 N 3714	Gen	Ge-Di	Tunnel-Di	34a	DO-17		-
1 N 3715	Gen	Ge-Di	Tunnel-Di	34a	DO-17		-
1 N 3716	Gen	Ge-Di	Tunnel-Di	34a	DO-17		-
1 N 3717	Gen	Ge-Di	Tunnel-Di	34a	DO-17		-
1 N 3718	Gen	Ge-Di	Tunnel-Di	34a	DO-17		-
1 N 3719	Gen	Ge-Di	Tunnel-Di	34a	DO-17		-
1 N 3720	Gen	Ge-Di	Tunnel-Di	34a	DO-17		-
1 N 3721	Gen	Ge-Di	Tunnel-Di	34a	DO-17		-
1 N 3722	USA	Si-Di	Min, S, 50V, <10ns	31a	=DO-18		(BA 218, BAX 13, BAX 91, 1N4148...49,++) ⁶
1 N 3723	Sem, Sol	Si-Di	Rr, 1000V, 0,75A, Uf<2,2V(0,75A)	31a	DO-15		BY 127, BY 133, BY 227, 1N4007, ++
1 N 3724		Si-Di	=1N3723: 1200V	31a	DO-15		BY 127, BY 133, BY 227, GP 10Q, ++
1 N 3725		Si-Di	=1N3723: 1400V	31a	DO-15		BY 400, BY 448, EM 516, GP 10W, ++
1 N 3726		Si-Di	=1N3723: 1600V	31a	DO-15		BY 400, DM 513, EM 516, GP 10Y
1 N 3727		Si-Di	=1N3723: 1800V	31a	DO-15		DM 516
1 N 3728	Sem, Ssi	Si-Di	Rr, Uni, 550V, 0,2A	31a	DO-7		BA 158...159, BA 199/550, BAY 89...90, ++
1 N 3729	Sem, Ssi	Si-Di	Rr, S, 600V, <500ns	31a	DO-7		BY 208/600, BY 295/600, BY 407, ++
1 N 3730	USA	Si-Di	S, 80V, <15ns	31a	DO-7		BAW 26...27
1 N 3731	USA	Si-Di	SS, 100V, 0,175A, <3ns	31a	DO-7		-
1 N 3732	USA	Z-Di	5,1V, 5%, 1W	34a	DO-1		BZV22/C5V1, BZX61/C5V1, ZPY5,1, 1N5918++
1 N 3733	Mw	Si-Di	UHF, S-Band Mx	Koax	DO-22		-
1 N 3734		Opto					-
1 N 3735	USA, Tho	Si-Di	P Rr, 100V, 250A(Tc=130°), Uf<1,3V(250A, 130°)	73a	DO-9		-
1 N 3736		Si-Di	=1N3735: 200V	73a	DO-9		-
1 N 3737		Si-Di	=1N3735: 300V	73a	DO-9		-
1 N 3738		Si-Di	=1N3735: 400V	73a	DO-9		-
1 N 3739		Si-Di	=1N3735: 500V	73a	DO-9		-
1 N 3740		Si-Di	=1N3735: 600V	73a	DO-9		-
1 N 3741		Si-Di	=1N3735: 800V	73a	DO-9		-
1 N 3742		Si-Di	=1N3735: 1000V	73a	DO-9		-
1 N 3743		Si-Di	=1N3735: 1200V	73a	DO-9		-
1 N 3744		Si-Di	=1N3735: 1400V	73a	DO-9		-
1 N 3735R...3744R		Si-Di	=1N3735...3744:	73b	DO-9		DS 40...A

Original	Fabric.	Constr.	Info	(Compl. Fig.	JAEGER	Fig.	International
1 N 3745	USA	Si-Di	UHF, X-Band Mx	Koax	DO-22	-	-
1 N 3746	USA	Si-Di	UHF, X-Band Mx	Koax	DO-22	-	-
1 N 3747	USA	Si-Di	UHF, X-Band Mx	Koax	DO-22	-	-
1 N 3748	Edl,Sem	Si-Di	Rr, 200V, 0.5A, Uf<1.5V(0.5A)	31a	DO-7	BY 126...127, BY 133...134, 1N4003...07, ++	
1 N 3749		Si-Di	=1N3748: 400V	31a	DO-7	BY 126...127, BY 133...134, 1N4004...07, ++	
1 N 3750		Si-Di	=1N3748: 600V	31a	DO-7	BY 126...127, BY 133...134, 1N4005...07, ++	
1 N 3751		Si-Di	=1N3748: 800V	31a	DO-7	BY 127, BY 133, BY 227, 1N4006...07, ++	
1 N 3752		Si-Di	=1N3748: 1000V	31a	DO-7	BY 127, BY 133, BY 227, 1N4007, ++	
1 N 3753	Idc,Sem	Ge-Di	Uni, 55V	31a	DO-7	AA 117...118, AA 132...134, 1N34, 1N54, ++	
1 N 3754	Rca,Sem,Tos	Si-Di	Rr, 100V, 0.125A, Uf<1V(0.125A)	2c	=TO-1 BA 159	31a	BA 157...159, BY 204/4, BY 206...207, ++
1 N 3755		Si-Di	=1N3754: 200V	2c	=TO-1 BA 159	31a	BA 157...159, BY 204/4, BY 206...207, ++
1 N 3756		Si-Di	=1N3754: 400V	2c	=TO-1 BA 159	31a	BA 157...159, BY 204/4, BY 206...207, ++
1 N 3757	USA	Si-Di	Rr, 200V, 1A, Uf<1V(1.5A)	31a	DO-7	BY 126...127, BY 133...134, 1N4003...07, ++	
1 N 3758		Si-Di	=1N3757: 400V	31a	DO-7	BY 126...127, BY 133...134, 1N4004...07, ++	
1 N 3759		Si-Di	=1N3757: 600V	31a	DO-7	BY 126...127, BY 133...134, 1N4005...07, ++	
1 N 3760		Si-Di	=1N3757: 800V	31a	DO-7	BY 127, BY 133, BY 227, 1N4006...07, ++	
1 N 3761		Si-Di	=1N3757: 1000V	31a	DO-7	BY 127, BY 133, BY 227, 1N4007, ++	
1 N 3762	Sem	Si-Di	kV-Rr, 7.5kV, 0.065A, Uf<12V(10mA)	31a	(19x7mm0)	BYX 90, 1N5183	
1 N 3763	Idc,Msc,Sie	Ref-Di	20V(10mA), 5%, +0.002%/°C, <35Ω, 1.5W	31a	SOD-18	ZTK 22	
1 N 3764	USA	Si-Di	kV-Rr, 3kV, 0.4A, Uf<6.5V	31a	(33x5x5mm)	1N1733A	
1 N 3765	USA,Mot,Tho	Si-Di	P Rr, 700V, 35A(Tc=140°), Uf<1.8V(35A, 140°)	32a	DO-5	1N4528	
1 N 3766		Si-Di	=1N3765: 800V	32a	DO-5	1N4528	
1 N 3767		Si-Di	=1N3765: 900V	32a	DO-5	1N4529	
1 N 3768		Si-Di	=1N3765: 1000V	32a	DO-5	1N4529	
1 N 3765R...3768R		Si-Di	=1N3765...3768:	32ab	DO-5	D 34C/...C	
1 N 3765T...3768T		Si-Di	=1N3765...3768:	73a	SOD-5	-	
1 N 3769	USA	Ge-Di	Uni, 90V	31a	DO-7	AA 117...118, AA 132...133	
1 N 3770	Miv	Si-Di	UHF Tuning	-	-	-	
1 N 3771	Mdc,Spe	Trigger-Di	Ub>170V, lh>4mA	31a	DO-7	-	
1 N 3772	Mdc,Spe	Trigger-Di	Ub=15...25V, lb<0.4mA, lh<50mA, Itsm=10A	31a	-	-	
1 N 3773	USA	Ge-Di	S, 25V, <40ns	31a	DO-7	-	
1 N 3774	Idc,Sem	Ref-Di	1.15V(10mA), 2%, <20Ω, 0.34W	31a	(17x8mm0)	-	
1 N 3775	USA	Si-Di	P Rr, 1500V, 3.3A(Tc=50°), Uf<1.5V(2A)	32a	DO-4	-	
1 N 3776	Cri	Z-Di	10V, 10%, 6W	32	=DO-4	BZX98/C10, BZY93/C10, ZL10, 1N2974,++	
1 N 3777	USA	Si-Di	P Rr, 800V, 35A(Tc=140°), Uf<1.8V(35A)	32a	DO-5	1N3766...68, 1N4528...30	
1 N 3778	Mic,Pai	Si-Di	UHF, C/X-Band Dem	Koax	DO-22	-	
1 N 3779	Inr,Sie,++	Ref-Di	6.5V(7.5mA) 3%, ±0.015%/°C, <10Ω, 0.4W, -55...+100°	31a	DO-7	BZV 10, BZV 27, BZX 90, 1N4580	
1 N 3780		Ref-Di	=1N3779: ±0.01%/°C	31a	DO-7	BZV 10, BZV 27, BZX 90, 1N4580	
1 N 3781		Ref-Di	=1N3779: ±0.005%/°C	31a	DO-7	BZV 11, BZV 28, BZX 91, 1N4581	
1 N 3782		Ref-Di	=1N3779: ±0.002%/°C	31a	DO-7	BZV 12, BZV 29, BZX 92, 1N4582	
1 N 3783		Ref-Di	=1N3779: ±0.001%/°C	31a	DO-7	BZV 13, BZV 30, BZX 93, 1N4583	
1 N 3784		Ref-Di	=1N3779: 0.0005%/°C	31a	DO-7	BZV 14, BZV 31, BZV 94, 1N4584	
1 N 3785	USA,Mot	Z-Di	6.8V, 20%, 1.5W	2c	TO-39	-	
1 N 3786		Z-Di	=1N3785: 7.5V	2c	TO-39	-	
1 N 3787		Z-Di	=1N3785: 8.2V	2c	TO-39	-	
1 N 3788		Z-Di	=1N3785: 9.1V	2c	TO-39	-	
1 N 3789		Z-Di	=1N3785: 10V	2c	TO-39	-	
1 N 3790		Z-Di	=1N3785: 11V	2c	TO-39	-	
1 N 3791		Z-Di	=1N3785: 12V	2c	TO-39	-	
1 N 3792		Z-Di	=1N3785: 13V	2c	TO-39	-	
1 N 3793		Z-Di	=1N3785: 15V	2c	TO-39	-	
1 N 3794		Z-Di	=1N3785: 16V	2c	TO-39	-	
1 N 3795		Z-Di	=1N3785: 18V	2c	TO-39	-	
1 N 3796		Z-Di	=1N3785: 20V	2c	TO-39	-	
1 N 3797		Z-Di	=1N3785: 22V	2c	TO-39	-	
1 N 3798		Z-Di	=1N3785: 24V	2c	TO-39	-	
1 N 3799		Z-Di	=1N3785: 27V	2c	TO-39	-	
1 N 3800		Z-Di	=1N3785: 30V	2c	TO-39	-	
1 N 3801		Z-Di	=1N3785: 33V	2c	TO-39	-	
1 N 3802		Z-Di	=1N3785: 36V	2c	TO-39	-	
1 N 3803		Z-Di	=1N3785: 39V	2c	TO-39	-	
1 N 3804		Z-Di	=1N3785: 43V	2c	TO-39	-	
1 N 3805		Z-Di	=1N3785: 47V	2c	TO-39	-	
1 N 3806		Z-Di	=1N3785: 51V	2c	TO-39	-	
1 N 3807		Z-Di	=1N3785: 56V	2c	TO-39	-	
1 N 3808		Z-Di	=1N3785: 62V	2c	TO-39	-	
1 N 3809		Z-Di	=1N3785: 68V	2c	TO-39	-	
1 N 3810		Z-Di	=1N3785: 75V	2c	TO-39	-	
1 N 3811		Z-Di	=1N3785: 82V	2c	TO-39	-	
1 N 3812		Z-Di	=1N3785: 91V	2c	TO-39	-	
1 N 3813		Z-Di	=1N3785: 100V	2c	TO-39	-	
1 N 3814		Z-Di	=1N3785: 110V	2c	TO-39	-	
1 N 3815		Z-Di	=1N3785: 120V	2c	TO-39	-	
1 N 3816		Z-Di	=1N3785: 130V	2c	TO-39	-	
1 N 3817		Z-Di	=1N3785: 150V	2c	TO-39	-	
1 N 3818		Z-Di	=1N3785: 160V	2c	TO-39	-	
1 N 3819		Z-Di	=1N3785: 180V	2c	TO-39	-	
1 N 3820		Z-Di	=1N3785: 200V	2c	TO-39	-	
1 N 3785A...3820A		Z-Di	=1N3785...3820: 10%	2c	TO-39	-	
1 N 3785B...3820B		Z-Di	=1N3785...3820: 5%	2c	TO-39	-	
1 N 3821	USA,Sie,Tho	Z-Di	3.3V, 10%, 1W	34a	DO-13	BZW22/..., BZX61/..., ZPY..., 1N5913...22,++	
1 N 3822		Z-Di	=1N3821: 3.6V	34a	DO-13	-	
1 N 3823		Z-Di	=1N3821: 3.9V	34a	DO-13	-	
1 N 3824		Z-Di	=1N3821: 4.3V	34a	DO-13	-	
1 N 3825		Z-Di	=1N3821: 4.7V	34a	DO-13	-	
1 N 3826		Z-Di	=1N3821: 5.1V	34a	DO-13	-	
1 N 3827		Z-Di	=1N3821: 5.6V	34a	DO-13	-	
1 N 3828		Z-Di	=1N3821: 6.2V	34a	DO-13	-	
1 N 3829		Z-Di	=1N3821: 6.8V	34a	DO-13	-	
1 N 3830		Z-Di	=1N3821: 7.5V	34a	DO-13	-	
1 N 3821A...3830A		Z-Di	=1N3821...3830: 5%	34a	DO-13	-	
1 N 3831	USA,Itt	Trigger-Di	0.15A, Itsm=5A, Ub=16-24V, lb<0.125mA, lh=0.5-15mA	31a	DO-7	4E20..., 4E20M...	
1 N 3832		Trigger-Di	=1N3831: Ub=21...29V	31a	DO-7	-	

Original	Fabric.	Constr.	Info	{ Compl. Fig.	JAEGER	Fig.	International
1 N 3833		Trigger-Di	=1N3831: Ub=26...34V	31a	DO-7		4E30..., 4E30M...
1 N 3834		Trigger-Di	=1N3831: Ub=31...39V	31a	DO-7		4E40..., 4E40M...
1 N 3835		Trigger-Di	=1N3831: Ub=36...44V	31a	DO-7		4E40..., 4E40M...
1 N 3836		Trigger-Di	=1N3831: Ub=41...49V	31a	DO-7		4E50..., 4E50M...
1 N 3837		Trigger-Di	=1N3831: Ub=46...54V	31a	DO-7		4E50..., 4E50M...
1 N 3838		Trigger-Di	=1N3831: Ub=90...110V	31a	DO-7		4E100..., 4E100M...
1 N 3839		Trigger-Di	=1N3831: Ub=16...24V, lh=14...50mA	31a	DO-7		4E20..., 4E20M...
1 N 3840		Trigger-Di	=1N3839: Ub=21...29V, lh=14...50mA	31a	DO-7		-
1 N 3841		Trigger-Di	=1N3839: Ub=26...34V, lh=14...50mA	31a	DO-7		4E30..., 4E30M...
1 N 3842		Trigger-Di	=1N3839: Ub=31...39V, lh=14...50mA	31a	DO-7		4E40..., 4E40M...
1 N 3843		Trigger-Di	=1N3839: Ub=36...44V, lh=14...50mA	31a	DO-7		4E40..., 4E40M...
1 N 3844		Trigger-Di	=1N3839: Ub=41...49V, lh=14...50mA	31a	DO-7		4E50..., 4E50M...
1 N 3845		Trigger-Di	=1N3839: Ub=46...54V, lh=14...50mA	31a	DO-7		4E50..., 4E50M...
1 N 3846		Trigger-Di	=1N3839: Ub=90...110V, lh=14...50mA	31a	DO-7		4E100..., 4E100M...
1 N 3847	Kmc	Ge-Di	Tunnel-Di				-
1 N 3848	Kmc	Ge-Di	Tunnel-Di				-
1 N 3849	Kmc	Ge-Di	Tunnel-Di				-
1 N 3850	Kmc	Ge-Di	Tunnel-Di				-
1 N 3851	Kmc	Ge-Di	Tunnel-Di				-
1 N 3852	Kmc	Ge-Di	Tunnel-Di				-
1 N 3853	Kmc	Ge-Di	Tunnel-Di				-
1 N 3854	Kmc	Ge-Di	Tunnel-Di				-
1 N 3855	Kmc	Ge-Di	Tunnel-Di				-
1 N 3856	Kmc	Ge-Di	Tunnel-Di				-
1 N 3857	Kmc	Ge-Di	Tunnel-Di				-
1 N 3858	Kmc	Ge-Di	Tunnel-Di				-
1 N 3859	Kmc	Ge-Di	Tunnel-Di				-
1 N 3860	Kmc	Ge-Di	Tunnel-Di				-
1 N 3861	Kmc	Ge-Di	Tunnel-Di				-
1 N 3862	Kmc	Ge-Di	Tunnel-Di				-
1 N 3863	Kmc	Ge-Di	Tunnel-Di				-
1 N 3864	USA	Si-Di	S, 125V, <900ns	31a	DO-7		BA 173, BAV 19...21, BAX 15...17, ++
1 N 3865	Idc,Sem	Ge-Di	Uni, 80V	31a	DO-7		1N270
1 N 3866	USA	Si-Di	Rr, 200V, 1A, Uf<1,1V(1A)	31a	DO-29		BY 126...127, BY 133...134, 1N4003...07, ++
1 N 3867		Si-Di	=1N3866: 400V	31a	DO-29		BY 126...127, BY 133...134, 1N4004...07, ++
1 N 3868		Si-Di	=1N3866: 600V	31a	DO-29		BY 126...127, BY 133...134, 1N4005...07, ++
1 N 3869	USA	Si-Di	Rr, 1000V, 0,5A	31a	DO-29		BA 159; BY 127, BY 133, 1N4007, ++
1 N 3870		Si-Di	=1N3879: 1500V	31a	DO-29		BY 269, DM 513, EM 516, GP 10W, ++
1 N 3871		Si-Di	=1N3879: 2000V, 0,25A	31a	DO-29		BAY 91, BY 203/20, SHG 2
1 N 3872	USA	Si-Di	S, 90V, <15ns	31a	DO-7		BA 202...203, BAV 16, BAY 43
1 N 3873	USA	Si-Di	SS, 90V, 0,15A, <4ns	31a	DO-7		BA 219, BAW 47
1 N 3874	USA	Si-Di	=1N3879: Iso Stud	32a	DO-10		-
1 N 3875		Si-Di	=1N3880: Iso Stud	32a	DO-10		-
1 N 3876		Si-Di	=1N3881: Iso Stud	32a	DO-10		-
1 N 3877		Si-Di	=1N3882: Iso Stud	32a	DO-10		-
1 N 3878		Si-Di	=1N3883: Iso Stud	32a	DO-10		-
1 N 3879(A)	USA,Mot,Rca Phi,Sie,Tho	Si-Di	P FRr, 50V, 6A(Tc=100°), Uf<1,4V(6A), <200ns A: Uf<0,9V(6A)	32a	DO-4		BYX 62/800
1 N 3880(A)		Si-Di	=1N3879: 100V	32a	DO-4		BYX 62/800
1 N 3881(A)		Si-Di	=1N3879: 200V	32a	DO-4		BYX 62/800
1 N 3882(A)		Si-Di	=1N3879: 300V	32a	DO-4		BYX 62/800
1 N 3883(A)		Si-Di	=1N3879: 400V	32a	DO-4		BYX 62/800
1 N 3879R...3883R		Si-Di	=1N3879:	32b	DO-4		BYX 62/800R
1 N 3884	USA	Si-Di	=1N3889: Iso Stud	32a	DO-10		-
1 N 3885		Si-Di	=1N3890: Iso Stud	32a	DO-10		-
1 N 3886		Si-Di	=1N3891: Iso Stud	32a	DO-10		-
1 N 3887		Si-Di	=1N3892: Iso Stud	32a	DO-10		-
1 N 3888		Si-Di	=1N3893: Iso Stud	32a	DO-10		-
1 N 3889(A)	USA,Mot,Rca Phi,Sie,Tho	Si-Di	P FRr, 50V, 12A(Tc=100°), Uf<1,4V(12A), <200ns A: Uf<0,95V(12A)	32a	DO-4		BYX 62/800
1 N 3890(A)		Si-Di	=1N3889: 100V	32a	DO-4		BYX 62/800
1 N 3891(A)		Si-Di	=1N3889: 200V	32a	DO-4		BYX 62/800
1 N 3892(A)		Si-Di	=1N3889: 300V	32a	DO-4		BYX 62/800
1 N 3893(A)		Si-Di	=1N3889: 400V	32a	DO-4		BYX 62/800
1 N 3889R...3893R		Si-Di	=1N3889:	32b	DO-4		BYX 62/800R
1 N 3894	Sem,Ssi	Si-Di	Rr, Uni, 400V, 0,4A, Uf<1V(0,4A)	31a	DO-7		BA 157...159, BY 204/4, BY 207, ++
1 N 3895	Sem,Ssi	Si-Di	Rr, Uni, 350V, 0,4A, Uf<1V(0,2A)	31a	DO-7		BA 157...159, BY 204/4, BY 206...207, ++
1 N 3896	Idc,Sem	Z-Di	0,775V(50mA), 5%, -0,2%/°C, <2,5Ω, 0,25W	31a	DO-7		-
1 N 3897	Idc,Sem	Z-Di	1,5V(30mA), 5%, -0,22%/°C, <5Ω, 0,25W	31a	DO-7		-
1 N 3898	Idc,Sem	Z-Di	2V(20mA), 5%, -0,23%/°C, <10Ω, 0,25W	31a	DO-7		-
1 N 3899	USA,Phi,Tho	Si-Di	P FRr, 50V, 20A(Tc=100°), Uf<1,4V(20A), <200ns	32a	DO-5		BYT 65/600, 1N3909...13
1 N 3900		Si-Di	=1N3899: 100V	32a	DO-5		BYT 65/600, 1N3910...13
1 N 3901		Si-Di	=1N3899: 200V	32a	DO-5		BYT 65/600, 1N3911...13
1 N 3902		Si-Di	=1N3899: 300V	32a	DO-5		BYT 65/600, 1N3912...13
1 N 3903		Si-Di	=1N3899: 400V	32a	DO-5		BYT 65/600, 1N3913
1 N 3899R...3903R		Si-Di	=1N3899: 400V	32b	DO-5		BYT 65/600R, 1N3909R...13R
1 N 3904	Sem,Ssi	Si-Di	=1N3899: Iso Stud	32a	DO-11		1N3914...18
1 N 3905		Si-Di	=1N3900: Iso Stud	32a	DO-11		1N3915...18
1 N 3906		Si-Di	=1N3901: Iso Stud	32a	DO-11		1N3916...18
1 N 3907		Si-Di	=1N3902: Iso Stud	32a	DO-11		1N3917...18
1 N 3908		Si-Di	=1N3903: Iso Stud	32a	DO-11		1N3918
1 N 3909	USA,Phi,Tho	Si-Di	P FRr, 50V, 30A(Tc=100°), Uf<1,4V(30A), <200ns	32a	DO-5		MR 860...866
1 N 3910		Si-Di	=1N3909: 100V	32a	DO-5		MR 861...866
1 N 3911		Si-Di	=1N3909: 200V	32a	DO-5		MR 862...866
1 N 3912		Si-Di	=1N3909: 300V	32a	DO-5		MR 864...866
1 N 3913		Si-Di	=1N3909: 400V	32a	DO-5		MR 864...866
1 N 3909R...3913R		Si-Di	=1N3909...3913:	32b	DO-5		MR 864R...866R
1 N 3914		Si-Di	=1N3909: Iso Stud	32a	DO-11		-
1 N 3915		Si-Di	=1N3910: Iso Stud	32a	DO-11		-
1 N 3916		Si-Di	=1N3911: Iso Stud	32a	DO-11		-
1 N 3917		Si-Di	=1N3912: Iso Stud	32a	DO-11		-
1 N 3918		Si-Di	=1N3913: Iso Stud	32a	DO-11		-
1 N 3919	USA	Si-Di	P Rr, 1000V, 5A(Tc=100°), Uf<2V(5A)	32a	DO-4		BYX 38/1200, BYX 39/1200

Original	Fabric.	Constr.	Info	{Compl. Fig.	JAEGER	Fig.	International
1 N 3920		Si-Di	=1N3919: 1500V	32a	DO-4	-	-
1 N 3921		Si-Di	=1N3919: 2000V	32a	DO-4	-	-
1 N 3922		Si-Di	=1N3919: 2500V	32a	DO-4	-	-
1 N 3923		Si-Di	=1N3919: 3000V	32a	DO-4	-	-
1 N 3924	USA	Si-Di	P Rr, 1000V, 10A(Tc=100°), Uf<2V(10A)	32a	DO-4	-	BYX 42/1200, BYX 98/1200
1 N 3925		Si-Di	=1N3924: 1500V	32a	DO-4	-	-
1 N 3926		Si-Di	=1N3924: 2000V	32a	DO-4	-	-
1 N 3927		Si-Di	=1N3924: 2500V	32a	DO-4	-	-
1 N 3928		Si-Di	=1N3924: 3000V	32a	DO-4	-	-
1 N 3929	USA	Si-Di	Rr, 1000V, 1A, Uf<2V(1A)	34a	DO-13	-	BY 127, BY 133, BY 227, 1N4007, ++
1 N 3930		Si-Di	=1N3929: 1500V	34a	DO-13	-	BY 269, DM 513, EM 516, GP 10W
1 N 3931		Si-Di	=1N3929: 2000V	34a	DO-13	-	-
1 N 3932		Si-Di	=1N3929: 2500V	34a	DO-13	-	-
1 N 3933		Si-Di	=1N3929: 3000V	34a	DO-13	-	-
1 N 3934	USA	Si-Di	P Rr, 1200V, 10A(Tc=25°), Uf<2V(10A)	32a	DO-4	-	BYX 42/1200, BYX 98/1200
1 N 3935	Spe	Trigger-Di	Ub=26...34V, Ib<15µA, Ih<45mA, Itsm=10A	31a	DO-7	-	-
1 N 3936	Spe	Trigger-Di	Ub=16...24V, Ib<0,125mA, Ih<11mA, Itsm=10A	31a	DO-7	-	-
1 N 3937	Itt	Trigger-Di	Ub=90...110V, Ib<0,125mA, Ih<6mA, Itsm=10A	31a	DO-7	-	-
1 N 3938	USA,Tho	Si-Di	Rr, contr.av., 200V, 2A, Uf<1,1V(2A)	34a	DO-13	-	BYW 52...56, 1N5060...62
1 N 3939		Si-Di	=1N3938: 400V	34a	DO-13	-	BYW 53...56, 1N5060...62
1 N 3940		Si-Di	=1N3938: 600V	34a	DO-13	-	BYW 54...56, 1N5061...62
1 N 3941		Si-Di	=1N3938: 800V	34a	DO-13	-	BYW 55...56, 1N5062
1 N 3942		Si-Di	=1N3938: 1000V	34a	DO-13	-	BYW 56
1 N 3943	Sol	Z-Di	2,5V, 0,75W	34a	DO-13	-	-
1 N 3944	USA	Ge-Di	S, 15V, <12ns	31a	DO-7	-	AAZ 48, 1N995
1 N 3945	Gen,Trw	Si-Di	VHF Tuning	31a	DO-14	-	-
1 N 3946	Gen,Trw	Si-Di	VHF Tuning	31a	DO-14	-	-
1 N 3947	Gen,Trw	Si-Di	VHF Tuning	31a	DO-14	-	-
1 N 3948		Si-Di	Tunnel-Di	-	-	-	-
1 N 3949	USA,Sie	Z-Di	20V, 5%, 10W(Tc=25°)	2c	DO-4	-	BZX98/C20, BZY93/C20, ZX20, 1N2984,++
1 N 3950	USA	Z-Di	20V, 5%, 1,5W	2c	TO-39	-	-
1 N 3951	USA	Z-Di	25V, 5%, 1,5W	2c	TO-39	-	-
1 N 3952	Sem	Si-Di	Rr, 130V, 0,2A	31a	DO-7	-	BA 189...190, BAY 20...21, BAY 45...46, ++
1 N 3953	Idc,Sem	Ge-Di	S, 40V, <300ns	31a	DO-7	-	AAZ 28, 1N631, 1N633
1 N 3954	Idc,Msc,Sem	Si-Di	SS, 50V, <4ns	31a	DO-7	-	BAW 62, BAX 95, 1N4148...49, 1N4446...49++
1 N 3955	old	Si-Di	P Rr, 100V, 70A(Tc=150°), Uf<1,3V(70A)	32	DO-5	-	-
1 N 3956	Idc,Sem	Si-Di	SS, 30V, 2ns	31a	DO-7	-	BA 218, BAX 13, BAX 91, 1N4148...49, ++
1 N 3957(GP)	USA,Sie	Si-Di	=1N3611: 1000V	{GP: SOD-22 31a	DO-41	-	BY 127, BY 133, BY 227, 1N4007, ++
1 N 3958(C)	USA	Si-Di	P Rr, 100V, 3,5A, Uf<1,3V(3,5A), <3µs(C: 1µs)	32a	DO-4	-	BYX 38/300, BYX 39/600
1 N 3959(C)		Si-Di	=1N3958: 200V	32a	DO-4	-	BYX 38/300, BYX 39/600
1 N 3960(C)		Si-Di	=1N3958: 300V	32a	DO-4	-	BYX 38/300, BYX 39/600
1 N 3961(C)		Si-Di	=1N3958: 400V	32a	DO-4	-	BYX 38/600, BYX 39/600
1 N 3962(C)		Si-Di	=1N3958: 500V	32a	DO-4	-	BYX 38/600, BYX 39/600
1 N 3963(C)		Si-Di	=1N3958: 600V	32a	DO-4	-	BYX 38/600, BYX 39/600
1 N 3964	USA	Si-Di	P Rr, contr.av., 200V, 22A(Tc=120°), Uf<0,6(26A)	32a	DO-4	-	BYX 25/600
1 N 3965		Si-Di	=1N3964: 400V	32a	DO-4	-	BYX 25/600
1 N 3966		Si-Di	=1N3964: 600V	32a	DO-4	-	BYX 25/600
1 N 3967		Si-Di	=1N3964: 800V	32a	DO-4	-	BYX 25/800
1 N 3968	USA	Si-Di	P Rr, contr.av., 200V, 50A(Tc=120°), Uf<0,6V(60A)	32a	DO-5	-	-
1 N 3969		Si-Di	=1N3968: 400V	32a	DO-5	-	-
1 N 3970		Si-Di	=1N3968: 600V	32a	DO-5	-	-
1 N 3971		Si-Di	=1N3968: 800V	32a	DO-5	-	-
1 N 3972	USA	Si-Di	P Rr, contr.av., 200V, 104A(Tc=120°), Uf<0,6V(150A)	73a	DO-8	-	-
1 N 3973		Si-Di	=1N3972: 400V	73a	DO-8	-	-
1 N 3974		Si-Di	=1N3972: 600V	73a	DO-8	-	-
1 N 3975		Si-Di	=1N3972: 800V	73a	DO-8	-	-
1 N 3976	USA	Si-Di	P Rr, contr.av., 200V, 250A(Tc=120°), Uf<0,6V(250A)	73a	DO-9	-	-
1 N 3977		Si-Di	=1N3976: 400V	73a	DO-9	-	-
1 N 3978		Si-Di	=1N3976: 600V	73a	DO-9	-	-
1 N 3979		Si-Di	=1N3976: 800V	73a	DO-9	-	-
1 N 3981	USA	Si-Di	Rr, Uni, 200V, 3A, Uf<1V(0,9A)	31a	DO-35	-	BY 251...255, BYW 17/200, 1N5402...08, ++
1 N 3982		Si-Di	=1N3981: 400V	31a	DO-35	-	BY 252...255, BYW 17/400, 1N5404...08, ++
1 N 3983		Si-Di	=1N3981: 600V	31a	DO-35	-	BY 253...255, BYW 17/400, 1N5406...08, ++
1 N 3984	USA,Sie	Z-Di	5,5V, 5%, 10W(Tc=25°)	32a	DO-4	-	BZX98/C5V6, BZY93/C5V6, ZX5,6, 1N3997,++
1 N 3985		Z-Di	=1N3984: 6V	32a	DO-4	-	BZX98/C6V2, BZY93/C6V2, ZX6,2, 1N3998,++
1 N 3986		Z-Di	=1N3984: 6,2V	32a	DO-4	-	BZX98/C6V2, BZY93/C6V2, ZX6,2, 1N3998,++
1 N 3987	USA,Tho	Si-Di	P Rr, 700V, 6A(Tc=150°), Uf<1,2V(5A)	32a	DO-4	-	BYX 38/900, BYX 39/800
1 N 3988		Si-Di	=1N3987: 800V	32a	DO-4	-	BYX 38/900, BYX 39/800
1 N 3989		Si-Di	=1N3987: 900V	32a	DO-4	-	BYX 38/900, BYX 39/1000
1 N 3990		Si-Di	=1N3987: 1000V	32a	DO-4	-	BYX 38/1200, BYX 39/1000
1 N 3987R...3990R		Si-Di	=1N3987...3990:	32b	DO-4	-	BYX 38/...R, BYX 39/...R
1 N 3991	Idc,Sem	Ge-Di	Uni, 35V	31a	DO-7	-	AA 117...118, AA 132...134, 1N34, 1N54, ++
1 N 3992	Edi,Sem	Si-Di	kV-Rr, 4kV, Uf<5V(0,25A)	31a	(10x4x4mm)	-	GP 02-40, MR 250-4, 1N1734A
1 N 3993	USA,Mot,Sie	Z-Di	3,9V, 10%, 10W(Tc=55°)	32a	DO-4	-	BZX98/..., BZY93/..., ZL..., ZX...
1 N 3994		Z-Di	=1N3993: 4,3V	32a	DO-4	-	-
1 N 3995		Z-Di	=1N3993: 4,7V	32a	DO-4	-	-
1 N 3996		Z-Di	=1N3993: 5,1V	32a	DO-4	-	-
1 N 3997		Z-Di	=1N3993: 5,6V	32a	DO-4	-	-
1 N 3998		Z-Di	=1N3993: 6,2V	32a	DO-4	-	-
1 N 3999		Z-Di	=1N3993: 6,8V	32a	DO-4	-	-
1 N 4000		Z-Di	=1N3993: 7,5V	32a	DO-4	-	-
1 N 3993A...4000A		Z-Di	=1N3993...4000: 5%	32a	DO-4	-	-
1N 4001(D,G,K,P,S)	USA,EUR,JAP	Si-Di	Rr, Uni, 50V, 1A, Uf<1,1V(1A) D: SOD-81, G: SOD-57, K,P: SOD-22, S: DO-41	31a	SOD-22	1N4007 31a	BY 126...127, BY 133...135, 1N5614...22, ++
1 N 4002(D,G,P,S)		Si-Di	=1N4001: 100V	31a	SOD-22	1N4007 31a	BY 126...127, BY 133...135, 1N5614...22, ++
1 N 4003(D,G,P,S)		Si-Di	=1N4001: 200V	31a	SOD-22	1N4007 31a	BY 126...127, BY 133...134, 1N5614...22, ++
1 N 4004(D,G,P,S)		Si-Di	=1N4001: 400V	31a	SOD-22	1N4007 31a	BY 126...127, BY 133...134, 1N5618...22, ++
1 N 4005(D,G,P,S)		Si-Di	=1N4001: 600V	31a	SOD-22	1N4007 31a	BY 126...127, BY 133...134, 1N5618...22, ++
1 N 4006(D,G,P,S)		Si-Di	=1N4001: 800V	31a	SOD-22	1N4007 31a	BY 127, BY 133, BY 227, 1N5620...22, ++
1 N 4007(D,G,P,S)		Si-Di	=1N4001: 1000V	31a	SOD-22	1N4007 31a	BY 127, BY 133, BY 227, 1N5622, ++
1 N 4007 KH		Si-Di	=1N4001: 1600V	31a	SOD-22	-	DM 513, DM 516, EM 516, GP 10Y
1 N 4007 KS		Si-Di	=1N4001: 1250V	31a	SOD-22	BY 133 31a	BY 133, BYX 95, EM 513, GP 10V,++
1 N 4008	USA	Ge-Di	S, 12V, 0,1A, <70ns	31a	DO-7	-	AAZ 18

Original	Fabric.	Constr.	Info	{Compl. Fig.	JAEGER	Fig.	International	
1 N 4009	USA,Phi,Tho	Si-Di	SS, 25/35V, 0,1/0,5A, Uf<1V(30mA), <4ns	31a	DO-7	1N4148	31a	BA 318, BAY 38, BAX 80, 1N4148...49, ++
1 N 4010	USA,Sie	Ref-Di	6,2V(7,5mA), 5%, ±0,01%/°C, <15Ω, 0,4W	31a	DO-7			BZV 10, BZV 27, BZX 90, 1N4580
1 N 4011	Sem,Ssi	Si-Di	Rr, 1000V, 0,5A	34a	DO-13			BA 159, BY 127, BY 133, 1N4007, ++
1 N 4012	USA	Si-Di	P Rr, 700V, 12A(Tc=150°), Uf<1,3V(12A)	32a	DO-4			BYW 88/800, BYX 80...81, 1N4509...11, ++
1 N 4013		Si-Di	=1N4012: 800V	32a	DO-4			BYW 88/800, BYX 80...81, 1N4509...11, ++
1 N 4014		Si-Di	=1N4012: 900V	32a	DO-4			BYW 88/1000, BYX 81, 1N4510...11, ++
1 N 4015		Si-Di	=1N4012: 1000V	32a	DO-4			BYW 88/1000, BYX 81, 1N4510...11, ++
1 N 4016	USA	Z-Di	8,2V, 20%, 5W(Tc=25°)	=32				(BZX98/..., BZY93/..., ZX..., 1N2972...3005)6
1 N 4017		Z-Di	=1N4016: 9,1V	=32				
1 N 4018		Z-Di	=1N4016: 10V	=32				
1 N 4019		Z-Di	=1N4016: 11V	=32				
1 N 4020		Z-Di	=1N4016: 12V	=32				
1 N 4021		Z-Di	=1N4016: 13V	=32				
1 N 4022		Z-Di	=1N4016: 15V	=32				
1 N 4023		Z-Di	=1N4016: 16V	=32				
1 N 4024		Z-Di	=1N4016: 18V	=32				
1 N 4025		Z-Di	=1N4016: 20V	=32				
1 N 4026		Z-Di	=1N4016: 22V	=32				
1 N 4027		Z-Di	=1N4016: 24V	=32				
1 N 4028		Z-Di	=1N4016: 27V	=32				
1 N 4029		Z-Di	=1N4016: 30V	=32				
1 N 4030		Z-Di	=1N4016: 33V	=32				
1 N 4031		Z-Di	=1N4016: 36V	=32				
1 N 4032		Z-Di	=1N4016: 39V	=32				
1 N 4033		Z-Di	=1N4016: 43V	=32				
1 N 4034		Z-Di	=1N4016: 47V	=32				
1 N 4035		Z-Di	=1N4016: 51V	=32				
1 N 4036		Z-Di	=1N4016: 56V	=32				
1 N 4037		Z-Di	=1N4016: 62V	=32				
1 N 4038		Z-Di	=1N4016: 68V	=32				
1 N 4039		Z-Di	=1N4016: 75V	=32				
1 N 4040		Z-Di	=1N4016: 82V	=32				
1 N 4041		Z-Di	=1N4016: 91V	=32				
1 N 4042		Z-Di	=1N4016: 100V	=32				
1 N 4016A...4042A		Z-Di	=1N4016...4042: 10%	=32				
1 N 4016B...4042B		Z-Di	=1N4016...4042: 5%	=32				
1 N 4043	Idc	Si-Di	Min, SS, 25V, <4ns	=31a	=DO-20			(BA 218, BAX 13, BAX 91, 1N4148...49,++)6
1 N 4044	USA	Si-Di	P Rr, 50V, 275A(Tc=120°), Uf<1,35V(275A)	73a	DO-9			
1 N 4045		Si-Di	=1N4044: 100V	73a	DO-9			
1 N 4046		Si-Di	=1N4044: 150V	73a	DO-9			
1 N 4047		Si-Di	=1N4044: 200V	73a	DO-9			
1 N 4048		Si-Di	=1N4044: 250V	73a	DO-9			
1 N 4049		Si-Di	=1N4044: 300V	73a	DO-9			
1 N 4050		Si-Di	=1N4044: 400V	73a	DO-9			
1 N 4051		Si-Di	=1N4044: 500V	73a	DO-9			
1 N 4052		Si-Di	=1N4044: 600V	73a	DO-9			
1 N 4053		Si-Di	=1N4044: 700V	73a	DO-9			
1 N 4054		Si-Di	=1N4044: 800V	73a	DO-9			
1 N 4055		Si-Di	=1N4044: 900V	73a	DO-9			
1 N 4056		Si-Di	=1N4044: 1000V	73a	DO-9			
1 N 4044R...4056R		Si-Di	=1N4044...4056:	73b	DO-9			
1 N 4057(A)	USA,Mot,Sie	Ref-Di	12,4V(10mA), 5%, ±0,005%/°C, <25Ω, 1,5W,-55...+100° A: ±0,002%/°C	31a	(13x6mm0)			
1 N 4058(A)		Ref-Di	=1N4057: 14,6V, <30Ω	31a	(13x6mm0)			
1 N 4059(A)		Ref-Di	=1N4057: 16,8V, <30Ω	31a	(13x6mm0)			
1 N 4060(A)		Ref-Di	=1N4057: 18,5V, <30Ω	31a	(13x6mm0)			
1 N 4061(A)		Ref-Di	=1N4057: 21V, <35Ω	31a	(13x6mm0)			
1 N 4062(A)		Ref-Di	=1N4057: 23V, <40Ω	31a	(13x6mm0)			
1 N 4063(A)		Ref-Di	=1N4057: 27V, <45Ω	31a	(13x6mm0)			
1 N 4064(A)		Ref-Di	=1N4057: 30V, <50Ω	31a	(13x6mm0)			
1 N 4065(A)		Ref-Di	=1N4057: 33V, <55Ω	31a	(13x6mm0)			
1 N 4066(A)		Ref-Di	=1N4057: 37V(7,5mA), <80Ω	31a	(13x6mm0)			
1 N 4067(A)		Ref-Di	=1N4057: 43V(7,5mA), <90Ω	31a	(13x6mm0)			
1 N 4068(A)		Ref-Di	=1N4057: 47V(7,5mA), <100Ω	31a	(13x6mm0)			
1 N 4069(A)		Ref-Di	=1N4057: 51V(7,5mA), <110Ω, 2W	31a	(19x6mm0)			
1 N 4070(A)		Ref-Di	=1N4057: 56V(7,5mA), <120Ω, 2W	31a	(19x6mm0)			
1 N 4071(A)		Ref-Di	=1N4057: 62V(7,5mA), <135Ω, 2W	31a	(19x6mm0)			
1 N 4072(A)		Ref-Di	=1N4057: 68V(5mA), <230Ω, 2W	31a	(19x6mm0)			
1 N 4073(A)		Ref-Di	=1N4057: 75V(5mA), <250Ω, 2W	31a	(19x6mm0)			
1 N 4074(A)		Ref-Di	=1N4057: 82V(5mA), <270Ω, 2W	31a	(19x6mm0)			
1 N 4075(A)		Ref-Di	=1N4057: 87V(5mA), <290Ω, 2W	31a	(19x6mm0)			
1 N 4076(A)		Ref-Di	=1N4057: 91V(5mA), <310Ω, 2W	31a	(19x6mm0)			
1 N 4077(A)		Ref-Di	=1N4057: 100V(5mA), <340Ω, 2W	31a	(19x6mm0)			
1 N 4078(A)		Ref-Di	=1N4057: 105V(2,5mA), <700Ω, 2W	31a	(19x6mm0)			
1 N 4079(A)		Ref-Di	=1N4057: 110V(2,5mA), <740Ω, 2W	31a	(19x6mm0)			
1 N 4080(A)		Ref-Di	=1N4057: 120V(2,5mA), <800Ω, 2W	31a	(19x6mm0)			
1 N 4081(A)		Ref-Di	=1N4057: 130V(2,5mA), <840Ω, 2,5W	31a	(29x8mm0)			
1 N 4082(A)		Ref-Di	=1N4057: 140V(2,5mA), <960Ω, 2,5W	31a	(29x8mm0)			
1 N 4083(A)		Ref-Di	=1N4057: 150V(2,5mA), <1020Ω, 2,5W	31a	(29x8mm0)			
1 N 4084(A)		Ref-Di	=1N4081: 175V(2,5mA), <1150Ω, 2,5W	31a	(29x8mm0)			
1 N 4085(A)		Ref-Di	=1N4081: 200V(2,5mA), <1350Ω, 2,5W	31a	(29x8mm0)			
1 N 4086	USA	Si-Di	S, 70V, <200ns	31a	DO-7			BAW 49...50, BAX 15...17, BAY 72, ++
1 N 4087	USA	Si-Di	SS, 50V, <2,5ns	31a	DO-7			BA 318, BAY 38, BAY 95, 1N4148...49, ++
1 N 4088	USA	Ge-Di	Uni, 30V	31a	DO-7			AA 117...118, AA 132...14, 1N34, 1N54, ++
1 N 4089	USA	Si-Di	Rr, 400V, 1,1A	31a	DO-27			BY 126...127, BY 133...134, 1N4004...07, ++
1 N 4090	Gen	Ge-Di	Tunnel-Di	34a	DO-17			
1 N 4091	Mrv	Si-Di	UHF Tuning	Koax	DO-22			
1 N 4092	USA	Si-Di	Uni, 50V	31a	DO-7			BA 127, BA 187...190, 1N4148...49, ++
1 N 4093	USA	Si-Di	Uni, 50V	31a	DO-7			BA 127, BA 187...190, 1N4148...49, ++
1 N 4094	Gsi	Z-Di	9,4V, 2%, 1W					
1 N 4095	USA,Sie	Z-Di	5V, 10%, 0,33W	31a	DO-7			BZX55/C5V1, BZX79/C5V1, ZPD5, 1, 1N5231++
1 N 4096	USA	Z-Di	90V, 5%, 3W	31a	SOD-17			BZT03/..., BZV40/..., BZV48/..., 1N5377...83
1 N 4097		Z-Di	=1N4096: 100V	31a	SOD-17			

Original	Fabric.	Constr.	Info	{Compl. Fig.	JAEGER	Fig.	International	
1 N 4098		Z-Di	=1N4096: 150V	31a	SOD-17			
1 N 4099	USA,Sie,Tho	Z-Di	6,8V, 5%, 0,4W, In, Ur<40µV	31a	DO-7,DO-35		BZV 39/...	
1 N 4100		Z-Di	=1N4099: 7,5V	31a	DO-7,DO-35			
1 N 4101		Z-Di	=1N4099: 8,2V	31a	DO-7,DO-35			
1 N 4102		Z-Di	=1N4099: 8,7V	31a	DO-7,DO-35			
1 N 4103		Z-Di	=1N4099: 9,1V	31a	DO-7,DO-35			
1 N 4104		Z-Di	=1N4099: 10V	31a	DO-7,DO-35			
1 N 4105		Z-Di	=1N4099: 11V	31a	DO-7,DO-35			
1 N 4106		Z-Di	=1N4099: 12V	31a	DO-7,DO-35			
1 N 4107		Z-Di	=1N4099: 13V	31a	DO-7,DO-35			
1 N 4108		Z-Di	=1N4099: 14V	31a	DO-7,DO-35			
1 N 4109		Z-Di	=1N4099: 15V	31a	DO-7,DO-35			
1 N 4110		Z-Di	=1N4099: 16V	31a	DO-7,DO-35			
1 N 4111		Z-Di	=1N4099: 17V	31a	DO-7,DO-35			
1 N 4112		Z-Di	=1N4099: 18V	31a	DO-7,DO-35			
1 N 4113		Z-Di	=1N4099: 19V	31a	DO-7,DO-35			
1 N 4114		Z-Di	=1N4099: 20V	31a	DO-7,DO-35			
1 N 4115		Z-Di	=1N4099: 22V	31a	DO-7,DO-35			
1 N 4116		Z-Di	=1N4099: 24V	31a	DO-7,DO-35			
1 N 4117		Z-Di	=1N4099: 25V	31a	DO-7,DO-35			
1 N 4118		Z-Di	=1N4099: 27V	31a	DO-7,DO-35			
1 N 4119		Z-Di	=1N4099: 28V	31a	DO-7,DO-35			
1 N 4120		Z-Di	=1N4099: 30V	31a	DO-7,DO-35			
1 N 4121		Z-Di	=1N4099: 33V	31a	DO-7			
1 N 4122		Z-Di	=1N4099: 36V	31a	DO-7			
1 N 4123		Z-Di	=1N4099: 39V	31a	DO-7			
1 N 4124		Z-Di	=1N4099: 43V	31a	DO-7			
1 N 4125		Z-Di	=1N4099: 47V	31a	DO-7			
1 N 4126		Z-Di	=1N4099: 51V	31a	DO-7			
1 N 4127		Z-Di	=1N4099: 56V	31a	DO-7			
1 N 4128		Z-Di	=1N4099: 60V	31a	DO-7			
1 N 4129		Z-Di	=1N4099: 62V	31a	DO-7			
1 N 4130		Z-Di	=1N4099: 68V	31a	DO-7			
1 N 4131		Z-Di	=1N4099: 75V	31a	DO-7			
1 N 4132		Z-Di	=1N4099: 82V	31a	DO-7			
1 N 4133		Z-Di	=1N4099: 87V	31a	DO-7			
1 N 4134		Z-Di	=1N4099: 91V	31a	DO-7			
1 N 4135		Z-Di	=1N4099: 100V	31a	DO-7			
1 N 4136	USA	Si-Di	P Rr, 200V, 70A(Tc=100°), Uf<1,6V(70A, 100°)	32a	DO-5			
1 N 4137		Si-Di	=1N4136: 400V	32a	DO-5			
1 N 4138		Si-Di	=1N4136: 600V	32a	DO-5			
1 N 4139	USA	Si-Di	Rr, 50V, 3A, Uf<1V(3A, 50°)	31a	(9x7mm0)		BY 251...255, BYW 17/100, 1N5400...08, ++	
1 N 4140		Si-Di	=1N4139: 100V	31a	(9x7mm0)		BY 251...255, BYW 17/100, 1N5401...08, ++	
1 N 4141		Si-Di	=1N4139: 200V	31a	(9x7mm0)		BY 251...255, BYW 17/200, 1N5402...08, ++	
1 N 4142		Si-Di	=1N4139: 400V	31a	(9x7mm0)		BY 252...255, BYW 17/400, 1N5404...08, ++	
1 N 4143		Si-Di	=1N4139: 600V	31a	(9x7mm0)		BY 253...255, BYW 17/600, 1N5406...08, ++	
1 N 4144		Si-Di	=1N4139: 800V	31a	(9x7mm0)		BY 254...255, BYW 17/800, 1N5407...08, ++	
1 N 4145		Si-Di	=1N4139: 1000V	31a	(9x7mm0)		BY 255, BYW 17/1000, 1N5408, ++	
1 N 4146		Si-Di	=1N4139: 1200V	31a	(9x7mm0)		BY 255, BY 228, BYW 17/1200	
1 N 4147	USA	Si-Di	S, 30V, Uf<1V(30mA), 10ns	31a	DO-7	1N4148	31a	BA 218, BAX 13, BAX 91, 1N4148...49, ++
1 N 4148	USA,EUR,JAP	Si-Di	SS, 75/100V, 0,2A, Uf<1V(10mA), <4ns, <4pF(0V)	31a	DO-35	1N4148	31a	BAW 62, BAW 76, BAX 95, 1N4446...49, ++
1 N 4148 SMD		Si-Di	=1N4148: SMD	72a(3,4mm)	SOD-80	1N4148(SMD)		
1 N 4149		Si-Di	=1N4148: <2pF(0V)	31a	DO-35	1N4148	31a	BAW 62, BAW 76, BAX 95, 1N4446...49, ++
1 N 4150	USA,EUR,JAP	Si-Di	SS, 50V, 0,2/0,6A, Uf<1V(0,2A), <4ns	31a	DO-35	1N4148	31a	BAW 62, BAW 76, BAX 95, 1N4148...49, ++
1 N 4151	USA,EUR,JAP	Si-Di	SS, 50/75V, 0,2/0,45A, Uf<1V(0,05A), <4ns	31a	DO-35	1N4148	31a	BAW 62, BAW 76, BAX 95, 1N4148...49, ++
1 N 4152	USA,EUR,JAP	Si-Di	SS, 30/40V, 0,2/0,45A, Uf<0,81V(10mA), <4ns	31a	DO-35	1N4148	31a	BAW 62, BAW 76, BAX 95, 1N4148...49, ++
1 N 4153		Si-Di	=1N4152: 50/75V	31a	DO-35	1N4148	31a	BAW 62, BAW 76, BAX 95, 1N4148...49, ++
1 N 4154	USA,EUR,JAP	Si-Di	SS, 25/35V, 0,2/0,45A, Uf<1V(30mA), <4ns	31a	DO-35	1N4148	31a	BAW 62, BAW 76, BAX 95, 1N4148...49, ++
1 N 4155	USA	Si-Di	Uni, 400V, 0,2A, Uf<1V(0,1A), <10µs	31a	DO-7			BA 157...159, BA 199/450, BAY 89, ++
1 N 4156	USA,Gen	Si-St	20V, 0,4W, Uf<1,41V(1mA)<1,84V(100mA)	31a	DO-7			BZ 102/1V4, BZX 75/C1V4, ZTE 1,5
1 N 4157		Si-St	=1N4156: Uf<2,05V(1mA)/2,66V(100mA)	31a	DO-7			BZ 102/2V1, BZX 75/C2V1, ZTE 1
1 N 4158	USA,Fer,Tho	Z-Di	6,8V, 20%, 1W	31a	DO-29	Z-Diode 6,8V	31a	BZW22/..., BZX61/..., ZPY..., 1N5921...56, ++
1 N 4159		Z-Di	=1N4158: 7,5V	31a	DO-29	Z-Diode 7,5V	31a	
1 N 4160		Z-Di	=1N4158: 8,2V	31a	DO-29	Z-Diode 8,2V	31a	
1 N 4161		Z-Di	=1N4158: 9,1V	31a	DO-29	Z-Diode 9,1V	31a	
1 N 4162		Z-Di	=1N4158: 10V	31a	DO-29	Z-Diode 10V	31a	
1 N 4163		Z-Di	=1N4158: 11V	31a	DO-29	Z-Diode 11V	31a	
1 N 4164		Z-Di	=1N4158: 12V	31a	DO-29	Z-Diode 12V	31a	
1 N 4165		Z-Di	=1N4158: 13V	31a	DO-29	Z-Diode 13V	31a	
1 N 4166		Z-Di	=1N4158: 15V	31a	DO-29	Z-Diode 15V	31a	
1 N 4167		Z-Di	=1N4158: 16V	31a	DO-29	Z-Diode 16V	31a	
1 N 4168		Z-Di	=1N4158: 18V	31a	DO-29	Z-Diode 18V	31a	
1 N 4169		Z-Di	=1N4158: 20V	31a	DO-29	Z-Diode 20V	31a	
1 N 4170		Z-Di	=1N4158: 22V	31a	DO-29	Z-Diode 22V	31a	
1 N 4171		Z-Di	=1N4158: 24V	31a	DO-29	Z-Diode 24V	31a	
1 N 4172		Z-Di	=1N4158: 27V	31a	DO-29	Z-Diode 27V	31a	
1 N 4173		Z-Di	=1N4158: 30V	31a	DO-29	Z-Diode 30V	31a	
1 N 4174		Z-Di	=1N4158: 33V	31a	DO-29	Z-Diode 33V	31a	
1 N 4175		Z-Di	=1N4158: 36V	31a	DO-29	Z-Diode 36V	31a	
1 N 4176		Z-Di	=1N4158: 39V	31a	DO-29	Z-Diode 39V	31a	
1 N 4177		Z-Di	=1N4158: 43V	31a	DO-29	Z-Diode 43V	31a	
1 N 4178		Z-Di	=1N4158: 47V	31a	DO-29	Z-Diode 47V	31a	
1 N 4179		Z-Di	=1N4158: 51V	31a	DO-29	Z-Diode 51V	31a	
1 N 4180		Z-Di	=1N4158: 56V	31a	DO-29	Z-Diode 56V	31a	
1 N 4181		Z-Di	=1N4158: 62V	31a	DO-29	Z-Diode 62V	31a	
1 N 4182		Z-Di	=1N4158: 68V	31a	DO-29	Z-Diode 68V	31a	
1 N 4183		Z-Di	=1N4158: 75V	31a	DO-29	Z-Diode 75V	31a	
1 N 4184		Z-Di	=1N4158: 82V	31a	DO-29	Z-Diode 82V	31a	
1 N 4185		Z-Di	=1N4158: 91V	31a	DO-29	Z-Diode 91V	31a	
1 N 4186		Z-Di	=1N4158: 100V	31a	DO-29	Z-Diode 100V	31a	
1 N 4187		Z-Di	=1N4158: 110V	31a	DO-29	Z-Diode 110V	31a	
1 N 4188		Z-Di	=1N4158: 120V	31a	DO-29	Z-Diode 120V	31a	
1 N 4189		Z-Di	=1N4158: 130V	31a	DO-29	Z-Diode 130V	31a	

Original	Fabric.	Constr.	Info	{ Compl. Fig.	JAEGER	Fig.	International	
1 N 4190		Z-Di	=1N4158: 150V	31a	DO-29	Z-Diode 150V	31a	
1 N 4191		Z-Di	=1N4158: 160V	31a	DO-29	Z-Diode 160V	31a	
1 N 4192		Z-Di	=1N4158: 180V	31a	DO-29	Z-Diode 180V	31a	
1 N 4193		Z-Di	=1N4158: 200V	31a	DO-29	Z-Diode 200V	31a	
1 N 4158A....4193A		Z-Di	=1N4158...4193: 10%	31a	DO-29	Z-Diode C200	31a	
1 N 4158B....4193B		Z-Di	=1N4158...4193: 5%	31a	DO-29			
1 N 4194	Nae	Z-Di	6.8V, 20%, 10W	32a	DO-4		BZX98/..., BZY93/..., ZX..., 1N2970...3015	
1 N 4195		Z-Di	=1N4194: 7.5V	32a	DO-4			
1 N 4196		Z-Di	=1N4194: 8.2V	32a	DO-4			
1 N 4197		Z-Di	=1N4194: 9.1V	32a	DO-4			
1 N 4198		Z-Di	=1N4194: 10V	32a	DO-4			
1 N 4199		Z-Di	=1N4194: 11V	32a	DO-4			
1 N 4200		Z-Di	=1N4194: 12V	32a	DO-4			
1 N 4201		Z-Di	=1N4194: 13V	32a	DO-4			
1 N 4202		Z-Di	=1N4194: 14V	32a	DO-4			
1 N 4203		Z-Di	=1N4194: 15V	32a	DO-4			
1 N 4204		Z-Di	=1N4194: 16V	32a	DO-4			
1 N 4205		Z-Di	=1N4194: 17V	32a	DO-4			
1 N 4206		Z-Di	=1N4194: 18V	32a	DO-4			
1 N 4207		Z-Di	=1N4194: 19V	32a	DO-4			
1 N 4208		Z-Di	=1N4194: 20V	32a	DO-4			
1 N 4209		Z-Di	=1N4194: 22V	32a	DO-4			
1 N 4210		Z-Di	=1N4194: 24V	32a	DO-4			
1 N 4211		Z-Di	=1N4194: 25V	32a	DO-4			
1 N 4212		Z-Di	=1N4194: 27V	32a	DO-4			
1 N 4213		Z-Di	=1N4194: 30V	32a	DO-4			
1 N 4214		Z-Di	=1N4194: 33V	32a	DO-4			
1 N 4215		Z-Di	=1N4194: 36V	32a	DO-4			
1 N 4216		Z-Di	=1N4194: 39V	32a	DO-4			
1 N 4217		Z-Di	=1N4194: 43V	32a	DO-4			
1 N 4218		Z-Di	=1N4194: 45V	32a	DO-4			
1 N 4219		Z-Di	=1N4194: 47V	32a	DO-4			
1 N 4220		Z-Di	=1N4194: 50V	32a	DO-4			
1 N 4221		Z-Di	=1N4194: 51V	32a	DO-4			
1 N 4222		Z-Di	=1N4194: 52V	32a	DO-4			
1 N 4223		Z-Di	=1N4194: 56V	32a	DO-4			
1 N 4224		Z-Di	=1N4194: 62V	32a	DO-4			
1 N 4225		Z-Di	=1N4194: 68V	32a	DO-4			
1 N 4226		Z-Di	=1N4194: 75V	32a	DO-4			
1 N 4227		Z-Di	=1N4194: 82V	32a	DO-4			
1 N 4228		Z-Di	=1N4194: 91V	32a	DO-4			
1 N 4229		Z-Di	=1N4194: 100V	32a	DO-4			
1 N 4230		Z-Di	=1N4194: 105V	32a	DO-4			
1 N 4231		Z-Di	=1N4194: 110V	32a	DO-4			
1 N 4232		Z-Di	=1N4194: 120V	32a	DO-4			
1 N 4233		Z-Di	=1N4194: 130V	32a	DO-4			
1 N 4234		Z-Di	=1N4194: 140V	32a	DO-4			
1 N 4235		Z-Di	=1N4194: 150V	32a	DO-4			
1 N 4236		Z-Di	=1N4194: 160V	32a	DO-4			
1 N 4237		Z-Di	=1N4194: 175V	32a	DO-4			
1 N 4238		Z-Di	=1N4194: 180V	32a	DO-4			
1 N 4239		Z-Di	=1N4194: 200V	32a	DO-4			
1 N 4194A....4239A		Z-Di	=1N4194...4239: 10%	32a	DO-4			
1 N 4194B....4239B		Z-Di	=1N4194...4239: 5%	32a	DO-4			
1 N 4240	Idc,Sie	Z-Di	5V, 2%, 10W(Tc=25°)	32	DO-4		BZX 98/5V1, BZY 93/C5V1, ZX 5.1	
1 N 4241	Idc,Sie	Z-Di	6V, 2%, 10W	32	DO-4		BZX 98/C6V2, BZY 93/C6V2, ZX 6.2	
1 N 4242	USA	Si-Di	2x SS, 40V, <2ns	42			-	
1 N 4243	USA	Si-Di	4x SS, 40V, <2ns				-	
1 N 4244	USA,Tho	Si-Di	SS, 10V, 0.05A, <0.75ns	31a	DO-7		BAY 82, 1N4376	
1 N 4245(GP)	USA,Sie	Si-Di	Rr, Uni, 200V, 1A, Uf<1.2V(1A), <5µs,	IGP: SOD-22 31a	SOD-57	1N4007	31a	BY 126...127, BY 133...134, 1N4003...07, ++
1 N 4246(GP)		Si-Di	=1N4245: 400V	31a	SOD-57	1N4007	31a	BY 126...127, BY 133...134, 1N4004...07, ++
1 N 4247(GP)		Si-Di	=1N4245: 600V	31a	SOD-57	1N4007	31a	BY 126...127, BY 133...134, 1N4005...07, ++
1 N 4248(GP)		Si-Di	=1N4245: 800V	31a	SOD-57	1N4007	31a	BY 127, BY 133, BY 227, 1N4006...07, ++
1 N 4249(GP)		Si-Di	=1N4245: 1000V	31a	SOD-57	1N4007	31a	BY 127, BY 133, BY 227, 1N4007, ++
1 N 4250	USA	Si-Di	Rr, 800V, 0.5A, Uf<1.7V(0.5A)	31a	DO-14			BY 127, BY 133, BY 227, 1N4006...07, ++
1 N 4251		Si-Di	=1N4250: 1000V	31a	DO-14			BY 127, BY 133, BY 227, 1N4007, ++
1 N 4252		Si-Di	=1N4250: 1200V	31a	DO-14			BY 127, BY 133, BY 227, BY 268, GP 100++
1 N 4253		Si-Di	=1N4250: 1500V	31a	DO-14			BY 269, DM 513, EM 516, GP 10W, ++
1 N 4254	USA	Si-Di	Rr, 1500V, 0.25A, Uf<3.5V(0.1A)	31a	DO-14			BAY 91, BY 203/16, GP 02-20, SHG 1.5, ++
1 N 4255		Si-Di	=1N4254: 2000V	31a	DO-14			BAY 91, BY 203/20, GP 02-20, SHG 2, ++
1 N 4256		Si-Di	=1N4254: 2500V	31a	DO-14			GP 02-30, MR 250-3, SHG 2.5
1 N 4257		Si-Di	=1N4254: 3000V	31a	DO-14			GP 02-30, MR 250-3, SHG 2.5
1 N 4258	Nae	Z-Di	6.8V, 20%, 10W	21	TO-64			(BZX98/..., BZY93/..., ZX..., 1N2970...3015) ⁴
1 N 4259		Z-Di	=1N4258: 7.5V	21	TO-64			
1 N 4260		Z-Di	=1N4258: 8.2V	21	TO-64			
1 N 4261		Z-Di	=1N4258: 9.1V	21	TO-64			
1 N 4262		Z-Di	=1N4258: 10V	21	TO-64			
1 N 4263		Z-Di	=1N4258: 11V	21	TO-64			
1 N 4264		Z-Di	=1N4258: 12V	21	TO-64			
1 N 4265		Z-Di	=1N4258: 13V	21	TO-64			
1 N 4266		Z-Di	=1N4258: 15V	21	TO-64			
1 N 4267		Z-Di	=1N4258: 16V	21	TO-64			
1 N 4268		Z-Di	=1N4258: 18V	21	TO-64			
1 N 4269		Z-Di	=1N4258: 20V	21	TO-64			
1 N 4270		Z-Di	=1N4258: 22V	21	TO-64			
1 N 4271		Z-Di	=1N4258: 24V	21	TO-64			
1 N 4272		Z-Di	=1N4258: 27V	21	TO-64			
1 N 4273		Z-Di	=1N4258: 30V	21	TO-64			
1 N 4274		Z-Di	=1N4258: 33V	21	TO-64			
1 N 4275		Z-Di	=1N4258: 36V	21	TO-64			
1 N 4276		Z-Di	=1N4258: 39V	21	TO-64			
1 N 4277		Z-Di	=1N4258: 43V	21	TO-64			
1 N 4278		Z-Di	=1N4258: 47V	21	TO-64			

Original	Fabric.	Constr.	Info	(Compl. Fig.	JAEGER	Fig.	International
1 N 4279		Z-Di	=1N4258: 51V	21		TO-64	
1 N 4280		Z-Di	=1N4258: 56V	21		TO-64	
1 N 4281		Z-Di	=1N4258: 62V	21		TO-64	
1 N 4282		Z-Di	=1N4258: 68V	21		TO-64	
1 N 4283		Z-Di	=1N4258: 75V	21		TO-64	
1 N 4284		Z-Di	=1N4258: 82V	21		TO-64	
1 N 4285		Z-Di	=1N4258: 91V	21		TO-64	
1 N 4286		Z-Di	=1N4258: 100V	21		TO-64	
1 N 4287		Z-Di	=1N4258: 110V	21		TO-64	
1 N 4288		Z-Di	=1N4258: 120V	21		TO-64	
1 N 4289		Z-Di	=1N4258: 130V	21		TO-64	
1 N 4290		Z-Di	=1N4258: 150V	21		TO-64	
1 N 4291		Z-Di	=1N4258: 160V	21		TO-64	
1 N 4292		Z-Di	=1N4258: 180V	21		TO-64	
1 N 4293		Z-Di	=1N4258: 200V	21		TO-64	
1 N 4258A...4293A		Z-Di	=1N4258...4293: 10%	21		TO-64	
1 N 4258B...4293B		Z-Di	=1N4258...4293: 5%	21		TO-64	
1 N 4294	USA	Si-Di	UHF, S-Band Mx	Koax		DO-22	-
1 N 4295(A)	USA	Ref-Di	10V(10mA), 2%(A=1%), ±0,012%/°C, <20Ω, 0,4W	31a		DO-7	-
1 N 4296(A)	USA	Ref-Di	10V(20mA), 2%(A=1%), ±0,012%/°C, <10Ω, 1W	34a		DO-13	-
1 N 4297(A,B)	USA	Ref-Di	8,8V(200mA), 5%, ±0,01%/°C, <1,4Ω, 10W(Tc=25°) 0...+75°, A: -55...+100°, B: -55...+150°	32		DO-4	-
1 N 4298(A,B)		Ref-Di	=1N4297: ±0,005%/°C	32		DO-4	-
1 N 4299(A,B)		Ref-Di	=1N4297: 11,3V(150mA), <1,6Ω	32		DO-4	-
1 N 4300(A,B)		Ref-Di	=1N4299: ±0,005%/°C	32		DO-4	-
1 N 4301(A,B)		Ref-Di	=1N4297: 8,8V(1A), <0,6Ω, 50W(Tc=25°)	32		DO-5	-
1 N 4302(A,B)		Ref-Di	=1N4301: ±0,005%/°C	32		DO-5	-
1 N 4303(A,B)		Ref-Di	=1N4297: 11,3V(750mA), <0,8Ω, 50W(Tc=25°)	32		DO-5	-
1 N 4304(A,B)		Ref-Di	=1N4303: ±0,005%/°C	32		DO-5	-
1 N 4305	USA,Hit,Tho	Si-Di	SS, 50/75V, 0,1/0,4A, Uf<0,85V(10mA), <4ns	31a		DO-35	BAW 62, BAW 76, BAX 95, 1N4148...49, ++
1 N 4306	USA	Si-Di	2x SS, 75V, 0,2A, <4ns	42			-
1 N 4307	USA	Si-Di	4x SS, 75V, 0,2A, <4ns				-
1 N 4308	USA,Tho	Si-Di	SS, 100V, <2ns	31a		DO-7	BAW 62, BAW 76, BAX 95, 1N4148...49, ++
1 N 4309	USA,Tho	Si-Di	SS, 50V, <2ns	31a		DO-7	(BAW 24...27)
1 N 4310	USA,Tho	Si-Di	SS, 75V, <2ns	31a		DO-7	(BAW 26...27)
1 N 4311	USA,Tho	Si-Di	SS, 100V, <2ns	31a		DO-7	(BAV 14)
1 N 4312	USA,Tho	Si-Di	SS, 150V, <2ns	31a		DO-7	(BAV 14)
1 N 4313	USA,Tho	Si-Di	SS, 100V, <2ns	31a		DO-7	BAW 62, BAW 76, BAX 95, 1N4148...49, ++
1 N 4314		Si-Di	=1N4308: Min	31a		-DO-18	-1N4308
1 N 4315		Si-Di	=1N4309: Min	31a		-DO-18	-1N4309
1 N 4316		Si-Di	=1N4310: Min	31a		-DO-18	-1N4310
1 N 4317		Si-Di	=1N4311: Min	31a		-DO-18	-1N4311
1 N 4318		Si-Di	=1N4312: Min	31a		-DO-18	-1N4312
1 N 4319		Si-Di	=1N4313: Min	31a		-DO-18	-1N4313
1 N 4320	USA	Si-Di					
1 N 4321	USA	Z-Di	50V, 10%, 3W	31a		DO-35	BZT03/C51, BZV40/C51, BZV48/C51
1 N 4322	USA	Si-Di	SS, 75V, <6ns	31a		DO-7	BAW 62, BAW 76, BAX 95, 1N4148...49, ++
1 N 4323	USA	Z-Di	6,8V, 20%, 1W	31a		DO-7	BZW22/..., BZX61/..., ZPY..., 1N5921...56, ++
1 N 4324		Z-Di	=1N4323: 7,5V	31a		DO-7	
1 N 4325		Z-Di	=1N4323: 8,2V	31a		DO-7	
1 N 4326		Z-Di	=1N4323: 9,1V	31a		DO-7	
1 N 4327		Z-Di	=1N4323: 10V	31a		DO-7	
1 N 4328		Z-Di	=1N4323: 11V	31a		DO-7	
1 N 4329		Z-Di	=1N4323: 12V	31a		DO-7	
1 N 4330		Z-Di	=1N4323: 13V	31a		DO-7	
1 N 4331		Z-Di	=1N4323: 15V	31a		DO-7	
1 N 4332		Z-Di	=1N4323: 16V	31a		DO-7	
1 N 4333		Z-Di	=1N4323: 18V	31a		DO-7	
1 N 4334		Z-Di	=1N4323: 20V	31a		DO-7	
1 N 4335		Z-Di	=1N4323: 22V	31a		DO-7	
1 N 4336		Z-Di	=1N4323: 24V	31a		DO-7	
1 N 4337		Z-Di	=1N4323: 27V	31a		DO-7	
1 N 4338		Z-Di	=1N4323: 30V	31a		DO-7	
1 N 4339		Z-Di	=1N4323: 33V	31a		DO-7	
1 N 4340		Z-Di	=1N4323: 36V	31a		DO-7	
1 N 4341		Z-Di	=1N4323: 39V	31a		DO-7	
1 N 4342		Z-Di	=1N4323: 43V	31a		DO-7	
1 N 4343		Z-Di	=1N4323: 47V	31a		DO-7	
1 N 4344		Z-Di	=1N4323: 51V	31a		DO-7	
1 N 4345		Z-Di	=1N4323: 56V	31a		DO-7	
1 N 4346		Z-Di	=1N4323: 62V	31a		DO-7	
1 N 4347		Z-Di	=1N4323: 68V	31a		DO-7	
1 N 4348		Z-Di	=1N4323: 75V	31a		DO-7	
1 N 4349		Z-Di	=1N4323: 82V	31a		DO-7	
1 N 4350		Z-Di	=1N4323: 91V	31a		DO-7	
1 N 4351		Z-Di	=1N4323: 100V	31a		DO-7	
1 N 4352		Z-Di	=1N4323: 110V	31a		DO-7	
1 N 4353		Z-Di	=1N4323: 120V	31a		DO-7	
1 N 4354		Z-Di	=1N4323: 130V	31a		DO-7	
1 N 4355		Z-Di	=1N4323: 150V	31a		DO-7	
1 N 4356		Z-Di	=1N4323: 160V	31a		DO-7	
1 N 4357		Z-Di	=1N4323: 180V	31a		DO-7	
1 N 4358		Z-Di	=1N4323: 200V	31a		DO-7	
1 N 4323A...4358A		Z-Di	=1N4323...4358: 10%	31a		DO-7	
1 N 4323B...4358B		Z-Di	=1N4323...4358: 5%	31a		DO-7	
1 N 4359	Sol	Si-Di	Rauschdiode/White Noise Diode, 200V, 0,6W	31a		DO-27	-
1 N 4360	USA,Sie	Z-Di	2,4V, 5%, 0,25W	31a		DO-7	BZX55/C2V4, BZX79/C2V4, 1N5221, ++
1 N 4361	USA	Si-Di	Rr, 900V, 0,5A, Uf<1,3V(0,5A)	31a		DO-27	BY 127, BY 133, BY 227, 1N4007, ++
1 N 4362	USA	Si-St	0,4W, Uf=0,65V(1mA), <40Ω	31a		DO-7	BA220, BZ102/0V7, BZX55/C0V8, ZPD1, ++
1 N 4363	USA	Si-Di	S, 120V, 0,1A, Uf<1V(0,2A), <40ns	31a		DO-7	BA 197...198, BAV 19...21, 1N3070, ++
1 N 4364	USA,Tix	Si-Di	Rr, 100V, 0,75A, Uf<1,1V(0,75A)	34a		DO-1	BY 126...127, BY 133...135, 1N4002...07, ++
1 N 4365		Si-Di	=1N4364: 200V	34a		DO-1	BY 126...127, BY 133...134, 1N4003...07, ++
1 N 4366		Si-Di	=1N4364: 300V	34a		DO-1	BY 126...127, BY 133...134, 1N4004...07, ++

Original	Fabric.	Constr.	Info	(Compl. Fig.	JAEGER	Fig.	International	
1 N 4367		Si-Di	=1N4364: 400V	34a	DO-1		BY 126...127, BY 133...134, 1N4004...07, ++	
1 N 4368		Si-Di	=1N4364: 500V	34a	DO-1		BY 126...127, BY 133...134, 1N4005...07, ++	
1 N 4369		Si-Di	=1N4364: 600V	34a	DO-1		BY 126...127, BY 133...134, 1N4005...07, ++	
1 N 4364R...4369R		Si-Di	=1N4364...4369:	34b	DO-1		-1N4364...4369	
1 N 4370	USA, Sie, Tho	Z-Di	2,4V, 10%, 0,4W	31a	DO-7		BZX55/... BZX79/... ZPD..., 1N5221...25	
1 N 4371		Z-Di	=1N4370: 2,7V	31a	DO-7			
1 N 4372		Z-Di	=1N4370: 3V	31a	DO-7			
1 N 4370A...4372A		Z-Di	=1N4370...4372: 5%	31a	DO-7			
1 N 4373		Si-Di	SS, 80V, 4ns				BAW 62, BAW 76, BAX 95, 1N4148...49, ++	
1 N 4374	Scn	Si-Di	Rr, 1500V, 0,75A	34a	DO-1		BY 269, BY 350/1500, DM 513, GP 10W, ++	
1 N 4375	Idc, Spe	Si-Di	SS, 60V, <6ns	31a	-DO-41		BA 218, BAX 13, BAX 91, 1N4148...49, ++	
1 N 4376	USA	Si-Di	SS, 10V, 0,05A, <6ns	31a	DO-7		BAY 82, 1N4244	
1 N 4377	Scn, Sem	Si-Di	kV-Rr, 2,5kV, 0,75A				-	
1 N 4378		Opto						
1 N 4379	Miv, Slid	Si-Di	UHF, S-Band-Dem	31a	DO-7		-	
1 N 4380	USA	Si-Di	SS, 50V, 0,05A, <1,8ns	31a	DO-7		-	
1 N 4381	USA	Ge-Di	S, 25V, <100ns	31a	DO-7		AAY 27, AAZ 18, 1N3592	
1 N 4382	Msc	Si-Di	SS, 55V, <5,5ns	31a	-DO-35		BAW 76	
1 N 4383(GP)	USA, Gie, Tho	Si-Di	Rr, 200V, 1A, Uf<1,1V(1A), 2μs,	(GP: DO-15) 31a	DO-29	BY 133	31a	BY 126...127, BY 133...134, 1N4003...07, ++
1 N 4384(GP)		Si-Di	=1N4383: 400V	31a	DO-29	BY 133	31a	BY 126...127, BY 133...134, 1N4004...07, ++
1 N 4385(GP)		Si-Di	=1N4383: 600V	31a	DO-29	BY 133	31a	BY 126...127, BY 133...134, 1N4003...07, ++
1 N 4386	Pai	Si-Di	UHF Multiplier, PQ>32,5W(150MHz)	32a	DO-4		-	
1 N 4387	Mot, Pai	Si-Di	UHF Multiplier, PQ>15W(450MHz)	32a	DO-4		-	
1 N 4388	Mot, Pai	Si-Di	UHF Multiplier, PQ>11W(1000MHz)	32a	DO-4		-	
1 N 4389	Idc	Si-Di	Uni, 5V	31a	DO-7		-	
1 N 4390	USA	Si-Di	SS, 20V, <0,5ns	31a	DO-7		-	
1 N 4391	USA	Si-Di	SS, 20V, <0,5ns	31a	DO-7		-	
1 N 4392	USA	Si-Di	SS, 15V, <0,5ns	31a	DO-7		-	
1 N 4393(A,B)	Msc, Ssi	Si-Di	Tunnel-Di	34	DO-17		-	
1 N 4394(A,B)	Msc, Ssi	Si-Di	Tunnel-Di	34	DO-17		-	
1 N 4395(A,B)	Msc, Ssi	Si-Di	Tunnel-Di	34	DO-17		-	
1 N 4396(A,B)	Msc, Ssi	Si-Di	Tunnel-Di	34	DO-17		-	
1 N 4397(A,B)	Msc, Ssi	Si-Di	Tunnel-Di	34	DO-17		-	
1 N 4398(A,B)	Msc, Ssi	Si-Di	Tunnel-Di	34	DO-17		-	
1 N 4399(A,B)	Msc, Ssi	Si-Di	Tunnel-Di	34	DO-17		-	
1 N 4400	USA	Z-Di	6,8V, 20%, 1W	31a	SOD-51		BZW22/... BZX61/... ZPY..., 1N5921...56, ++	
1 N 4401		Z-Di	=1N4400: 7,5V	31a	SOD-51			
1 N 4402		Z-Di	=1N4400: 8,2V	31a	SOD-51			
1 N 4403		Z-Di	=1N4400: 9,1V	31a	SOD-51			
1 N 4404		Z-Di	=1N4400: 10V	31a	SOD-51			
1 N 4405		Z-Di	=1N4400: 11V	31a	SOD-51			
1 N 4406		Z-Di	=1N4400: 12V	31a	SOD-51			
1 N 4407		Z-Di	=1N4400: 13V	31a	SOD-51			
1 N 4408		Z-Di	=1N4400: 15V	31a	SOD-51			
1 N 4409		Z-Di	=1N4400: 16V	31a	SOD-51			
1 N 4410		Z-Di	=1N4400: 18V	31a	SOD-51			
1 N 4411		Z-Di	=1N4400: 20V	31a	SOD-51			
1 N 4412		Z-Di	=1N4400: 22V	31a	SOD-51			
1 N 4413		Z-Di	=1N4400: 24V	31a	SOD-51			
1 N 4414		Z-Di	=1N4400: 27V	31a	SOD-51			
1 N 4415		Z-Di	=1N4400: 30V	31a	SOD-51			
1 N 4416		Z-Di	=1N4400: 33V	31a	SOD-51			
1 N 4417		Z-Di	=1N4400: 36V	31a	SOD-51			
1 N 4418		Z-Di	=1N4400: 39V	31a	SOD-51			
1 N 4419		Z-Di	=1N4400: 43V	31a	SOD-51			
1 N 4420		Z-Di	=1N4400: 47V	31a	SOD-51			
1 N 4421		Z-Di	=1N4400: 51V	31a	SOD-51			
1 N 4422		Z-Di	=1N4400: 56V	31a	SOD-51			
1 N 4423		Z-Di	=1N4400: 62V	31a	SOD-51			
1 N 4424		Z-Di	=1N4400: 68V	31a	SOD-51			
1 N 4425		Z-Di	=1N4400: 75V	31a	SOD-51			
1 N 4426		Z-Di	=1N4400: 82V	31a	SOD-51			
1 N 4427		Z-Di	=1N4400: 91V	31a	SOD-51			
1 N 4428		Z-Di	=1N4400: 100V	31a	SOD-51			
1 N 4429		Z-Di	=1N4400: 110V	31a	SOD-51			
1 N 4430		Z-Di	=1N4400: 120V	31a	SOD-51			
1 N 4431		Z-Di	=1N4400: 130V	31a	SOD-51			
1 N 4432		Z-Di	=1N4400: 150V	31a	SOD-51			
1 N 4433		Z-Di	=1N4400: 160V	31a	SOD-51			
1 N 4434		Z-Di	=1N4400: 180V	31a	SOD-51			
1 N 4435		Z-Di	=1N4400: 200V	31a	SOD-51			
1 N 4400A...4435A		Z-Di	=1N4400...4435: 10%	31a	SOD-51			
1 N 4400B...4435B		Z-Di	=1N4400...4435: 5%	31a	SOD-51			
1 N 4436	old	Si-Di	P Rr, 200V, 10A(Tc=100°), Uf<1,2V(10A)				-	
1 N 4437		Si-Di	=1N4436: 400V				-	
1 N 4438		Si-Di	=1N4436: 600V				-	
1 N 4439		Si-Di	=1N4436: 800V				-	
1 N 4440		Si-Di	=1N4436: 1000V				-	
1 N 4441	old	Si-Di	FRr, 1500V, 25mA, Uf<4V(25mA), <300ns	31a	SOD-34		BY 203/16, BY 269, SHG 1,5	
1 N 4442		Si-Di	SS, 30V, 1ns	31a			BA 218, BAX 13, BAX 91, 1N4148...49, ++	
1 N 4443		Si-Di	SS, 30V, 0,6ns				BA 218, BAX 13, BAX 91, 1N4148...49, ++	
1 N 4444	USA, Tix, Tho	Si-Di	SS, 50/70V, 0,225/0,6A, Uf<1V(0,1A), <7ns	31a	DO-35		BAW 62, BAW 76, BAX 95, 1N4148...49, ++	
1 N 4445	USA, Tho	Si-Di	SS, 70/125V, Uf<0,68V(1mA), <4ns	31a	DO-35		BA 219, BAX 96	
1 N 4446	USA, EUR	Si-Di	SS, 75/100V, 0,15/0,45A, Uf<1V(20mA), <4ns, <4pF	31a	DO-35	1N4148	31a	BAW 62, BAX 95, 1N4148...49, 1N4151, ++
1 N 4447		Si-Di	=1N4446: <2pF(0V)	31a	DO-35	1N4148	31a	BAW 62, BAX 95, 1N4148...49, 1N4151, ++
1 N 4448		Si-Di	=1N4446: Uf<1V(100mA)	31a	DO-35	1N4148	31a	BAW 62, BAX 95, 1N4148...49, 1N4151, ++
1 N 4449		Si-Di	=1N4446: Uf<1V(30mA), <2pF(0V)	31a	DO-35	1N4148	31a	BAW 62, BAX 95, 1N4148...49, 1N4151, ++
1 N 4450	USA, EUR, Hit	Si-Di	SS, 30V, 0,2/0,6A, Uf<1V(0,2A), <4ns	31a	DO-35	1N4148	31a	BA 221, BAY 74, 1N4148...49, 1N4154, ++
1 N 4451	USA, EUR	Si-Di	SS, 30V, 0,2/0,6A, Uf<1V(0,3A), <10ns	31a	DO-35	1N4148	31a	BA 221, BAY 74, 1N4148...49, 1N4154, ++
1 N 4452	USA	Si-Di	S, 30/40V, Uf<1V(0,6A), <20ns	31a			BAV 15...16, BAV 44, BAW 24...27	
1 N 4453	USA	Si-St	20/30V, 0,5W, Uf<0,71V(1mA)/0,92V(100mA)	31a	DO-7/DO-35		BA220, BZ102/0V7, BZX55/COV8, ZPD1, ++	
1 N 4454	USA, EUR, Hit	Si-Di	SS, 50V, 0,15/0,45A, Uf<1V(10mA), <10ns	31a	DO-35	1N4148	31a	BAW 62, BAX 95, 1N4148...49, 1N4151, ++
1 N 4455	Gen, Tix, Uni	Si-Di	Uni, 50V, 0,52V(0,1mA)	31a	DO-6		BA 128, BA 147/50, BA 222, 1N5194, ++	

Original	Fabric.	Constr.	Info	{Compl. Fig.	JAEGER	Fig.	International
1 N 4456	Idc,Sem	Si-Di	SS, 30/35V, Uf<1V(0,15A), <1,5ns	31a	DO-7	-	-
1 N 4457	Idc,Sem	Si-Di	SS, 40/50V, Uf<1V(0,2A), <1,5ns	31a	DO-7	-	-
1 N 4458	USA	Si-Di	P Rr, 800V, 5A(Tc=150°), Uf<1,5V(5A, 150°)	32a	DO-4	-	BYX 38/900, BYX 39/800
1 N 4459		Si-Di	=1N4458: 1000V	32a	DO-4	-	BYX 38/1200, BYX 39/1000
1 N 4458R...4459R		Si-Di	=1N4458...4459:	32b	DO-4	-	BYX 38/...R, BYX 39/...R
1 N 4460	USA	Z-Di	6,2V, 5%, 1,5W	31a	SOD-17	-	BZV47/..., BZY97/..., ZY..., 1N5920...56,++
1 N 4461		Z-Di	=1N4460: 6,8V	31a	SOD-17	-	-
1 N 4462		Z-Di	=1N4460: 7,5V	31a	SOD-17	-	-
1 N 4463		Z-Di	=1N4460: 8,2V	31a	SOD-17	-	-
1 N 4464		Z-Di	=1N4460: 9,1V	31a	SOD-17	-	-
1 N 4465		Z-Di	=1N4460: 10V	31a	SOD-17	-	-
1 N 4466		Z-Di	=1N4460: 11V	31a	SOD-17	-	-
1 N 4467		Z-Di	=1N4460: 12V	31a	SOD-17	-	-
1 N 4468		Z-Di	=1N4460: 13V	31a	SOD-17	-	-
1 N 4469		Z-Di	=1N4460: 15V	31a	SOD-17	-	-
1 N 4470		Z-Di	=1N4460: 16V	31a	SOD-17	-	-
1 N 4471		Z-Di	=1N4460: 18V	31a	SOD-17	-	-
1 N 4472		Z-Di	=1N4460: 20V	31a	SOD-17	-	-
1 N 4473		Z-Di	=1N4460: 22V	31a	SOD-17	-	-
1 N 4474		Z-Di	=1N4460: 24V	31a	SOD-17	-	-
1 N 4475		Z-Di	=1N4460: 27V	31a	SOD-17	-	-
1 N 4476		Z-Di	=1N4460: 30V	31a	SOD-17	-	-
1 N 4477		Z-Di	=1N4460: 33V	31a	SOD-17	-	-
1 N 4478		Z-Di	=1N4460: 36V	31a	SOD-17	-	-
1 N 4479		Z-Di	=1N4460: 39V	31a	SOD-17	-	-
1 N 4480		Z-Di	=1N4460: 43V	31a	SOD-17	-	-
1 N 4481		Z-Di	=1N4460: 47V	31a	SOD-17	-	-
1 N 4482		Z-Di	=1N4460: 51V	31a	SOD-17	-	-
1 N 4483		Z-Di	=1N4460: 56V	31a	SOD-17	-	-
1 N 4484		Z-Di	=1N4460: 62V	31a	SOD-17	-	-
1 N 4485		Z-Di	=1N4460: 68V	31a	SOD-17	-	-
1 N 4486		Z-Di	=1N4460: 75V	31a	SOD-17	-	-
1 N 4487		Z-Di	=1N4460: 82V	31a	SOD-17	-	-
1 N 4488		Z-Di	=1N4460: 91V	31a	SOD-17	-	-
1 N 4489		Z-Di	=1N4460: 100V	31a	SOD-17	-	-
1 N 4490		Z-Di	=1N4460: 110V	31a	SOD-17	-	-
1 N 4491		Z-Di	=1N4460: 120V	31a	SOD-17	-	-
1 N 4492		Z-Di	=1N4460: 130V	31a	SOD-17	-	-
1 N 4493		Z-Di	=1N4460: 150V	31a	SOD-17	-	-
1 N 4494		Z-Di	=1N4460: 160V	31a	SOD-17	-	-
1 N 4495		Z-Di	=1N4460: 180V	31a	SOD-17	-	-
1 N 4496		Z-Di	=1N4460: 200V	31a	SOD-17	-	-
1 N 4497	Sem,Ssi	Si-Di	kV-Rr, 1,6kV, 0,75A			-	-
1 N 4498		Si-Di	=1N4497: 3kV			-	-
1 N 4499	Idc,Sem	Z-Di	6,2V, 5%, 1W	31a	DO-7	-	BZV22/C6V2, BZX61/C6V2, ZPY6,2, 1N5920++
1 N 4500	USA	Si-Di	SS, 80V, <4ns	31a	DO-7	-	BAW 62, BAX 95, 1N4148...49, 1N4151, ++
1 N 4501	Idc,Msc	Ref-Di	7V(10mA), 5%, ±0,01%/°C, <10Ω, 0,21W	31a	(18x8mm0)	-	-
1 N 4502	Idc,Sem	Ge-Di	Uni, 20V	31a	DO-7	-	AA 117...119, AA 132...134, 1N34, 1N54, ++
1 N 4503	Msc,Trw	Z-Di	33V, 10%, 3W	31a	SOD-51	-	BZT 03/C,D33
1 N 4504	Msc,Trw	Z-Di	200V, 10%, 3W	31a	SOD-51	-	BZT 03/C,D200
1 N 4505	USA	Si-Di	kV-Rr, 6kV, 0,1A	31a	DO-4	-	BYX 90, 1N5183
1 N 4506	USA	Si-Di	P Rr, contr.av., 200V, 12A(Tc=135°), Uf<1,4V(12A)	32a	DO-4	-	BYX 25/600
1 N 4507		Si-Di	=1N4506: 400V	32a	DO-4	-	BYX 25/600
1 N 4508		Si-Di	=1N4506: 600V	32a	DO-4	-	BYX 25/600
1 N 4509		Si-Di	=1N4506: 800V	32a	DO-4	-	BYX 25/800
1 N 4510		Si-Di	=1N4506: 1000V	32a	DO-4	-	BYX 25/1000
1 N 4511		Si-Di	=1N4506: 1200V	32a	DO-4	-	BYX 25/1200
1 N 4512	Ssi	Si-Di	Uni, 10V	12a		-	BA 128, BA 147/25, BA 222, 1N5194, ++
1 N 4513	USA	Si-Di	Rr, 2000V, 0,25A	31a	DO-27	-	BAY 91, BY 203/20, HVG 2, SHG 2, ++
1 N 4514	USA	Si-Di	Rr, 800V, 1,1A	31a	DO-27	-	BY 127, BY 133, BY 227, 1N4006...07, ++
1 N 4517	USA	Si-Di	Rr, 200V, 2A	31a	DO-27	-	BY 251...255, BY 259/300, 1N5060...62, ++
1 N 4523	USA	Ge-Di	SS, 15V, <8ns	31a	DO-7	-	AA 21
1 N 4524	USA	Ge-Di	SS, 10V, <3ns	31a	DO-7	-	1N995
1 N 4525	USA	Si-Di	P Rr, contr.av., 200V, 35A(Tc=115°), Uf<1,4V(35A)	32a	DO-5	-	BYX 56/600
1 N 4526		Si-Di	=1N4525: 400V	32a	DO-5	-	BYX 56/600
1 N 4527		Si-Di	=1N4525: 600V	32a	DO-5	-	BYX 56/600
1 N 4528		Si-Di	=1N4525: 800V	32a	DO-5	-	BYX 56/800
1 N 4529		Si-Di	=1N4525: 1000V	32a	DO-5	-	BYX 56/1000
1 N 4530		Si-Di	=1N4525: 1200V	32a	DO-5	-	BYX 56/1200
1 N 4531	USA,Phi,Tho	Si-Di	SS, 75/75V, 0,15/0,45A, Uf<1V(10mA), <4ns	31a	DO-34	1N4148	31a BAW 62, BAX 95, 1N4148...49, 1N4151, ++
1 N 4532	USA,Phi,Tho	Si-Di	SS, 75/75V, 0,15/0,45A, Uf<1V(10mA), <2ns	31a	DO-34	1N4148	31a BAW 62, BAX 95, 1N4148...49, 1N4151, ++
1 N 4533	USA,Phi,Tho	Si-Di	SS, 40/40V, 75/225mA, Uf<0,81V(10mA), <2ns	31a	DO-34	1N4148	31a BAW 62, BAX 95, 1N4148...49, 1N4151, ++
1 N 4534	USA,Phi,Tho	Si-Di	SS, 75V, 75/225mA, Uf<0,81V(10mA), <2ns	31a	DO-34	1N4148	31a BAW 62, BAX 95, 1N4148...49, 1N4151, ++
1 N 4535	USA,Sie	Z-Di	bidirectional, 3,45V, 5%, 0,5W	31a	DO-7	-	-
1 N 4536	USA,Hit	Si-Di	SS, 25V, 0,075A, Uf<1V(30mA), <2ns	31a	DO-34	-	BA 218, BAX 13, BAX 91, 1N4148...49, ++
1 N 4537	USA	Si-Di	P Rr, 1500/1800V, 3A(Tc=100°), Uf<1,85V(3A)	32a	DO-4	-	-
1 N 4538		Si-Di	=1N4537: 2000/2400V	32a	DO-4	-	-
1 N 4539		Si-Di	=1N4537: 2500/3000V	32a	DO-4	-	-
1 N 4540		Si-Di	=1N4537: 3000/3600V	32a	DO-4	-	-
1 N 4541	Sem,Trw	Si-Di	Rr, 225V, 0,4A, Uf<1V(0,4A)	31a	DO-14	-	BA 157...159, BY 204/4, BY 206...207, ++
1 N 4542		Si-Di	=1N4541: 400V	31a	DO-14	-	BA 157...159, BY 204/4, BY 207, ++
1 N 4543		Si-Di	=1N4541: 600V	31a	DO-14	-	BA 158...159, BY 204/8, BY 207, ++
1 N 4544		Si-Di	=1N4541: 800V	31a	DO-14	-	BA 159, BY 204/8, BY 208/800, ++
1 N 4545		Si-Di	=1N4541: 1000V	31a	DO-14	-	BA 159, BY 204/10, BY 208/1000, ++
1 N 4546	Sem	Si-Di	kV-Rr, 25kV, 1A			-	-
1 N 4547	Idc,Sem	Si-Di	HFS, 25V, <60ns			-	-
1 N 4548	Idc,Sem	Si-Di	Min, SS, 25V, <2ns	31a	=DO-18	-	(BA 217, BA 317, BAY 71, 1N4148...49,++)6
1 N 4549	USA,Mot,Sie	Z-Di	3,9V, 20%, 50W(Tc=75°)	32b	DO-5	-	-
1 N 4550		Z-Di	=1N4549: 4,3V	32b	DO-5	-	-
1 N 4551		Z-Di	=1N4549: 4,7V	32b	DO-5	-	-
1 N 4552		Z-Di	=1N4549: 5,1V	32b	DO-5	-	-
1 N 4553		Z-Di	=1N4549: 5,6V	32b	DO-5	-	-
1 N 4554		Z-Di	=1N4549: 6,2V	32b	DO-5	-	-

Original	Fabric.	Constr.	Info	{Compl. Fig.	JAEGER	Fig.	International
1 N 4555		Z-Di	=1N4549: 6,8V	32b		DO-5	
1 N 4556		Z-Di	=1N4549: 7,5V	32b		DO-5	
1 N 4549A....4556A		Z-Di	=1N4549...4556: 10%	32b		DO-5	
1 N 4549B....4556B		Z-Di	=1N4549...4556: 5%	32b		DO-5	
1 N 4549R....4556R		Z-Di	=1N4549...4556:	32a		DO-5	
1 N 4557	USA,Mot,Sie	Z-Di	3,9V, 20%, 50W(Tc=75°)	23n		TO-3	
1 N 4558		Z-Di	=1N4557: 4,3V	23n		TO-3	
1 N 4559		Z-Di	=1N4557: 4,7V	23n		TO-3	
1 N 4560		Z-Di	=1N4557: 5,1V	23n		TO-3	
1 N 4561		Z-Di	=1N4557: 5,6V	23n		TO-3	
1 N 4562		Z-Di	=1N4557: 6,2V	23n		TO-3	
1 N 4563		Z-Di	=1N4557: 6,8V	23n		TO-3	
1 N 4564		Z-Di	=1N4557: 7,5V	23n		TO-3	
1 N 4557A....4564A		Z-Di	=1N4557...4564: 10%	23n		TO-3	
1 N 4557B....4564B		Z-Di	=1N4557...4564: 5%	23n		TO-3	
1 N 4557R....4564R		Z-Di	=1N4557...4564:	23f		TO-3	
1 N 4565(A,B)	USA,Sie,Tho	Ref-Di	6,4V(0,5mA), 5%, ±0,01%/°C, <200Ω, 0,4W, 0...+75° A: -55...+100°, B: -55...+150°	31a		DO-7,DO-35	BZV 10, BZV 27, BZX 90
1 N 4566(A,B)		Ref-Di	=1N4565: ±0,005%/°C	31a		DO-7,DO-35	BZV 11, BZV 28, BZX 91
1 N 4567(A,B)		Ref-Di	=1N4565: ±0,002%/°C	31a		DO-7,DO-35	BZV 12, BZV 29, BZX 92
1 N 4568(A,B)		Ref-Di	=1N4565: ±0,001%/°C	31a		DO-7,DO-35	BZV 13, BZV 30, BZX 93
1 N 4569(A,B)		Ref-Di	=1N4565: ±0,0005%/°C	31a		DO-7,DO-35	BZV 14, BZV 31, BZX 94
1 N 4570(A,B)		Ref-Di	=1N4565: 6,4V(1mA), <100Ω	31a		DO-7,DO-35	
1 N 4571(A,B)		Ref-Di	=1N4566: 6,4V(1mA), <100Ω	31a		DO-7,DO-35	
1 N 4572(A,B)		Ref-Di	=1N4567: 6,4V(1mA), <100Ω	31a		DO-7,DO-35	
1 N 4573(A,B)		Ref-Di	=1N4568: 6,4V(1mA), <100Ω	31a		DO-7,DO-35	
1 N 4574(A,B)		Ref-Di	=1N4569: 6,4V(1mA), <100Ω	31a		DO-7,DO-35	
1 N 4575(A,B)		Ref-Di	=1N4565: 6,4V(2mA), <50Ω	31a		DO-7,DO-35	
1 N 4576(A,B)		Ref-Di	=1N4566: 6,4V(2mA), <50Ω	31a		DO-7,DO-35	
1 N 4577(A,B)		Ref-Di	=1N4567: 6,4V(2mA), <50Ω	31a		DO-7,DO-35	
1 N 4578(A,B)		Ref-Di	=1N4568: 6,4V(2mA), <50Ω	31a		DO-7,DO-35	
1 N 4579(A,B)		Ref-Di	=1N4569: 6,4V(2mA), <50Ω	31a		DO-7,DO-35	
1 N 4580(A,B)		Ref-Di	=1N4565: 6,4V(4mA), <25Ω	31a		DO-7,DO-35	
1 N 4581(A,B)		Ref-Di	=1N4566: 6,4V(4mA), <25Ω	31a		DO-7,DO-35	
1 N 4582(A,B)		Ref-Di	=1N4567: 6,4V(4mA), <25Ω	31a		DO-7,DO-35	
1 N 4583(A,B)		Ref-Di	=1N4568: 6,4V(4mA), <25Ω	31a		DO-7,DO-35	
1 N 4584(A,B)		Ref-Di	=1N4569: 6,4V(4mA), <25Ω	31a		DO-7,DO-35	
1 N 4585(GP)	USA,Gie,Tho	Si-Di	Rr, 800V, 1A, Uf<1,1V(1A)	IGP: DO-15	31a	DO-29	BY 127, BY 133, BY 227, 1N4006...07, ++
1 N 4586(GP)		Si-Di	=1N4585: 1000V		31a	DO-29	BY 127, BY 133, BY 227, 1N4007, ++
1 N 4587	USA	Si-Di	P Rr, 100V, 150A(Tc=110°), Uf<1,4V(150A, 110°)		73a	DO-8	-
1 N 4588		Si-Di	=1N4587: 200V		73a	DO-8	-
1 N 4589		Si-Di	=1N4587: 300V		73a	DO-8	-
1 N 4590		Si-Di	=1N4587: 400V		73a	DO-8	-
1 N 4591		Si-Di	=1N4587: 500V		73a	DO-8	-
1 N 4592		Si-Di	=1N4587: 600V		73a	DO-8	-
1 N 4593		Si-Di	=1N4587: 800V		73a	DO-8	-
1 N 4594		Si-Di	=1N4587: 1000V		73a	DO-8	-
1 N 4595		Si-Di	=1N4587: 1200V		73a	DO-8	-
1 N 4596		Si-Di	=1N4587: 1400V		73a	DO-8	-
1 N 4587R....4596R		Si-Di	=1N4587...4596:		73b	DO-8	-
1 N 4598(A)	Tdy	Si-Di	VHF Tuning, 90V		31a	DO-7	-
1 N 4599(A)	Tdy	Si-Di	VHF Tuning, 110V		31a	DO-7	-
1 N 4600	Miv,Sld	Si-Di	UHF, M-Band Mx, 10...16GHz	Koax		DO-37	-
1 N 4601	Miv,Sld	Si-Di	UHF, M-Band Mx, 10...16GHz	Koax		DO-37	-
1 N 4602	USA	Si-Di	UHF, M-Band Mx, 10...16GHz	Koax		DO-37	-
1 N 4603	USA	Si-Di	UHF, Ku-Band Mx, 12,5...17,5GHz	Koax		DO-37	-
1 N 4604	USA	Si-Di	UHF, Ku-Band Mx, 12,5...17,5GHz	Koax		DO-37	-
1 N 4605	USA	Si-Di	UHF, Ku-Band Mx, 12,5...17,5GHz	Koax		DO-37	-
1 N 4606	USA,Tix	Si-Di	SS, 85V, 0,35A, <6ns		31a	DO-35	BAV 10, BAW 55, BAW 76, BAX 81
1 N 4607	USA,Tix	Si-Di	SS, 85V, 0,35A, <15ns		31a	DO-35	BAV 10, BAW 55, BAW 76, BAX 81
1 N 4608	USA,Tix	Si-Di	SS, 85V, 0,35A, <15ns		31a	DO-35	BAV 10, BAW 55, BAW 76, BAX 81
1 N 4609(A)	Idc,Msc	Si-Di	VHF Tuning		31a	DO-7	-
1 N 4610	USA	Si-Di	SS, 80V, <4ns		31a	DO-7	BAW 62, BAW 76, BAX 95, 1N4148...49, ++
1 N 4611(A,B,C)	USA	Ref-Di	6,6V(2mA), 5%, ±0,005%/°C, <75Ω, 0,25W A: ±0,002%/°C, B: ±0,001%/°C, C: ±0,0005%/°C		31a	DO-7	BZV 11...14, BZV 28...31, 1N4575...84, ++
1 N 4612(A,B,C)		Ref-Di	=1N4611: 6,6V(5mA), <25Ω		31a	DO-7	
1 N 4613(A,B,C)		Ref-Di	=1N4611: 6,6V(10mA), <15Ω		31a	DO-7	
1 N 4614	USA,Sie,Tho	Z-Di	In, 1,8V, 5%, 0,25W, Ur<1pV		31a	DO-7,DO-35	-
1 N 4615		Z-Di	=1N4614: 2V		31a	DO-7,DO-35	-
1 N 4616		Z-Di	=1N4614: 2,2V		31a	DO-7,DO-35	-
1 N 4617		Z-Di	=1N4614: 2,4V		31a	DO-7,DO-35	-
1 N 4618		Z-Di	=1N4614: 2,7V		31a	DO-7,DO-35	-
1 N 4619		Z-Di	=1N4614: 3V		31a	DO-7,DO-35	-
1 N 4620		Z-Di	=1N4614: 3,3V		31a	DO-7,DO-35	-
1 N 4621		Z-Di	=1N4614: 3,6V		31a	DO-7,DO-35	-
1 N 4622		Z-Di	=1N4614: 3,9V		31a	DO-7,DO-35	-
1 N 4623		Z-Di	=1N4614: 4,3V		31a	DO-7,DO-35	-
1 N 4624		Z-Di	=1N4614: 4,7V		31a	DO-7,DO-35	-
1 N 4625		Z-Di	=1N4614: 5,1V		31a	DO-7,DO-35	-
1 N 4626		Z-Di	=1N4614: 5,6V		31a	DO-7,DO-35	-
1 N 4627		Z-Di	=1N4614: 6,2V		31a	DO-7,DO-35	-
1 N 4628	USA,Sie	Z-Di	6,8V, 5%, 0,6W		31a	DO-14	BZX55/..., BZX83/..., ZPD..., 1N5235...61, ++
1 N 4629		Z-Di	=1N4628: 7,5V		31a	DO-14	
1 N 4630		Z-Di	=1N4628: 8,2V		31a	DO-14	
1 N 4631		Z-Di	=1N4628: 9,1V		31a	DO-14	
1 N 4632		Z-Di	=1N4628: 10V		31a	DO-14	
1 N 4633		Z-Di	=1N4628: 11V		31a	DO-14	
1 N 4634		Z-Di	=1N4628: 12V		31a	DO-14	
1 N 4635		Z-Di	=1N4628: 13V		31a	DO-14	
1 N 4636		Z-Di	=1N4628: 15V		31a	DO-14	
1 N 4637		Z-Di	=1N4628: 16V		31a	DO-14	
1 N 4638		Z-Di	=1N4628: 18V		31a	DO-14	
1 N 4639		Z-Di	=1N4628: 20V		31a	DO-14	

Original	Fabric.	Constr.	Info	{Compl. Fig.	JAEGER	Fig.	International
1 N 4640		Z-Di	=1N4628: 22V	31a		DO-14	
1 N 4641		Z-Di	=1N4628: 24V	31a		DO-14	
1 N 4642		Z-Di	=1N4628: 27V	31a		DO-14	
1 N 4643		Z-Di	=1N4628: 30V	31a		DO-14	
1 N 4644		Z-Di	=1N4628: 33V	31a		DO-14	
1 N 4645		Z-Di	=1N4628: 36V	31a		DO-14	
1 N 4646		Z-Di	=1N4628: 39V	31a		DO-14	
1 N 4647		Z-Di	=1N4628: 43V	31a		DO-14	
1 N 4648		Z-Di	=1N4628: 47V	31a		DO-14	
1 N 4649	USA	Z-Di	3.3V, 5%, 1W	31a		DO-15	BZW22/..., BZX61/..., ZPY..., 1N5913...41,++
1 N 4650		Z-Di	=1N4649: 3.6V	31a		DO-15	
1 N 4651		Z-Di	=1N4649: 3.9V	31a		DO-15	
1 N 4652		Z-Di	=1N4649: 4.3V	31a		DO-15	
1 N 4653		Z-Di	=1N4649: 4.7V	31a		DO-15	
1 N 4654		Z-Di	=1N4649: 5.1V	31a		DO-15	
1 N 4655		Z-Di	=1N4649: 5.6V	31a		DO-15	
1 N 4656		Z-Di	=1N4649: 6.2V	31a		DO-15	
1 N 4657		Z-Di	=1N4649: 6.8V	31a		DO-15	
1 N 4658		Z-Di	=1N4649: 7.5V	31a		DO-15	
1 N 4659		Z-Di	=1N4649: 8.2V	31a		DO-15	
1 N 4660		Z-Di	=1N4649: 9.1V	31a		DO-15	
1 N 4661		Z-Di	=1N4649: 10V	31a		DO-15	
1 N 4662		Z-Di	=1N4649: 11V	31a		DO-15	
1 N 4663		Z-Di	=1N4649: 12V	31a		DO-15	
1 N 4664		Z-Di	=1N4649: 13V	31a		DO-15	
1 N 4665		Z-Di	=1N4649: 15V	31a		DO-15	
1 N 4666		Z-Di	=1N4649: 16V	31a		DO-15	
1 N 4667		Z-Di	=1N4649: 18V	31a		DO-15	
1 N 4668		Z-Di	=1N4649: 20V	31a		DO-15	
1 N 4669		Z-Di	=1N4649: 22V	31a		DO-15	
1 N 4670		Z-Di	=1N4649: 24V	31a		DO-15	
1 N 4671		Z-Di	=1N4649: 27V	31a		DO-15	
1 N 4672		Z-Di	=1N4649: 30V	31a		DO-15	
1 N 4673		Z-Di	=1N4649: 33V	31a		DO-15	
1 N 4674		Z-Di	=1N4649: 36V	31a		DO-15	
1 N 4675		Z-Di	=1N4649: 39V	31a		DO-15	
1 N 4676		Z-Di	=1N4649: 43V	31a		DO-15	
1 N 4677		Z-Di	=1N4649: 47V	31a		DO-15	
1 N 4678	USA, Mot, Sie	Z-Di	1.8V, 5%, 0.25W	31a		DO-7	BZX79/..., BZX55/..., ZPD..., 1N5221...60,++
1 N 4679		Z-Di	=1N4678: 2V	31a		DO-7	
1 N 4680		Z-Di	=1N4678: 2.2V	31a		DO-7	
1 N 4681		Z-Di	=1N4678: 2.4V	31a		DO-7	
1 N 4682		Z-Di	=1N4678: 2.7V	31a		DO-7	
1 N 4683		Z-Di	=1N4678: 3V	31a		DO-7	
1 N 4684		Z-Di	=1N4678: 3.3V	31a		DO-7	
1 N 4685		Z-Di	=1N4678: 3.6V	31a		DO-7	
1 N 4686		Z-Di	=1N4678: 3.9V	31a		DO-7	
1 N 4687		Z-Di	=1N4678: 4.3V	31a		DO-7	
1 N 4688		Z-Di	=1N4678: 4.7V	31a		DO-7	
1 N 4689		Z-Di	=1N4678: 5.1V	31a		DO-7	
1 N 4690		Z-Di	=1N4678: 5.6V	31a		DO-7	
1 N 4691		Z-Di	=1N4678: 6.2V	31a		DO-7	
1 N 4692		Z-Di	=1N4678: 6.8V	31a		DO-7	
1 N 4693		Z-Di	=1N4678: 7.5V	31a		DO-7	
1 N 4694		Z-Di	=1N4678: 8.2V	31a		DO-7	
1 N 4695		Z-Di	=1N4678: 8.7V	31a		DO-7	
1 N 4696		Z-Di	=1N4678: 9.1V	31a		DO-7	
1 N 4697		Z-Di	=1N4678: 10V	31a		DO-7	
1 N 4698		Z-Di	=1N4678: 11V	31a		DO-7	
1 N 4699		Z-Di	=1N4678: 12V	31a		DO-7	
1 N 4700		Z-Di	=1N4678: 13V	31a		DO-7	
1 N 4701		Z-Di	=1N4678: 14V	31a		DO-7	
1 N 4702		Z-Di	=1N4678: 15V	31a		DO-7	
1 N 4703		Z-Di	=1N4678: 16V	31a		DO-7	
1 N 4704		Z-Di	=1N4678: 17V	31a		DO-7	
1 N 4705		Z-Di	=1N4678: 18V	31a		DO-7	
1 N 4706		Z-Di	=1N4678: 19V	31a		DO-7	
1 N 4707		Z-Di	=1N4678: 20V	31a		DO-7	
1 N 4708		Z-Di	=1N4678: 22V	31a		DO-7	
1 N 4709		Z-Di	=1N4678: 24V	31a		DO-7	
1 N 4710		Z-Di	=1N4678: 25V	31a		DO-7	
1 N 4711		Z-Di	=1N4678: 27V	31a		DO-7	
1 N 4712		Z-Di	=1N4678: 28V	31a		DO-7	
1 N 4713		Z-Di	=1N4678: 30V	31a		DO-7	
1 N 4714		Z-Di	=1N4678: 33V	31a		DO-7	
1 N 4715		Z-Di	=1N4678: 36V	31a		DO-7	
1 N 4716		Z-Di	=1N4678: 39V	31a		DO-7	
1 N 4717		Z-Di	=1N4678: 43V	31a		DO-7	
1 N 4718	USA	Si-Di	.S, 50V, <180ns	31a		DO-7	BYT 52A, BYX 92/50, MR 810, RGP 10A, ++
1 N 4719	USA, Mot	Si-Di	Rr, 50V, 3A(Tc=75°), Uf<0.9V(3A)	34a		DO-1	RGP 30 M 31a BY 396...399, RGP 30A, (BY 205/100,++) ⁴
1 N 4720		Si-Di	=1N4719: 100V	34a		DO-1	RGP 30 M 31a BY 396...399, RGP 30B, (BY 205/100,++) ⁴
1 N 4721		Si-Di	=1N4719: 200V	34a		DO-1	RGP 30 M 31a BY 397...399, RGP 30D, (BY 205/200,++) ⁴
1 N 4722		Si-Di	=1N4719: 400V	34a		DO-1	RGP 30 M 31a BY 398...399, RGP 30G, (BY 205/400,++) ⁴
1 N 4723		Si-Di	=1N4719: 600V	34a		DO-1	RGP 30 M 31a BY 228, BY 399, RGP 30J, (BY 205/600,++) ⁴
1 N 4724		Si-Di	=1N4719: 800V	34a		DO-1	RGP 30 M 31a BY 228, BY 399, RGP 30K, (BY 205/800,++) ⁴
1 N 4725		Si-Di	=1N4719: 1000V	34a		DO-1	RGP 30 M 31a BY 228, BY 438, RGP 30M, (BY 206/1000,++) ⁴
1 N 4719R...4725R		Si-Di	=1N4719...4725:	34b		DO-1	*1N4719...25
1 N 4726	USA, Tix	Si-Di	SS, 20V, 0.06A	31a		DO-7	
1 N 4727	USA, Tix	Si-Di	SS, 20V, 0.075A	31a		DO-35	
1 N 4728	USA, EUR, Hit	Z-Di	3.3V, 10%, 1W	31a		SOD-22	Z-Diode 3.3V 31a BZW22/..., BZX61/..., ZPY..., 1N5913...49,++
1 N 4729		Z-Di	=1N4728: 3.6V	31a		SOD-22	Z-Diode 3.6V 31a
1 N 4730		Z-Di	=1N4728: 3.9V	31a		SOD-22	Z-Diode 3.9V 31a
1 N 4731		Z-Di	=1N4728: 4.3V	31a		SOD-22	Z-Diode 4.3V 31a

Original	Fabric.	Constr.	Info	(Compl. Fig.	JAEGER	Fig.	International
1 N 4732		Z-Di	=1N3728: 4,7V	31a	SOD-22	Z-Diode 4,7V	31a
1 N 4733		Z-Di	=1N4728: 5,1V	31a	SOD-22	Z-Diode 5,1V	31a
1 N 4734		Z-Di	=1N4728: 5,6V	31a	SOD-22	Z-Diode 5,6V	31a
1 N 4735		Z-Di	=1N4728: 6,2V	31a	SOD-22	Z-Diode 6,2V	31a
1 N 4736		Z-Di	=1N4728: 6,8V	31a	SOD-22	Z-Diode 6,8V	31a
1 N 4737		Z-Di	=1N4728: 7,5V	31a	SOD-22	Z-Diode 7,5V	31a
1 N 4738		Z-Di	=1N4728: 8,2V	31a	SOD-22	Z-Diode 8,2V	31a
1 N 4739		Z-Di	=1N4728: 9,1V	31a	SOD-22	Z-Diode 9,1V	31a
1 N 4740		Z-Di	=1N4728: 10V	31a	SOD-22	Z-Diode 10V	31a
1 N 4741		Z-Di	=1N4728: 11V	31a	SOD-22	Z-Diode 11V	31a
1 N 4742		Z-Di	=1N4728: 12V	31a	SOD-22	Z-Diode 12V	31a
1 N 4743		Z-Di	=1N4728: 13V	31a	SOD-22	Z-Diode 13V	31a
1 N 4744		Z-Di	=1N4728: 15V	31a	SOD-22	Z-Diode 15V	31a
1 N 4745		Z-Di	=1N4728: 16V	31a	SOD-22	Z-Diode 16V	31a
1 N 4746		Z-Di	=1N4728: 18V	31a	SOD-22	Z-Diode 18V	31a
1 N 4747		Z-Di	=1N4728: 20V	31a	SOD-22	Z-Diode 20V	31a
1 N 4748		Z-Di	=1N4728: 22V	31a	SOD-22	Z-Diode 22V	31a
1 N 4749		Z-Di	=1N4728: 24V	31a	SOD-22	Z-Diode 24V	31a
1 N 4750		Z-Di	=1N4728: 27V	31a	SOD-22	Z-Diode 27V	31a
1 N 4751		Z-Di	=1N4728: 30V	31a	SOD-22	Z-Diode 30V	31a
1 N 4752		Z-Di	=1N4728: 33V	31a	SOD-22	Z-Diode 33V	31a
1 N 4753		Z-Di	=1N4728: 36V	31a	SOD-22	Z-Diode 36V	31a
1 N 4754		Z-Di	=1N4728: 39V	31a	SOD-22	Z-Diode 39V	31a
1 N 4755		Z-Di	=1N4728: 43V	31a	SOD-22	Z-Diode 43V	31a
1 N 4756		Z-Di	=1N4728: 47V	31a	SOD-22	Z-Diode 47V	31a
1 N 4757		Z-Di	=1N4728: 51V	31a	SOD-22	Z-Diode 51V	31a
1 N 4758		Z-Di	=1N4728: 56V	31a	SOD-22	Z-Diode 56V	31a
1 N 4759		Z-Di	=1N4728: 62V	31a	SOD-22	Z-Diode 62V	31a
1 N 4760		Z-Di	=1N4728: 68V	31a	SOD-22	Z-Diode 68V	31a
1 N 4761		Z-Di	=1N4728: 75V	31a	SOD-22	Z-Diode 75V	31a
1 N 4762		Z-Di	=1N4728: 82V	31a	SOD-22	Z-Diode 82V	31a
1 N 4763		Z-Di	=1N4728: 91V	31a	SOD-22	Z-Diode 91V	31a
1 N 4764		Z-Di	=1N4728: 100V	31a	SOD-22	Z-Diode 100V	31a
1 N 4728A...4764A		Z-Di	=1N4728...4764: 5%	31a	SOD-22		
1 N 4765(A,B)	USA,Sie,Tho	Ref-Di	9,1V(0,5mA), 5%, ±0,01%/°C, <350Ω, 0,25W, 0...+75° A: -55...+100°, B: -55...+150°	31a	DO-7,DO-35		1N935
1 N 4766(A,B)		Ref-Di	=1N4765: ±0,005%/°C	31a	DO-7,DO-35		1N936
1 N 4767(A,B)		Ref-Di	=1N4765: ±0,002%/°C	31a	DO-7,DO-35		1N937
1 N 4768(A,B)		Ref-Di	=1N4765: ±0,001%/°C	31a	DO-7,DO-35		1N938
1 N 4769(A,B)		Ref-Di	=1N4765: ±0,0005%/°C	31a	DO-7,DO-35		1N939
1 N 4770(A,B)		Ref-Di	=1N4765: 9,1V(1mA), <200Ω	31a	DO-7,DO-35		
1 N 4771(A,B)		Ref-Di	=1N4766: 9,1V(1mA), <200Ω	31a	DO-7,DO-35		
1 N 4772(A,B)		Ref-Di	=1N4767: 9,1V(1mA), <200Ω	31a	DO-7,DO-35		
1 N 4773(A,B)		Ref-Di	=1N4768: 9,1V(1mA), <200Ω	31a	DO-7,DO-35		
1 N 4774(A,B)		Ref-Di	=1N4769: 9,1V(1mA), <200Ω	31a	DO-7,DO-35		
1 N 4775(A,B)		Ref-Di	=1N4765: 8,5V(0,5mA), <200Ω	31a	DO-7,DO-35		1N3154
1 N 4776(A,B)		Ref-Di	=1N4766: 8,5V(0,5mA), <200Ω	31a	DO-7,DO-35		1N3155
1 N 4777(A,B)		Ref-Di	=1N4767: 8,5V(0,5mA), <200Ω	31a	DO-7,DO-35		1N3156
1 N 4778(A,B)		Ref-Di	=1N4768: 8,5V(0,5mA), <200Ω	31a	DO-7,DO-35		1N3157
1 N 4779(A,B)		Ref-Di	=1N4769: 8,5V(0,5mA), <200Ω	31a	DO-7,DO-35		-
1 N 4780(A,B)		Ref-Di	=1N4765: 8,5V(1mA), <100Ω	31a	DO-7,DO-35		1N3154
1 N 4781(A,B)		Ref-Di	=1N4766: 8,5V(1mA), <100Ω	31a	DO-7,DO-35		1N3155
1 N 4782(A,B)		Ref-Di	=1N4767: 8,5V(1mA), <100Ω	31a	DO-7,DO-35		1N3156
1 N 4783(A,B)		Ref-Di	=1N4768: 8,5V, <100Ω	31a	DO-7,DO-35		1N3157
1 N 4784(A,B)		Ref-Di	=1N4769: 8,5V(1mA), <100Ω	31a	DO-7,DO-35		-
1 N 4785	Rca	Ge-Di	TV Damper/Booster-Di, 60/320V, 7A, Uf<0,77V(7A)	23	TO-3		AY 102
1 N 4786(A...D)	Tdy,Trw	Si-Di	VHF Tuning	31a	DO-14		-
1 N 4787(A...D)	Tdy,Trw	Si-Di	VHF Tuning	31a	DO-14		-
1 N 4788(A...D)	Tdy,Trw	Si-Di	VHF Tuning	31a	DO-14		-
1 N 4789(A...D)	Tdy,Trw	Si-Di	VHF Tuning	31a	DO-14		-
1 N 4790(A...D)	Tdy,Trw	Si-Di	VHF Tuning	31a	DO-14		-
1 N 4791(A...D)	Tdy,Trw	Si-Di	VHF Tuning	31a	DO-14		-
1 N 4792(A...D)	Tdy,Trw	Si-Di	VHF Tuning	31a	DO-14		-
1 N 4793(A...D)	Tdy,Trw	Si-Di	VHF Tuning	31a	DO-14		-
1 N 4794(A...D)	Tdy,Trw	Si-Di	VHF Tuning	31a	DO-14		-
1 N 4795(A...D)	Tdy,Trw	Si-Di	VHF Tuning	31a	DO-14		-
1 N 4796(A...D)	Tdy,Trw	Si-Di	VHF Tuning	31a	DO-14		-
1 N 4797(A...D)	Tdy,Trw	Si-Di	VHF Tuning	31a	DO-14		-
1 N 4798(A...D)	Tdy,Trw	Si-Di	VHF Tuning	31a	DO-14		-
1 N 4799(A...D)	Tdy,Trw	Si-Di	VHF Tuning	31a	DO-14		-
1 N 4800(A...D)	Tdy,Trw	Si-Di	VHF Tuning	31a	DO-14		-
1 N 4801(A...D)	Tdy,Trw	Si-Di	VHF Tuning	31a	DO-14		-
1 N 4802(A...D)	Tdy,Trw	Si-Di	VHF Tuning	31a	DO-14		-
1 N 4803(A...D)	Tdy,Trw	Si-Di	VHF Tuning	31a	DO-14		-
1 N 4804(A...D)	Tdy,Trw	Si-Di	VHF Tuning	31a	DO-14		-
1 N 4805(A...D)	Tdy,Trw	Si-Di	VHF Tuning	31a	DO-14		-
1 N 4806(A...D)	Tdy,Trw	Si-Di	VHF Tuning	31a	DO-14		-
1 N 4807(A...D)	Tdy,Trw	Si-Di	VHF Tuning	31a	DO-14		-
1 N 4808(A...D)	Tdy,Trw	Si-Di	VHF Tuning	31a	DO-14		-
1 N 4809(A...D)	Tdy,Trw	Si-Di	VHF Tuning	31a	DO-14		-
1 N 4810(A...D)	Tdy,Trw	Si-Di	VHF Tuning	31a	DO-14		-
1 N 4811(A...D)	Tdy,Trw	Si-Di	VHF Tuning	31a	DO-14		-
1 N 4812(A...D)	Tdy,Trw	Si-Di	VHF Tuning	31a	DO-14		-
1 N 4813(A...D)	Tdy,Trw	Si-Di	VHF Tuning	31a	DO-14		-
1 N 4814(A...D)	Tdy,Trw	Si-Di	VHF Tuning	31a	DO-14		-
1 N 4815(A...D)	Tdy,Trw	Si-Di	VHF Tuning	31a	DO-14		-
1 N 4816(A)	USA,Gie	Si-Di	Rr, 50V, 1,5A, Uf<1,3V(1,5A)	31a	DO-27		BY 226...227, BY 251...255, 1N5391...99, ++
1 N 4817(A)		Si-Di	=1N4816: 100V	31a	DO-27		BY 226...227, BY 251...255, 1N5392...99, ++
1 N 4818(A)		Si-Di	=1N4816: 200V	31a	DO-27		BY 226...227, BY 251...255, 1N5393...99, ++
1 N 4819(A)		Si-Di	=1N4816: 300V	31a	DO-27		BY 226...227, BY 252...255, 1N5394...99, ++
1 N 4820(A)		Si-Di	=1N4816: 400V	31a	DO-27		BY 226...227, BY 252...255, 1N5395...99, ++
1 N 4821(A)		Si-Di	=1N4816: 500V	31a	DO-27		BY 226...227, BY 253...255, 1N5396...99, ++
1 N 4822(A)		Si-Di	=1N4816: 600V	31a	DO-27		BY 226...227, BY 253...255, 1N5397...99, ++

Original	Fabric.	Constr.	Info	{Compl. Fig.	JAEGER	Fig.	International
1 N 4823	USA	Si-Di	Frr, 100V, 1A, Uf<1,25V(1A), <100ns	34a	DO-13		BYV 12...16, BYX 92/100, EGP 10B, ++
1 N 4824		Si-Di	=1N4823: 200V	34a	DO-13		BYV 13...16, BYX 92/200, EGP 10D, ++
1 N 4825		Si-Di	=1N4823: 400V	34a	DO-13		BYT 52G, BYV 13...16, BYX 92/400, ++
1 N 4826		Si-Di	=1N4823: 600V	34a	DO-13		BYT 52J, BYV 14...16, BYV 36C, ++
1 N 4827	USA	Ge-Di	S, 30V, 200ns	31a	DO-7		AAY 28, 1N631, 1N633
1 N 4828	USA,Gen	Si-St	20/30V, 0,4W, Uf<1,1V(100mA)	31a	DO-7,DO-35		-
1 N 4829		Si-St	=1N4828: Uf<1,87V(100mA)	31a	DO-7,DO-35		-
1 N 4830		Si-St	=1N4828: Uf<2,69V(100mA)	31a	DO-7,DO-35		-
1 N 4831	USA,Tix	Z-Di	bidirectional, 9,1V, 20%, 1,2W	31a	DO-29		-
1 N 4832		Z-Di	=1N4831: 10V	31a	DO-29		-
1 N 4833		Z-Di	=1N4831: 11V	31a	DO-29		-
1 N 4834		Z-Di	=1N4831: 12V	31a	DO-29		-
1 N 4835		Z-Di	=1N4831: 13V	31a	DO-29		-
1 N 4836		Z-Di	=1N4831: 15V	31a	DO-29		-
1 N 4837		Z-Di	=1N4831: 16V	31a	DO-29		-
1 N 4838		Z-Di	=1N4831: 18V	31a	DO-29		-
1 N 4839		Z-Di	=1N4831: 20V	31a	DO-29		-
1 N 4840		Z-Di	=1N4831: 22V	31a	DO-29		-
1 N 4841		Z-Di	=1N4831: 24V	31a	DO-29		-
1 N 4842		Z-Di	=1N4831: 27V	31a	DO-29		-
1 N 4843		Z-Di	=1N4831: 30V	31a	DO-29		-
1 N 4844		Z-Di	=1N4831: 33V	31a	DO-29		-
1 N 4845		Z-Di	=1N4831: 36V	31a	DO-29		-
1 N 4846		Z-Di	=1N4831: 39V	31a	DO-29		-
1 N 4847		Z-Di	=1N4831: 43V	31a	DO-29		-
1 N 4848		Z-Di	=1N4831: 47V	31a	DO-29		-
1 N 4849		Z-Di	=1N4831: 51V	31a	DO-29		-
1 N 4850		Z-Di	=1N4831: 56V	31a	DO-29		-
1 N 4851		Z-Di	=1N4831: 62V	31a	DO-29		-
1 N 4852		Z-Di	=1N4831: 68V	31a	DO-29		-
1 N 4853		Z-Di	=1N4831: 75V	31a	DO-29		-
1 N 4854		Z-Di	=1N4831: 82V	31a	DO-29		-
1 N 4855		Z-Di	=1N4831: 91V	31a	DO-29		-
1 N 4856		Z-Di	=1N4831: 100V	31a	DO-29		-
1 N 4857		Z-Di	=1N4831: 110V	31a	DO-29		-
1 N 4858		Z-Di	=1N4831: 120V	31a	DO-29		-
1 N 4859		Z-Di	=1N4831: 130V	31a	DO-29		-
1 N 4860		Z-Di	=1N4831: 150V	31a	DO-29		-
1 N 4831A...4860A		Z-Di	=1N4831...4860: 10%	31a	DO-29		-
1 N 4831B...4860B		Z-Di	=1N4831...4860: 5%	31a	DO-29		-
1 N 4861	USA,Hit	Si-Di	S, 40V, <1µs	31a	DO-35		BA 127, BA 147/50, BA 187...190, ++
1 N 4862	USA,Hit	Si-Di	S, 70V, <1µs	31a	DO-35		BA 127, BA 147/100, BA 188...190, ++
1 N 4863	USA,Gen,Hit	Si-Di	SS, 70V, 0,2A, <7ns	31a	DO-35		BAW 62, BAW 76, BAX 95, 1N4148...49, ++
1 N 4864	USA,Gen,Hit	Si-Di	SS, 125V, 0,2A, <4ns	31a	DO-35		(BA 203)
1 N 4865	USA	Si-Di	kV-Rr, 1,5kV, 1,25A				-
1 N 4866		Si-Di	=1N4865: 2,5kV				-
1 N 4867		Si-Di	=1N4865: 3kV				-
1 N 4868		Si-Di	=1N4865: 5kV				-
1 N 4869		Si-Di	=1N4865: 7,5kV				-
1 N 4870		Si-Di	=1N4865: 10kV				-
1 N 4871		Si-Di	=1N4865: 12kV				-
1 N 4872		Si-Di	=1N4865: 15kV				-
1 N 4873		Si-Di	=1N4865: 20kV				-
1 N 4874		Si-Di	=1N4865: 25kV				-
1 N 4875		Si-Di	=1N4865: 30kV				-
1 N 4876		Si-Di	=1N4865: 40kV				-
1 N 4877		Si-Di	=1N4865: 50kV				-
1 N 4878	USA	Si-Di	P Rr, 100V, 100A(Tc=120°), Uf<1,3V(100A, 120°)	73a	DO-8		1N3288...97
1 N 4879	USA	Si-Di	P Rr, 100V, 160A(Tc=120°), Uf<1,3V(160A, 120°)	73a	DO-9		1N4587...96
1 N 4880		Si-Di	P Rr, 250V, 160A(Tc=120°), Uf<1,2V(250A, 120°)	73a	DO-9		1N3735...44
1 N 4881	USA	Z-Di	20V, 10%, 3W	31a	SOD-51		BZT 03/C,D20
1 N 4882	USA	Z-Di	36V, 10%, 3W	31a	SOD-51		BZT 03/C,D,36
1 N 4883	USA	Z-Di	12V, 5%, 3W	31a	SOD-51		BZT 03/C12
1 N 4884		Z-Di	=1N4881: 5%	31a	SOD-51		BZT 03/C20
1 N 4885	Phi	Si-Di	HF Multiplier	32	DO-4		-
1 N 4886	Phi	Si-Di	HF Multiplier	32	DO-4		-
1 N 4887		Si-Di	=1N4865: 75kV				-
1 N 4888	Idc	Si-Di	SS, 12V, <0,5ns	31a	DO-7		BAY 82, 1N4244, 1N4376
1 N 4889	Trw	Z-Di	62V, 5%, 5W	31a	SOD-51		BZV40/C62, BZV 48/C62, 1N5372
1 N 4890(A)	USA,Sie	Ref-Di	6,35V(7,5mA), 5%, ±0,001%/°C, <10Ω, 0,4W ΔUz<318µV/1000h, +25...+100°, A: -55...+100°	31a	DO-7		-
1 N 4891(A)		Ref-Di	=1N4890: ±0,0005%/°C	31a	DO-7		-
1 N 4892(A)		Ref-Di	=1N4890: ΔUz<127µV/1000h	31a	DO-7		-
1 N 4893(A)		Ref-Di	=1N4890: ±0,0005%/°C, ΔUz<127µV/1000h	31a	DO-7		-
1 N 4894(A)		Ref-Di	=1N4890: ΔUz<64µV/1000h	31a	DO-7		-
1 N 4895(A)		Ref-Di	=1N4890: ±0,0005%/°C, ΔUz<64µV/1000h	31a	DO-7		-
1 N 4896(A)	Mot,Sie,++	Ref-Di	ln, 12,8V(0,5mA), 5%, ±0,01%/°C, <400Ω, 0,4W ±25...+100°, A: -55...+100°	31a	DO-7		-
1 N 4897(A)		Ref-Di	=1N4896: ±0,005%/°C	31a	DO-7		-
1 N 4898(A)		Ref-Di	=1N4896: ±0,002%/°C	31a	DO-7		-
1 N 4899(A)		Ref-Di	=1N4896: ±0,001%/°C	31a	DO-7		-
1 N 4900(A)		Ref-Di	=1N4896: 12,8V(1mA), <200Ω	31a	DO-7		-
1 N 4901(A)		Ref-Di	=1N4900: ±0,005%/°C	31a	DO-7		-
1 N 4902(A)		Ref-Di	=1N4900: ±0,002%/°C	31a	DO-7		-
1 N 4903(A)		Ref-Di	=1N4900: ±0,001%/°C	31a	DO-7		-
1 N 4904(A)		Ref-Di	=1N4896: 12,8V(2mA), <100Ω	31a	DO-7		-
1 N 4905(A)		Ref-Di	=1N4904: ±0,005%/°C	31a	DO-7		-
1 N 4906(A)		Ref-Di	=1N4904: ±0,002%/°C	31a	DO-7		-
1 N 4907(A)		Ref-Di	=1N4904: ±0,001%/°C	31a	DO-7		-
1 N 4908(A)		Ref-Di	=1N4896: 12,8V(4mA), <50Ω	31a	DO-7		-
1 N 4909(A)		Ref-Di	=1N4908: ±0,005%/°C	31a	DO-7		-
1 N 4910(A)		Ref-Di	=1N4908: ±0,002%/°C	31a	DO-7		-
1 N 4911(A)		Ref-Di	=1N4908: ±0,001%/°C	31a	DO-7		-

Original	Fabric.	Constr.	Info	{ Compl. Fig.	JAEGER	Fig.	International		
1 N 4912(A)		Ref-Di	=1N4896: 12.8V(7.5mA), <25 Ω	31a	DO-7	-	-		
1 N 4913(A)		Ref-Di	=1N4912: $\pm 0.005\%$ / $^{\circ}$ C	31a	DO-7	-	-		
1 N 4914(A)		Ref-Di	=1N4912: $\pm 0.002\%$ / $^{\circ}$ C	31a	DO-7	-	-		
1 N 4915(A)		Ref-Di	=1N4912: $\pm 0.001\%$ / $^{\circ}$ C	31a	DO-7	-	-		
1 N 4916(A)		Ref-Di	=1N4896: 19.2V(0.5mA), <600 Ω	31a	DO-7	-	-		
1 N 4917(A)		Ref-Di	=1N4916: $\pm 0.005\%$ / $^{\circ}$ C	31a	DO-7	-	-		
1 N 4918(A)		Ref-Di	=1N4916: $\pm 0.002\%$ / $^{\circ}$ C	31a	DO-7	-	-		
1 N 4919(A)		Ref-Di	=1N4896: 19.2V(1mA), <300 Ω	31a	DO-7	-	-		
1 N 4920(A)		Ref-Di	=1N4919: $\pm 0.005\%$ / $^{\circ}$ C	31a	DO-7	-	-		
1 N 4921(A)		Ref-Di	=1N4919: $\pm 0.002\%$ / $^{\circ}$ C	31a	DO-7	-	-		
1 N 4922(A)		Ref-Di	=1N4896: 19.2V(2mA), <150 Ω	31a	DO-7	-	-		
1 N 4923(A)		Ref-Di	=1N4922: $\pm 0.005\%$ / $^{\circ}$ C	31a	DO-7	-	-		
1 N 4924(A)		Ref-Di	=1N4922: $\pm 0.002\%$ / $^{\circ}$ C	31a	DO-7	-	-		
1 N 4925(A)		Ref-Di	=1N4896: 19.2V(4mA), <75 Ω	31a	DO-7	-	-		
1 N 4926(A)		Ref-Di	=1N4925: $\pm 0.005\%$ / $^{\circ}$ C	31a	DO-7	-	-		
1 N 4927(A)		Ref-Di	=1N4925: $\pm 0.002\%$ / $^{\circ}$ C	31a	DO-7	-	-		
1 N 4928(A)		Ref-Di	=1N4925: $\pm 0.001\%$ / $^{\circ}$ C	31a	DO-7	-	-		
1 N 4929(A)		Ref-Di	=1N4896: 19.2V(7.5mA), <36 Ω	31a	DO-7	-	-		
1 N 4930(A)		Ref-Di	=1N4929: $\pm 0.005\%$ / $^{\circ}$ C	31a	DO-7	-	-		
1 N 4931(A)		Ref-Di	=1N4929: $\pm 0.002\%$ / $^{\circ}$ C	31a	DO-7	-	-		
1 N 4932(A)		Ref-Di	=1N4929: $\pm 0.001\%$ / $^{\circ}$ C	31a	DO-7	-	-		
1 N 4933(GP)	USA, EUR	Si-Di	FRr, 50V, 1A, Uf<1, 1V(1A), <200ns	31a	SOD-22	BYD 33 M	31a	BYT 52A, BYX 92/50, EGP 10A, RGP 10A, ++	
1 N 4934(GP)		Si-Di	=1N4933: 100V	31a	SOD-22	BYD 33 M	31a	BYT 52B, BYX 92/100, EGP 10B, RGP 10B, ++	
1 N 4935(GP)		Si-Di	=1N4933: 200V	31a	SOD-22	BYD 33 M	31a	BYT 52D, BYX 92/200, EGP 10D, RGP 10D, ++	
1 N 4936(GP)		Si-Di	=1N4933: 400V	31a	SOD-22	BYD 33 M	31a	BY 201/4, BYT 52G, BYX 92/400, RGP 10G, ++	
1 N 4937(GP)		Si-Di	=1N4933: 600V	31a	SOD-22	BYD 33 M	31a	BY 201/6, BYT 52J, BYX 92/600, RGP 10J, ++	
1 N 4938	USA, Fch, Hit	Si-Di	S, 175/200V, 0,2/0,6A, Uf<1V(0,1A), <50ns, =1N3070	31a	DO-35	-	-	-1N3070	
1 N 4939	Phi	Ge-Di	UHF, Ka-Band Mx		Koax	SOD-42	-	-	
1 N 4940	Phi	Ge-Di	UHF, X-Band Mx		Koax	SOD-42	-	-	
1 N 4941	Phi	GaAs-Di	UHF Tuning		Koax	SOD-31	-	-	
1 N 4942(GP)	USA, Sie, Tho	Si-Di	FRr, 200V, 1A, Uf<1, 3V(1A), <150ns	IGP: SOD-22	31a	SOD-5	BYD 33 M	31a	BYT 52D, BYX 92/200, EGP 10D, RGP 10D, ++
1 N 4943(GP)		Si-Di	=1N4942: 300V	31a	SOD-51	BYD 33 M	31a	BYT 52G, BYX 92/300, RGP 10G, ++	
1 N 4944(GP)		Si-Di	=1N4942: 400V	31a	SOD-51	BYD 33 M	31a	BYT 52G, BYX 92/400, RGP 10G, ++	
1 N 4945(GP)		Si-Di	=1N4942: 500V	31a	SOD-51	BYD 33 M	31a	BY 201/6, BYT 52J, RGP 10J, ++	
1 N 4946(GP)		Si-Di	=1N4942: 600V, <250ns	31a	SOD-51	BYD 33 M	31a	BY 201/6, BYT 52J, RGP 10J, ++	
1 N 4947(GP)		Si-Di	=1N4942: 800V, <250ns	31a	SOD-51	BYD 33 M	31a	BYV 15...16, BYT 52K, RGP 10K, ++	
1 N 4948(GP)		Si-Di	=1N4942: 1000V, <500ns	31a	SOD-51	BYD 33 M	31a	BYV 16, BYV 38, BYT 52M, RGP 10M, ++	
1 N 4949	Idc, Inr	Si-Di	SS, 35V, <0,3ns	31a	DO-7	-	-	-	
1 N 4950	USA	Si-Di	SS, 30V, <4ns	31a	DO-7	-	-	BA 218, BAX 13, BAX 91, 1N4148...49, ++	
1 N 4951	Gen	Si-Di	Dual, TV HA Sync, 20V, 25mA, Uf<0,85V(1mA)	7e	TO-98	(2x1N4148)	31a	-	
1 N 4952	Gen	Si-Di	=1N4951: 50V	7e	TO-98	(2x1N4148)	31a	-	
1 N 4953	Hew	-Di	SS, 30V		Koax	SOD-31	-	-	
1 N 4954	USA	Z-Di	6,8V, 5%, 5W	31a	SOD-51	-	-	BZV 40/..., BZV 48/..., 1N5342...5388	
1 N 4955		Z-Di	=1N4954: 7,5V	31a	SOD-51	-	-	-	
1 N 4956		Z-Di	=1N4954: 8,2V	31a	SOD-51	-	-	-	
1 N 4957		Z-Di	=1N4954: 9,1V	31a	SOD-51	-	-	-	
1 N 4958		Z-Di	=1N4954: 10V	31a	SOD-51	-	-	-	
1 N 4959		Z-Di	=1N4954: 11V	31a	SOD-51	-	-	-	
1 N 4960		Z-Di	=1N4954: 12V	31a	SOD-51	-	-	-	
1 N 4961		Z-Di	=1N4954: 13V	31a	SOD-51	-	-	-	
1 N 4962		Z-Di	=1N4954: 15V	31a	SOD-51	-	-	-	
1 N 4963		Z-Di	=1N4954: 16V	31a	SOD-51	-	-	-	
1 N 4964		Z-Di	=1N4954: 18V	31a	SOD-51	-	-	-	
1 N 4965		Z-Di	=1N4954: 20V	31a	SOD-51	-	-	-	
1 N 4966		Z-Di	=1N4954: 22V	31a	SOD-51	-	-	-	
1 N 4967		Z-Di	=1N4954: 24V	31a	SOD-51	-	-	-	
1 N 4968		Z-Di	=1N4954: 27V	31a	SOD-51	-	-	-	
1 N 4969		Z-Di	=1N4954: 30V	31a	SOD-51	-	-	-	
1 N 4970		Z-Di	=1N4954: 33V	31a	SOD-51	-	-	-	
1 N 4971		Z-Di	=1N4954: 36V	31a	SOD-51	-	-	-	
1 N 4972		Z-Di	=1N4954: 39V	31a	SOD-51	-	-	-	
1 N 4973		Z-Di	=1N4954: 43V	31a	SOD-51	-	-	-	
1 N 4974		Z-Di	=1N4954: 47V	31a	SOD-51	-	-	-	
1 N 4975		Z-Di	=1N4954: 51V	31a	SOD-51	-	-	-	
1 N 4976		Z-Di	=1N4954: 56V	31a	SOD-51	-	-	-	
1 N 4977		Z-Di	=1N4954: 62V	31a	SOD-51	-	-	-	
1 N 4978		Z-Di	=1N4954: 68V	31a	SOD-51	-	-	-	
1 N 4979		Z-Di	=1N4954: 75V	31a	SOD-51	-	-	-	
1 N 4980		Z-Di	=1N4954: 82V	31a	SOD-51	-	-	-	
1 N 4981		Z-Di	=1N4954: 91V	31a	SOD-51	-	-	-	
1 N 4982		Z-Di	=1N4954: 100V	31a	SOD-51	-	-	-	
1 N 4983		Z-Di	=1N4954: 110V	31a	SOD-51	-	-	-	
1 N 4984		Z-Di	=1N4954: 120V	31a	SOD-51	-	-	-	
1 N 4985		Z-Di	=1N4954: 130V	31a	SOD-51	-	-	-	
1 N 4986		Z-Di	=1N4954: 150V	31a	SOD-51	-	-	-	
1 N 4987		Z-Di	=1N4954: 160V	31a	SOD-51	-	-	-	
1 N 4988		Z-Di	=1N4954: 180V	31a	SOD-51	-	-	-	
1 N 4989		Z-Di	=1N4954: 200V	31a	SOD-51	-	-	-	
1 N 4990		Z-Di	=1N4954: 220V	31a	SOD-51	-	-	-	
1 N 4991		Z-Di	=1N4954: 240V	31a	SOD-51	-	-	-	
1 N 4992		Z-Di	=1N4954: 270V	31a	SOD-51	-	-	-	
1 N 4993		Z-Di	=1N4954: 300V	31a	SOD-51	-	-	-	
1 N 4994		Z-Di	=1N4954: 330V	31a	SOD-51	-	-	-	
1 N 4995		Z-Di	=1N4954: 360V	31a	SOD-51	-	-	-	
1 N 4996		Z-Di	=1N4954: 390V	31a	SOD-51	-	-	-	
1 N 4954A...4996A		Z-Di	=1N4954...4996: 10%	31a	SOD-51	-	-	-	
1 N 4954B...4996B		Z-Di	=1N4954...4996: 20%	31a	SOD-51	-	-	-	
1 N 4997(R)	USA, Mot	Si-Di	=1N4719		-	-	-	-1N4719	
1 N 4998(R)	USA, Mot	Si-Di	=1N4720		-	-	-	-1N4720	
1 N 4999(R)	USA, Mot	Si-Di	=1N4721		-	-	-	-1N4721	
1 N 5000(R)	USA, Mot	Si-Di	=1N4722		-	-	-	-1N4722	
1 N 5001(R)	USA, Mot	Si-Di	=1N4723		-	-	-	-1N4723	
1 N 5002(R)	USA, Mot	Si-Di	=1N4724		-	-	-	-1N4724	

Original	Fabric.	Constr.	Info	{Compl. Fig.	JAEGER	Fig.	International	
1 N 5003(R)	USA,Mot	Si-Di	=1N4725				=1N4725	
1 N 5004	USA	Si-Di	Rr, 100V, 1A, Uf<1.3V(1A, 40°)	34a	DO-13		BY 126...127, BY 133...134, 1N4002...07, ++	
1 N 5005		Si-Di	=1N5004: 200V	34a	DO-13		BY 126...127, BY 133...134, 1N4003...07, ++	
1 N 5006		Si-Di	=1N5004: 400V	34a	DO-13		BY 126...127, BY 133...134, 1N4004...07, ++	
1 N 5007		Si-Di	=1N5004: 600V	34a	DO-13		BY 126...127, BY 133...134, 1N4005...07, ++	
1 N 5008	USA	Z-Di	3.3V, 10%, 2.5W	31a	SOD-18		BZD 23/..., BZT 03/..., BZX 70/...	
1 N 5009		Z-Di	=1N5008: 3.6V	31a	SOD-18			
1 N 5010		Z-Di	=1N5008: 3.9V	31a	SOD-18			
1 N 5011		Z-Di	=1N5008: 4.3V	31a	SOD-18			
1 N 5012		Z-Di	=1N5008: 4.7V	31a	SOD-18			
1 N 5013		Z-Di	=1N5008: 5.1V	31a	SOD-18			
1 N 5014		Z-Di	=1N5008: 5.6V	31a	SOD-18			
1 N 5015		Z-Di	=1N5008: 6.2V	31a	SOD-18			
1 N 5016		Z-Di	=1N5008: 6.8V	31a	SOD-18			
1 N 5017		Z-Di	=1N5008: 7.5V	31a	SOD-18			
1 N 5018		Z-Di	=1N5008: 8.2V	31a	SOD-18			
1 N 5019		Z-Di	=1N5008: 9.1V	31a	SOD-18			
1 N 5020		Z-Di	=1N5008: 10V	31a	SOD-18			
1 N 5021		Z-Di	=1N5008: 11V	31a	SOD-18			
1 N 5022		Z-Di	=1N5008: 12V	31a	SOD-18			
1 N 5023		Z-Di	=1N5008: 13V	31a	SOD-18			
1 N 5024		Z-Di	=1N5008: 14V	31a	SOD-18			
1 N 5025		Z-Di	=1N5008: 15V	31a	SOD-18			
1 N 5026		Z-Di	=1N5008: 16V	31a	SOD-18			
1 N 5027		Z-Di	=1N5008: 17V	31a	SOD-18			
1 N 5028		Z-Di	=1N5008: 18V	31a	SOD-18			
1 N 5029		Z-Di	=1N5008: 19V	31a	SOD-18			
1 N 5030		Z-Di	=1N5008: 20V	31a	SOD-18			
1 N 5031		Z-Di	=1N5008: 22V	31a	SOD-18			
1 N 5032		Z-Di	=1N5008: 24V	31a	SOD-18			
1 N 5033		Z-Di	=1N5008: 25V	31a	SOD-18			
1 N 5034		Z-Di	=1N5008: 27V	31a	SOD-18			
1 N 5035		Z-Di	=1N5008: 30V	31a	SOD-18			
1 N 5036		Z-Di	=1N5008: 33V	31a	SOD-18			
1 N 5037		Z-Di	=1N5008: 36V	31a	SOD-18			
1 N 5038		Z-Di	=1N5008: 39V	31a	SOD-18			
1 N 5039		Z-Di	=1N5008: 43V	31a	SOD-18			
1 N 5040		Z-Di	=1N5008: 45V	31a	SOD-18			
1 N 5041		Z-Di	=1N5008: 47V	31a	SOD-18			
1 N 5042		Z-Di	=1N5008: 50V	31a	SOD-18			
1 N 5043		Z-Di	=1N5008: 51V	31a	SOD-18			
1 N 5044		Z-Di	=1N5008: 52V	31a	SOD-18			
1 N 5045		Z-Di	=1N5008: 56V	31a	SOD-18			
1 N 5046		Z-Di	=1N5008: 62V	31a	SOD-18			
1 N 5047		Z-Di	=1N5008: 68V	31a	SOD-18			
1 N 5048		Z-Di	=1N5008: 75V	31a	SOD-18			
1 N 5049		Z-Di	=1N5008: 82V	31a	SOD-18			
1 N 5050		Z-Di	=1N5008: 91V	31a	SOD-18			
1 N 5051		Z-Di	=1N5008: 100V	31a	SOD-18			
1 N 5008A...5051A		Z-Di	=1N5008...5051: 5%	31a	SOD-18			
1 N 5052(A)	USA	Si-Di	Rr, 700V, 1.5A, Uf<1.3V(1.5A, 40°)	31a	DO-27	BYD 33 M	31a	BY 227, BYX 85...86, GP 15K, 1N5398...99++
1 N 5053(A)		Si-Di	=1N5052: 800V	31a	DO-27	BYD 33 M	31a	BY 227, BYX 85...86, GP 15K, 1N5398...99++
1 N 5054(A)		Si-Di	=1N5052: 1000V	31a	DO-27	BYD 33 M	31a	BY 227, BYX 86, GP 15M, 1N5399, ++
1 N 5055	USA	Si-Di	Rr, 100V, 1A, Uf<1.4V(1A, 40°)	31a	DO-29			BY 126...127, BY 133...135, 1N4002...07, ++
1 N 5056		Si-Di	=1N5055: 200V	31a	DO-29			BY 126...127, BY 133...134, 1N4003...07, ++
1 N 5057		Si-Di	=1N5055: 300V, 0.8A, Uf<1.4V(0.8A, 40°)	31a	DO-29			BY 126...127, BY 133...134, 1N4004...07, ++
1 N 5058		Si-Di	=1N5055: 400V, 0.8A, Uf<1.4V(0.8A, 40°)	31a	DO-29			BY 126...127, BY 133...134, 1N4004...07, ++
1 N 5059(GP)	USA, EUR, Hit	Si-Di	Rr, contr.av., 200V, 2A, Uf<1.15V(2.5A), 3<6µs GP: DO-15	31a	SOD-57	BYW 95 C	31a	BYD 140...M, BYW 52...56
1 N 5060(GP)		Si-Di	=1N5059: 400V	31a	SOD-57	BYW 95 C	31a	BYD 14G...M, BYW 53...56
1 N 5061(GP)		Si-Di	=1N5059: 600V	31a	SOD-57	BYW 95 C	31a	BYD 14J...M, BYW 54...56
1 N 5062(GP)		Si-Di	=1N5059: 800V	31a	SOD-57	BYW 96 E	31a	BYD 14K...M, BYW 55...56
1 N 5063	USA	Z-Di	6.8V, 5%, 3W	31a	SOD-17			BZT03/..., BZV40/..., BZV48/..., 1N5342...88
1 N 5064		Z-Di	=1N5063: 7.5V	31a	SOD-17			
1 N 5065		Z-Di	=1N5063: 8.2V	31a	SOD-17			
1 N 5066		Z-Di	=1N5063: 9.1V	31a	SOD-17			
1 N 5067		Z-Di	=1N5063: 10V	31a	SOD-17			
1 N 5068		Z-Di	=1N5063: 11V	31a	SOD-17			
1 N 5069		Z-Di	=1N5063: 13V	31a	SOD-17			
1 N 5070		Z-Di	=1N5063: 14V	31a	SOD-17			
1 N 5071		Z-Di	=1N5063: 15V	31a	SOD-17			
1 N 5072		Z-Di	=1N5063: 16V	31a	SOD-17			
1 N 5073		Z-Di	=1N5063: 18V	31a	SOD-17			
1 N 5074		Z-Di	=1N5063: 22V	31a	SOD-17			
1 N 5075		Z-Di	=1N5063: 24V	31a	SOD-17			
1 N 5076		Z-Di	=1N5063: 27V	31a	SOD-17			
1 N 5077		Z-Di	=1N5063: 30V	31a	SOD-17			
1 N 5078		Z-Di	=1N5063: 33V	31a	SOD-17			
1 N 5079		Z-Di	=1N5063: 36V	31a	SOD-17			
1 N 5080		Z-Di	=1N5063: 39V	31a	SOD-17			
1 N 5081		Z-Di	=1N5063: 40V	31a	SOD-17			
1 N 5082		Z-Di	=1N5063: 43V	31a	SOD-17			
1 N 5083		Z-Di	=1N5063: 45V	31a	SOD-17			
1 N 5084		Z-Di	=1N5063: 47V	31a	SOD-17			
1 N 5085		Z-Di	=1N5063: 50V	31a	SOD-17			
1 N 5086		Z-Di	=1N5063: 51V	31a	SOD-17			
1 N 5087		Z-Di	=1N5063: 56V	31a	SOD-17			
1 N 5088		Z-Di	=1N5063: 60V	31a	SOD-17			
1 N 5089		Z-Di	=1N5063: 62V	31a	SOD-17			
1 N 5090		Z-Di	=1N5063: 68V	31a	SOD-17			
1 N 5091		Z-Di	=1N5063: 70V	31a	SOD-17			
1 N 5092		Z-Di	=1N5063: 75V	31a	SOD-17			
1 N 5093		Z-Di	=1N5063: 80V	31a	SOD-17			

Original	Fabric.	Constr.	Info	{Compl. Fig.	JAEGER	Fig.	International
1 N 5094		Z-Di	=1N5063: 82V	31a	SOD-17		
1 N 5095		Z-Di	=1N5063: 91V	31a	SOD-17		
1 N 5096		Z-Di	=1N5063: 110V	31a	SOD-17		
1 N 5097		Z-Di	=1N5063: 120V	31a	SOD-17		
1 N 5098		Z-Di	=1N5063: 130V	31a	SOD-17		
1 N 5099		Z-Di	=1N5063: 140V	31a	SOD-17		
1 N 5100		Z-Di	=1N5063: 160V	31a	SOD-17		
1 N 5101		Z-Di	=1N5063: 170V	31a	SOD-17		
1 N 5102		Z-Di	=1N5063: 180V	31a	SOD-17		
1 N 5103		Z-Di	=1N5063: 190V	31a	SOD-17		
1 N 5104		Z-Di	=1N5063: 200V	31a	SOD-17		
1 N 5105		Z-Di	=1N5063: 220V	31a	SOD-17		
1 N 5106		Z-Di	=1N5063: 240V	31a	SOD-17		
1 N 5107		Z-Di	=1N5063: 260V	31a	SOD-17		
1 N 5108		Z-Di	=1N5063: 270V	31a	SOD-17		
1 N 5109		Z-Di	=1N5063: 280V	31a	SOD-17		
1 N 5110		Z-Di	=1N5063: 300V	31a	SOD-17		
1 N 5111		Z-Di	=1N5063: 320V	31a	SOD-17		
1 N 5112		Z-Di	=1N5063: 330V	31a	SOD-17		
1 N 5113		Z-Di	=1N5063: 340V	31a	SOD-17		
1 N 5114		Z-Di	=1N5063: 360V	31a	SOD-17		
1 N 5115		Z-Di	=1N5063: 380V	31a	SOD-17		
1 N 5116		Z-Di	=1N5063: 390V	31a	SOD-17		
1 N 5117		Z-Di	=1N5063: 400V	31a	SOD-17		
1 N 5118	USA	Z-Di	14V, 5%, 5W	31a	SOD-51		BZV 40/..., BZV 48/..., 1N5351...5388
1 N 5119		Z-Di	=1N5118: 40V	31a	SOD-51		
1 N 5120		Z-Di	=1N5118: 45V	31a	SOD-51		
1 N 5121		Z-Di	=1N5118: 50V	31a	SOD-51		
1 N 5122		Z-Di	=1N5118: 60V	31a	SOD-51		
1 N 5123		Z-Di	=1N5118: 70V	31a	SOD-51		
1 N 5124		Z-Di	=1N5118: 80V	31a	SOD-51		
1 N 5125		Z-Di	=1N5118: 90V	31a	SOD-51		
1 N 5126		Z-Di	=1N5118: 140V	31a	SOD-51		
1 N 5127		Z-Di	=1N5118: 170V	31a	SOD-51		
1 N 5128		Z-Di	=1N5118: 190V	31a	SOD-51		
1 N 5129		Z-Di	=1N5118: 260V	31a	SOD-51		
1 N 5130		Z-Di	=1N5118: 280V	31a	SOD-51		
1 N 5131		Z-Di	=1N5118: 320V	31a	SOD-51		
1 N 5132		Z-Di	=1N5118: 340V	31a	SOD-51		
1 N 5133		Z-Di	=1N5118: 380V	31a	SOD-51		
1 N 5134		Z-Di	=1N5118: 400V	31a	SOD-51		
1 N 5136(A)	Cod	Si-Di	VHF Tuning	31a	DO-7		-
1 N 5137(A)	Cod	Si-Di	VHF Tuning	31a	DO-7		-
1 N 5138(A)	Cod	Si-Di	VHF Tuning	31a	DO-7		-
1 N 5139(A)	USA,Mot,Tho	Si-Di	VHF Tuning	31a	DO-7		-
1 N 5140(A)	USA,Mot,Tho	Si-Di	VHF Tuning	31a	DO-7		-
1 N 5141(A)	USA,Mot,Tho	Si-Di	VHF Tuning	31a	DO-7		-
1 N 5142(A)	USA,Mot,Tho	Si-Di	VHF Tuning	31a	DO-7		-
1 N 5143(A)	USA,Mot,Tho	Si-Di	VHF Tuning	31a	DO-7		-
1 N 5144(A)	USA,Mot,Tho	Si-Di	VHF Tuning	31a	DO-7		-
1 N 5145(A)	USA,Mot,Tho	Si-Di	VHF Tuning	31a	DO-7		-
1 N 5146(A)	USA,Mot,Tho	Si-Di	VHF Tuning	31a	DO-7		-
1 N 5147(A)	USA,Mot,Tho	Si-Di	VHF Tuning	31a	DO-7		-
1 N 5148(A)	USA,Mot,Tho	Si-Di	VHF Tuning	31a	DO-7		-
1 N 5149(A)	Fer,Mot,Pai	Si-Di	Step-recovery, UHF Multiplier	Koax	SOD-43		-
1 N 5150(A)	Fer,Mot,Pai	Si-Di	Step-recovery, UHF Multiplier	Koax	SOD-43		-
1 N 5151	Mot,Phi,++	Si-Di	Step-recovery, UHF Multiplier	Koax	DO-19		-
1 N 5152(A)	Mot,Phi,++	Si-Di	Step-recovery, UHF Multiplier	Koax	SOD-31		-
1 N 5153(A)	Mot,Phi,++	Si-Di	Step-recovery, UHF Multiplier	Koax	SOD-43		-
1 N 5154	Mot,Phi,++	Si-Di	Step-recovery, UHF Multiplier	Koax	DO-19		-
1 N 5155(A)	Mot,Phi,++	Si-Di	Step-recovery, UHF Multiplier	Koax	SOD-31		-
1 N 5156	Mot,Phi,++	Si-Di	Step-recovery, UHF Multiplier	Koax	SOD-31		-
1 N 5157	Mot,Phi,++	Si-Di	Step-recovery, UHF Multiplier	Koax	DO-19		-
1 N 5158	Mot	Trigger-Di	0,15A, I _{tsm} =10A, U _b =8...10V, I _b <0,05mA, I _h =1...20mA	31a	DO-7		-
1 N 5159		Trigger-Di	=1N5158: U _b =9...11V	31a	DO-7		-
1 N 5160		Trigger-Di	=1N5158: U _b =10...12V	31a	DO-7		-
1 N 5161	Sol	Si-Di	Rauschdiode/Noise Diode, 260V, 0,6W	31a	DO-27		-
1 N 5162	USA	Si-Di	P Rr, 1200V, 150A(T _c =150°), U _f <1,2V(150A, 150°)	73a	DO-30		1N4595...96
1 N 5163	Hew	Si-Di	Snap-off Diode, SS, 35V, <0,5ns	31a	DO-7		-
1 N 5164	Hew	Si-Di	Snap-off Diode, SS, 35V, <0,4ns	31a	DO-7		-
1 N 5165(A)	Hew	Si-Di	Schottky, HF.S, 30V, U _f <1V(50mA)	31a	DO-35		-
1 N 5166(A)	Hew	Si-Di	Schottky, HF.S, 30V, U _f <1V(35mA)	31a	DO-35		-
1 N 5167(A)	Hew	Si-Di	Schottky, HF.S, 20V, U _f <1V(35mA)	31a	DO-35		-
1 N 5168	Hew	Si-Di	Schottky, HF, U _f <1V(75mA)	31a	DO-35		-
1 N 5169	Hew	Si-Di	Schottky, HF, U _f <1V(75mA)	31a	DO-35		-
1 N 5170	USA	Si-Di	Rr, 15V, 2A, U _f <1,2V(2A, 50°)	31a	DO-27		BY 251...255, BYW 52...56, 1N5400...08, ++
1 N 5171		Si-Di	=1N5170: 50V	31a	DO-27		BY 251...255, BYW 52...56, 1N5401...08, ++
1 N 5172		Si-Di	=1N5170: 100V	31a	DO-27		BY 251...255, BYW 52...56, 1N5401...08, ++
1 N 5173		Si-Di	=1N5170: 300V	31a	DO-27		BY 252...255, BYW 53...56, 1N5404...08, ++
1 N 5174		Si-Di	=1N5170: 400V	31a	DO-27		BY 252...255, BYW 53...56, 1N5404...08, ++
1 N 5175		Si-Di	=1N5170: 500V	31a	DO-27		BY 253...255, BYW 54...56, 1N5406...08, ++
1 N 5176		Si-Di	=1N5170: 600V	31a	DO-27		BY 253...255, BYW 54...56, 1N5406...08, ++
1 N 5177		Si-Di	=1N5170: 800V	31a	DO-27		BY 254...255, BYW 55...56, 1N5407...08, ++
1 N 5178		Si-Di	=1N5170: 1000V	31a	DO-27		BY 255, BYW 56, GP 20M, 1N5408, ++
1 N 5179	Gen.Idc.	Si-St	20/30V, 0,4W, U _f <2,5V(0,1mA)/<3,2V(10mA)	31a	DO-7		BZ 102/2V8, BZV 86/2V6, BZX 75/C2V8
1 N 5180	Sem.Trw	Si-Di	Rr, 120V, 4A, U _f <1,25V(4A)	31a	SOD-51		BY 500/200, MR 752...760, MR 822...826, ++
1 N 5181	USA,Tho	Si-Di	kV-Rr, 4kV, 0,1A, U _f <10V(0,1A)	31a	DO-29		HVG 4, 1N1734
1 N 5182		Si-Di	=1N5181: 5kV	31a	DO-29		HVG 5, 1N1734
1 N 5183		Si-Di	=1N5181: 7,5kV	31a	DO-29		BYX 90
1 N 5184		Si-Di	=1N5181: 10kV	31a	DO-29		1N3052
1 N 5185(A)	USA,Gie	Si-Di	Rr, S, 50V, 3...4A, <250...400ns	31a	SOD-51		BY 500/100, BYV 61...63, MR 820...826, ++
1 N 5186(A)		Si-Di	=1N5185: 100V	31a	SOD-51		BY 500/100, BYV 62...63, MR 821...826, ++
1 N 5187(A)		Si-Di	=1N5185: 200V	31a	SOD-51		BY 500/200, EGP 50D, FE 50, MR 822...826

Original	Fabric.	Constr.	Info	(Compl. Fig.	JAEGER	Fig.	International	
1 N 5188(A)		Si-Di	=1N5185: 400V	31a	SOD-51		BY 500/400, MR 824...826	
1 N 5189(A)		Si-Di	=1N5185: 500V	31a	SOD-51		BY 500/600, MR 826	
1 N 5190(A)		Si-Di	=1N5185: 600V	31a	SOD-51		BY 500/600, MR 826	
1 N 5194	USA, Tix	Si-Di	Rr, Uni, 80V, 0,2A, Uf<1V(0,1A)	31a	DO-35		BA 157...159, BA 188...190, BAY 19...20, ++	
1 N 5195		Si-Di	=1N5194: 200V	31a	DO-35		BA 157...159, BA 190, BAY 21, ++	
1 N 5196		Si-Di	=1N5194: 250V	31a	DO-35		BA 157...159, BAY 46, BAY 88...90, ++	
1 N 5197	USA	Si-Di	Rr, 50V, 3A, Uf<1V(3A, 55°)	31a	DO-27		BY 251...255, BYW 17/100, 1N5400...08, ++	
1 N 5198		Si-Di	=1N5197: 100V	31a	DO-27		BY 251...255, BYW 17/100, 1N5401...08, ++	
1 N 5199		Si-Di	=1N5197: 200V	31a	DO-27		BY 251...255, BYW 17/200, 1N5402...08, ++	
1 N 5200		Si-Di	=1N5197: 400V	31a	DO-27		BY 252...255, BYW 17/400, 1N5404...08, ++	
1 N 5201		Si-Di	=1N5197: 600V	31a	DO-27		BY 253...255, BYW 17/600, 1N5406...08, ++	
1 N 5206	Sem, Trw	Si-Di	Rr, Uni, 400/440V, 2A, Uf<1,1V(2A)	31a	SOD-17		BY 253...255, BYW 54...56, 1N5061...62, ++	
1 N 5207	Sem, Trw	Si-Di	Rr, Uni, 400/440V, 4A, Uf<1,25V(4A)	31a	SOD-51		BY 500/600, MR 756...760, MR 826	
1 N 5208	Sem, Tix	Si-Di	Uni, 70V, 0,075A, Uf<1V(20mA)	31a	DO-35		BA 147/100, BA 188...190, 1N5606...09, ++	
1 N 5209	Sem, Tix	Si-Di	Uni, 150V, 0,055A, Uf<1V(7mA)	31a	DO-35		BA 147/150, BA 189...190, 1N5606...07, ++	
1 N 5210		Si-Di	Uni, 200V, 0,04A, Uf<1V(3mA)	31a	DO-35		BA 147/230, BAY 21, BAY 88...90, ++	
1 N 5211	Rca, Sem, Ssi	Si-Di	Rr, 200V, 1A, Uf<1,2V(1A)	34a	DO-13		BY 126...127, BY 133...134, 1N4003...07, ++	
1 N 5212		Si-Di	=1N5211: 400V	34a	DO-13		BY 126...127, BY 133...134, 1N4004...07, ++	
1 N 5213		Si-Di	=1N5211: 600V	34a	DO-13		BY 126...127, BY 133...134, 1N4005...07, ++	
1 N 5214		Si-Di	=1N5211: 800V	34a	DO-13		BY 127, BY 133, BY 227, 1N4006...07, ++	
1 N 5215		Si-Di	=1N5211: Iso	34a(Iso)	DO-13		-1N5211	
1 N 5216		Si-Di	=1N5212: Iso	34a(Iso)	DO-13		-1N5212	
1 N 5217		Si-Di	=1N5213: Iso	34a(Iso)	DO-13		-1N5213	
1 N 5218		Si-Di	=1N5214: Iso	34a(Iso)	DO-13		-1N5214	
1 N 5219	Msc, Sem	Si-Di	SS, 30V, <2ns	31a	DO-7		BA 218, BAX 13, BAX 91, 1N4148...49, ++	
1 N 5220	Msc, Sem	Si-Di	SS, 30V, <0,7ns	31a	DO-7		-	
1 N 5221	USA, EUR, JAP	Z-Di	2,4V, 20%, 0,5W	31a	DO-35	Z-Diode 2,4V	31a	BZX55/..., BZX83/..., ZPD..., 1N5985...6031+
1 N 5222		Z-Di	=1N5221: 2,5V	31a	DO-35	Z-Diode 2,4V	31a	
1 N 5223		Z-Di	=1N5221: 2,7V	31a	DO-35	Z-Diode 2,7V	31a	
1 N 5224		Z-Di	=1N5221: 2,8V	31a	DO-35	Z-Diode 2,7V	31a	
1 N 5225		Z-Di	=1N5221: 3,0V	31a	DO-35	Z-Diode 3V	31a	
1 N 5226		Z-Di	=1N5221: 3,3V	31a	DO-35	Z-Diode 3,3V	31a	
1 N 5227		Z-Di	=1N5221: 3,6V	31a	DO-35	Z-Diode 3,6V	31a	
1 N 5228		Z-Di	=1N5221: 3,9V	31a	DO-35	Z-Diode 3,9V	31a	
1 N 5229		Z-Di	=1N5221: 4,3V	31a	DO-35	Z-Diode 4,3V	31a	
1 N 5230		Z-Di	=1N5221: 4,7V	31a	DO-35	Z-Diode 4,7V	31a	
1 N 5231		Z-Di	=1N5221: 5,1V	31a	DO-35	Z-Diode 5,1V	31a	
1 N 5232		Z-Di	=1N5221: 5,6V	31a	DO-35	Z-Diode 5,6V	31a	
1 N 5233		Z-Di	=1N5221: 6,0V	31a	DO-35	Z-Diode 6,2V	31a	
1 N 5234		Z-Di	=1N5221: 6,2V	31a	DO-35	Z-Diode 6,2V	31a	
1 N 5235		Z-Di	=1N5221: 6,8V	31a	DO-35	Z-Diode 6,8V	31a	
1 N 5236		Z-Di	=1N5221: 7,5V	31a	DO-35	Z-Diode 7,5V	31a	
1 N 5237		Z-Di	=1N5221: 8,2V	31a	DO-35	Z-Diode 8,2V	31a	
1 N 5238		Z-Di	=1N5221: 8,7V	31a	DO-35	Z-Diode 8,2V	31a	
1 N 5239		Z-Di	=1N5221: 9,1V	31a	DO-35	Z-Diode 9,1V	31a	
1 N 5240		Z-Di	=1N5221: 10V	31a	DO-35	Z-Diode 10V	31a	
1 N 5241		Z-Di	=1N5221: 11V	31a	DO-35	Z-Diode 11V	31a	
1 N 5242		Z-Di	=1N5221: 12V	31a	DO-35	Z-Diode 12V	31a	
1 N 5243		Z-Di	=1N5221: 13V	31a	DO-35	Z-Diode 13V	31a	
1 N 5244		Z-Di	=1N5221: 14V	31a	DO-35	Z-Diode 13V	31a	
1 N 5245		Z-Di	=1N5221: 15V	31a	DO-35	Z-Diode 15V	31a	
1 N 5246		Z-Di	=1N5221: 16V	31a	DO-35	Z-Diode 16V	31a	
1 N 5247		Z-Di	=1N5221: 17V	31a	DO-35	Z-Diode 18V	31a	
1 N 5248		Z-Di	=1N5221: 18V	31a	DO-35	Z-Diode 18V	31a	
1 N 5249		Z-Di	=1N5221: 19V	31a	DO-35	Z-Diode 20V	31a	
1 N 5250		Z-Di	=1N5221: 20V	31a	DO-35	Z-Diode 20V	31a	
1 N 5251		Z-Di	=1N5221: 22V	31a	DO-35	Z-Diode 22V	31a	
1 N 5252		Z-Di	=1N5221: 24V	31a	DO-35	Z-Diode 24V	31a	
1 N 5253		Z-Di	=1N5221: 25V	31a	DO-35	Z-Diode 24V	31a	
1 N 5254		Z-Di	=1N5221: 27V	31a	DO-35	Z-Diode 27V	31a	
1 N 5255		Z-Di	=1N5221: 28V	31a	DO-35	Z-Diode 27V	31a	
1 N 5256		Z-Di	=1N5221: 30V	31a	DO-35	Z-Diode 30V	31a	
1 N 5257		Z-Di	=1N5221: 33V	31a	DO-35	Z-Diode 33V	31a	
1 N 5258		Z-Di	=1N5221: 36V	31a	DO-35	Z-Diode 36V	31a	
1 N 5259		Z-Di	=1N5221: 39V	31a	DO-35	Z-Diode 39V	31a	
1 N 5260		Z-Di	=1N5221: 43V	31a	DO-35	Z-Diode 43V	31a	
1 N 5261		Z-Di	=1N5221: 47V	31a	DO-35	Z-Diode 47V	31a	
1 N 5262		Z-Di	=1N5221: 51V	31a	DO-35	Z-Diode 51V	31a	
1 N 5263		Z-Di	=1N5221: 56V	31a	DO-35	Z-Diode 56V	31a	
1 N 5264		Z-Di	=1N5221: 60V	31a	DO-35	Z-Diode 62V	31a	
1 N 5265		Z-Di	=1N5221: 62V	31a	DO-35	Z-Diode 62V	31a	
1 N 5266		Z-Di	=1N5221: 68V	31a	DO-35	Z-Diode 68V	31a	
1 N 5267		Z-Di	=1N5221: 75V	31a	DO-35	Z-Diode 75V	31a	
1 N 5268		Z-Di	=1N5221: 82V	31a	DO-35	Z-Diode 82V	31a	
1 N 5269		Z-Di	=1N5221: 87V	31a	DO-35	Z-Diode 91V	31a	
1 N 5270		Z-Di	=1N5221: 91V	31a	DO-35	Z-Diode 91V	31a	
1 N 5271		Z-Di	=1N5221: 100V	31a	DO-35	Z-Diode 100V	31a	
1 N 5272		Z-Di	=1N5221: 110V	31a	DO-35	Z-Diode 110V	31a	
1 N 5273		Z-Di	=1N5221: 120V	31a	DO-35	Z-Diode 120V	31a	
1 N 5274		Z-Di	=1N5221: 130V	31a	DO-35	Z-Diode 130V	31a	
1 N 5275		Z-Di	=1N5221: 140V	31a	DO-35	Z-Diode 150V	31a	
1 N 5276		Z-Di	=1N5221: 150V	31a	DO-35	Z-Diode 150V	31a	
1 N 5277		Z-Di	=1N5221: 160V	31a	DO-35	Z-Diode 160V	31a	
1 N 5278		Z-Di	=1N5221: 170V	31a	DO-35	Z-Diode 180V	31a	
1 N 5279		Z-Di	=1N5221: 180V	31a	DO-35	Z-Diode 180V	31a	
1 N 5280		Z-Di	=1N5221: 190V	31a	DO-35	Z-Diode 200V	31a	
1 N 5281		Z-Di	=1N5221: 200V	31a	DO-35	Z-Diode 200V	31a	
1 N 5221A...5281A		Z-Di	=1N5221...5281: 10%	31a	DO-35	Z-DiodeV	31a	
1 N 5221B...5281B		Z-Di	=1N5221...5281: 5%	31a	DO-35	Z-DiodeV	31a	
1 N 5282(A)	USA	Si-Di	SS, 80V, 0,2A, <4ns	31a	DO-35		BAW 62, BAW 76, BAX 95, 1N4148...49, ++	
1 N 5283...5314	USA, Mot	Si-Di	FED, Strom-Stabi/Current Regulation	31a	DO-7		-	
1 N 5315	Msc, Sem	Si-Di	SS, 100V, 0,2A, <4ns	31a	DO-34		BAW 62, BAW 76, BAX 95, 1N4148...49, ++	
1 N 5316	Msc, Sem	Si-Di	SS, 100V, 0,135A, <4ns	31a	DO-34		BAW 62, BAW 76, BAX 95, 1N4148...49, ++	

Original	Fabric.	Constr.	Info	{Compl. Fig.	JAEGER	Fig.	International
1 N 5317	Fch,Msc,Sem	Si-Di	SS, 80V, 0,125A, <4ns	31a	DO-34		BAW 62, BAW 76, BAX 95, 1N4148...49, ++
1 N 5318	Fch,Msc,Sem	Si-Di	SS, 75V, 0,125A, <4ns	31a	DO-34		BAW 62, BAW 76, BAX 95, 1N4148...49, ++
1 N 5319	Fch,Msc,Sem	Si-Di	SS, 40V, 0,1A, <4ns	31a	DO-34		BAW 62, BAW 76, BAX 95, 1N4148...49, ++
1 N 5320	USA	Si-Di	S, 120V, 1A, <250ns	31a	SOD-17		BY 201/2, BY 296...299, BYX 58/200, ++
1 N 5321	Sol	Si-Di	Schottky, 30V, Uf<1V(50mA)	31a	DO-35		-
1 N 5322	Sol	Si-Di	Schottky, 30V, Uf<1V(35mA)	31a	DO-35		-
1 N 5323	Sol	Si-Di	Schottky, 20V, Uf<1V(35mA)	31a	DO-35		-
1 N 5324	USA	Si-Di	kV-Rr, 15k, 0,01A	31a	(38x13mm0)		HS 10
1 N 5326	Trw	Si-Di	Rr, 200V, 12A	31a	(5x13mm0)		-
1 N 5329	Sem	Si-Di	kV-Rr, 6kV, 0,135A	31a	(16x10mm0)		BYX 90, 1N5183
1 N 5330	Sem	Si-Di	Rr, 1500V, 0,54A	31a	(13x5mm0)		BY 269, DM 513, EM 516, GP 10W, ++
1 N 5331	USA,Gen	Si-Di	P Rr, 1200V, 12A(Tc=150°), Uf<0,55V(12A, 150°)	32a	DO-4		BYW 88/1200, 1N4511
1 N 5332	USA,Gen	Si-Di	P Rr, 1200V, 35A(Tc=140°), Uf<1,7V(35A, 140°)	32a	DO-5		1N4530
1 N 5333	USA,Mot,Sie	Z-Di	3,3V, 20%, 5W	31a	-DO-27		BZV 40/..., BZV 48/...
1 N 5334		Z-Di	=1N5333: 3,6V	31a	-DO-27		
1 N 5335		Z-Di	=1N5333: 3,9V	31a	-DO-27		
1 N 5336		Z-Di	=1N5333: 4,3V	31a	-DO-27		
1 N 5337		Z-Di	=1N5333: 4,7V	31a	-DO-27		
1 N 5338		Z-Di	=1N5333: 5,1V	31a	-DO-27		
1 N 5339		Z-Di	=1N5333: 5,6V	31a	-DO-27		
1 N 5340		Z-Di	=1N5333: 6V	31a	-DO-27		
1 N 5341		Z-Di	=1N5333: 6,2V	31a	-DO-27		
1 N 5342		Z-Di	=1N5333: 6,8V	31a	-DO-27		
1 N 5343		Z-Di	=1N5333: 7,5V	31a	-DO-27		
1 N 5344		Z-Di	=1N5333: 8,2V	31a	-DO-27		
1 N 5345		Z-Di	=1N5333: 8,7V	31a	-DO-27		
1 N 5346		Z-Di	=1N5333: 9,1V	31a	-DO-27		
1 N 5347		Z-Di	=1N5333: 10V	31a	-DO-27		
1 N 5348		Z-Di	=1N5333: 11V	31a	-DO-27		
1 N 5349		Z-Di	=1N5333: 12V	31a	-DO-27		
1 N 5350		Z-Di	=1N5333: 13V	31a	-DO-27		
1 N 5351		Z-Di	=1N5333: 14V	31a	-DO-27		
1 N 5352		Z-Di	=1N5333: 15V	31a	-DO-27		
1 N 5353		Z-Di	=1N5333: 16V	31a	-DO-27		
1 N 5354		Z-Di	=1N5333: 17V	31a	-DO-27		
1 N 5355		Z-Di	=1N5333: 18V	31a	-DO-27		
1 N 5356		Z-Di	=1N5333: 19V	31a	-DO-27		
1 N 5357		Z-Di	=1N5333: 20V	31a	-DO-27		
1 N 5358		Z-Di	=1N5333: 22V	31a	-DO-27		
1 N 5359		Z-Di	=1N5333: 24V	31a	-DO-27		
1 N 5360		Z-Di	=1N5333: 25V	31a	-DO-29		
1 N 5361		Z-Di	=1N5333: 27V	31a	-DO-27		
1 N 5362		Z-Di	=1N5333: 28V	31a	-DO-27		
1 N 5363		Z-Di	=1N5333: 30V	31a	-DO-27		
1 N 5364		Z-Di	=1N5333: 33V	31a	-DO-27		
1 N 5365		Z-Di	=1N5333: 36V	31a	-DO-27		
1 N 5366		Z-Di	=1N5333: 39V	31a	-DO-27		
1 N 5367		Z-Di	=1N5333: 43V	31a	-DO-27		
1 N 5368		Z-Di	=1N5333: 47V	31a	-DO-27		
1 N 5369		Z-Di	=1N5333: 51V	31a	-DO-27		
1 N 5370		Z-Di	=1N5333: 56V	31a	-DO-27		
1 N 5371		Z-Di	=1N5333: 60V	31a	-DO-27		
1 N 5372		Z-Di	=1N5333: 62V	31a	-DO-27		
1 N 5373		Z-Di	=1N5333: 68V	31a	-DO-27		
1 N 5374		Z-Di	=1N5333: 75V	31a	-DO-27		
1 N 5375		Z-Di	=1N5333: 82V	31a	-DO-27		
1 N 5376		Z-Di	=1N5333: 87V	31a	-DO-27		
1 N 5377		Z-Di	=1N5333: 91V	31a	-DO-27		
1 N 5378		Z-Di	=1N5333: 100V	31a	-DO-27		
1 N 5379		Z-Di	=1N5333: 110V	31a	-DO-27		
1 N 5380		Z-Di	=1N5333: 120V	31a	-DO-27		
1 N 5381		Z-Di	=1N5333: 130V	31a	-DO-27		
1 N 5382		Z-Di	=1N5333: 140V	31a	-DO-27		
1 N 5383		Z-Di	=1N5333: 150V	31a	-DO-27		
1 N 5384		Z-Di	=1N5333: 160V	31a	-DO-27		
1 N 5385		Z-Di	=1N5333: 170V	31a	-DO-27		
1 N 5386		Z-Di	=1N5333: 180V	31a	-DO-27		
1 N 5387		Z-Di	=1N5333: 190V	31a	-DO-27		
1 N 5388		Z-Di	=1N5333: 200V	31a	-DO-27		
1 N 5333A...5388A		Z-Di	=1N5333...5388: 10%	31a	-DO-27		
1 N 5333B...5388B		Z-Di	=1N5333...5388: 5%	31a	-DO-27		
1 N 5389	Edi	Si-Di	kV-Rr, 40kV, Uf<80V(0,1A), 200ns	31a			-
1 N 5390	Fch,Tho	Si-Di	Schottky, 5V, Uf<0,55V(10mA)	31a	DO-7		-
1 N 5391(A)	USA,Mot,Tho	Si-Di	Rr, 50V, 1,5A, Uf<1,4V(1,5A, 70°), 2µs	31a	DO-15		BY 251...255, BY 226...227, BYW 52...56, ++
1 N 5392(A)		Si-Di	=1N5391: 100V	31a	DO-15		BY 251...255, BY 226...227, BYW 52...56, ++
1 N 5393(A)		Si-Di	=1N5391: 200V	31a	DO-15		BY 251...255, BY 226...227, BYW 52...56, ++
1 N 5394(A)		Si-Di	=1N5391: 300V	31a	DO-15		BY 252...255, BY 226...227, BYW 53...56, ++
1 N 5395(A)		Si-Di	=1N5391: 400V	31a	DO-15		BY 252...255, BY 226...227, BYW 53...56, ++
1 N 5396(A)		Si-Di	=1N5391: 500V	31a	DO-15		BY 253...255, BY 226...227, BYW 54...56, ++
1 N 5397(A)		Si-Di	=1N5391: 600V	31a	DO-15		BY 253...255, BY 226...227, BYW 54...56, ++
1 N 5398(A)		Si-Di	=1N5391: 800V	31a	DO-15		BY 254...255, BY 227, BYW 55...56, ++
1 N 5399(A)		Si-Di	=1N5391: 1000V	31a	DO-15		BY 255, BY 227, BYW 56, GP 15M, ++
1 N 5400(K)	USA,Mot,Tho	Si-Di	Rr, 50V, 3A, Uf<1,2V(9,4A), 5µs, K: DO-15	31a	DO-27A	BY 255	BY 251...255, BYW 17/100, BYW 82, ++
1 N 5401(K)		Si-Di	=1N5400: 100V	31a	DO-27A	BY 255	BY 251...255, BYW 17/100, BYW 82, ++
1 N 5402(K)		Si-Di	=1N5400: 200V	31a	DO-27A	BY 255	BY 251...255, BYW 17/200, BYW 82, ++
1 N 5403(K)		Si-Di	=1N5400: 300V	31a	DO-27A	BY 255	BY 252...255, BYW 17/400, BYW 83, ++
1 N 5404(K)		Si-Di	=1N5400: 400V	31a	DO-27A	BY 255	BY 252...255, BYW 17/400, BYW 83, ++
1 N 5405(K)		Si-Di	=1N5400: 500V	31a	DO-27A	BY 255	BY 253...255, BYW 17/600, BYW 84, ++
1 N 5406(K)		Si-Di	=1N5400: 600V	31a	DO-27A	BY 255	BY 253...255, BYW 17/600, BYW 84, ++
1 N 5407(K)		Si-Di	=1N5400: 800V	31a	DO-27A	BY 255	BY 254...255, BYW 17/800, BYW 85, ++
1 N 5408(K)		Si-Di	=1N5400: 1000V	31a	DO-27A	BY 255	BY 255, BYW 17/1000, BYW 86, ++
1 N 5409	USA	Si-Di	P Rr, 300V, 40A(Tc=100°), Uf<1,2V(40A, 100°)	32a	DO-5		BYX 97/300
1 N 5410	USA	Si-Di	P Rr, 300V, 12A(Tc=100°), Uf<1V(12A, 100°)	32a	DO-4		BYW 88/300, BYX 78...81, 1N4507...11, ++

Original	Fabric.	Constr.	Info	{Compl. Fig.	JAEGER	Fig.	International	
1 N 5411	Rca	Diac	Ub=29...35V, Ib<0,05mA, Itsm=2A	31I	DO-26	BR 100	31	1N5761, N413M, BR 100, D3202Y, D0201YR
1 N 5412	Hit,Msc,Sem	Si-Di	SS, 40V, 0,2A, <2ns	31a	DO-35			BAW 62, BAW 76, BAX 95, 1N4148...49, ++
1 N 5413	Hit,Msc,Sem	Si-Di	SS, 80V, 0,2A, <2ns	31a	DO-35			BAW 62, BAW 76, BAX 95, 1N4148...49, ++
1 N 5414	Hit,Msc,Sem	Si-Di	SS, 100V, 0,2A, <2ns	31a	DO-35			BAW 62, BAW 76, BAX 95, 1N4148...49, ++
1 N 5415	USA,Gie,Tho	Si-Di	FRr, 50V, 3A, Uf<1,1V(3A), <150ns	31a	SOD-64			BYW 16/100, BYW 72...78, RGP 30A, ++
1 N 5416		Si-Di	=1N5415: 100V	31a	SOD-64			BYW 16/100, BYW 72...78, RGP 30B, ++
1 N 5417		Si-Di	=1N5415: 200V	31a	SOD-64			BYW 16/200, BYW 72...78, RGP 30D, ++
1 N 5418		Si-Di	=1N5415: 400V	31a	SOD-64			BYW 16/400, BYW 74...78, RGP 30G, ++
1 N 5419		Si-Di	=1N5415: 500V, <250ns	31a	SOD-64			BYW 16/600, BYW 76...78, RGP 30K, ++
1 N 5420		Si-Di	=1N5415: 600V, <400ns	31a	SOD-64			BYW 16/600, BYW 76...78, RGP 30K, ++
1 N 5421	Cod,Miv	Si-Di	VHF Tuning, 200V	31a	(8x8x4mm)			-
1 N 5422	Cod,Miv	Si-Di	VHF Tuning, 200V	31a	(8x8x4mm)			-
1 N 5423	Cod,Miv	Si-Di	VHF Tuning, 200V	31a	(8x8x4mm)			-
1 N 5424	Cod,Miv	Si-Di	VHF Tuning, 100V	31a	(8x8x4mm)			-
1 N 5425	Cod,Miv	Si-Di	VHF Tuning, 100V	31a	(8x8x4mm)			-
1 N 5426	Miv	Si-Di	25V					-
1 N 5427	Fch	Si-Di	SS, RadH, 75V, <4ns	31a	DO-7			-
1 N 5428	Fch	Si-Di	S, RadH, 200V, <50ns	31a	DO-7			-
1 N 5429	Fch	Si-Di	RadH, 200V	31a	DO-7			-
1 N 5430	Fch	Si-Di	SS, RadH, 75V, <4ns	31a	DO-7			-
1 N 5431	FCh	Si-Di	SS, RadH, 80V, <4ns	31a	DO-35			-
1 N 5432	Fch	Si-Di	SS, RadH, 20V, <0.75ns	31a	DO-7			-
1 N 5433	Ssi,Trw	Si-Di	FRr, 720V, 2mA, Uf<1,2V(2m), <400ns	31a	SOD-51			BA 158...159, BY 204/8, BY 203/12, ++
1 N 5434	Ssi,Trw	Si-Di	FRr, 720V, 2mA, Uf<1,1V(2mA), <400ns	31a	SOD-51			BA 158...159, BY 204/8, BY 203/12, ++
1 N 5435	Ssi,Trw	Si-Di	P FRr, 720V, 12A(Tc=25°), Uf<1,1V(12A)	31a				-
1 N 5436	Miv,Slid	Si-Di	UHF, Ku-Band Mx, 16GHz	Koax	DO-37			-
1 N 5437	Miv,Slid	Si-Di	UHF, Ku-Band Mx, 16GHz	Koax	DO-37			-
1 N 5438	Miv,Slid	Si-Di	UHF, Ku-Band Mx, 16GHz	Koax	DO-37			-
1 N 5441(A....D)	Mot,Tho,++	Si-Di	FM/VHF AFC/Tuning	31a	DO-7			-
1 N 5442(A....D)	Mot,Tho,++	Si-Di	FM/VHF AFC/Tuning	31a	DO-7			-
1 N 5443(A....D)	Mot,Tho,++	Si-Di	FM/VHF AFC/Tuning	31a	DO-7			-
1 N 5444(A....D)	Mot,Tho,++	Si-Di	FM/VHF AFC/Tuning	31a	DO-7			-
1 N 5445(A....D)	Mot,Tho,++	Si-Di	FM/VHF AFC/Tuning	31a	DO-7			-
1 N 5446(A....D)	Mot,Tho,++	Si-Di	FM/VHF AFC/Tuning	31a	DO-7			-
1 N 5447(A....D)	Mot,Tho,++	Si-Di	FM/VHF AFC/Tuning	31a	DO-7			-
1 N 5448(A....D)	Mot,Tho,++	Si-Di	FM/VHF AFC/Tuning	31a	DO-7			-
1 N 5449(A....D)	Mot,Tho,++	Si-Di	FM/VHF AFC/Tuning	31a	DO-7			-
1 N 5450(A....D)	Mot,Tho,++	Si-Di	FM/VHF AFC/Tuning	31a	DO-7			-
1 N 5451(A....D)	Mot,Tho,++	Si-Di	FM/VHF AFC/Tuning	31a	DO-7			-
1 N 5452(A....D)	Mot,Tho,++	Si-Di	FM/VHF AFC/Tuning	31a	DO-7			-
1 N 5453(A....D)	Mot,Tho,++	Si-Di	FM/VHF AFC/Tuning	31a	DO-7			-
1 N 5454(A....D)	Mot,Tho,++	Si-Di	FM/VHF AFC/Tuning	31a	DO-7			-
1 N 5455(A....D)	Mot,Tho,++	Si-Di	FM/VHF AFC/Tuning	31a	DO-7			-
1 N 5456(A....D)	Mot,Tho,++	Si-Di	FM/VHF AFC/Tuning	31a	DO-7			-
1 N 5461(A....D)	Mot,Miv,Tdy	Si-Di	FM...UHF AFC/Tuning	31a	DO-7			-
1 N 5462(A....D)	Mot,Miv,Tdy	Si-Di	FM...UHF AFC/Tuning	31a	DO-7			-
1 N 5463(A....D)	Mot,Miv,Tdy	Si-Di	FM...UHF AFC/Tuning	31a	DO-7			-
1 N 5464(A....D)	Mot,Miv,Tdy	Si-Di	FM...UHF AFC/Tuning	31a	DO-7			-
1 N 5465(A....D)	Mot,Miv,Tdy	Si-Di	FM...UHF AFC/Tuning	31a	DO-7			-
1 N 5466(A....D)	Mot,Miv,Tdy	Si-Di	FM...UHF AFC/Tuning	31a	DO-7			-
1 N 5467(A....D)	Mot,Miv,Tdy	Si-Di	FM...UHF AFC/Tuning	31a	DO-7			-
1 N 5468(A....D)	Mot,Miv,Tdy	Si-Di	FM...UHF AFC/Tuning	31a	DO-7			-
1 N 5469(A....D)	Mot,Miv,Tdy	Si-Di	FM...UHF AFC/Tuning	31a	DO-7			-
1 N 5470(A....D)	Mot,Miv,Tdy	Si-Di	FM...UHF AFC/Tuning	31a	DO-7			-
1 N 5471(A....D)	Mot,Miv,Tdy	Si-Di	FM...UHF AFC/Tuning	31a	DO-7			-
1 N 5472(A....D)	Mot,Miv,Tdy	Si-Di	FM...UHF AFC/Tuning	31a	DO-7			-
1 N 5473(A....D)	Mot,Miv,Tdy	Si-Di	FM...UHF AFC/Tuning	31a	DO-7			-
1 N 5474(A....D)	Mot,Miv,Tdy	Si-Di	FM...UHF AFC/Tuning	31a	DO-7			-
1 N 5475(A....D)	Mot,Miv,Tdy	Si-Di	FM...UHF AFC/Tuning	31a	DO-7			-
1 N 5476(A....D)	Mot,Miv,Tdy	Si-Di	FM...UHF AFC/Tuning	31a	DO-7			-
1 N 5477	USA	Si-Di	kV-Rr, 6kV, 0,6A					-
1 N 5478	USA	Si-Di	=1N5477: 7,2kV					-
1 N 5479	USA	Si-Di	=1N5477: 8,4kV					-
1 N 5480	USA	Si-Di	=1N5477: 9,6kV					-
1 N 5481	USA	Si-Di	=1N5477: 12kV					-
1 N 5482	USA	Si-Di	kV-Rr, 2,4kV, 1A	31a				-
1 N 5483	USA	Si-Di	=1N5482: 3,6kV	31a				-
1 N 5484	USA	Si-Di	=1N5482: 4,8kV	31a				-
1 N 5485	USA	Si-Di	=1N5482: 6kV	31a				-
1 N 5518	USA,Mot	Z-Di	3,3V, 20%, 0,4W	31a	DO-7			BZX55/..., BZX55/..., ZPD..., 1N5226...57, ++
1 N 5519		Z-Di	=1N5518: 3,6V	31a	DO-7			
1 N 5520		Z-Di	=1N5518: 3,9V	31a	DO-7			
1 N 5521		Z-Di	=1N5518: 4,3V	31a	DO-7			
1 N 5522		Z-Di	=1N5518: 4,7V	31a	DO-7			
1 N 5523		Z-Di	=1N5518: 5,1V	31a	DO-7			
1 N 5524		Z-Di	=1N5518: 5,6V	31a	DO-7			
1 N 5525		Z-Di	=1N5518: 6,2V	31a	DO-7			
1 N 5526		Z-Di	=1N5518: 6,8V	31a	DO-7			
1 N 5527		Z-Di	=1N5518: 7,5V	31a	DO-7			
1 N 5528		Z-Di	=1N5518: 8,2V	31a	DO-7			
1 N 5529		Z-Di	=1N5518: 9,1V	31a	DO-7			
1 N 5530		Z-Di	=1N5518: 10V	31a	DO-7			
1 N 5531		Z-Di	=1N5518: 11V	31a	DO-7			
1 N 5532		Z-Di	=1N5518: 12V	31a	DO-7			
1 N 5533		Z-Di	=1N5518: 13V	31a	DO-7			
1 N 5534		Z-Di	=1N5518: 14V	31a	DO-7			
1 N 5535		Z-Di	=1N5518: 15V	31a	DO-7			
1 N 5536		Z-Di	=1N5518: 16V	31a	DO-7			
1 N 5537		Z-Di	=1N5518: 17V	31a	DO-7			
1 N 5538		Z-Di	=1N5518: 18V	31a	DO-7			
1 N 5539		Z-Di	=1N5518: 19V	31a	DO-7			
1 N 5540		Z-Di	=1N5518: 20V	31a	DO-7			
1 N 5541		Z-Di	=1N5518: 22V	31a	DO-7			

Original	Fabric.	Constr.	Info	(Compl. Fig.	JAEGER	Fig.	International
1 N 5542		Z-Di	=1N5518: 24V	31a		DO-7	
1 N 5543		Z-Di	=1N5518: 25V	31a		DO-7	
1 N 5544		Z-Di	=1N5518: 28V	31a		DO-7	
1 N 5545		Z-Di	=1N5518: 30V	31a		DO-7	
1 N 5546		Z-Di	=1N5518: 33V	31a		DO-7	
1 N 5510A...5546A		Z-Di	=1N5518...5546: 10%	31a		DO-7	
1 N 5510B...5546B		Z-Di	=1N5518...5546: 5%	31a		DO-7	
1 N 5510C...5546C		Z-Di	=1N5518...5546: 2%	31a		DO-7	
1 N 5510D...5546D		Z-Di	=1N5518...5546: 1%	31a		DO-7	
1 N 5550	USA,Gie	Si-Di	FRr, 200V, 3A, Uf<1V(3A), <2µs	31a		SOD-64	BY 251...255, BYW 17/200, BYW 82...86, ++
1 N 5551		Si-Di	=1N5550: 400V	31a		SOD-64	BY 252...255, BYW 17/400, BYW 83...86, ++
1 N 5552		Si-Di	=1N5550: 600V	31a		SOD-64	BY 253...255, BYW 17/600, BYW 84...86, ++
1 N 5553		Si-Di	=1N5550: 800V	31a		SOD-64	BY 254...255, BYW 17/800, BYW 85...86, ++
1 N 5554		Si-Di	=1N5550: 1000V	31a		SOD-64	BY 255, BYW 17/1000, BYW 86, 1N5408, ++
1 N 5555	USA,Sie	Z-Di	TAZ, 33V, 1,5kW(1ms)	34a		DO-13	1N5645
1 N 5556		Z-Di	=1N5555: 43,7V	34a		DO-13	1N5648
1 N 5557		Z-Di	=1N5555: 54V	34a		DO-13	1N5651
1 N 5558		Z-Di	=1N5555: 191V	34a		DO-13	1N5664
1 N 5559	USA	Z-Di	6,8V, 20%, 1W	31a		SOD-17	BZW22/..., BZX61/..., ZPY..., 1N5921...56,++
1 N 5560		Z-Di	=1N5559: 7,5V	31a		SOD-17	
1 N 5561		Z-Di	=1N5559: 8,2V	31a		SOD-17	
1 N 5562		Z-Di	=1N5559: 9,1V	31a		SOD-17	
1 N 5563		Z-Di	=1N5559: 10V	31a		SOD-17	
1 N 5564		Z-Di	=1N5559: 11V	31a		SOD-17	
1 N 5565		Z-Di	=1N5559: 12V	31a		SOD-17	
1 N 5566		Z-Di	=1N5559: 13V	31a		SOD-17	
1 N 5567		Z-Di	=1N5559: 15V	31a		SOD-17	
1 N 5568		Z-Di	=1N5559: 16V	31a		SOD-17	
1 N 5569		Z-Di	=1N5559: 18V	31a		SOD-17	
1 N 5570		Z-Di	=1N5559: 20V	31a		SOD-17	
1 N 5571		Z-Di	=1N5559: 22V	31a		SOD-17	
1 N 5572		Z-Di	=1N5559: 24V	31a		SOD-17	
1 N 5573		Z-Di	=1N5559: 27V	31a		SOD-17	
1 N 5574		Z-Di	=1N5559: 30V	31a		SOD-17	
1 N 5575		Z-Di	=1N5559: 33V	31a		SOD-17	
1 N 5576		Z-Di	=1N5559: 36V	31a		SOD-17	
1 N 5577		Z-Di	=1N5559: 39V	31a		SOD-17	
1 N 5578		Z-Di	=1N5559: 43V	31a		SOD-17	
1 N 5579		Z-Di	=1N5559: 47V	31a		SOD-17	
1 N 5580		Z-Di	=1N5559: 51V	31a		SOD-17	
1 N 5581		Z-Di	=1N5559: 56V	31a		SOD-17	
1 N 5582		Z-Di	=1N5559: 62V	31a		SOD-17	
1 N 5583		Z-Di	=1N5559: 68V	31a		SOD-17	
1 N 5584		Z-Di	=1N5559: 75V	31a		SOD-17	
1 N 5585		Z-Di	=1N5559: 82V	31a		SOD-17	
1 N 5586		Z-Di	=1N5559: 91V	31a		SOD-17	
1 N 5587		Z-Di	=1N5559: 100V	31a		SOD-17	
1 N 5588		Z-Di	=1N5559: 110V	31a		SOD-17	
1 N 5589		Z-Di	=1N5559: 120V	31a		SOD-17	
1 N 5590		Z-Di	=1N5559: 130V	31a		SOD-17	
1 N 5591		Z-Di	=1N5559: 150V	31a		SOD-17	
1 N 5592		Z-Di	=1N5559: 160V	31a		SOD-17	
1 N 5593		Z-Di	=1N5559: 180V	31a		SOD-17	
1 N 5594		Z-Di	=1N5559: 200V	31a		SOD-17	
1 N 5559A...5594A		Z-Di	=1N5559...5594: 10%	31a		SOD-17	
1 N 5559B...5594B		Z-Di	=1N5559...5594: 5%	31a		SOD-17	
1 N 5595	USA	Si-Di	KV-Rr, 5kV, 1,15A				-
1 N 5596	USA	Si-Di	KV-Rr, 7,5kV, 0,87A				-
1 N 5597	USA	Si-Di	KV-Rr, 10kV, 0,7A				-
1 N 5598	USA	Si-Di	KV-Rr, 15kV, 0,47A				-
1 N 5599	USA	Si-Di	KV-Rr, 2,5kV, 2,1A				-
1 N 5600	USA	Si-Di	KV-Rr, 5kV, 1,4A				-
1 N 5601	USA	Si-Di	KV-Rr, 7,5kV, 0,92A				-
1 N 5602	USA	Si-Di	KV-Rr, 2,5kV, 4,6A				-
1 N 5603	USA	Si-Di	KV-Rr, 5kV, 3,5A				-
1 N 5604	USA	Si-Di	KV-Rr, 7,5kV, 2,3A				-
1 N 5605	USA,Itt	Si-Di	Uni, 70V	31a		DO-35	BA 188...190, BAY 19...21, BAY 45...46, ++
1 N 5606	USA,Itt	Si-Di	Uni, 150V, 0,1A	31a		DO-35	BA 189...190, BAY 20...21, BAY 45...46, ++
1 N 5607	USA,Itt	Si-Di	Uni, 200V, 0,15A	31a		DO-35	BA 190, BAW 52, BAY 21, BAY 46, ++
1 N 5608	USA,Hit,Itt	Si-Di	S, 120V, 0,15A, <300ns	31a		DO-35	BA 157...159, BAV 19...21, BAX 15...17, ++
1 N 5609	USA,Hit,Itt	Si-Di	S, 120V, 0,15A, <300ns	31a		DO-35	BA 157...159, BAV 19...21, BAX 15...17, ++
1 N 5610	Uni	Z-Di	=1N5555:	31a		SOD-64	+1N5555
1 N 5611	Uni	Z-Di	=1N5556:	31a		SOD-64	+1N5556
1 N 5612	Uni	Z-Di	=1N5557:	31a		SOD-64	+1N5557
1 N 5613		Z-Di	=1N5558:	31a			+1N5558
1 N 5614	USA,Sie,Tho	Si-Di	Rr, 200V, 1A, Uf<1,2V(1A), <2µs	31a		SOD-57	BY 126...127, BY 133...134, 1N4003...07, ++
1 N 5615	USA,Sie,Tho	Si-Di	FRr, 200V, 1A, Uf<1,2V(1A), <150ns	31a		SOD-57	BY 201/2, BYT 52D, BYX 92/200, ++
1 N 5616		Si-Di	=1N5614: 400V	31a		SOD-57	BY 126...127, BY 133...134, 1N4004...07, ++
1 N 5617		Si-Di	=1N5615: 400V	31a		SOD-57	BY 201/4, BYT 52G, BYX 92/400, ++
1 N 5618		Si-Di	=1N5614: 600V	31a		SOD-57	BY 126...127, BY 133...134, 1N4005...07, ++
1 N 5619		Si-Di	=1N5615: 600V	31a		SOD-57	BY 201/6, BYT 52J, RGP 10J, ++
1 N 5620		Si-Di	=1N5614: 800V	31a		SOD-57	BY 127, BY 133, BY 227, 1N4006...07, ++
1 N 5621		Si-Di	=1N5615: 800V	31a		SOD-57	BYV 15...16, BYT 52K, RGP 10K, ++
1 N 5622		Si-Di	=1N5614: 1000V	31a		SOD-57	BY 127, BY 133, BY 227, 1N4007, ++
1 N 5623		Si-Di	=1N5615: 1000V	31a		SOD-57	BYV 16, BYV 36E, BYT 52M, RGP 10M, ++
1 N 5624(GP)	USA,EUR,Nec	Si-Di	Rr, 200V, 5A, Uf<1V(3A), 3µs,	(GP: DO-27A) 31a		SOD-64	BY 500/200, MR 752...760, MR 822...826
1 N 5625(GP)		Si-Di	=1N5624: 400V	31a		SOD-64	BY 500/400, MR 754...760, MR 824...826
1 N 5626(GP)		Si-Di	=1N5624: 600V	31a		SOD-64	BY 500/600, MR 756...760, MR 826
1 N 5627(GP)		Si-Di	=1N5624: 800V	31a		SOD-64	BY 214/800, MR 758...760
1 N 5628	Gen	Si-Di	KV-Rr, 3kV, 500A, Uf<1,51(1500A)				-
1 N 5629(A)	USA,Sie,Tho	Z-Di	TAZ, 6,8V, 10%(A=5%), Pbr=1,5kW(1ms)	34a		DO-13	1N6267...6303,(1N6036...72, 1N6138...73)
1 N 5630(A)		Z-Di	=1N5629: 7,5V	34a		DO-13	
1 N 5631(A)		Z-Di	=1N5629: 8,2V	34a		DO-13	

Original	Fabric.	Constr.	Info	{Compl. Fig.	JAEGER	Fig.	International
1 N 5632(A)		Z-Di	=1N5629: 9,1V	34a		DO-13	
1 N 5633(A)		Z-Di	=1N5629: 10V	34a		DO-13	
1 N 5634(A)		Z-Di	=1N5629: 11V	34a		DO-13	
1 N 5635(A)		Z-Di	=1N5629: 12V	34a		DO-13	
1 N 5636(A)		Z-Di	=1N5629: 13V	34a		DO-13	
1 N 5637(A)		Z-Di	=1N5629: 15V	34a		DO-13	
1 N 5638(A)		Z-Di	=1N5629: 16V	34a		DO-13	
1 N 5639(A)		Z-Di	=1N5629: 18V	34a		DO-13	
1 N 5640(A)		Z-Di	=1N5629: 20V	34a		DO-13	
1 N 5641(A)		Z-Di	=1N5629: 22V	34a		DO-13	
1 N 5642(A)		Z-Di	=1N5629: 24V	34a		DO-13	
1 N 5643(A)		Z-Di	=1N5629: 27V	34a		DO-13	
1 N 5644(A)		Z-Di	=1N5629: 30V	34a		DO-13	
1 N 5645(A)		Z-Di	=1N5629: 33V	34a		DO-13	
1 N 5646(A)		Z-Di	=1N5629: 36V	34a		DO-13	
1 N 5647(A)		Z-Di	=1N5629: 39V	34a		DO-13	
1 N 5648(A)		Z-Di	=1N5629: 43V	34a		DO-13	
1 N 5649(A)		Z-Di	=1N5629: 47V	34a		DO-13	
1 N 5650(A)		Z-Di	=1N5629: 51V	34a		DO-13	
1 N 5651(A)		Z-Di	=1N5629: 56V	34a		DO-13	
1 N 5652(A)		Z-Di	=1N5629: 62V	34a		DO-13	
1 N 5653(A)		Z-Di	=1N5629: 68V	34a		DO-13	
1 N 5654(A)		Z-Di	=1N5629: 75V	34a		DO-13	
1 N 5655(A)		Z-Di	=1N5629: 82V	34a		DO-13	
1 N 5656(A)		Z-Di	=1N5629: 91V	34a		DO-13	
1 N 5657(A)		Z-Di	=1N5629: 100V	34a		DO-13	
1 N 5658(A)		Z-Di	=1N5629: 110V	34a		DO-13	
1 N 5659(A)		Z-Di	=1N5629: 120V	34a		DO-13	
1 N 5660(A)		Z-Di	=1N5629: 130V	34a		DO-13	
1 N 5661(A)		Z-Di	=1N5629: 150V	34a		DO-13	
1 N 5662(A)		Z-Di	=1N5629: 160V	34a		DO-13	
1 N 5663(A)		Z-Di	=1N5629: 170V	34a		DO-13	
1 N 5664(A)		Z-Di	=1N5629: 180V	34a		DO-13	
1 N 5665(A)		Z-Di	=1N5629: 200V	34a		DO-13	
1 N 5620P1...5665P1		Z-Di	=1N5629...5665:	31a		DO-27	
1 N 5666	Sie.Sty	Z-Di	1,6V, 20%, 0,25W	2		=TO-18	BZX55/..., BZX79/..., ZPD..., 1N5221...32,++
1 N 5667		Z-Di	=1N5666: 1,8V	2		=TO-18	
1 N 5668		Z-Di	=1N5666: 2V	2		=TO-18	
1 N 5669		Z-Di	=1N5666: 2,2V	2		=TO-18	
1 N 5670		Z-Di	=1N5666: 2,5V	2		=TO-18	
1 N 5671		Z-Di	=1N5666: 2,8V	2		=TO-18	
1 N 5672		Z-Di	=1N5666: 3,1V	2		=TO-18	
1 N 5673		Z-Di	=1N5666: 3,4V	2		=TO-18	
1 N 5674		Z-Di	=1N5666: 3,7V	2		=TO-18	
1 N 5675		Z-Di	=1N5666: 4,1V	2		=TO-18	
1 N 5676		Z-Di	=1N5666: 4,5V	2		=TO-18	
1 N 5677		Z-Di	=1N5666: 4,9V	2		=TO-18	
1 N 5678		Z-Di	=1N5666: 5,4V	2		=TO-18	
1 N 5666A...5678A		Z-Di	=1N5666...5678: 10%	2		=TO-18	
1 N 5679	Gie	Si-Di	Rr, 50V, 1A, U<1,1V(1A, 100°)	31a		DO-29	BY 126...127, BY 133...135, 1N4001...07, ++
1 N 5680		Si-Di	=1N5679: 100V	31a		DO-29	BY 126...127, BY 133...135, 1N4001...07, ++
1 N 5681(A,B)	Cod,Trw	Si-Di	VHF Tuning	31a		DO-7	-
1 N 5682(A,B)	Cod,Trw	Si-Di	VHF Tuning	31a		DO-7	-
1 N 5683(A,B)	Cod,Trw	Si-Di	VHF Tuning	31a		DO-7	-
1 N 5684(A,B)	Cod,Trw	Si-Di	VHF Tuning	31a		DO-7	-
1 N 5685(A,B)	Cod,Trw	Si-Di	VHF Tuning	31a		DO-7	-
1 N 5686(A,B)	Cod,Trw	Si-Di	VHF Tuning	31a		DO-7	-
1 N 5687(A,B)	Cod,Trw	Si-Di	VHF Tuning	31a		DO-7	-
1 N 5688(A,B)	Cod,Trw	Si-Di	VHF Tuning	31a		DO-7	-
1 N 5689(A,B)	Cod,Trw	Si-Di	VHF Tuning	31a		DO-7	-
1 N 5690(A,B)	Cod,Trw	Si-Di	VHF Tuning	31a		DO-7	-
1 N 5691(A,B)	Cod,Trw	Si-Di	VHF Tuning	31a		DO-7	-
1 N 5692(A,B)	Cod,Trw	Si-Di	VHF Tuning	31a		DO-7	-
1 N 5693(A,B)	Cod,Trw	Si-Di	VHF Tuning	31a		DO-7	-
1 N 5694(A,B)	Cod,Trw	Si-Di	VHF Tuning	31a		DO-7	-
1 N 5695(A,B)	Cod,Trw	Si-Di	VHF Tuning	31a		DO-7	-
1 N 5696(A,B)	Cod,Trw	Si-Di	VHF Tuning	31a		DO-7	-
1 N 5697(A,B)	Cod,Trw	Si-Di	VHF Tuning	31a		DO-7	-
1 N 5698(A,B)	Cod,Trw	Si-Di	VHF Tuning	31a		DO-7	-
1 N 5699(A,B)	Cod,Trw	Si-Di	VHF Tuning	31a		DO-7	-
1 N 5700(A,B)	Cod,Trw	Si-Di	VHF Tuning	31a		DO-7	-
1 N 5701(A,B)	Cod,Trw	Si-Di	VHF Tuning	31a		DO-7	-
1 N 5702(A,B)	Cod,Trw	Si-Di	VHF Tuning	31a		DO-7	-
1 N 5703(A,B)	Cod,Trw	Si-Di	VHF Tuning	31a		DO-7	-
1 N 5704(A,B)	Cod,Trw	Si-Di	VHF Tuning	31a		DO-7	-
1 N 5705(A,B)	Cod,Trw	Si-Di	VHF Tuning	31a		DO-7	-
1 N 5706(A,B)	Cod,Trw	Si-Di	VHF Tuning	31a		DO-7	-
1 N 5707(A,B)	Cod,Trw	Si-Di	VHF Tuning	31a		DO-7	-
1 N 5708(A,B)	Cod,Trw	Si-Di	VHF Tuning	31a		DO-7	-
1 N 5709(A,B)	Cod,Trw	Si-Di	VHF Tuning	31a		DO-7	-
1 N 5710(A,B)	Cod,Trw	Si-Di	VHF Tuning	31a		DO-7	-
1 N 5711	USA,Tho	Si-Di	Schottky, VHF/UHF Dem, 50/70V, 15mA, <2pF(0V)	31a		DO-35	BAR 28, HSS 102
1 N 5712	USA,Tho	Si-Di	Schottky, VHF/UHF Dem, 12/20V, 35mA, <1,2pF(0V)	31a		DO-35	BAR 10, 1S1992, 1SS101, 1SS109
1 N 5713	USA	Si-Di	Schottky, 12V, <1,2pF(0V)	31a		DO-7	-
1 N 5714	Tdy	Si-Di	VHF Tuning, 200V	31a		DO-27	-
1 N 5715	Tdy	Si-Di	VHF Tuning, 200V	31a		DO-27	-
1 N 5716	Tdy	Si-Di	VHF Tuning, 200V	31a		DO-27	-
1 N 5717	Tdy	Si-Di	VHF Tuning, 100V	31a		-	-
1 N 5718	Tdy	Si-Di	VHF Tuning, 100V	31a		-	-
1 N 5719	Hew,Mic	Si-Di	Uni, 100V	31a		DO-34	BA 188...190, BA 147/100, 1N5606...09, ++
1 N 5720	Itt,Hit	Si-Di	S, 30V, <10ns	31a		DO-35	BA 317, BAW 53, BAY 71, 1N4148...49, ++
1 N 5721	Itt,Hit	Si-Di	=1N5720: 15V	31a		DO-35	BA 317, BAW 53, BAY 71, 1N4148...49, ++
1 N 5726	Itt,Hit	Si-Di	S, 60V, <10ns	31a		DO-35	BAV 14, BAW 26...27

Original	Fabric.	Constr.	Info	{Compl. Fig.	JAEGER	Fig.	International
1 N 5727	Itt,Hit	Si-Di	=1N5726: 50V	31a	DO-35		BAV 14, BAW 24...27
1 N 5728	USA,Phi,Sie	Z-Di	4,7V, 0,4W	31a	DO-35	Z-Diode 4,7V	31a BZX55/..., BZX79/..., ZPD..., 1N5230...67,++
1 N 5729		Z-Di	=1N5728: 5,1V	31a	DO-35	Z-Diode 5,1V	31a
1 N 5730		Z-Di	=1N5728: 5,6V	31a	DO-35	Z-Diode 5,6V	31a
1 N 5731		Z-Di	=1N5728: 6,2V	31a	DO-35	Z-Diode 6,2V	31a
1 N 5732		Z-Di	=1N5728: 6,8V	31a	DO-35	Z-Diode 6,8V	31a
1 N 5733		Z-Di	=1N5728: 7,5V	31a	DO-35	Z-Diode 7,5V	31a
1 N 5734		Z-Di	=1N5728: 8,2V	31a	DO-35	Z-Diode 8,2V	31a
1 N 5735		Z-Di	=1N5728: 9,1V	31a	DO-35	Z-Diode 9,1V	31a
1 N 5736		Z-Di	=1N5728: 10V	31a	DO-35	Z-Diode 10V	31a
1 N 5737		Z-Di	=1N5728: 11V	31a	DO-35	Z-Diode 11V	31a
1 N 5738		Z-Di	=1N5728: 12V	31a	DO-35	Z-Diode 12V	31a
1 N 5739		Z-Di	=1N5728: 13V	31a	DO-35	Z-Diode 13V	31a
1 N 5740		Z-Di	=1N5728: 15V	31a	DO-35	Z-Diode 15V	31a
1 N 5741		Z-Di	=1N5728: 16V	31a	DO-35	Z-Diode 16V	31a
1 N 5742		Z-Di	=1N5728: 18V	31a	DO-35	Z-Diode 18V	31a
1 N 5743		Z-Di	=1N5728: 20V	31a	DO-35	Z-Diode 20V	31a
1 N 5744		Z-Di	=1N5728: 22V	31a	DO-35	Z-Diode 22V	31a
1 N 5745		Z-Di	=1N5728: 24V	31a	DO-35	Z-Diode 24V	31a
1 N 5746		Z-Di	=1N5728: 27V	31a	DO-35	Z-Diode 27V	31a
1 N 5747		Z-Di	=1N5728: 30V	31a	DO-35	Z-Diode 30V	31a
1 N 5748		Z-Di	=1N5728: 33V	31a	DO-35	Z-Diode 33V	31a
1 N 5749		Z-Di	=1N5728: 36V	31a	DO-35	Z-Diode 36V	31a
1 N 5750		Z-Di	=1N5728: 39V	31a	DO-35	Z-Diode 39V	31a
1 N 5751		Z-Di	=1N5728: 43V	31a	DO-35	Z-Diode 43V	31a
1 N 5752		Z-Di	=1N5728: 47V	31a	DO-35	Z-Diode 47V	31a
1 N 5753		Z-Di	=1N5728: 51V	31a	DO-35	Z-Diode 51V	31a
1 N 5754		Z-Di	=1N5728: 56V	31a	DO-35	Z-Diode 56V	31a
1 N 5755		Z-Di	=1N5728: 62V	31a	DO-35	Z-Diode 62V	31a
1 N 5756		Z-Di	=1N5728: 68V	31a	DO-35	Z-Diode 68V	31a
1 N 5757		Z-Di	=1N5728: 75V	31a	DO-35	Z-Diode 75V	31a
1 N 5728A...5757A		Z-Di	=1N5728...5757: 5%	31a	DO-35		
1 N 5728B...5757B		Z-Di	=1N5728...5757: 2%	31a	DO-35		
1 N 5728C...5757C		Z-Di	=1N5728...5757: 1%	31a	DO-35		
1 N 5758	Mot	Diac	Ub=16...24V, Ib<0,1mA, Itsm=2A	7I	TO-92		-
1 N 5758 A	Mot	Diac	Ub=18...22V, Ib<0,025mA, Itsm=2A	7I	TO-92		-
1 N 5759	Mot	Diac	Ub=20...28V, Ib<0,1mA, Itsm=2A	7I	TO-92		-
1 N 5759 A	Mot	Diac	Ub=22...26V, Ib<0,025mA, Itsm=2A	7I	TO-92		-
1 N 5760	Mot	Diac	Ub=24...32V, Ib<0,1mA, Itsm=2A	7I	TO-92		N 413L, D 3202U
1 N 5760 A	Mot	Diac	Ub=26...30V, Ib<0,025mA, Itsm=2A	7I	TO-92		(N 413L, D 3202U) ⁷
1 N 5761	Mot	Diac	Ub=28...36V, Ib<0,1mA, Itsm=2A	7I	TO-92	BR 100	31 N 413M, BR 100, D 3202Y, D 0201YR
1 N 5761 A	Mot	Diac	Ub=30...34V, Ib<0,025mA, Itsm=2A	7I	TO-92	(BR 100) ⁷	31 (N 413M, BR 100, D 3202Y, D 0201YR) ⁷
1 N 5762	Mot	Diac	Ub=32...40V, Ib<0,1mA, Itsm=2A	7I	TO-92		N 413N, D 3202U
1 N 5762 A	Mot	Diac	Ub=34...38V, Ib<0,025mA, Itsm=2A	7I	TO-92		(N 413N, D 3202U) ⁷
1 N 5763	Del	Si-Di	P Rr, 26V, 300A(Tc=100°), Uf<1,2V(300A)				-
1 N 5764	Miv	GaAs-Di	UHF, Ku-Band Mx	Koax	DO-37		-
1 N 5766	Sol	Si-Di	FRr, 110V, Uf<1,7V(30A), <400ns	32a	DO-5		1N4525...4530
1 N 5767	Uni	Si-Di	Uni, 100V	31a	DO-34		BA 147/100, BA 188...190, 1N5606...09, ++
1 N 5768	Fch	Si-Di	8-Di Logik-Gatter/Logic Gate, 60V, 0,3A, <20ns	10-FLP	TO-89		-
1 N 5770	Fch	Si-Di	8-Di Logik-Gatter/Logic Gate, 60V, 0,3A, <20ns	10-FLP	TO-89		-
1 N 5772	Fch	Si-Di	=1N5768: 16 Di	10-FLP	TO-89		-
1 N 5774	Fch	Si-Di	=1N5768: 16 Di	14-FLP	TO-86		-
1 N 5779	Mot	Trigger-Di	=1N5158: Ub=11...13V	31a	DO-7		-
1 N 5780	Mot	Trigger-Di	=1N5158: Ub=12...14V	31a	DO-7		-
1 N 5781	Mot	Trigger-Di	=1N5158: Ub=13...15V	31a	DO-7		-
1 N 5782	Mot	Trigger-Di	=1N5158: Ub=8...10V, Ib<0,1mA, lh=10...50mA	31a	DO-7		-
1 N 5783	Mot	Trigger-Di	=1N5158: Ub=9...11V, Ib<0,1mA, lh=10...50mA	31a	DO-7		-
1 N 5784	Mot	Trigger-Di	=1N5158: Ub=10...12V, Ib<0,1mA, lh=10...50mA	31a	DO-7		-
1 N 5785	Mot	Trigger-Di	=1N5158: Ub=11...13V, Ib<0,1mA, lh=10...50mA	31a	DO-7		-
1 N 5786	Mot	Trigger-Di	=1N5158: Ub=12...14V, Ib<0,1mA, lh=10...50mA	31a	DO-7		-
1 N 5787	Mot	Trigger-Di	=1N5158: Ub=13...15V, Ib<0,1mA, lh=10...50mA	31a	DO-7		-
1 N 5788	Mot	Trigger-Di	=1N5158: Ub=8...10V, Ib<0,1mA, lh=0,1...2mA	31a	DO-7		-
1 N 5789	Mot	Trigger-Di	=1N5158: Ub=9...11V, Ib<0,1mA, lh=0,1...2mA	31a	DO-7		-
1 N 5790	Mot	Trigger-Di	=1N5158: Ub=10...12V, Ib<0,1mA, lh=0,1...2mA	31a	DO-7		-
1 N 5791	Mot	Trigger-Di	=1N5158: Ub=11...13V, Ib<0,1mA, lh=0,1...2mA	31a	DO-7		-
1 N 5792	Mot	Trigger-Di	=1N5158: Ub=12...14V, Ib<0,1mA, lh=0,1...2mA	31a	DO-7		-
1 N 5793	Mot	Trigger-Di	=1N5158: Ub=13...15V, Ib<0,1mA, lh=0,1...2mA	31a	DO-7		-
1 N 5794	Fch	Si-Di	Rr, 50V, 1A, Uf<0,98V(1A, 75°)	31a	SOD-51		BY 126...127, BY 133...135, 1N4001...07, ++
1 N 5795		Si-Di	=1N5794: 100V	31a	SOD-51		BY 126...127, BY 133...135, 1N4002...07, ++
1 N 5796		Si-Di	=1N5794: 200V	31a	SOD-51		BY 126...127, BY 133...134, 1N4003...07, ++
1 N 5797		Si-Di	=1N5794: 400V	31a	SOD-51		BY 126...127, BY 133...134, 1N4004...07, ++
1 N 5798		Si-Di	=1N5794: 600V	31a	SOD-51		BY 126...127, BY 133...134, 1N4005...07, ++
1 N 5799		Si-Di	=1N5794: 800V	31a	SOD-51		BY 127, BY 133, BY 227, 1N4006...07, ++
1 N 5800		Si-Di	=1N5794: 1000V	31a	SOD-51		BY 127, BY 133, BY 227, 1N4007, ++
1 N 5802	USA,Gie	Si-Di	FRr, 50V, 2,5A, Uf<0,875V(1A), <25ns	31a	SOD-17	BYV 28/200	31a BYV 28/50, EGP 30A, FE 3A
1 N 5803		Si-Di	=1N5802: 75V	31a	SOD-17	BYV 28/200	31a BYV 28/100, EGP 30B, FE 3B
1 N 5804		Si-Di	=1N5802: 100V	31a	SOD-17	BYV 28/200	31a BYV 28/100, EGP 30B, FE 3B
1 N 5805		Si-Di	=1N5802: 125V	31a	SOD-17	BYV 28/200	31a BYV 28/150, EGP 30C, FE 3C
1 N 5806		Si-Di	=1N5802: 150V	31a	SOD-17	BYV 28/200	31a BYV 28/150, EGP 30C, FE 3C
1 N 5807	USA,Gie	Si-Di	FRr, 50V, 6A, Uf<0,875V(4A), <30ns	31a	SOD-51		BYV 61...63, FE 6A
1 N 5808		Si-Di	=1N5807: 75V	31a	SOD-51		BYV 62...63, FE 6B
1 N 5809		Si-Di	=1N5807: 100V	31a	SOD-51		BYV 62...63, FE 6B
1 N 5810		Si-Di	=1N5807: 125V	31a	SOD-51		BYV 63, FE 6C
1 N 5811		Si-Di	=1N5807: 150V	31a	SOD-51		BYV 63, FE 6C
1 N 5812	USA,Gie	Si-Di	P FRr, 50V, 20A, Uf<0,9V(10A), <25ns	32a	DO-4		BYW 77/50
1 N 5813		Si-Di	=1N5812: 75V	32a	DO-4		BYW 77/100
1 N 5814		Si-Di	=1N5812: 100V	32a	DO-4		BYW 77/100
1 N 5815		Si-Di	=1N5812: 125V	32a	DO-4		BYW 77/150
1 N 5816		Si-Di	=1N5812: 150V	32a	DO-4		BYW 77/150
1 N 5817	Gie,Mot,Phi Itt,Tho	Si-Di	Schottky Rr, 20V, 1A, Uf<0,45V(1A)	31a	DO-15	1N5822	31 BYS 21, BYV 10-20, SB 120
1 N 5818		Si-Di	=1N5817: 30V, Uf<0,55V(1A)	31a	DO-15, -41	1N5822	31a BYS 21, BYV 10-30, SB 130
1 N 5819		Si-Di	=1N5817: 40V, Uf<0,6V(1A)	31a	DO-15, -41	1N5822	31a BYS 21, BYV 10-40, SB 140

Original	Fabric.	Constr.	Info	{Compl. Fig.	JAEGER	Fig.	International	
1 N 5820	Gie,Mot	Si-Di	Schottky Rr, 20V, 3A, Uf<0,475V(3A)	31a	DO-27A	1N5822	31a	BYS 26, MBR 320, SB 320
1 N 5821		Si-Di	=1N5820: 30V, Uf<0,5V(3A)	31a	DO-27A	1N5822	31a	BYS 26, MBR 330, SB 330
1 N 5822	Gie,Mot	Si-Di	=1N5820: 40V, Uf<0,525V(3A)	31a	DO-27A	1N5822	31a	BYS 26, MBR 340, SB 340, HRP 24
1 N 5823	Mot	Si-Di	Schottky Rr, 20V, 5A, Uf<0,47V(15,7A)	34a	DO-1	BYS 27-45	31a	BYS 08, SB 520
1 N 5824		Si-Di	=1N5823: 30V, Uf<0,49V(15,7A)	34a	DO-1	BAS 27-45	31a	BYS 08, SB 530
1 N 5825		Si-Di	=1N5823: 40V, Uf<0,52(15,7A)	34a	DO-1	BYS 27-45	31a	BYS 08, SB 540
1 N 5826	Mot	Si-Di	Schottky P Rr, 20V, 15A(Tc=85°), Uf<0,44V(15A)	32a	DO-4			BYS 15, MBR 1520
1 N 5827		Si-Di	=1N5826: 30V, Uf<0,47V(15A)	32a	DO-4			BYS 15, MBR 1530
1 N 5828		Si-Di	=1N5826: 40V, Uf<0,5V(15A)	32a	DO-4			BYS 15, MBR 1540
1 N 5829	Mot	Si-Di	Schottky P Rr, 20V, 25A(Tc=85°), Uf<0,44V(25A)	32a	DO-4			BYS 30...32, BYS 35/20, MBR 2520
1 N 5830		Si-Di	=1N5829: 30V, Uf<0,46(25A)	32a	DO-4			BYS 30...32, BYS 35/30, MBR 2530
1 N 5831		Si-Di	=1N5829: 40V, Uf<0,48V(25A)	32a	DO-4			BYS 30...32, BYS 35/40, MBR 2540
1 N 5832	Mot	Si-Di	Schottky P Rr, 20V, 40A(Tc=75°), Uf<0,52(40A)	32a	DO-5			BYS 50...51, BYS 60/20, MBR 4020
1 N 5833		Si-Di	=1N5832: 30V, Uf<0,55V(40A)	32a	DO-5			BYS 50...51, BYS 60/30, MBR 4030
1 N 5834		Si-Di	=1N5832: 40V, Uf<0,59V(40A)	32a	DO-5			BYS 50...51, BYS 60/40, MBR 4040
1 N 5835	Cri	Si-Di	FRr, 30V, 3A, Uf<0,9V(3A), <100ns	31a	SOD-57	BYV 28/200	31a	BYV 28/50, EGP 30A, FE 3A
1 N 5836		Si-Di	=1N5835: 50V	31a	SOD-57	BYV 28/200	31a	BYV 28/50, EGP 30A, FE 3A
1 N 5837	Fer,Mot,Spr	Z-Di	2,4V, 20%, 0,5W	7d	TO-92	Z-Diode 2,4V	31a	BZX55/..., BZX83/..., ZPD..., 1N5221...81,++
1 N 5838		Z-Di	=1N5837: 2,5V	7d	TO-92	Z-Diode 2,4V	31a	
1 N 5839		Z-Di	=1N5837: 2,7V	7d	TO-92	Z-Diode 2,7V	31a	
1 N 5840		Z-Di	=1N5837: 2,8V	7d	TO-92	Z-Diode 2,7V	31a	
1 N 5841		Z-Di	=1N5837: 3V	7d	TO-92	Z-Diode 3V	31a	
1 N 5842		Z-Di	=1N5837: 3,3V	7d	TO-92	Z-Diode 3,3V	31a	
1 N 5843		Z-Di	=1N5837: 3,6V	7d	TO-92	Z-Diode 3,6V	31a	
1 N 5844		Z-Di	=1N5837: 3,9V	7d	TO-92	Z-Diode 3,9V	31a	
1 N 5845		Z-Di	=1N5837: 4,3V	7d	TO-92	Z-Diode 4,3V	31a	
1 N 5846		Z-Di	=1N5837: 4,7V	7d	TO-92	Z-Diode 4,7V	31a	
1 N 5847		Z-Di	=1N5837: 5,1V	7d	TO-92	Z-Diode 5,1V	31a	
1 N 5848		Z-Di	=1N5837: 5,6V	7d	TO-92	Z-Diode 5,6V	31a	
1 N 5849		Z-Di	=1N5837: 6V	7d	TO-92	Z-Diode 6,2V	31a	
1 N 5850		Z-Di	=1N5837: 6,2V	7d	TO-92	Z-Diode 6,2V	31a	
1 N 5851		Z-Di	=1N5837: 6,8V	7d	TO-92	Z-Diode 6,8V	31a	
1 N 5852		Z-Di	=1N5837: 7,5V	7d	TO-92	Z-Diode 7,5V	31a	
1 N 5853		Z-Di	=1N5837: 8,2V	7d	TO-92	Z-Diode 8,2V	31a	
1 N 5854		Z-Di	=1N5837: 8,7V	7d	TO-92	Z-Diode 9,1V	31a	
1 N 5855		Z-Di	=1N5837: 9,1V	7d	TO-92	Z-Diode 9,1V	31a	
1 N 5856		Z-Di	=1N5837: 10V	7d	TO-92	Z-Diode 10V	31a	
1 N 5857		Z-Di	=1N5837: 11V	7d	TO-92	Z-Diode 11V	31a	
1 N 5858		Z-Di	=1N5837: 12V	7d	TO-92	Z-Diode 12V	31a	
1 N 5859		Z-Di	=1N5837: 13V	7d	TO-92	Z-Diode 13V	31a	
1 N 5860		Z-Di	=1N5837: 14V	7d	TO-92	Z-Diode 15V	31a	
1 N 5861		Z-Di	=1N5837: 15V	7d	TO-92	Z-Diode 15V	31a	
1 N 5862		Z-Di	=1N5837: 16V	7d	TO-92	Z-Diode 16V	31a	
1 N 5863		Z-Di	=1N5837: 17V	7d	TO-92	Z-Diode 18V	31a	
1 N 5864		Z-Di	=1N5837: 18V	7d	TO-92	Z-Diode 18V	31a	
1 N 5865		Z-Di	=1N5837: 19V	7d	TO-92	Z-Diode 20V	31a	
1 N 5866		Z-Di	=1N5837: 20V	7d	TO-92	Z-Diode 20V	31a	
1 N 5867		Z-Di	=1N5837: 22V	7d	TO-92	Z-Diode 22V	31a	
1 N 5868		Z-Di	=1N5837: 24V	7d	TO-92	Z-Diode 24V	31a	
1 N 5869		Z-Di	=1N5837: 25V	7d	TO-92	Z-Diode 24V	31a	
1 N 5870		Z-Di	=1N5837: 27V	7d	TO-92	Z-Diode 27V	31a	
1 N 5871		Z-Di	=1N5837: 28V	7d	TO-92	Z-Diode 27V	31a	
1 N 5872		Z-Di	=1N5837: 30V	7d	TO-92	Z-Diode 30V	31a	
1 N 5873		Z-Di	=1N5837: 33V	7d	TO-92	Z-Diode 33V	31a	
1 N 5874		Z-Di	=1N5837: 36V	7d	TO-92	Z-Diode 36V	31a	
1 N 5875		Z-Di	=1N5837: 39V	7d	TO-92	Z-Diode 39V	31a	
1 N 5876		Z-Di	=1N5837: 43V	7d	TO-92	Z-Diode 43V	31a	
1 N 5877		Z-Di	=1N5837: 47V	7d	TO-92	Z-Diode 47V	31a	
1 N 5878		Z-Di	=1N5837: 51V	7d	TO-92	Z-Diode 51V	31a	
1 N 5879		Z-Di	=1N5837: 56V	7d	TO-92	Z-Diode 56V	31a	
1 N 5880		Z-Di	=1N5837: 60V	7d	TO-92	Z-Diode 62V	31a	
1 N 5881		Z-Di	=1N5837: 62V	7d	TO-92	Z-Diode 62V	31a	
1 N 5882		Z-Di	=1N5837: 68V	7d	TO-92	Z-Diode 68V	31a	
1 N 5883		Z-Di	=1N5837: 75V	7d	TO-92	Z-Diode 75V	31a	
1 N 5884		Z-Di	=1N5837: 82V	7d	TO-92	Z-Diode 82V	31a	
1 N 5885		Z-Di	=1N5837: 87V	7d	TO-92	Z-Diode 91V	31a	
1 N 5886		Z-Di	=1N5837: 91V	7d	TO-92	Z-Diode 91V	31a	
1 N 5887		Z-Di	=1N5837: 100V	7d	TO-92	Z-Diode 100V	31a	
1 N 5888		Z-Di	=1N5837: 110V	7d	TO-92	Z-Diode 110V	31a	
1 N 5889		Z-Di	=1N5837: 120V	7d	TO-92	Z-Diode 120V	31a	
1 N 5890		Z-Di	=1N5837: 130V	7d	TO-92	Z-Diode 130V	31a	
1 N 5891		Z-Di	=1N5837: 140V	7d	TO-92	Z-Diode 150V	31a	
1 N 5892		Z-Di	=1N5837: 150V	7d	TO-92	Z-Diode 150V	31a	
1 N 5893		Z-Di	=1N5837: 160V	7d	TO-92	Z-Diode 160V	31a	
1 N 5894		Z-Di	=1N5837: 170V	7d	TO-92	Z-Diode 180V	31a	
1 N 5895		Z-Di	=1N5837: 180V	7d	TO-92	Z-Diode 180V	31a	
1 N 5896		Z-Di	=1N5837: 190V	7d	TO-92	Z-Diode 200V	31a	
1 N 5897		Z-Di	=1N5837: 200V	7d	TO-92	Z-Diode 200V	31a	
1 N 5837A...5897A		Z-Di	=1N5837...5897: 10%	7d	TO-92			
1 N 5837B...5897B		Z-Di	=1N5837...5897: 5%	7d	TO-92			
1 N 5837C...5897C		Z-Di	=1N5837...5897: 2%	7d	TO-92			
1 N 5837D...5897D		Z-Di	=1N5837...5897: 1%	7d	TO-92			
1 N 5898	Gie	Si-Di	FRr, 50V, 3A, Uf<1V(3A), <5µs					BY 251...255, BYW 17/100, 1N5400...08, ++
1 N 5899		Si-Di	=1N5898: 100V					BY 251...255, BYW 17/100, 1N5401...08, ++
1 N 5900		Si-Di	=1N5898: 200V					BY 251...255, BYW 17/200, 1N5402...08, ++
1 N 5901		Si-Di	=1N5898: 400V					BY 252...255, BYW 17/400, 1N5404...08, ++
1 N 5902		Si-Di	=1N5898: 600V					BY 253...255, BYW 17/600, 1N5406...08, ++
1 N 5903		Si-Di	=1N5898: 800V					BY 254...255, BYW 17/800, 1N5407...08, ++
1 N 5904		Si-Di	=1N5898: 1000V					BY 255, BYW 17/1000, 1N5408, ++
1 N 5905		Si-Di	=1N5898: 1200V					BY 255, BY 438, BYW 17/1200
1 N 5906	Miv	Si-Di	UHF, Ku-Band Mx, 16GHz	Koax	DO-37			
1 N 5907	Scn,Sie,Tho	Z-Di	=1N5629: 6...7V	34a	DO-1			
1 N 5908		Z-Di	=1N5629: 6...7V	31a	DO-27			

Original	Fabric.	Constr.	Info	(Compl. Fig.	JAEGER	Fig.	International
1 N 5909...5912		Opto					
1 N 5913	USA,Mot.Sie	Z-Di	3,3V, 20%, 1,5W(Tc=75°)	31a	DO-41		BZW22/..., BZX61/..., ZPY..., BZY97/...
1 N 5914		Z-Di	=1N5913: 3,6V	31a	DO-41		
1 N 5915		Z-Di	=1N5913: 3,9V	31a	DO-41		
1 N 5916		Z-Di	=1N5913: 4,3V	31a	DO-41		
1 N 5917		Z-Di	=1N5913: 4,7V	31a	DO-41		
1 N 5918		Z-Di	=1N5913: 5,1V	31a	DO-41		
1 N 5919		Z-Di	=1N5913: 5,6V	31a	DO-41		
1 N 5920		Z-Di	=1N5913: 6,2V	31a	DO-41		
1 N 5921		Z-Di	=1N5913: 6,8V	31a	DO-41		
1 N 5922		Z-Di	=1N5913: 7,5V	31a	DO-41		
1 N 5923		Z-Di	=1N5913: 8,2V	31a	DO-41		
1 N 5924		Z-Di	=1N5913: 9,1V	31a	DO-41		
1 N 5925		Z-Di	=1N5913: 10V	31a	DO-41		
1 N 5926		Z-Di	=1N5913: 11V	31a	DO-41		
1 N 5927		Z-Di	=1N5913: 12V	31a	DO-41		
1 N 5928		Z-Di	=1N5913: 13V	31a	DO-41		
1 N 5929		Z-Di	=1N5913: 15V	31a	DO-41		
1 N 5930		Z-Di	=1N5913: 16V	31a	DO-41		
1 N 5931		Z-Di	=1N5913: 18V	31a	DO-41		
1 N 5932		Z-Di	=1N5913: 20V	31a	DO-41		
1 N 5933		Z-Di	=1N5913: 22V	31a	DO-41		
1 N 5934		Z-Di	=1N5913: 24V	31a	DO-41		
1 N 5935		Z-Di	=1N5913: 27V	31a	DO-41		
1 N 5936		Z-Di	=1N5913: 30V	31a	DO-41		
1 N 5937		Z-Di	=1N5913: 33V	31a	DO-41		
1 N 5938		Z-Di	=1N5913: 36V	31a	DO-41		
1 N 5939		Z-Di	=1N5913: 39V	31a	DO-41		
1 N 5940		Z-Di	=1N5913: 43V	31a	DO-41		
1 N 5941		Z-Di	=1N5913: 47V	31a	DO-41		
1 N 5942		Z-Di	=1N5913: 51V	31a	DO-41		
1 N 5943		Z-Di	=1N5913: 56V	31a	DO-41		
1 N 5944		Z-Di	=1N5913: 62V	31a	DO-41		
1 N 5945		Z-Di	=1N5913: 68V	31a	DO-41		
1 N 5946		Z-Di	=1N5913: 75V	31a	DO-41		
1 N 5947		Z-Di	=1N5913: 82V	31a	DO-41		
1 N 5948		Z-Di	=1N5913: 91V	31a	DO-41		
1 N 5949		Z-Di	=1N5913: 100V	31a	DO-41		
1 N 5950		Z-Di	=1N5913: 110V	31a	DO-41		
1 N 5951		Z-Di	=1N5913: 120V	31a	DO-41		
1 N 5952		Z-Di	=1N5913: 130V	31a	DO-41		
1 N 5953		Z-Di	=1N5913: 150V	31a	DO-41		
1 N 5954		Z-Di	=1N5913: 160V	31a	DO-41		
1 N 5955		Z-Di	=1N5913: 180V	31a	DO-41		
1 N 5956		Z-Di	=1N5913: 200V	31a	DO-41		
1 N 5913A...5956A		Z-Di	=1N5913...5956: 10%	31a	DO-41		
1 N 5913B...5956B		Z-Di	=1N5913...5956: 5%	31a	DO-41		
1 N 5913C...5956C		Z-Di	=1N5913...5956: 2%	31a	DO-41		
1 N 5913D...5956D		Z-Di	=1N5913...5956: 1%	31a	DO-41		
1 N 5957	Uni	PIN-Di	Ubr>100V, <0,4pF(50V), <3,5Ω	31a	SOD-17		
1 N 5985	USA,Mot.Sie	Z-Di	2,4V, 20%, 0,5W	31a	DO-35		BZX55/..., BZX83/..., ZPD..., 1N5221...81,...
1 N 5986		Z-Di	=1N5985: 2,7V	31a	DO-35		
1 N 5987		Z-Di	=1N5985: 3V	31a	DO-35		
1 N 5988		Z-Di	=1N5985: 3,3V	31a	DO-35		
1 N 5989		Z-Di	=1N5985: 3,6V	31a	DO-35		
1 N 5990		Z-Di	=1N5985: 3,9V	31a	DO-35		
1 N 5991		Z-Di	=1N5985: 4,3V	31a	DO-35		
1 N 5992		Z-Di	=1N5985: 4,7V	31a	DO-35		
1 N 5993		Z-Di	=1N5985: 5,1V	31a	DO-35		
1 N 5994		Z-Di	=1N5985: 5,6V	31a	DO-35		
1 N 5995		Z-Di	=1N5985: 6,2V	31a	DO-35		
1 N 5996		Z-Di	=1N5985: 6,8V	31a	DO-35		
1 N 5997		Z-Di	=1N5985: 7,5V	31a	DO-35		
1 N 5998		Z-Di	=1N5985: 8,2V	31a	DO-35		
1 N 5999		Z-Di	=1N5985: 9,1V	31a	DO-35		
1 N 6000		Z-Di	=1N5985: 10V	31a	DO-35		
1 N 6001		Z-Di	=1N5985: 11V	31a	DO-35		
1 N 6002		Z-Di	=1N5985: 12V	31a	DO-35		
1 N 6003		Z-Di	=1N5985: 13V	31a	DO-35		
1 N 6004		Z-Di	=1N5985: 15V	31a	DO-35		
1 N 6005		Z-Di	=1N5985: 16V	31a	DO-35		
1 N 6006		Z-Di	=1N5985: 18V	31a	DO-35		
1 N 6007		Z-Di	=1N5985: 20V	31a	DO-35		
1 N 6008		Z-Di	=1N5985: 22V	31a	DO-35		
1 N 6009		Z-Di	=1N5985: 24V	31a	DO-35		
1 N 6010		Z-Di	=1N5985: 27V	31a	DO-35		
1 N 6011		Z-Di	=1N5985: 30V	31a	DO-35		
1 N 6012		Z-Di	=1N5985: 33V	31a	DO-35		
1 N 6013		Z-Di	=1N5985: 36V	31a	DO-35		
1 N 6014		Z-Di	=1N5985: 39V	31a	DO-35		
1 N 6015		Z-Di	=1N5985: 43V	31a	DO-35		
1 N 6016		Z-Di	=1N5985: 47V	31a	DO-35		
1 N 6017		Z-Di	=1N5985: 51V	31a	DO-35		
1 N 6018		Z-Di	=1N5985: 56V	31a	DO-35		
1 N 6019		Z-Di	=1N5985: 62V	31a	DO-35		
1 N 6020		Z-Di	=1N5985: 68V	31a	DO-35		
1 N 6021		Z-Di	=1N5985: 75V	31a	DO-35		
1 N 6022		Z-Di	=1N5985: 82V	31a	DO-35		
1 N 6023		Z-Di	=1N5985: 91V	31a	DO-35		
1 N 6024		Z-Di	=1N5985: 100V	31a	DO-35		
1 N 6025		Z-Di	=1N5985: 110V	31a	DO-35		
1 N 6026		Z-Di	=1N5985: 120V	31a	DO-35		
1 N 6027		Z-Di	=1N5985: 130V	31a	DO-35		

Original	Fabric.	Constr.	Info	{Compl. Fig.	JAEGER	Fig.	International
1 N 6028		Z-Di	=1N5985: 150V	31a			
1 N 6029		Z-Di	=1N5985: 160V	31a			
1 N 6030		Z-Di	=1N5985: 180V	31a			
1 N 6031		Z-Di	=1N5985: 200V	31a			
1 N 5985A...6031A		Z-Di	=1N5985...6031: 10%	31a			
1 N 5985B...6031B		Z-Di	=1N5985...6031: 5%	31a			
1 N 5985C...6031C		Z-Di	=1N5985...6031: 2%	31a			
1 N 5985D...6031D		Z-Di	=1N5985...6031: 1%	31a			
1 N 6036(A)	USA,Tho	Z-Di	=1N5630: bidirectional/bi-polarity	34a			1N6138...6173
1 N 6037(A)		Z-Di	=1N5631: bidirectional/bi-polarity	34a			
1 N 6038(A)		Z-Di	=1N5632: bidirectional/bi-polarity	34a			
1 N 6039(A)		Z-Di	=1N5633: bidirectional/bi-polarity	34a			
1 N 6040(A)		Z-Di	=1N5634: bidirectional/bi-polarity	34a			
1 N 6041(A)		Z-Di	=1N5635: bidirectional/bi-polarity	34a			
1 N 6042(A)		Z-Di	=1N5636: bidirectional/bi-polarity	34a			
1 N 6043(A)		Z-Di	=1N5637: bidirectional/bi-polarity	34a			
1 N 6044(A)		Z-Di	=1N5638: bidirectional/bi-polarity	34a			
1 N 6045(A)		Z-Di	=1N5639: bidirectional/bi-polarity	34a			
1 N 6046(A)		Z-Di	=1N5640: bidirectional/bi-polarity	34a			
1 N 6047(A)		Z-Di	=1N5641: bidirectional/bi-polarity	34a			
1 N 6048(A)		Z-Di	=1N5642: bidirectional/bi-polarity	34a			
1 N 6049(A)		Z-Di	=1N5643: bidirectional/bi-polarity	34a			
1 N 6050(A)		Z-Di	=1N5644: bidirectional/bi-polarity	34a			
1 N 6051(A)		Z-Di	=1N5645: bidirectional/bi-polarity	34a			
1 N 6052(A)		Z-Di	=1N5646: bidirectional/bi-polarity	34a			
1 N 6053(A)		Z-Di	=1N5647: bidirectional/bi-polarity	34a			
1 N 6054(A)		Z-Di	=1N5648: bidirectional/bi-polarity	34a			
1 N 6055(A)		Z-Di	=1N5649: bidirectional/bi-polarity	34a			
1 N 6056(A)		Z-Di	=1N5650: bidirectional/bi-polarity	34a			
1 N 6057(A)		Z-Di	=1N5651: bidirectional/bi-polarity	34a			
1 N 6058(A)		Z-Di	=1N5652: bidirectional/bi-polarity	34a			
1 N 6059(A)		Z-Di	=1N5653: bidirectional/bi-polarity	34a			
1 N 6060(A)		Z-Di	=1N5654: bidirectional/bi-polarity	34a			
1 N 6061(A)		Z-Di	=1N5655: bidirectional/bi-polarity	34a			
1 N 6062(A)		Z-Di	=1N5656: bidirectional/bi-polarity	34a			
1 N 6063(A)		Z-Di	=1N5657: bidirectional/bi-polarity	34a			
1 N 6064(A)		Z-Di	=1N5658: bidirectional/bi-polarity	34a			
1 N 6065(A)		Z-Di	=1N5659: bidirectional/bi-polarity	34a			
1 N 6066(A)		Z-Di	=1N5660: bidirectional/bi-polarity	34a			
1 N 6067(A)		Z-Di	=1N5661: bidirectional/bi-polarity	34a			
1 N 6068(A)		Z-Di	=1N5662: bidirectional/bi-polarity	34a			
1 N 6069(A)		Z-Di	=1N5663: bidirectional/bi-polarity	34a			
1 N 6070(A)		Z-Di	=1N5664: bidirectional/bi-polarity	34a			
1 N 6071(A)		Z-Di	=1N5665: bidirectional/bi-polarity	34a			
1 N 6072(A)		Z-Di	=1N5665: 220V, bidirectional/bi-polarity	34a			
1 N 6073	Msc,Smt	Si-Di	FRr, 50V, 3A, Uf<2V(9.4A), 30ns	31a	BYV 28/200	31a	BYV 28/50, EGP 30A, FE 3A
1 N 6074		Si-Di	=1N6073: 100V	31a	BYV 28/200	31a	BYV 28/100, EGP 30B, FE 3B
1 N 6075		Si-Di	=1N6073: 150V	31a	BYV 28/200	31a	BYV 28/150, EGP 30C, FE 3C
1 N 6076	Msc,Smt	Si-Di	FRr, 50V, 6A, Uf<1,7V(18A), 30ns	31a			BYV 61...63, FE 6A
1 N 6077		Si-Di	=1N6076: 100V	31a			BYV 61...63, FE 6A
1 N 6078		Si-Di	=1N6076: 150V	31a			BYV 61...63, FE 6A
1 N 6079	Msc,Smt	Si-Di	FRr, 50V, 12A, Uf<1,5V(37A), 30ns	31a			-
1 N 6080		Si-Di	=1N 6079: 100V	31a			-
1 N 6081		Si-Di	=1N 6079: 150V	31a			-
1 N 6082	Ksw,Msc,Trw	Z-Di	4,3V, 20%, 0,4W	31a			BZX55/..., BZX79/..., ZPD..., 1N5229...40,++
1 N 6083		Z-Di	=1N6082: 4,7V	31a			
1 N 6084		Z-Di	=1N6082: 5,1V	31a			
1 N 6085		Z-Di	=1N6082: 5,6V	31a			
1 N 6086		Z-Di	=1N6082: 6,2V	31a			
1 N 6087		Z-Di	=1N6082: 6,8V	31a			
1 N 6088		Z-Di	=1N6082: 7,5V	31a			
1 N 6089		Z-Di	=1N6082: 8,2V	31a			
1 N 6090		Z-Di	=1N6082: 9,1V	31a			
1 N 6091		Z-Di	=1N6082: 10V	31a			
1 N 6082A...6091A		Z-Di	=1N6082...6091: 10%	31a			
1 N 6082B...6091B		Z-Di	=1N6082...6091: 5%	31a			
1 N 6082C...6091C		Z-Di	=1N6082...6091: 2%	31a			
1 N 6082D...6091D		Z-Di	=1N6082...6091: 1%	31a			
1 N 6095	USA,Inr,Mot	Si-Di	Schottky Rr, 30V, 25A(Tc=70°), Uf<0,86V(25A)	32a			BYS 30...32, BYV 121/35, MBR 2530
1 N 6096		Si-Di	=1N6095: 40V	32a			BYS 30...32, BYV 121/40, MBR 2540
1 N 6097	USA,Inr,Mot	Si-Di	Schottky Rr, 30V, 50A(Tc=70°), Uf<0,86V(50A)	32a			BYS 50...51, BYS 60/30, MBR 6030
1 N 6098		Si-Di	=1N6098: 40V	32a			BYS 50...51, BYS 60/40, MBR 6045
1 N 6099	Fch	Si-Di	=1N3595	31a			-1N3595
1 N 6100	Fch	Si-Di	7-Di Array, 65V, 0,35A, Uf<1V(0,1A), <15ns	14-FLP			-
1 N 6101		Si-Di	=1N6100:	14-DIP			-
1 N 6102(A)	USA,Gie,Tho	Z-Di	TAZ, bidirectional, 6,8V, 10%(A=5%), Pbr=500W(1ms)	31a			BZW 06/...B
1 N 6103(A)		Z-Di	=1N6102: 7,5V	31a			
1 N 6104(A)		Z-Di	=1N6102: 8,2V	31a			
1 N 6105(A)		Z-Di	=1N6102: 9,1V	31a			
1 N 6106(A)		Z-Di	=1N6102: 10V	31a			
1 N 6107(A)		Z-Di	=1N6102: 11V	31a			
1 N 6108(A)		Z-Di	=1N6102: 12V	31a			
1 N 6109(A)		Z-Di	=1N6102: 13V	31a			
1 N 6110(A)		Z-Di	=1N6102: 15V	31a			
1 N 6111(A)		Z-Di	=1N6102: 16V	31a			
1 N 6112(A)		Z-Di	=1N6102: 18V	31a			
1 N 6113(A)		Z-Di	=1N6102: 20V	31a			
1 N 6114(A)		Z-Di	=1N6102: 22V	31a			
1 N 6115(A)		Z-Di	=1N6102: 24V	31a			
1 N 6116(A)		Z-Di	=1N6102: 27V	31a			
1 N 6117(A)		Z-Di	=1N6102: 30V	31a			
1 N 6118(A)		Z-Di	=1N6102: 33V	31a			
1 N 6119(A)		Z-Di	=1N6102: 36V	31a			

Original	Fabric.	Constr.	Info	{Compl. Fig.	JAEGER	Fig.	International
1 N 6120(A)		Z-Di	=1N6102: 39V	31a		S0D-22	
1 N 6121(A)		Z-Di	=1N6102: 43V	31a		S0D-22	
1 N 6122(A)		Z-Di	=1N6102: 47V	31a		S0D-22	
1 N 6123(A)		Z-Di	=1N6102: 51V	31a		S0D-22	
1 N 6124(A)		Z-Di	=1N6102: 56V	31a		S0D-22	
1 N 6125(A)		Z-Di	=1N6102: 62V	31a		S0D-22	
1 N 6126(A)		Z-Di	=1N6102: 68V	31a		S0D-22	
1 N 6127(A)		Z-Di	=1N6102: 75V	31a		S0D-22	
1 N 6128(A)		Z-Di	=1N6102: 82V	31a		S0D-22	
1 N 6129(A)		Z-Di	=1N6102: 91V	31a		S0D-22	
1 N 6130(A)		Z-Di	=1N6102: 100V	31a		S0D-22	
1 N 6131(A)		Z-Di	=1N6102: 110V	31a		S0D-22	
1 N 6132(A)		Z-Di	=1N6102: 120V	31a		S0D-22	
1 N 6133(A)		Z-Di	=1N6102: 130V	31a		S0D-22	
1 N 6134(A)		Z-Di	=1N6102: 150V	31a		S0D-22	
1 N 6135(A)		Z-Di	=1N6102: 160V	31a		S0D-22	
1 N 6136(A)		Z-Di	=1N6102: 180V	31a		S0D-22	
1 N 6137(A)		Z-Di	=1N6102: 200V	31a		S0D-22	
1 N 6138(A)	USA,Tho	Z-Di	TAZ, bidirectional, 6,8V, 10%(A=5%), Pbr=1,5kW	31a		DO-15	1N6036...6072
1 N 6139(A)		Z-Di	=1N6138: 7.5V	31a		DO-15	
1 N 6140(A)		Z-Di	=1N6138: 8.2V	31a		DO-15	
1 N 6141(A)		Z-Di	=1N6138: 9,1V	31a		DO-15	
1 N 6142(A)		Z-Di	=1N6138: 10V	31a		DO-15	
1 N 6143(A)		Z-Di	=1N6138: 11V	31a		DO-15	
1 N 6144(A)		Z-Di	=1N6138: 12V	31a		DO-15	
1 N 6145(A)		Z-Di	=1N6138: 13V	31a		DO-15	
1 N 6146(A)		Z-Di	=1N6138: 15V	31a		DO-15	
1 N 6147(A)		Z-Di	=1N6138: 16V	31a		DO-15	
1 N 6148(A)		Z-Di	=1N6138: 18V	31a		DO-15	
1 N 6149(A)		Z-Di	=1N6138: 20V	31a		DO-15	
1 N 6150(A)		Z-Di	=1N6138: 22V	31a		DO-15	
1 N 6151(A)		Z-Di	=1N6138: 24V	31a		DO-15	
1 N 6152(A)		Z-Di	=1N6138: 27V	31a		DO-15	
1 N 6153(A)		Z-Di	=1N6138: 30V	31a		DO-15	
1 N 6154(A)		Z-Di	=1N6138: 33V	31a		DO-15	
1 N 6155(A)		Z-Di	=1N6138: 36V	31a		DO-15	
1 N 6156(A)		Z-Di	=1N6138: 39V	31a		DO-15	
1 N 6157(A)		Z-Di	=1N6138: 43V	31a		DO-15	
1 N 6158(A)		Z-Di	=1N6138: 47V	31a		DO-15	
1 N 6159(A)		Z-Di	=1N6138: 51V	31a		DO-15	
1 N 6160(A)		Z-Di	=1N6138: 56V	31a		DO-15	
1 N 6161(A)		Z-Di	=1N6138: 62V	31a		DO-15	
1 N 6162(A)		Z-Di	=1N6138: 68V	31a		DO-15	
1 N 6163(A)		Z-Di	=1N6138: 75V	31a		DO-15	
1 N 6164(A)		Z-Di	=1N6138: 82V	31a		DO-15	
1 N 6165(A)		Z-Di	=1N6138: 91V	31a		DO-15	
1 N 6166(A)		Z-Di	=1N6138: 100V	31a		DO-15	
1 N 6167(A)		Z-Di	=1N6138: 110V	31a		DO-15	
1 N 6168(A)		Z-Di	=1N6138: 120V	31a		DO-15	
1 N 6169(A)		Z-Di	=1N6138: 130V	31a		DO-15	
1 N 6170(A)		Z-Di	=1N6138: 150V	31a		DO-15	
1 N 6171(A)		Z-Di	=1N6138: 160V	31a		DO-15	
1 N 6172(A)		Z-Di	=1N6138: 180V	31a		DO-15	
1 N 6173(A)		Z-Di	=1N6138: 200V	31a		DO-15	
1 N 6262	Sie	Si-Di	P Rr, 200V, 85A(Tc=100°), Uf<1,25V(267A)	32a		DO-5	
1 N 6263	Hew,Itt,Tho	Si-Di	Schottky, VHF/UHF Dem, 60V, 15mA, <2,2pF(0V)	31a		DO-35	BAR 28, HSS 100, HSS 102
1 N 6267(A)	Gsi,Mot,Scn	Z-Di	=1N5629:	31a		DO-27	(1N6036...6072, 1N6138...6173)
1 N 6268(A)		Z-Di	=1N5630:	31a		DO-27	
1 N 6269(A)		Z-Di	=1N5631:	31a		DO-27	
1 N 6270(A)		Z-Di	=1N5632:	31a		DO-27	
1 N 6271(A)		Z-Di	=1N5633:	31a		DO-27	
1 N 6272(A)		Z-Di	=1N5634:	31a		DO-27	
1 N 6273(A)		Z-Di	=1N5635:	31a		DO-27	
1 N 6274(A)		Z-Di	=1N5636:	31a		DO-27	
1 N 6275(A)		Z-Di	=1N5637:	31a		DO-27	
1 N 6276(A)		Z-Di	=1N5638:	31a		DO-27	
1 N 6277(A)		Z-Di	=1N5639:	31a		DO-27	
1 N 6278(A)		Z-Di	=1N5640:	31a		DO-27	
1 N 6279(A)		Z-Di	=1N5641:	31a		DO-27	
1 N 6280(A)		Z-Di	=1N5642:	31a		DO-27	
1 N 6281(A)		Z-Di	=1N5643:	31a		DO-27	
1 N 6282(A)		Z-Di	=1N5644:	31a		DO-27	
1 N 6283(A)		Z-Di	=1N5645:	31a		DO-27	
1 N 6284(A)		Z-Di	=1N5646:	31a		DO-27	
1 N 6285(A)		Z-Di	=1N5647:	31a		DO-27	
1 N 6286(A)		Z-Di	=1N5648:	31a		DO-27	
1 N 6287(A)		Z-Di	=1N5649:	31a		DO-27	
1 N 6288(A)		Z-Di	=1N5650:	31a		DO-27	
1 N 6289(A)		Z-Di	=1N5651:	31a		DO-27	
1 N 6290(A)		Z-Di	=1N5652:	31a		DO-27	
1 N 6291(A)		Z-Di	=1N5653:	31a		DO-27	
1 N 6292(A)		Z-Di	=1N5654:	31a		DO-27	
1 N 6293(A)		Z-Di	=1N5655:	31a		DO-27	
1 N 6294(A)		Z-Di	=1N5656:	31a		DO-27	
1 N 6295(A)		Z-Di	=1N5657:	31a		DO-27	
1 N 6296(A)		Z-Di	=1N5658:	31a		DO-27	
1 N 6297(A)		Z-Di	=1N5659:	31a		DO-27	
1 N 6298(A)		Z-Di	=1N5660:	31a		DO-27	
1 N 6299(A)		Z-Di	=1N5661:	31a		DO-27	
1 N 6300(A)		Z-Di	=1N5662:	31a		DO-27	
1 N 6301(A)		Z-Di	=1N5663:	31a		DO-27	
1 N 6302(A)		Z-Di	=1N5664:	31a		DO-27	
1 N 6303(A)		Z-Di	=1N5665:	31a		DO-27	

Original	Fabric.	Constr.	Info	(Compl. Fig.	JAEGER	Fig.	International
1 N 6307	Hew	Si-Di	40V, Uf<1V(15mA), <2.5pF(0V)	31a		DO-35	-
1 N 6373	Mot	Z-Di	TAZ, 5V, 5W, Pbr=1,5kW	31a		DO-27	1N5629...49, 1N6267...6387
1 N 6374		Z-Di	=1N6373: 8V	31a		DO-27	
1 N 6375		Z-Di	=1N6373: 10V	31a		DO-27	
1 N 6376		Z-Di	=1N6373: 12V	31a		DO-27	
1 N 6377		Z-Di	=1N6373: 15V	31a		DO-27	
1 N 6378		Z-Di	=1N6373: 18V	31a		DO-27	
1 N 6379		Z-Di	=1N6373: 22V	31a		DO-27	
1 N 6380		Z-Di	=1N6373: 36V	31a		DO-27	
1 N 6381		Z-Di	=1N6373: 45V	31a		DO-27	
1 N 6382...6389		Z-Di	=1N6373...6381: bidirectional	31a		DO-27	1N6036...55, 1N6138...58
1 N 6478	Gie	Si-Di	SMD, Rr, 50V, 1A, Uf<1,1V(1A)	72a(5mm)	(MELF)		BYM 11-50, BYM 12-50
1 N 6479		Si-Di	=1M6478: 100V	72a(5mm)	(MELF)		BYM 11-100, BYM 12-100
1 N 6480		Si-Di	=1M6478: 200V	72a(5mm)	(MELF)		BYM 11-200, BYM 12-200
1 N 6481		Si-Di	=1M6478: 400V	72a(5mm)	(MELF)		BYM 11-400, BYM 12-400
1 N 6482		Si-Di	=1M6478: 600V	72a(5mm)	(MELF)		BYM 11-600, BYM 12-600
1 N 6483		Si-Di	=1M6478: 800V	72a(5mm)	(MELF)		BYM 11-800, BYM 12-800
1 N 6484		Si-Di	=1M6478: 1000V	72a(5mm)	(MELF)		BYM 11-1000, BYM 12-1000
1 N 6496	Fch	Si-Di	16x Di Array, 60V, Uf<1,5V(0,5A), <10ns	20Pin	(Ceramic)		-
1NA....1R							
1 O		Si-N	=2SD2359 (SMD-Marking)	39		SOT-89	-2SD2359
1 OP		N-FET	=2SK198-P (SMD-Marking)	35		SOT-23	-2SK198
1 OP		N-FET	=2SK662-P (SMD-Marking)	35(2mm)		SOT-323	-2SK662
1 OQ		N-FET	=2SK198-Q (SMD-Marking)	35		SOT-23	-2SK198
1 OQ		N-FET	=2SK662-Q (SMD-Marking)	35(2mm)		SOT-323	-2SK662
1 OR		N-FET	=2SK198-R (SMD-Marking)	35		SOT-23	-2SK198
1 OR		N-FET	=2SK662-R (SMD-Marking)	35(2mm)		SOT-323	-2SK662
1 P		Si-N	=FMMT 2222A (SMD-Marking)	35		SOT-23	-FMMT 2222A
1 P		Si-N	=MMBT 2222A (SMD-Marking)	35		SOT-23	-MMBT 2222A
1 P 137		Si-P+R	=RT 1P137L (SMD-Marking)	7(9mm)		TO-92L	-RT 1P137L
1 P 643	Itt	Si-Di	Frr, 50V, 1A, Uf<1,5V(1A)	31a		DO-15	BYD 33 M 31a BY 201/2, BYX 55/350, RGP 10A, ++
1 P 644		Si-Di	=1P643: 100V	31a		DO-15	BYD 33 M 31a BY 201/2, BYX 55/350, RGP 10B, ++
1 P 645		Si-Di	=1P643: 225V	31a		DO-15	BYD 33 M 31a BY 201/3, BYX 55/350, RGP 10G, ++
1 P 646		Si-Di	=1P643: 300V	31a		DO-15	BYD 33 M 31a BY 201/3, BYX 55/350, RGP 10G, ++
1 P 647		Si-Di	=1P643: 400V	31a		DO-15	BYD 33 M 31a BY 201/4, BYX 55/600, RGP 10G, ++
1 P 649		Si-Di	=1P643: 600V	31a		DO-15	BYD 33 M 31a BY 201/6, BYX 55/600, RGP 10J, ++
1 P 664		Si-Di	=BY 201/12	31a		1N4007	31a -BY 201/12
1 PS 181	Phi	Si-Di	=1PS193: Dual	35n		SOT-23	-
1 PS 184	Phi	Si-Di	=1PS193: Dual	35f		SOT-23	-
1 PS 193	Phi	Si-Di	SMD, SS, 80/85V, 0,215/0,5A, Uf<1,2V(0,1A), <4ns	35p		SOT-23	-
1 PS 226	Phi	Si-Di	=1PS193: Dual	35t		SOT-23	-
1 Q		Si-N	=MMBT 5088 (SMD-Marking)	35		SOT-23	-MMBT 5088
1 R		Si-N	=2SC4929 (SMD-Marking)	39		SOT-89	-2SC4929
1 R		Si-N	=MMBT 5089 (SMD-Marking)	35		SOT-23	-MMBT 5089
1 RM 40	Tho	Si-Di	kV-Rr, 4kV, 0,5A, Uf<8V(1A)				-
1 RM 80		Si-Di	=1RM40: 8kV, Uf<18V(1A)				-
1 RM 150		Si-Di	=1RM40: 15kV, Uf<28V(1A)				-
1 RM 250		Si-Di	=1RM40: 25kV, Uf<50V(1A)				-
1 RQ		Si-P	=2SB1585-Q (SMD-Marking)	-35		(T Mini)	-2SB1585
1 RQ		Si-P	=2SB970-Q (SMD-Marking)	35		SOT-23	-2SB970
1 RR		Si-P	=2SB1585-R (SMD-Marking)	-35		(T Mini)	-2SB1585
1 RR		Si-P	=2SB970-R (SMD-Marking)	35		SOT-23	-2SB970
1 RS		Si-P	=2SB1585-S (SMD-Marking)	-35		(T Mini)	-2SB1585
1 RS		Si-P	=2SB970-S (SMD-Marking)	35		SOT-23	-2SB970
1S							
1 S		Si-N	=2SD2413 (SMD-Marking)	39		SOT-89	-2SD2413
1 S 11	Mat	Ge-Di	Dem, 60V, 50mA	31a		SOD-6	AA 113, 1N34, 1N60
1 S 12	Mat	Ge-Di	Dem, 22,5V, 50mA	31a		SOD-6	AA 112...114, 1N34, 1N54, 1N60, ++
1 S 13	Mat	Ge-Di	Dem, 45V, 35mA	31a		SOD-6	AA 113, 1N34, 1N54, 1N60
1 S 14	Mat	Ge-Di	Dem, 45V, 35mA	31a		SOD-6	AA 113, 1N34, 1N54, 1N60
1 S 15	Mat	Ge-Di	Dem, 45V, 35mA	31a		SOD-6	AA 113, 1N34, 1N54, 1N60
1 S 16	Mat	Ge-Di	Dem, 45V, 35mA	31a		SOD-6	AA 113, 1N34, 1N54, 1N60
1 S 17	Mat	Ge-Di	Uni, 115V, 50mA	31a		SOD-6	AA 117...118, AA 132...133
1 S 18	Mat	Ge-Di	Uni, 115V, 50mA	31a		SOD-6	AA 117...118, AA 132...133
1 S 19	Mat	Ge-Di	Dem, 15V, 35mA	31a		SOD-6	AA 112...114, 1N34, 1N54, 1N60, ++
1 S 020	Tix	Si-Di	Rr, 100V, 1,5A	34a		DO-1	BY 251...255, BY 226...227, 1N5392...99, ++
1 S 20	Tos	Ge-Di	S, 30V, <500ns	31a		DO-7	AA 27...28, 1N276
1 S 021	Tix	Si-Di	=1S020: 200V	34a		DO-1	BY 251...255, BY 226...227, 1N5393...99, ++
1 S 21	Tos	Ge-Di	Dual Rr, 380V, 0,3A				-
1 S 22	Tos	Ge-Di	Rr, 380V, 0,3A				-
1 S 023	Tix	Si-Di	=1S020: 400V	34a		DO-1	BY 252...255, BY 226...227, 1N5395...99, ++
1 S 23	Tos	Ge-Di	=1S22: 300V				-
1 S 24	Tos	Ge-Di	=1S22: 200V				-
1 S 025	Tix	Si-Di	=1S020: 600V	34a		DO-1	BY 253...255, BY 226...227, 1N5397...99, ++
1 S 25	Tos	Ge-Di	=1S22: 100V				-
1 S 26	Njr	Ge-Di	Rr P, 100V, 3,5A	-34a			-
1 S 027	Tix	Si-Di	=1S020: 800V	34a		DO-1	BY 254...255, BY 227, 1N5398...99, ++
1 S 27	Njr	Ge-Di	Rr P, 70V, 10A				-
1 S 28	Njr	Ge-Di	Rr P, 50V, 0,5A	-34a			-
1 S 29	Njr	Ge-Di	=1S28: 150V	-34a			-
1 S 30	Njr	Ge-Di	=1S28: 250V	-34a			-
1 S 31	Njr	Ge-Di	=1S28: 300V	-34a			-
1 S 32	Tos	Ge-Di	Uni, 75V, 30mA	31a		DO-7	AA 133 31a AA 117...118, AA 132...133, 1N634
1 S 33	Tos	Ge-Di	Uni, 120V, 30mA	31a		DO-7	AA 133 31a AA 132...133, 1N634
1 S 34	Tos	Ge-Di	Uni, 75V, 30mA	31a		DO-7	AA 133 31a AA 117...118, AA 132...133, 1N634
1 S 35	Tos	Ge-Di	4x Di, Ringmodulator, 30V, 0,12A				-
1 S 36	Mat	Si-Di	Rr, Uni, 200V, 0,5A, Uf<1,3V(0,5A)	-34a			BY 126...127, BY 133...134, 1N4003...07, ++
1 S 37		Si-Di	=1S36: 400V	-34a			BY 126...127, BY 133...134, 1N4004...07, ++
1 S 38		Si-Di	=1S36: 700V	-34a			BY 127, BY 133, BY 227, 1N4006...07, ++
1 S 39		Si-Di	=1S36: 800V, 0,4A	-34a			BY 127, BY 133, BY 227, 1N4006...07, ++
1 S 40	Fui	Si-Di	Rr, Uni, 100V, 0,75A, Uf<1,2V(1A)	34a		DO-1	BY 126...127, BY 133...135, 1N4002...07, ++